

## Multiprotocol wireless 32-bit MCU Arm®-based Cortex®-M33 with TrustZone®, FPU, Bluetooth® LE, IEEE802.15.4 radio solution

Datasheet - preliminary data

### Features

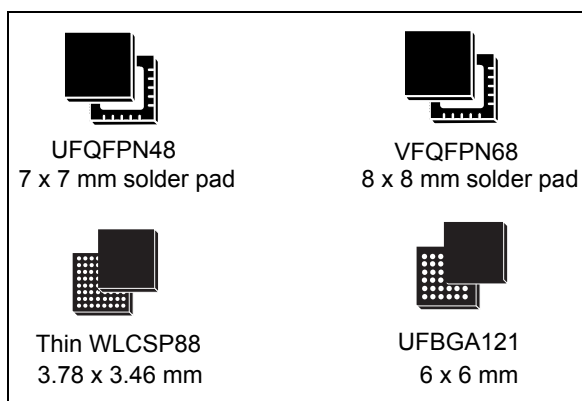
**Includes ST state-of-the-art patented technology**

#### Ultra-low-power radio

- 2.4 GHz radio
- RF transceiver supporting Bluetooth® LE, IEEE 802.15.4-2015 PHY and MAC, supporting Thread, Matter, and Zigbee®
- RX sensitivity: -96 dBm (Bluetooth® LE at 1 Mbps), -100 dBm (IEEE 802.15.4 at 250 kbps)
- Programmable output power up to +10 dBm, with 1 dB steps
- Support for external PA
- Packet traffic arbitration
- Integrated balun to reduce BOM
- Single crystal operation
- Suitable for systems requiring compliance with radio frequency regulations ETSI EN 300 328, EN 300 440, FCC CFR47 Part 15 and ARIB STD-T66

#### Bluetooth® LE

- LE 2M
- LE coded
- Direction finding
- LE power control
- Isochronous channels
- Extended advertising
- Periodic advertising
- LE secure connections
- LE audio
- Mesh networking
- Core specification v6.0



#### Ultra-low-power with FlexPowerControl

- 1.71 to 3.6 V power supply
- -40 to 85/105 °C ambient temperature range
- Autonomous peripherals with DMA, functional down to Stop 1 mode
- 120 nA Standby mode (16 wake-up pins)
- 1.33 µA Standby mode with RTC
- 1.15 µA Standby mode with 64-Kbyte SRAM
- 5.30 µA Stop 2 mode with 64-Kbyte SRAM
- 29 µA/MHz Run mode
- Radio: Rx 4.26 mA/Tx at 0 dBm 5.94 mA

#### Core

- Arm® 32-bit Cortex®-M33 CPU with TrustZone®, MPU, DSP, and FPU running at up to 100 MHz

#### ART Accelerator

- 8-Kbyte instruction cache allowing 0-wait-state execution from flash memory (frequency up to 100 MHz, 150 DMIPS)

#### Benchmarks

- 410 CoreMark® (4.10 CoreMark/MHz)

## Memories

- Up to 2-Mbyte dual bank flash memory with ECC, including 512 Kbytes with 100 Kcycles
- Up to 512-Kbyte SRAM, including 64 Kbytes with parity check
- 512-byte (32 rows) OTP

## Power management

- Embedded regulator LDO and SMPS step-down converter, supporting switch on-the-fly and voltage scaling

## Clock management

- 32 MHz crystal oscillator
- 32 kHz crystal oscillator (LSE)
- Internal low power 32 kHz ( $\pm 5\%$ ) RC
- Internal low frequency 32 kHz RC (500 ppm/ $^{\circ}\text{C}$ )
- Internal 16 MHz factory trimmed RC ( $\pm 1\%$ )
- PLL for system clock, audio, and ADC

## General-purpose input/output

- Up to 86 I/Os (most of them 5 V-tolerant) with interrupt capability, and up to 14 I/Os with independent supply down to 1.08 V

## Analog peripherals (independent supply)

- 12-bit ADC 2.5 Msps, up to 16-bit with hardware oversampling
- Two ultra-low-power comparators

## Communication peripherals

- One USB OTG high-speed with embedded PHY
- One SAI (serial audio interface)
- Four UARTs (ISO 7816, IrDA, modem)
- Three SPIs
- Four I2Cs FM+ (1 Mbit/s), SMBus/PMBus<sup>®</sup>

## System peripherals

- Touch sensing controller, up to 24 sensors, supporting touch key, linear, and rotary touch sensors
- One 16-bit, advanced motor control timer
- Three 16-bit timers and two 32-bit timers
- Two low power 16-bit timers (available in Stop mode)
- Two SysTick timers

- RTC with hardware calendar and calibration
- Two watchdogs
- 8-channel DMA controller, functional in Stop mode

## Security and cryptography

- Arm<sup>®</sup> TrustZone<sup>®</sup> and securable I/Os, memories, and peripherals
- Flexible life cycle scheme with read-out protection (RDP) and password protected debug
- Root of trust thanks to unique boot entry and secure hide protection area (HDP)
- Secure firmware installation (SFI), thanks to embedded root secure services (RSS)
- Secure data storage with hardware unique key (HUK)
- Secure firmware upgrade support with TF-M
- Two AES coprocessors, including one with DPA resistance
- Public key accelerator, DPA resistant
- HASH hardware accelerator
- True random number generator, NIST SP800-90B compliant
- 96-bit unique ID
- Active tamperers
- CRC calculation unit

## Development support

- Serial wire debug (SWD), JTAG
- Embedded trace (ETM)

## ECOPACK2 compliant packages

Table 1. Device summary

| Reference    | Part numbers   |
|--------------|--|
| STM32WBA62xx | STM32WBA62CG, STM32WBA62CI, STM32WBA62MG, STM32WBA62MI, STM32WBA62PG, STM32WBA62PI                             |
| STM32WBA63xx | STM32WBA63CG, STM32WBA63CI   |
| STM32WBA64xx | STM32WBA64CG, STM32WBA64CI   |
| STM32WBA65xx | STM32WBA65CG, STM32WBA65CI, STM32WBA65MG, STM32WBA65MI, STM32WBA65PG, STM32WBA65PI, STM32WBA65RG, STM32WBA65RI |

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# 1 Introduction

This document provides the ordering information and mechanical device characteristics of the STM32WBA6xxx microcontrollers, based on Arm® cores<sup>(a)</sup>. It must be read in conjunction with the reference manual (RM0515), available from the STMicroelectronics website [www.st.com](http://www.st.com).

For information on the device errata with respect to the datasheet and reference manual refer to the STM32WBA6xxx errata sheet (ES0644), available from the STMicroelectronics website [www.st.com](http://www.st.com).

For information on the Arm® Cortex®-M33 core, refer to the Cortex®-M33 Technical Reference Manual, available on the [www.arm.com](http://www.arm.com) website.

For information on 802.15.4, refer to the IEEE website ([www.ieee.org](http://www.ieee.org)).

For information on Bluetooth®, refer to [www.bluetooth.com](http://www.bluetooth.com).

arm

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## 2 Description

The STM32WBA6xxx multiprotocol wireless and ultra-low-power devices embed a powerful and ultra-low-power radio compliant with the Bluetooth® LE and with IEEE 802.15.4-2015. They contain a high-performance Arm® Cortex®-M33 32-bit RISC core, and operate at a frequency of up to 100 MHz.

The devices integrate a 2.4 GHz RADIO supporting Bluetooth® LE, Matter, Thread, and Zigbee®, and concurrent operation modes. They provide support for an array of up to eight antennas, and an external power amplifier. PTA (packet traffic arbitration) interface is supported as well.

The Cortex-M33 core features a single-precision floating-point unit (FPU), supporting all the Arm single-precision data-processing instructions and all the data types. This core implements a full set of DSP (digital signal processing) instructions and a memory protection unit (MPU) that enhances the application security.

The devices embed high-speed memories (up to 2-Mbyte flash, up to 512-Kbyte SRAM), an extensive range of enhanced I/Os, and peripherals connected to AHB and APB buses on the 32-bit multi-AHB bus matrix.

The security foundation is compliant with the TBSA (trusted-based security architecture) requirements from Arm. It embeds the features needed to implement secure boot, secure data storage, and secure firmware update. Besides these capabilities, the devices incorporate a secure firmware installation feature that allows the customer to secure the provisioning of the code during its production. A flexible life cycle is managed thanks to multiple levels readout protection and debug unlock with password.

Firmware hardware isolation is supported thanks to securable peripherals, memories and I/Os, and privilege configuration of peripherals and memories.

The devices feature protection mechanisms for embedded flash memory and SRAM: readout protection, write protection, secure, and hide protection areas.

Dedicated peripherals reinforce security: a fast AES coprocessor, a secure AES coprocessor with DPA resistance and hardware unique key that can be shared by hardware with fast AES, a PKA (public key accelerator) with DPA resistance, a HASH hardware accelerator, and a true random number generator.

The devices offer active tamper detection and protection against transient perturbation attacks, thanks to several internal monitoring generating secret data erase in case of attack. This helps to fit the PCI requirements for point of sales applications.

Hardware semaphores allow synchronization between software processes.

The devices offer one 12-bit ADC (2.5 Msps), up to two comparators, a low-power RTC, up to two 32-bit general-purpose timer, one 16-bit PWM timer for motor control, three 16-bit general-purpose timers, and two 16-bit low-power timers. They also feature standard and advanced communication interfaces, namely up to four I2Cs, up to three SPIs, one SAI, up to three USARTs, one low-power UART, and one USB OTG high-speed.

The devices operate in the -40 to 85 °C (105 °C junction) and -40 to 105 °C (125 °C junction) temperature ranges from a 1.71 to 3.6 V power supply.

The design of low-power applications is enabled by a comprehensive set of power-saving modes.

Many peripherals (including radio, communication, analog, and timer peripherals) can be functional and autonomous in Stop mode with direct memory access thanks to background autonomous mode (BAM) support.

Some independent power supplies are supported, like an analog independent supply input for ADC and comparators, USB OTG high-speed, 14 GPIOs and dedicated supply inputs for the 2.4 GHz RADIO.

The devices offer four packages, from 48 to 121 pins, with or without SMPS.

**Table 2. Device features and peripheral counts**

| Feature                                       |                           | STM32WBA62CI | STM32WBA62CG | STM32WBA63CI | STM32WBA63CG | STM32WBA64CI | STM32WBA64CG | STM32WBA65CI | STM32WBA65CG | STM32WBA65RI | STM32WBA65RG | STM32WBA62PI | STM32WBA62PG | STM32WBA65PI | STM32WBA65PG | STM32WBA62MI | STM32WBA62MG | STM32WBA65MI | STM32WBA65MG |  |
|---|---------------------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--|
| Flash memory density (Mbytes)                 |                           | 2            | 1            | 2            | 1            | 2            | 1            | 2            | 1            | 2            | 1            | 2            | 1            | 2            | 1            | 2            | 1            | 2            | 1            |  |
| SRAM density                                  | SRAM1 (Kbytes)            | 448          | 192          | 448          | 192          | 448          | 192          | 448          | 192          | 448          | 192          | 448          | 192          | 448          | 192          | 448          | 192          | 448          | 192          |  |
|   | SRAM2 (Kbytes)            | 64           |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |  |
| Bluetooth® LE                                 |                           | Yes          |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |  |
| IEEE802.15.4                                  |                           | No           | Yes          |              |              |              |              |              |              |              |              | No           | Yes          |              | No           | Yes          |              |              |              |  |
| SMPS  |                           | No           | Yes          |              | No           |              | Yes          |              |              | No           | Yes          |              | No           | Yes          |              |              |              |              |              |  |
| PTA   |                           | Yes          |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |  |
| External PA support                           |                           | No           | Yes          |              |              |              |              |              |              |              |              | No           | Yes          |              | No           | Yes          |              |              |              |  |
| BLE AoA, AoD support                          |                           | No           | Yes          |              |              |              |              |              |              |              |              | No           | Yes          |              | No           | Yes          |              |              |              |  |
| Timers  | Advanced control (16-bit) | 1            |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |  |
|   | General purpose (32-bit)  | 2            | 1            |              | 2            |              |              |              |              |              |              |              |              |              |              |              |              |              |              |  |
|   | General purpose (16-bit)  | 3            |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |  |
|   | Low power (16-bit)        | 2            |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |  |
|   | SysTick                   | 2            |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |  |
| Communication interfaces                      | SPI                       | 2            |              |              |              |              |              |              |              | 3            |              |              |              |              |              |              |              |              |              |  |
|   | I2C                       | 4            | 2            |              | 4            |              | 2            |              | 4            |              |              |              |              |              |              |              |              |              |              |  |
|   | USART                     | 3            | 2            |              | 3            |              |              |              |              |              |              |              |              |              |              |              |              |              |              |  |
|   | LPUART                    | 1            |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |  |
|   | SAI                       | 1            |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |  |
|   | USB OTG high-speed        | Yes          | No           |              | Yes          |              |              |              |              |              |              |              |              |              |              |              |              |              |              |  |
|   | IRTIM                     | No           | Yes          |              | No           |              |              |              |              | Yes          |              |              |              |              |              |              |              |              |              |  |
| RTC   |                           | Yes          |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |  |
| Tamper pins (active tamperers) <sup>(1)</sup> |                           | 4 (3)        |              | 5 (4)        |              | 4 (3)        |              |              |              |              | 6 (5)        |              |              |              |              |              |              |              |              |  |
| Wake-up pins                                  |                           | 11           |              | 14           |              | 11           |              | 10           |              | 14           |              | 16           |              |              |              |              |              |              |              |  |
| GPIOs   |                           | 34           |              | 31           |              | 34           |              | 30           |              | 46           |              | 86           |              |              |              | 54           |              |              |              |  |
| TSC (capacitive sensing channels)             |                           | 10           |              | 12           |              | 10           |              | 7            |              | 16           |              | 24           |              |              |              | 19           |              |              |              |  |
| 12-bit ADC4 (channels)                        |                           | 7            |              | 8            |              | 7            |              | 6            |              | 10           |              |              |              |              |              |              |              |              |              |  |
| Comparators                                   |                           | 1            |              | 2            |              | 1            |              |              |              | 2            |              |              |              |              |              |              |              |              |              |  |
| VREF  |                           | No           |              |              |              |              |              |              |              |              | Yes          |              |              |              |              |              |              |              |              |  |

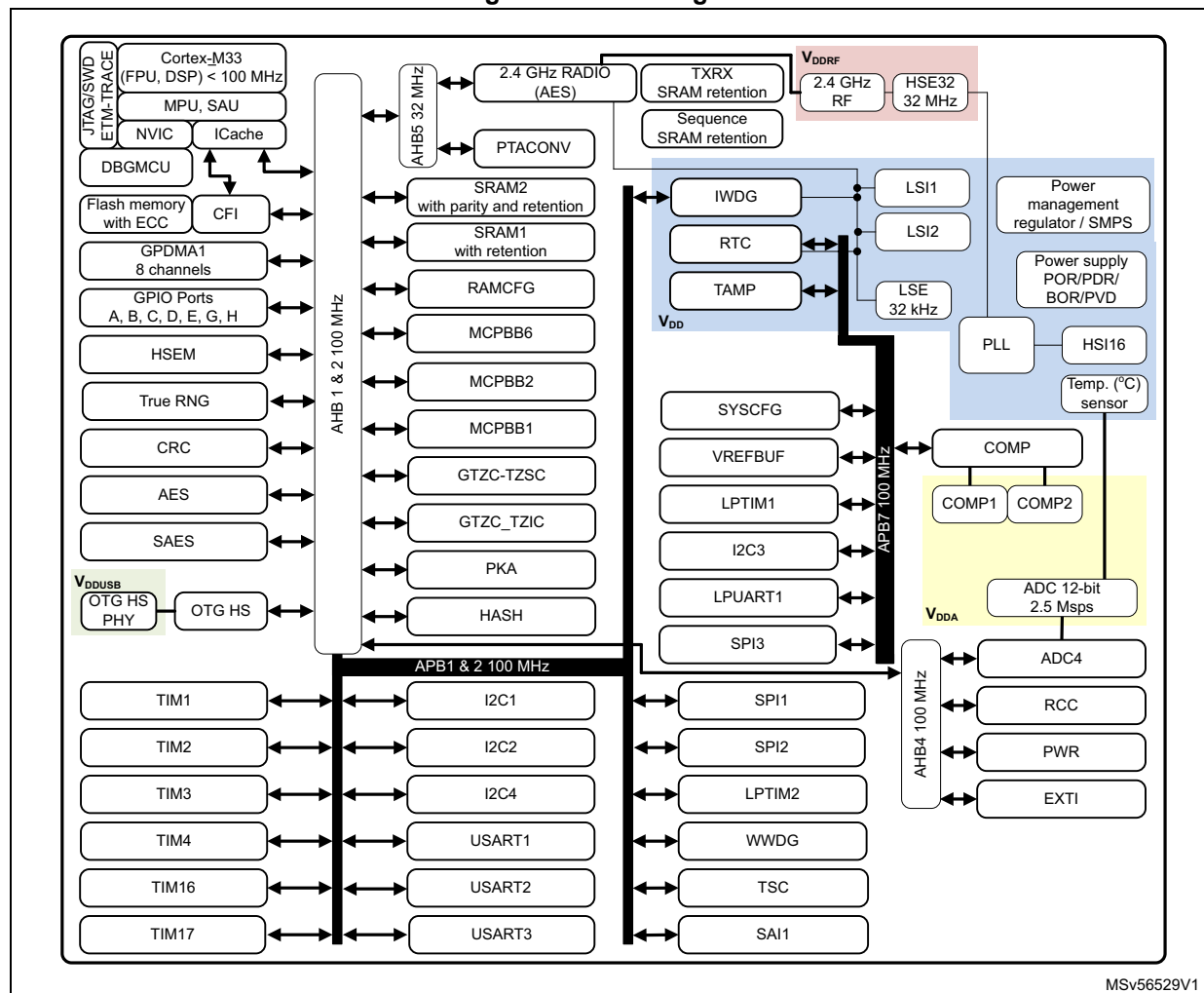
Table 2. Device features and peripheral counts (continued)

| Feature                      | STM32WBA62CI   | STM32WBA62CG | STM32WBA63CI | STM32WBA63CG | STM32WBA64CI | STM32WBA64CG | STM32WBA65CI | STM32WBA65CG | STM32WBA65RI | STM32WBA65RG | STM32WBA62PI | STM32WBA62PG | STM32WBA65PI | STM32WBA65PG | STM32WBA62MI | STM32WBA62MG | STM32WBA65MI | STM32WBA65MG |
|------------------------------|--|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|
| True random number generator | Yes  |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |
| SAES, AES                    | Yes  |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |
| Public key accelerator (PKA) | Yes  |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |
| HASH                         | Yes  |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |
| Debug ETM                    | No   |              |              |              |              |              |              |              | Yes          |              |              |              |              |              |              |              |              |              |
| Maximum CPU frequency        | 100 MHz  |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |
| Operating temperature        | Ambient: -40 to 85 °C / -40 to 105 °C<br>Junction: -40 to 105 °C / -40 to 125 °C |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |
| Operating voltage            | 1.71 to 3.6 V  |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |              |
| Package                      | UFQFPN48   |              |              |              |              |              |              |              | VFQ FPN68    |              | UFBGA121     |              |              |              | Thin WLCSP88 |              |              |              |

1. Active tamperers in output sharing mode (one output shared by all inputs).

Figure 1 shows the general block diagram of the devices.

Figure 1. Block diagram





## 3 Functional overview

### 3.1 Arm Cortex-M33 core with TrustZone, MPU, DSP, and FPU

The Cortex-M33 with TrustZone, MPU, DSP and FPU is a highly energy-efficient processor designed for microcontrollers and deeply embedded applications, especially those requiring efficient security.

The Cortex-M33 processor delivers a high computational performance with low-power consumption and an advanced response to interrupts. It features:

- Arm TrustZone technology, using the Armv8-M main extension supporting secure and nonsecure states
- MPUs (memory protection units), supporting up to 16 regions for secure and nonsecure applications
- Configurable SAU (secure attribute unit) supporting up to eight memory regions as secure or nonsecure
- Floating-point arithmetic functionality with support for single precision arithmetic

The processor supports a set of DSP instructions that allows an efficient signal processing and a complex algorithm execution.

The Cortex-M33 processor supports the following bus interfaces:

- System AHB (S-AHB) bus: used for any instruction fetch and data access to the memory-mapped SRAM, peripheral, and Vendor\_SYS regions of the Armv8-M memory map.
- Code AHB (C-AHB) bus: used for any instruction fetch and data access to the code region of the Armv8-M memory map.

### 3.2 ART Accelerator (ICACHE)

The ICACHE (instruction cache) is introduced on C-AHB code bus of Cortex-M33 processor to improve performance when fetching instruction (or data) from internal memories.

ICACHE offers the following features:

- Multibus interface:
  - Slave port receiving the memory requests from the Cortex-M33 C-AHB code execution port
  - Master1 port performing refill requests to internal flash memory
  - Master2 port performing refill requests to internal SRAM memories
  - Second slave port dedicated to ICACHE registers access

- Close to 0 wait-states instructions/data access performance:
  - 0 wait-states on cache hit
  - Hit-under-miss capability, allowing to serve new processor requests while a line refill (due to a previous cache miss) is still ongoing
  - Critical-word-first refill policy, minimizing processor stalls on cache miss
  - Hit ratio improved by two-ways set-associative architecture and pLRU-t replacement policy (pseudo-least-recently-used, based on binary tree), algorithm with best complexity/performance balance
  - Dual master ports to decouple internal flash memory and SRAM traffic, on fast and slow buses, respectively; also minimizing impact on interrupt latency
  - Optimal cache line refill thanks to AHB burst transactions (of the cache line size)
  - Performance monitoring by means of a hit counter and a miss counter
- Extension of cacheable region beyond the code memory space, by means of address remapping logic enabling the definition of four cacheable regions
- Power consumption reduced intrinsically (more accesses to cache memory rather to bigger main memories); even improved by configuring ICACHE as direct mapped (rather than the default two-ways set-associative mode)
- TrustZone security support
- Maintenance operation for software management of cache coherency
- Error management: detection of unexpected cacheable write access, with optional interrupt raising

### 3.3 Memory protection unit

The MPU is used to manage the CPU accesses to the memory and to prevent one task to accidentally corrupt the memory or the resources used by any other active task. This memory area is organized into up to 16 protected areas. The MPU regions and registers are banked across secure and nonsecure states.

The MPU is especially helpful for applications where some critical or certified code must be protected against the misbehavior of other tasks. It is usually managed by an RTOS (real-time operating system).

If a program accesses a memory location prohibited by the MPU, the RTOS can detect it and take action. In an RTOS environment, the kernel can dynamically update the MPU area setting based on the process to be executed.

The MPU is optional and can be bypassed for applications that do not need it.

### 3.4 Multi-AHB bus matrix

A 32-bit multi-AHB bus matrix interconnects all the masters (CPU, GPDMA1, USB OTG) and the slaves (flash memory, SRAMs, AHB, and APB) peripherals. It also ensures a seamless and efficient operation even when several peripherals work simultaneously.

## 3.5 Embedded flash memory

The devices feature an up to 2-Mbyte embedded flash memory, available to store programs and data. This memory supports 10000 cycles, and up to 100000 cycles on 64 pages (512 Kbytes).

A 128-bit instruction prefetch is implemented and can optionally be enabled.

The flash memory interface features dual-bank operation modes and read-while-write (RWW), hence a read operation to be performed from one bank while an erase or program operation is performed on the other bank. The dual-bank boot is also supported. Each bank contains up to 128 pages of 8 Kbytes. The flash memory also embeds a 512-byte one-time programmable (OTP) memory for user data.

The whole nonvolatile memory embeds the error correction code (ECC) feature supporting:

- single-error detection and correction
- double-error detection
- ECC fail address report

### 3.5.1 Flash memory protections

The user options allow the configuration of flexible protections:

- write protection (WRP) to protect areas against erasing and programming. Two areas per bank can be selected with 8-Kbyte granularity
- readout protection (RDP) to protect the whole memory, has four levels of protection available (see [Table 3](#) and [Table 4](#)):
  - Level 0: no readout protection
  - Level 0.5: available only when TrustZone is enabled  
All read/write operations (if no write protection is set) from/to the nonsecure flash memory are possible. The debug access to secure area is prohibited. Debug access to nonsecure area remains possible.
  - Level 1: memory readout protection  
The flash memory cannot be read from or written to if either the debug features are connected or the boot in RAM or bootloader are selected. If TrustZone is enabled, the nonsecure debug is possible and the boot in SRAM is not possible. Regressions from Level 1 to lower levels can be protected by password authentication.
  - Level 2: chip readout protection  
The debug features, the boot in RAM and the bootloader selection are disabled. A secure secret key can be configured in the secure options to allow the regression capability from Level 2 to Level 1. By default (key not configured), this Level 2 selection is irreversible and JTAG/SWD interfaces are disabled. If the secret key was previously configured in lower RDP levels, the device enables the RDP regression from Level 2 to Level 1 after password authentication through JTAG/SWD interface.

**Note:** *To reach the best protection level, it is recommended to activate TrustZone and to set RDP level 2 with password authentication regression enabled.*

**Table 3. Access status versus protection level and execution modes when TZEN = 0**

| Area                         | RDP level | User execution<br>(boot from flash memory) |                    |       | Debug/boot from RAM/ bootloader <sup>(1)</sup> |                    |                    |
|------------------------------|-----------|--|--------------------|-------|--|--------------------|--------------------|
|                              |           | Read                                       | Write              | Erase | Read   | Write              | Erase              |
| Flash main memory            | 1         | Yes  | Yes                | Yes   | No   | No                 | No <sup>(4)</sup>  |
|                              | 2         | Yes  | Yes                | Yes   | N/A  | N/A                | N/A                |
| System memory <sup>(2)</sup> | 1         | Yes  | No                 | No    | Yes  | No                 | No                 |
|                              | 2         | Yes  | No                 | No    | N/A  | N/A                | N/A                |
| Option bytes <sup>(3)</sup>  | 1         | Yes  | Yes <sup>(4)</sup> | N/A   | Yes  | Yes <sup>(4)</sup> | N/A                |
|                              | 2         | Yes  | No <sup>(5)</sup>  | N/A   | N/A  | N/A                | N/A                |
| OTP                          | 1         | Yes  | Yes <sup>(6)</sup> | N/A   | Yes  | Yes <sup>(6)</sup> | N/A                |
|                              | 2         | Yes  | Yes <sup>(6)</sup> | N/A   | N/A  | N/A                | N/A                |
| Backup registers             | 1         | Yes  | Yes                | N/A   | No   | No                 | N/A <sup>(7)</sup> |
|                              | 2         | Yes  | Yes                | N/A   | N/A  | N/A                | N/A                |
| SRAM2                        | 1         | Yes  | Yes                | N/A   | No   | No                 | N/A <sup>(8)</sup> |
|                              | 2         | Yes  | Yes                | N/A   | N/A  | N/A                | N/A                |

1. When the protection level 2 is active, the debug port, the boot from RAM, and the boot from system memory are disabled.
2. The system memory is only read-accessible, whatever the protection level (0, 1 or 2) and execution mode.
3. Option bytes are accessible only through the flash memory interface registers and OPSTRT bit.
4. The flash main memory is erased when the RDP option byte changes from level 1 to level 0.
5. SWAP\_BANK user option can be modified.
6. OTP can be written only once.
7. The backup registers are erased when RDP changes from level 1 to level 0.
8. All SRAMs are erased when RDP changes from level 1 to level 0.

**Table 4. Access status versus protection level and execution modes when TZEN = 1**

| Area                         | RDP level | User execution<br>(boot from flash memory) |                    |       | Debug/bootloader <sup>(1)</sup> |                    |                    |
|------------------------------|-----------|--|--------------------|-------|---------------------------------|--------------------|--------------------|
|                              |           | Read                                       | Write              | Erase | Read                            | Write              | Erase              |
| Flash main memory            | 0.5       | Yes  | Yes                | Yes   | Yes <sup>(2)</sup>              | Yes <sup>(2)</sup> | Yes <sup>(2)</sup> |
|                              | 1         | Yes  | Yes                | Yes   | No                              | No                 | No <sup>(5)</sup>  |
|                              | 2         | Yes  | Yes                | Yes   | N/A                             | N/A                | N/A                |
| System memory <sup>(3)</sup> | 0.5       | Yes  | No                 | No    | Yes                             | No                 | No                 |
|                              | 1         | Yes  | No                 | No    | Yes                             | No                 | No                 |
|                              | 2         | Yes  | No                 | No    | N/A                             | N/A                | N/A                |
| Option bytes <sup>(4)</sup>  | 0.5       | Yes  | Yes <sup>(5)</sup> | N/A   | Yes                             | Yes <sup>(5)</sup> | N/A                |
|                              | 1         | Yes  | Yes <sup>(5)</sup> | N/A   | Yes                             | Yes <sup>(5)</sup> | N/A                |
|                              | 2         | Yes  | No <sup>(6)</sup>  | N/A   | N/A                             | N/A                | N/A                |

**Table 4. Access status versus protection level and execution modes when TZEN = 1 (continued)**

| Area             | RDP level | User execution<br>(boot from flash memory) |                    |       | Debug/bootloader <sup>(1)</sup> |                    |                    |
|------------------|-----------|--|--------------------|-------|---------------------------------|--------------------|--------------------|
|                  |           | Read                                       | Write              | Erase | Read                            | Write              | Erase              |
| OTP              | 0.5       | Yes  | Yes <sup>(7)</sup> | N/A   | Yes                             | Yes <sup>(7)</sup> | N/A                |
|                  | 1         | Yes  | Yes <sup>(7)</sup> | N/A   | Yes                             | Yes <sup>(7)</sup> | N/A                |
|                  | 2         | Yes  | Yes <sup>(7)</sup> | N/A   | N/A                             | N/A                | N/A                |
| Backup registers | 0.5       | Yes  | Yes                | N/A   | Yes <sup>(2)</sup>              | Yes <sup>(2)</sup> | N/A <sup>(8)</sup> |
|                  | 1         | Yes  | Yes                | N/A   | No                              | No                 | N/A <sup>(8)</sup> |
|                  | 2         | Yes  | Yes                | N/A   | N/A                             | N/A                | N/A                |
| SRAM2            | 0.5       | Yes  | Yes                | N/A   | Yes <sup>(2)</sup>              | Yes <sup>(2)</sup> | N/A <sup>(9)</sup> |
|                  | 1         | Yes  | Yes                | N/A   | No                              | No                 | N/A <sup>(9)</sup> |
|                  | 2         | Yes  | Yes                | N/A   | N/A                             | N/A                | N/A                |

1. When the protection level 2 is active, the debug port and the bootloader mode are disabled.
2. Depends on TrustZone security access rights.
3. The system memory is only read-accessible, whatever the protection level (0, 1 or 2) and execution mode.
4. Option bytes are only accessible through the flash registers interface and OPSTRT bit.
5. The flash main memory is erased when the RDP option byte regresses from level 1 to level 0.
6. SWAP\_BANK user option can be modified.
7. OTP can be written only once.
8. The backup registers are erased when RDP changes from level 1 to level 0.
9. All SRAMs are erased when RDP changes from level 1 to level 0.

### 3.5.2 Additional flash memory protections when TrustZone is activated

When the TrustZone security is enabled through option bytes, the whole flash memory is secure after reset and the following protections are available:

- Nonvolatile watermark-based secure flash memory area  
The secure area can be accessed only in Secure mode. One area can be selected with a page granularity.
- Secure hide protection area (HDP)  
It is part of the flash memory secure area and can be protected to deny access to this area by any data read, write, and instruction fetch. For example, a software code in the secure flash memory hide protection area can be executed only once and deny any further access to this area until the next system reset. One area can be selected at the beginning of the secure area.
- Volatile block-based secure flash memory area  
Each page can be programmed on-the-fly as secure or nonsecure.

### 3.5.3 FLASH privilege protection

Each flash memory page can be programmed on-the-fly as privileged or unprivileged.

## 3.6 Embedded SRAMs

SRAM1 and SRAM2 are the main embedded SRAMs, each with specific features. These memories can be used for peripherals background autonomous mode (BAM).

The SRAMs can be powered down in Stop mode to reduce consumption:

- SRAM1: up to seven 64-Kbyte blocks (up to 448 Kbytes), can be retained in Standby mode
- SRAM2: one 64-Kbyte block with parity, can be retained in Standby mode.

### 3.6.1 SRAMs TrustZone security

When TrustZone security is enabled, SRAMs are secure after reset. SRAM1 and SRAM2 can be programmed as secure or nonsecure by blocks, using the block-based memory protection controller (MPCBB).

The granularity of SRAM secure block based is a page of 512 bytes.

### 3.6.2 SRAMs privilege protection

The SRAM1 and SRAM2 can be programmed as privileged or unprivileged by blocks, using the MPCBB. The granularity of SRAM block-based privilege is a page of 512 bytes.

## 3.7 TrustZone security architecture

The security architecture is based on Arm TrustZone with the Armv8-M main extension.

The TZEN option bit in the FLASH\_OTPR register activates the TrustZone security.

When TrustZone is enabled, the SAU (security attribution unit) and IDAU (implementation defined attribution unit) define the access permissions based on secure and nonsecure state.

- SAU: up to eight SAU configurable regions are available for security attribution.
- IDAU: provides a first memory partition as nonsecure or nonsecure callable attributes. It is then combined with the results from the SAU security attribution and the higher security state is selected.

Based on IDAU security attribution, the flash memory, system SRAM and peripheral memory space is aliased twice for secure and nonsecure states.

[Table 5](#) shows an example of typical SAU regions configuration based on IDAU regions.

**Table 5. Example of memory map security attribution versus SAU configuration regions**

| Region description            | Address range              | IDAU security attribution | SAU security attribution typical configuration | Final security attribution |
|-------------------------------|----------------------------|---------------------------|--|----------------------------|
| ICACHE Re-mappable (Reserved) | 0x0000 0000<br>0x07FF FFFF | Nonsecure                 | Secure or nonsecure or nonsecure callable      |                            |
| Code flash memory and SRAM    | 0x0800 0000<br>0x0BFF FFFF | Nonsecure                 |  |                            |
|                               | 0x0C00 0000<br>0x0FFF FFFF | Nonsecure callable        | Secure or NSC                                  |                            |

Table 5. Example of memory map security attribution versus SAU configuration regions (contin-

| Region description            | Address range              | IDAU security attribution | SAU security attribution typical configuration | Final security attribution |
|-------------------------------|----------------------------|---------------------------|--|----------------------------|
| ICACHE Re-mappable (Reserved) | 0x1000 0000<br>0x17FF FFFF | Nonsecure                 | Nonsecure                                      |                            |
|                               | 0x1800 0000<br>0x1FFF FFFF |                           |  |                            |
| SRAM                          | 0x2000 0000<br>0x2FFF FFFF | Nonsecure                 |  |                            |
|                               | 0x3000_0000<br>0x3FFF FFFF | Nonsecure callable        | Secure or nonsecure callable                   |                            |
| Peripherals                   | 0x4000 0000<br>0x4FFF FFFF | Nonsecure                 |  |                            |
|                               | 0x5000 0000<br>0x5FFF FFFF | Nonsecure callable        | Secure or nonsecure callable                   |                            |
| Reserved                      | 0x6000 0000<br>0xDFFF FFFF | Nonsecure                 | Secure or nonsecure or nonsecure callable      |                            |

### 3.7.1 TrustZone peripheral classification

When the TrustZone security is active, a peripheral can be either securable or TrustZone-aware type as follows:

- Securable: peripheral protected by an AHB/APB firewall gate that is controlled from TZSC to define security properties
- TrustZone-aware: peripheral connected directly to AHB or APB bus and implementing a specific TrustZone behavior such as a subset of registers being secure

### 3.7.2 Default TrustZone security state

The default system security state is detailed below:

- CPU: Cortex-M33 is in secure state after reset. The boot address must be in secure area.
- Memory map: SAU is fully secure after reset, hence all memory map is fully secure. Up to eight SAU configurable regions are available for security attribution.
- Flash memory:
  - Flash memory security area is defined by watermark user options.
  - Flash memory block based area is nonsecure after reset.
- SRAMs:
  - All are secure after reset, MPCBB is secure.
- Peripherals:
  - Securable peripherals are nonsecure after reset.
  - TrustZone-aware peripherals are nonsecure after reset.
- All GPIOs are secure after reset.

- Interrupts:
  - NVIC: All interrupts are secure after reset. NVIC is banked for secure and nonsecure state.
  - TZIC: All illegal access interrupts are disabled after reset.

### 3.8 Boot modes

At startup, a BOOT0 pin, nBOOT0 and NSBOOTADDx[24:0] (x = 0, 1), and SECBOOTADD0[24:0] option bytes are used to select the boot memory address that includes:

- Boot from any address in user flash memory
- Boot from system memory bootloader
- Boot from any address in embedded SRAM
- Boot from RSS (root security services)

The BOOT0 value comes from the PH3-BOOT0 pin or from an option bit, depending upon the value of a user option bit to free the GPIO pad if needed.

The bootloader is located in the system memory, programmed by ST during production. It is used to program the flash memory by using USART, I<sup>2</sup>C, SPI or USB OTG in device mode.

The bootloader is available on all devices. Refer to AN2606 *STM32 microcontroller system memory boot mode*, available on [www.st.com](http://www.st.com), for more details.

The RSS are embedded in the flash memory area named secure information block, programmed during ST production. For example, the RSS enables the SFI (secure firmware installation), thanks to the RSSE (RSS extension firmware). This feature allows the customers to produce the confidentiality of the firmware to be provisioned into the STM32, when production is subcontracted to untrusted third party.

The RSS is available on all devices, after enabling the TrustZone through the TZEN option bit. Refer to AN4992 *STM32 MCUs secure firmware install (SFI) overview*, available on [www.st.com](http://www.st.com), for more details.

Refer to [Table 6](#) and [Table 7](#), respectively, for boot modes with TrustZone disabled and enabled.

**Table 6. Boot modes when TrustZone is disabled (TZEN = 0)**

| nBOOT0<br>FLASH_<br>OPTR[27] | BOOT0<br>pin PH3 | nSWBOOT0<br>FLASH_<br>OPTR[26] | Boot address<br>option-bytes<br>selection | Boot area  | ST programmed<br>default value    |
|------------------------------|------------------|--------------------------------|---|--|-----------------------------------|
| -                            | 0                | 1                              | NSBOOTADD0[24:0]                          | Boot address defined by<br>user option bytes<br>NSBOOTADD0[24:0] | Flash memory:<br>0x08000 000      |
| -                            | 1                | 1                              | NSBOOTADD1[24:0]                          | Boot address defined by<br>user option bytes<br>NSBOOTADD1[24:0] | System bootloader:<br>0x0BF9 0000 |



Table 6. Boot modes when TrustZone is disabled (TZEN = 0) (continued)

| nBOOT0<br>FLASH_<br>OPTR[27] | BOOT0<br>pin PH3 | nSWBOOT0<br>FLASH_<br>OPTR[26] | Boot address<br>option-bytes<br>selection | Boot area  | ST programmed<br>default value    |
|------------------------------|------------------|--------------------------------|---|--|-----------------------------------|
| 1                            | -                | 0                              | NSBOOTADD0[24:0]                          | Boot address defined by<br>user option bytes<br>NSBOOTADD0[24:0] | Flash memory:<br>0x0800 0000      |
| 0                            | -                | 0                              | NSBOOTADD1[24:0]                          | Boot address defined by<br>user option bytes<br>NSBOOTADD1[24:0] | System bootloader:<br>0x0BF9 0000 |

Table 7. Boot modes when TrustZone is enabled (TZEN = 1)

| BOOT_LOCK | nBOOT0<br>FLASH_<br>OPTR[27] | BOOT0<br>pin<br>PH3 | nSWBOOT0<br>FLASH_<br>OPTR[26] | RSS command | Boot address<br>option bytes<br>selection | Boot area  | ST<br>programmed<br>default value |
|-----------|------------------------------|---------------------|--------------------------------|-------------|---|--|-----------------------------------|
| 0         | -                            | 0                   | 1                              | 0           | SECBOOT-<br>ADD0[24:0]                    | Secure boot address defined<br>by user option bytes<br>SECBOOTADD0[24:0] | Flash memory:<br>0x0C00 0000      |
|           | -                            | 1                   | 1                              | 0           | N/A                                       | RSS  | RSS:<br>0x0FF8 0000               |
|           | 1                            | -                   | 0                              | 0           | SECBOOT-<br>ADD0[24:0]                    | Secure boot address defined<br>by user option bytes<br>SECBOOTADD0[24:0] | Flash memory:<br>0x0C00 0000      |
|           | 0                            | -                   | 0                              | 0           | N/A                                       | RSS  | RSS:<br>0x0FF8 0000               |
|           | -                            | -                   | -                              | ≠0          | N/A                                       | RSS  | RSS:<br>0x0FF8 0000               |
| 1         | -                            | -                   | -                              | -           | SECBOOT-<br>ADD0[24:0]                    | Secure boot address defined<br>by user option bytes<br>SECBOOTADD0[24:0] | Flash memory:<br>0x0C00 0000      |

When TrustZone is enabled by setting the TZEN option bit, the boot space must be in the secure area. The SECBOOTADD0[24:0] option bytes are used to select the boot secure memory address.

A unique boot entry option can be selected by setting the BOOT\_LOCK option bit, allowing to boot always at the address selected by SECBOOTADD0[24:0] option bytes. All other boot options are ignored.

The boot address option bytes allow to program any boot memory address, but the allowed address space depends on the flash memory RDP level. If the programmed boot memory address is out of the allowed memory mapped area when RDP level is 0.5 or higher, the default boot address is forced either in secure or nonsecure flash memory, depending on TrustZone security option, as detailed in [Table 8](#).

Table 8. Boot space versus RDP protection

| RDP | TZEN = 1  | TZEN = 0   |
|-----|---|--|
| 0   | Any boot address  | Any boot address   |
| 0.5 | Boot address only in RSS or secure flash memory:<br>0x0C00 0000 - 0x0C1F FFFF.<br>Otherwise, forced boot address is 0x0FF8 0000 | N/A  |
| 1   |   | Any boot address   |
| 2   |   | Boot address only in flash memory:<br>0x0800 0000 - 0x081F FFFF.<br>Otherwise, forced boot address is: 0x0800 0000 |

### 3.9 Global TrustZone controller (GTZC)

GTZC is used to configure TrustZone and privileged attributes within the full system.

The GTZC includes different sub-blocks:

- **TZSC:** TrustZone security controller  
Defines the secure/privilege state of slave/master peripherals. The TZSC block informs some peripherals (such as RCC or GPIO) about the secure status of each securable peripheral.
- **TZIC:** TrustZone illegal access controller  
Gathers all security illegal access events in the system and generates a secure interrupt towards NVIC.
- **MPCBB:** block-based memory protection controller  
Controls secure states of all memory blocks (512-byte pages) of the associated SRAM. This peripheral configures the internal RAM in a TrustZone system product having segmented SRAM with programmable-security and privileged attributes.

The GTZC main features are:

- Independent 32-bit AHB interfaces for TZSC, TZIC and MPCBB
- Secure and nonsecure access supported for privileged/unprivileged part of TZSC
- Set of registers to define product security settings:
  - Secure/privilege access mode for securable peripherals
  - Secure/privilege access mode for securable memories
  - Illegal access interrupt notification

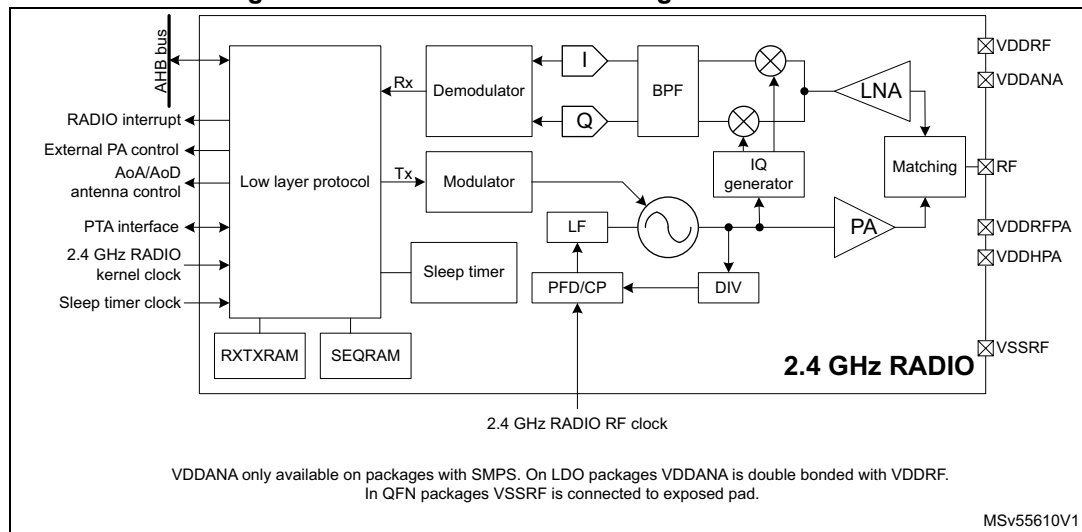
### 3.10 2.4 GHz RADIO

The 2.4 GHz RADIO is ultra-low-power, operating in the 2.4 GHz ISM band. It provides Bluetooth® LE 1 Mbps coded, 1 Mbps, and 2 Mbps noncoded GFSK, and IEEE802.15.4 chip rate 2 Mchip/s, spreading mode DSSS, data rate 125 kbps and 250 kbps, O-QPSK-C modulation. It is compliant with the Bluetooth® LE, Matter, Thread, and Zigbee specifications, and with radio regulations including ETSI EN 300 328, EN 300 440, EN 301 489-17, ARIB STD-T66, FCC CFR47 part 15 section 15.205, 15.209, 15.247 and 15.249, IC RSS-139 and RSS-210.

The 2.4 GHz RADIO supports the following features:

- Radio protocol:
  - Bluetooth® LE
  - IEEE802.15.4
  - Concurrent mode
- Bluetooth® LE
  - Data rate 1 Mbps, 2 Mbps, 500 kbps, and 125 kbps.
  - Device privacy and network privacy modes
  - Anonymous device address types
  - Advertising extension PDUs
  - Advertising channel index
  - Periodic advertising synchronous transfer
  - High duty cycle, nonconnectable advertising
  - Channel selection algorithm #2
  - Angle of arrival (AoA), angle of departure (AoD)
  - Up to 20 connections in any role in addition to advertiser and scanner roles
  - Audio connected isochronous streams
  - Audio broadcast isochronous streams
- IEEE 802.15.4 features:
  - Beacon management
  - 16-bit short and 64-bit IEEE addressing modes
  - PAN formation along with association and disassociation
  - Full handshake protocol for transfer reliability, frame validation, and acknowledgment frame delivery
  - IEEE802.15.4 2020 MAC for nonbeaconed PANs
- Matter
- Thread
- Zigbee
- External PA support
- Packet traffic arbitration

Figure 2. 2.4 GHz RADIO block diagram



### 3.11 PTA interface

The PTA interface enables packet traffic arbitration with other connectivity devices, as WiFi

PTA main features:

- based on IEEE802.15.2 standard
- supports both grant and deny signaling
- supports from 1- up to 4-wire protocols
- programmable transmit receive PTA\_STATUS polarity
- programmable priority polarity
- programmable grant polarity
- programmable active polarity
- programmable PTA\_ACTIVE timing
- programmable PTA\_STATUS time multiplexed priority timing
- programmable transmit packet abort

### 3.12 Power supply management

The power controller (PWR) main features are:

- Power supplies and supply domains
  - Core domain ( $V_{CORE}$ )
  - $V_{DD}$  and backup domain
  - Analog domain ( $V_{DDA}$ )
  - SMPS power stage ( $V_{DDSMPS}$ , available only on SMPS packages)
  - $V_{DDUSB}$  domain USB OTG (available only on USB packages)
  - $V_{DDRF}$  for 2.4 GHz RADIO
- System supply voltage regulation
  - SMPS step-down converter

- Voltage regulator (LDO)
- Power supply supervision
  - BOR monitor
  - PVD monitor
- Power management
  - Operating modes
  - Voltage scaling control
  - Low-power modes
- TrustZone security and privilege protection

### 3.12.1 Power supply schemes

The devices require a 1.71 to 3.6 V  $V_{DD}$  operating voltage supply. Several independent supplies can be provided for specific peripherals:

- $V_{DD} = 1.71$  to 3.6 V (functionality guaranteed down to  $V_{BORx}$  minimum value)  
External power supply for the I/Os, the internal regulator, the system analog such as reset, power management, and internal clocks, and the backup domain. It is provided externally through the VDD pins. VDDRF must be connected to the same supply used for VDD.
- $V_{DDIO2} = 1.08$  to 3.6 V  
External power supply for 14 I/Os (GPIOG[15:2]). The  $V_{DDIO2}$  voltage level is independent from the  $V_{DD}$  voltage and must be connected to VDD (preferably) or to VSS pin when these I/Os are not used.
- $V_{DDA} = 1.58$  (COMP) / 1.62 (ADC) to 3.6 V  
External analog power supply for ADC and comparators. The  $V_{DDA}$  voltage level is independent from the  $V_{DD}$  voltage and must be connected to VDD (preferably) or to VSS pin when these peripherals are not used.
- $V_{REF+}$   
Reference voltage for the ADC. It is also the output of the internal voltage reference buffer (VREFBUF) when enabled. The  $V_{REF+}$  can be connected to VSS pin when ADC and VREFBUF are not used. The VREF+ pin is not available on all packages, when not available, it is bonded to VDDA.
- $V_{DDUSB} = 3.0$  to 3.6 V  
External power supply for the USB OTG transceiver. It is provided externally through the VDDUSB pin. The  $V_{DDUSB}$  voltage level is independent from the  $V_{DD}$  voltage and must be connected to VDD (preferably) or to VSS pin when the USB OTG is not used.
- $V_{DDSMPS} = 1.71$  to 3.6 V  
External power supply for the SMPS step down converter. It is provided externally through VDDSMPS supply pin, and must be connected to the same supply as  $V_{DD}$ .
- $V_{LXSMPS}$  is the switched SMPS step down converter output.  
The SMPS power supply pins are available only on a specific package with SMPS step-down converter option.
- $V_{DDRF} = 1.71$  to 3.6 V  
External power supply for the 2.4 GHz RADIO, it must be connected to the same supply used for VDD.
- $V_{DDANA} = 0$  to 3.6 V (must be  $\geq 1.2$  V for 2.4 GHz RADIO operation)

An external power supply for the 2.4 GHz RADIO, can be connected to  $V_{DD11}$ . The  $V_{DDANA}$  supply must be equal or lower than  $V_{DDRF}$ .

- $V_{DDRFPA} = 0$  to 3.6 V (must be  $\geq 1.2$  V for 2.4 GHz RADIO operation)

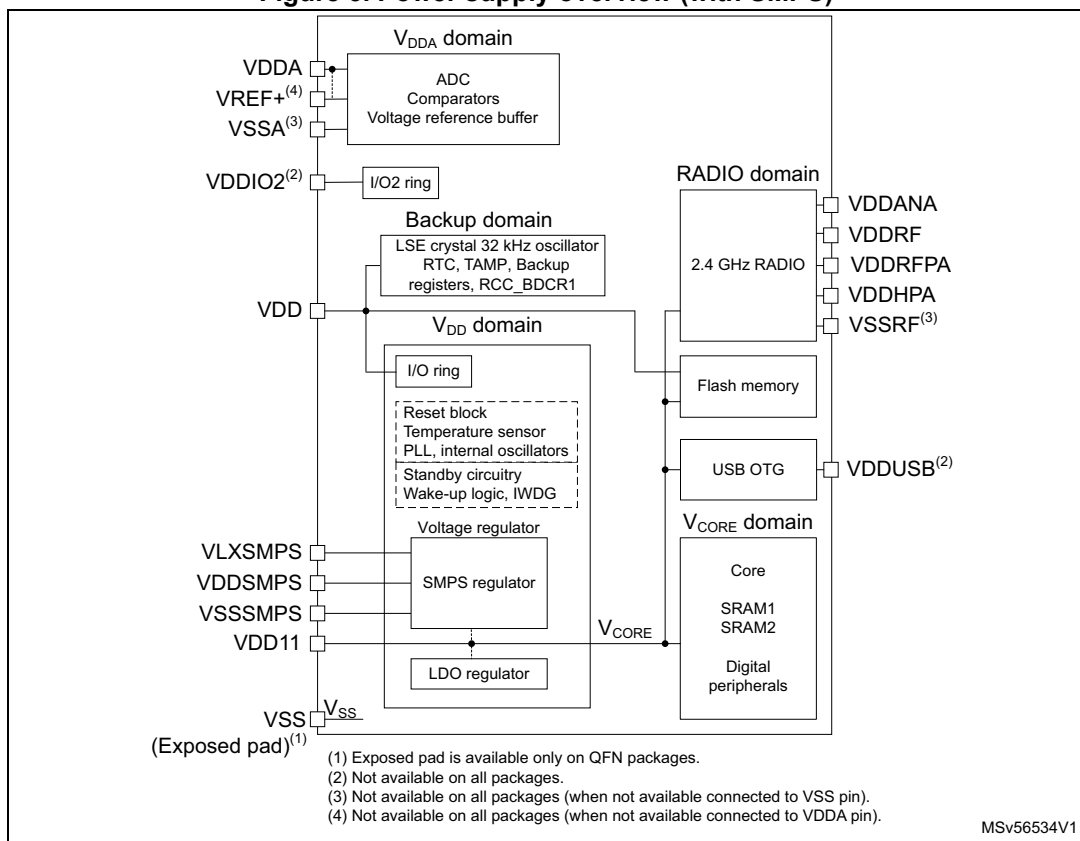
An external power supply for the 2.4 GHz RADIO and power amplifier regulator, can be connected to  $V_{DD11}$ . The maximum reachable transmit output power is determined by  $V_{DDRFPA}$  supply level. The  $V_{DDRFPA}$  supply must be equal or lower than  $V_{DDRF}$ .

The devices embed two regulators: one LDO and one SMPS in parallel to provide the  $V_{CORE}$  supply for digital peripherals, SRAM1, SRAM2, 2.4 GHz RADIO and embedded flash memory. The LDO generates this voltage on VCAP pin connected to a 4.7  $\mu\text{F}$  (typical) external capacitor. The SMPS generates this voltage on VDD11 pin, with a total a 4.7  $\mu\text{F}$  (typical) external capacitor. The SMPS requires an external 2.2  $\mu\text{H}$  (typical) coil.

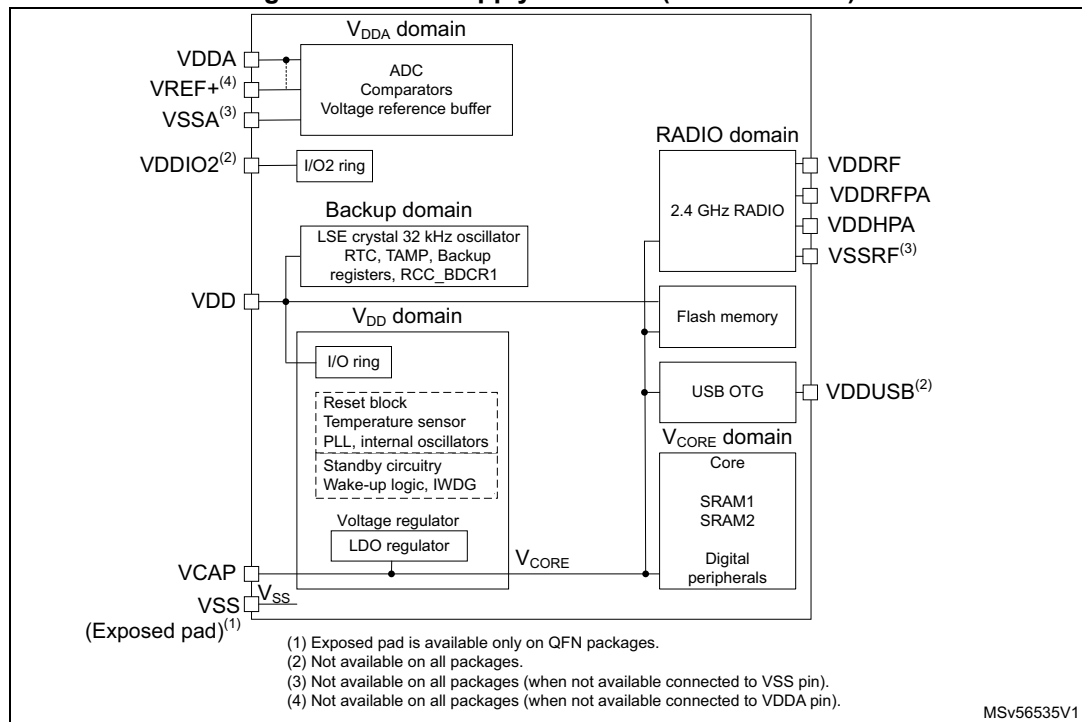
Both regulators can provide two different voltages (voltage scaling), and can operate in Stop modes.

It is possible to switch from SMPS to LDO and from LDO to SMPS on-the-fly.

**Figure 3. Power supply overview (with SMPS)**



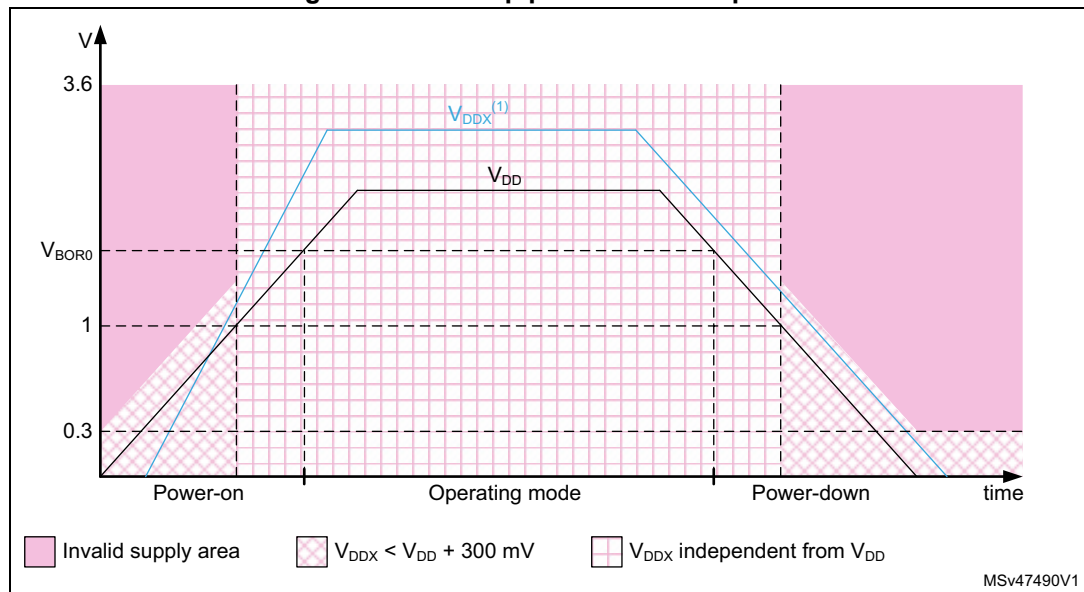
### Figure 4. Power supply overview (without SMPS)



During power-up and power-down phases, the following power sequence requirements must be respected:

- When  $V_{DD}$  is below 1 V, other power supplies (namely  $V_{DDA}$ ,  $V_{DDIO2}$ ,  $V_{DDUSB}$ ) must remain below  $V_{DD} + 300$  mV.
- When  $V_{DD}$  is equal to or above 1 V, other power supplies are independent.
- During the power-down phase,  $V_{DD}$  can temporarily become lower than other supplies only if the energy provided to the MCU remains below 1 mJ. This allows external decoupling capacitors to be discharged with different time constants during the power-down transient phase.

Figure 5. Power-up/power-down sequence



1.  $V_{DDX}$  refers to power supplies  $V_{DDA}$ ,  $V_{DDIO2}$ , and  $V_{DDUSB}$ .

### 3.12.2 Power supply supervisor

The devices have an integrated ultra-low-power BOR (brownout reset) active in all modes. The BOR ensures proper operation after power on and during power down. The devices remain in reset mode when the monitored supply voltage  $V_{DD}$  is below a specified threshold, without the need for an external reset circuit.

The lowest BOR level is 1.71 V at power on, and other higher thresholds can be selected through option bytes. The devices feature an embedded PVD (programmable voltage detector) that monitors the  $V_{DD}$  power supply and compares it to the  $V_{PVD}$  threshold.

An interrupt can be generated when  $V_{DD}$  drops below and/or rises above the  $V_{PVD}$  threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

The devices support dynamic voltage scaling to optimize power consumption in Run mode. The voltage from the main regulator that supplies the logic ( $V_{CORE}$ ) can be adjusted according to the system's maximum operating frequency.

The main regulator operates in the following ranges:

- Range 1 ( $V_{CORE} = 1.2 \text{ V}$ ) with CPU and peripherals running at up to 100 MHz
- Range 2 ( $V_{CORE} = 0.9 \text{ V}$ ) with CPU and peripherals running at up to 16 MHz

#### Low-power modes

The devices support different low-power modes to achieve the best compromise between low-power consumption, startup time, available peripherals, and available wake-up sources.



**Table 9. Operating modes overview**

| Mode  | Regulator <sup>(1)</sup> | CPU | Flash memory      | SRAM              | Clocks | DMA and peripherals <sup>(2)</sup>   | 2.4 GHz RADIO states  | Wake-up source         |
|-------|--------------------------|-----|-------------------|-------------------|--------|--------------------------------------|---|------------------------|
| Run   | Range 1                  | Yes | ON <sup>(3)</sup> | ON                | Any    | All                                  | No effect. 2.4 GHz RADIO and 2.4 GHz RADIO sleep timer interrupts cause the device to exit Sleep mode. Radio connections are maintained.  | N/A                    |
|       | Range 2                  |     |                   |                   |        | All except USB OTG and 2.4 GHz RADIO | The 2.4 GHz RADIO full configuration is retained but is no longer capable to transmit and receive packets. The 2.4 GHz RADIO sleep timer interrupt causes the device to exit Stop mode. Radio connections are maintained. |                        |
| Sleep | Range 1                  | No  | ON                | ON <sup>(4)</sup> | Any    | All                                  | No effect. 2.4 GHz RADIO and 2.4 GHz RADIO sleep timer interrupts cause the device to exit Sleep mode. Radio connections are maintained.  | Any interrupt or event |
|       | Range 2                  |     |                   |                   |        | All except USB OTG and 2.4 GHz RADIO | The 2.4 GHz RADIO full configuration is retained but is no longer capable to transmit and receive packets. The 2.4 GHz RADIO sleep timer interrupt causes the device to exit Stop mode. Radio connections are maintained. |                        |



Table 9. Operating modes overview (continued)

| Mode   | Regulator <sup>(1)</sup> | CPU | Flash memory | SRAM              | Clocks                    | DMA and peripherals <sup>(2)</sup>  | 2.4 GHz RADIO states  | Wake-up source   |
|--------|--------------------------|-----|--------------|-------------------|---------------------------|---|---|--|
| Stop 0 | Range 1                  | No  | OFF          | ON <sup>(5)</sup> | LSE<br>LSI <sup>(6)</sup> | BOR, PVD,<br>RTC, TAMP, IWDG,<br>2.4 GHz RADIO sleep timer,<br>ADC4 <sup>(7)</sup> (temperature sensor),<br>COMPx (x = 1, 2),<br>USARTx (x = 1..3) <sup>(8)</sup> ,<br>LPUART1,<br>SPIx (x = 1..3) <sup>(9)</sup> ,<br>I2Cx (x = 1..4) <sup>(10)</sup> ,<br>LPTIMx (x = 1, 2) <sup>(11)</sup> ,<br>GPIO, GPDMA1 <sup>(12)</sup> ,<br>2.4 GHz RADIO<br>All other peripherals are frozen. | The 2.4 GHz RADIO autonomously transmits and receives packets. 2.4 GHz RADIO and 2.4 GHz RADIO sleep timer interrupts cause the device to exit Stop 0 mode. Radio connections are maintained                              | Reset pin, all I/Os, BOR, PVD, RTC, TAMP, IWDG, 2.4 GHz RADIO sleep timer, ADC4 (temperature sensor), COMPx (x = 1, 2), USARTx (x = 1..3), LPUART1, SPIx (x = 1..3), I2Cx (x = 1..4), LPTIMx (x = 1, 2), GPDMA1, 2.4 GHz RADIO |
|        | Range 2                  |     |              |                   |                           | All from Stop 0 Range 1 except USB OTG and 2.4 GHz RADIO  | The 2.4 GHz RADIO full configuration is retained but is no longer capable to transmit and receive packets. The 2.4 GHz RADIO sleep timer interrupt causes the device to exit Stop mode. Radio connections are maintained. | All from Stop 0 Range 1 except USB OTG and 2.4 GHz RADIO   |

Table 9. Operating modes overview (continued)

| Mode                   | Regulator <sup>(1)</sup> | CPU | Flash memory | SRAM              | Clocks     | DMA and peripherals <sup>(2)</sup>  | 2.4 GHz RADIO states   | Wake-up source  |
|------------------------|--------------------------|-----|--------------|-------------------|------------|---|--|---|
| Stop 1 <sup>(13)</sup> | LPR                      | No  | OFF          | ON <sup>(5)</sup> | LSI<br>LSE | BOR, PVD, RTC, TAMP, IWDG, 2.4 GHz RADIO sleep timer, ADC4 (temperature sensor), COMPx (x = 1, 2), USARTx (x = 1..3), LPUART1, SPIx (x = 1..3), I2Cx (x = 1..4), LPTIMx (x = 1, 2), GPIO<br>All other peripherals are frozen. | The 2.4 GHz RADIO full configuration is retained but is no longer capable to transmit and receive packets. The 2.4 GHz RADIO sleep timer interrupt causes the device to exit Stop mode. Radio connections are maintained.  | Reset pin, all I/Os, BOR, PVD, RTC, TAMP, IWDG, 2.4 GHz RADIO sleep timer, ADC4 (temperature sensor), COMPx (x = 1, 2), USARTx (x = 1..3), LPUART1, SPIx (x = 1..3), I2Cx (x = 1..4), LPTIMx (x = 1, 2) |
| Stop 2 <sup>(14)</sup> | LPR                      | No  | OFF          | ON <sup>(5)</sup> | LSI<br>LSE | BOR, PVD, RTC, TAMP, IWDG, 2.4 GHz RADIO sleep timer, LPUART1, SPI3, I2C3, LPTIM1, GPIO<br>All other peripherals are powered off.   | The 2.4 GHz RADIO is powered down, only the minimum configuration information is retained. It is no longer capable to transmit and receive packets. The 2.4 GHz RADIO sleep timer interrupt causes the device to exit Stop 2 mode. Radio connections are maintained. | Reset pin, all I/Os, BOR, PVD, RTC, TAMP, IWDG, 2.4 GHz RADIO sleep timer, LPUART1, SPI3, I2C3, LPTIM1  |



Table 9. Operating modes overview (continued)

| Mode              | Regulator <sup>(1)</sup> | CPU         | Flash memory | SRAM              | Clocks     | DMA and peripherals <sup>(2)</sup>  | 2.4 GHz RADIO states  | Wake-up source  |
|-------------------|--------------------------|-------------|--------------|-------------------|------------|---|---|---|
| Standby retention | LPR                      | Powered off | OFF          | ON <sup>(5)</sup> | LSI<br>LSE | BOR, RTC, TAMP, IWDG, 2.4 GHz RADIO sleep timer<br>All other peripherals are powered off.<br>I/O configuration can be retained, floating, pull-up or pull-down. | The 2.4 GHz RADIO is powered down, only the minimum configuration information is retained. It is no longer capable to transmit and receive packets. The 2.4 GHz RADIO sleep timer interrupt causes the device to exit Standby mode. Radio connections are maintained. | Reset pin, WKUPx (x = 1...8), BOR, RTC, TAMP, IWDG, 2.4 GHz RADIO sleep timer |
| Standby           | OFF                      |             |              | Powered off       |            | All from mode Standby retention except 2.4 GHz RADIO sleep timer  | The 2.4 GHz RADIO and 2.4 GHz RADIO sleep timer are powered down. Radio connections are lost.   | All from mode Standby retention except 2.4 GHz RADIO sleep timer              |

1. LPR means that the main regulator is OFF and the low-power regulator is ON.
2. All peripherals can be active or clock gated to save power consumption.
3. The flash memory can be put in power-down and its clock can be gated off when executing from SRAM.
4. The SRAM1 and SRAM2 clocks can be gated on or off independently.
5. The SRAM can be individually powered off to save power consumption.
6. HSI16 can be temporary enabled upon peripheral request, for autonomous functions with DMA or wake-up from Stop event detections.
7. The ADC conversion is functional and autonomous with DMA in Stop 0 mode, and can generate a wake-up interrupt on conversion events.
8. UART and LPUART transmission and reception is functional and autonomous with DMA in Stop 0 mode, and can generate a wake-up interrupt on transfer events.
9. SPI transmission and reception is functional and autonomous with DMA in Stop 0 mode, and can generate a wake-up interrupt on transfer events.
10. I2C transmission and reception is functional and autonomous with DMA in Stop 0 mode, and can generate a wake-up interrupt on transfer events.
11. LPTIM is functional and autonomous with DMA in Stop 0 mode, and can generate a wake-up interrupt on all events.
12. GPDMA is functional and autonomous in Stop 0 mode, and can generate a wake-up interrupt on events.
13. Active peripherals ADC, COMP, USART, LPUART, SPI, I2C, and LPTIM, can generate bus clock request and/or a wake-up interrupt on event.
14. Active peripherals LPUART1, SPI3, I2C3, and LPTIM1, can generate bus clock request and/or a wake-up interrupt on event.

By default, the microcontroller is in Run mode after a system or a power on reset. It is up to the user to select one of the low-power modes described below:

- **Sleep mode**

In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt or event occurs.

- **Stop 0 and Stop 1 modes**

Stop modes achieve the lowest power consumption while retaining the content of SRAM and registers. All clocks in the  $V_{CORE}$  domain are stopped, the PLL, the HSI16, and the HSE32 crystal oscillators are disabled. The LSE or LSI is still running.

The RTC, TAMP, IWDG and 2.4 GHz RADIO sleep timer can remain active.

Some peripherals are autonomous and can operate in Stop modes by requesting their kernel clock and their bus clock when needed, to transfer data with DMA. Stop 0 modes will be entered. Refer to [PWR background autonomous mode \(BAM\)](#) for more details. In Stop modes the bus clocks when requested use HSI16.

Stop 0 offer the largest number of active peripherals, with or without DMA, and wake-up sources, a smaller wake-up time but a higher consumption than Stop 1.

In Stop 0 mode, the main regulator remains ON, allowing a very fast wake-up time, but with higher power consumption.

Stop 1 is the lowest power mode with full retention, but the functional peripherals and sources of wake-up are reduced.

The BOR can be configured in ultra-low-power mode to further reduce consumption during Stop 1 mode.

The system clock when exiting from Stop 0 or Stop 1 modes is HSI16.

- **Stop 2 mode**

Stop mode achieves the lowest power consumption while retaining the content of SRAM and some registers. All clocks in the  $V_{CORE}$  domain are stopped, the PLL, the HSI16, and the HSE32 crystal oscillators are disabled. The LSE or LSI is still running.

The RTC, TAMP, IWDG and 2.4 GHz RADIO sleep timer can remain active.

A reduced set of peripherals are autonomous and can operate in Stop 2 mode by requesting their kernel clock and their bus clock when needed. Refer to [PWR background autonomous mode \(BAM\)](#) for more details.

Stop 2 is the lowest power mode with partial retention, but the functional peripherals and sources of wake-up are reduced.

The BOR can be configured in ultra-low-power mode to further reduce power consumption during Stop 2 mode.

The system clock when exiting from Stop 2 modes is HSI16.

- **Standby mode**

The Standby mode is used to achieve the lowest power consumption. The internal regulator is switched off so that the  $V_{CORE}$  domain is powered off. The PLL, the HSI16, and the HSE32 crystal oscillators are also switched off. The LSE or LSI is still running.

The RTC and IWDG can remain active.

The BOR always remains active in Standby mode.

The BOR can be configured in ultra-low-power mode to further reduce power consumption during Standby mode.

The state of each I/O during Standby mode can be retained with internal pull-up, internal pull-down or floating.

After entering Standby mode, SRAMs and register contents are lost except for registers in the Backup domain and Standby circuitry.

Optionally, the full SRAM1 and/or SRAM2 can be retained in Standby mode, supplied by the low-power regulator (Standby with RAM retention mode).

The device exits Standby mode when an external reset (NRST pin), an IWDG event or reset, WKUP pin event (configurable rising or falling edge), an RTC event occurs (alarm, periodic wake-up, timestamp), or a tamper detection. The tamper detection can be raised either due to external pins or due to an internal failure detection.

The system clock after wake-up is HSI16.

### **PWR background autonomous mode (BAM)**

The devices support BAM (background autonomous mode), that allows peripherals to be functional and autonomous in Stop mode (Stop 0, Stop 1 and Stop 2 modes), so without any software running.

In Stop 0 modes, the autonomous peripherals are the following: ADC4, LPTIMx ( $x = 1, 2$ ), USARTx ( $x = 1..3$ ), LPUART1, SPIx ( $x = 1..3$ ), I2Cx ( $x = 1..4$ ), 2.4 GHz RADIO and GPDMA1. In this mode the GPDMA1 can be used to transfer data or control peripherals and access SRAM1 and SRAM2. The ADC4 can also be used to measure temperature. The 2.4 GHz RADIO is only autonomous in Stop 0 range 1.

In Stop 1 mode, the autonomous peripherals are the following: ADC4, LPTIMx ( $x = 1, 2$ ), USARTx ( $x = 1..3$ ), LPUART1, SPIx ( $x = 1..3$ ), I2Cx ( $x = 1..4$ ). These peripherals can request a transition to Stop 0 mode allowing then data transfers with GPDMA1.

In Stop 2 mode, the autonomous peripherals are the following: LPTIM1, LPUART1, SPI3, I2C3. These peripherals can request a transition to Run mode allowing then data transfers.

Those peripherals support the features detailed below:

- Functionality in Stop mode thanks to its own independent clock (named kernel clock) request capability: the peripheral kernel clock is automatically switched on when requested by a peripheral, and automatically switched off when no peripheral requests it.
- DMA transfers supported in Stop 0 mode thanks to system clock request capability: the system clock (HSI16) automatically switched on when requested by a peripheral, and automatically switched off when no peripheral requests it. When the system clock is requested by an autonomous peripheral, Stop 0 mode is automatically entered and the system clock is woken up and distributed to all peripherals enabled in the RCC. This allows the DMA to access the enabled SRAM, and any enabled peripheral register (for

instance GPIO registers). When no peripheral requests its bus clock Stop 1 mode is automatically re-entered when Stop 1 mode selected as low-power mode.

- Automatic start of the peripheral thanks to hardware synchronous or asynchronous triggers (such as I/Os edge detection and low-power timer event).
- Wake-up from Stop mode with peripheral interrupt.

The GPDMA is fully functional and the linked-list is updated in Stop 0 mode, allowing the different DMA transfers to be linked without any CPU wake-up. This can be used to chain different peripherals transfers, or to write peripherals registers in order to change their configuration while remaining in Stop 0 mode.

The DMA transfers from memory to memory can be started by hardware synchronous or asynchronous triggers, and the DMA transfers between peripherals and memories can also be gated by those triggers.

Here below some use-cases that can be done while remaining in Stop mode:

- A/D conversion triggered by a low-power timer (or any other trigger)
  - wake-up from Stop mode on analog watchdog if the A/D conversion result is out of programmed thresholds
  - wake-up from Stop mode on DMA buffer event
- I<sup>2</sup>C slave reception or transmission, SPI reception, UART/LPUART reception
  - wake-up at the end of peripheral transfer or on DMA buffer event
- I<sup>2</sup>C controller transfer, SPI transmission, UART/LPUART transmission, triggered by a low-power timer (or any other trigger):
  - example: sensor periodic read
  - wake-up at the end of peripheral transfer or on DMA buffer event
- Bridges between peripherals
  - example: ADC converted data transferred by communication peripherals
- Data transfer from/to GPIO to/from SRAM for:
  - controlling external components
  - implementing data transmission and reception protocols

**Table 10. Functionalities depending on the working mode<sup>(1)</sup>**

| Peripheral       | Run              |         | Sleep            |         | Stop 0           |                  |                    | Stop 1           |                    | Stop 2           |                    | Standby retention |                    | Standby |                    |
|------------------|------------------|---------|------------------|---------|------------------|------------------|--------------------|------------------|--------------------|------------------|--------------------|-------------------|--------------------|---------|--------------------|
|                  | Range 1          | Range 2 | Range 1          | Range 2 | Range 1          | Range 2          | Wake-up capability | -                | Wake-up capability | -                | Wake-up capability | -                 | Wake-up capability | -       | Wake-up capability |
| CPU              | Y                |         | R                |         | R                | -                |                    | R                | -                  | R                | -                  | -                 | -                  | -       | -                  |
| Flash memory     | O <sup>(2)</sup> |         | O <sup>(2)</sup> |         | R                | -                |                    | R                | -                  | R                | -                  | R                 | -                  | R       | -                  |
| Flash interface  | O                |         | R                |         | R                | -                |                    | R                | -                  | R                | -                  | -                 | -                  | -       | -                  |
| SRAM1            | O                |         | O                |         | O <sup>(3)</sup> | -                |                    | O <sup>(3)</sup> | -                  | O <sup>(3)</sup> | -                  | O <sup>(3)</sup>  | -                  | -       | -                  |
| SRAM2            | O                |         | O                |         | O <sup>(3)</sup> | O <sup>(4)</sup> |                    | O <sup>(3)</sup> |                    | O <sup>(3)</sup> |                    | O <sup>(3)</sup>  | -                  | -       | -                  |
| RAMCFG           | O                |         | R                |         | R                | -                |                    | R                | -                  | R                | -                  | -                 | -                  | -       | -                  |
| Backup registers | O                |         | O                |         | O                | -                |                    | R                | -                  | R                | -                  | R                 | -                  | R       | -                  |

Table 10. Functionalities depending on the working mode<sup>(1)</sup> (continued)

| Peripheral                | Run     |         | Sleep   |         | Stop 0           |                   |                    | Stop 1           |                    | Stop 2           |                    | Standby retention   |                    | Standby             |                    |
|---------------------------|---------|---------|---------|---------|------------------|-------------------|--------------------|------------------|--------------------|------------------|--------------------|---------------------|--------------------|---------------------|--------------------|
|                           | Range 1 | Range 2 | Range 1 | Range 2 | Range 1          | Range 2           | Wake-up capability | -                | Wake-up capability | -                | Wake-up capability | -                   | Wake-up capability | -                   | Wake-up capability |
| PWR                       | O       |         | O       |         | R                | -                 |                    | R <sup>(5)</sup> | -                  | R <sup>(5)</sup> | -                  | -                   | -                  | -                   | -                  |
| RCC                       | O       |         | O       |         | R <sup>(6)</sup> | -                 |                    | R <sup>(6)</sup> | -                  | R <sup>(6)</sup> | -                  | -                   | -                  | -                   | -                  |
| EXTI                      | O       |         | R       |         | R                | -                 |                    | R                | -                  | R                | -                  | -                   | -                  | -                   | -                  |
| SYSCFG                    | O       |         | R       |         | R                | -                 |                    | R                | -                  | R                | -                  | -                   | -                  | -                   | -                  |
| ICACHE                    | O       |         | R       |         | R                | -                 |                    | R                | -                  | R                | -                  | -                   | -                  | -                   | -                  |
| 2.4 GHz RADIO             | O       | R       | O       | R       | O                | R                 | O                  | R                | -                  | -                | -                  | -                   | -                  | -                   | -                  |
| 2.4 GHz RADIO SRAM        | O       | R       | O       | R       | O                | R                 | -                  | R                | -                  | R                | -                  | R                   | -                  | -                   | -                  |
| PTACONV                   | O       |         | O       |         | O                | R                 | -                  | R                | -                  | - <sup>(7)</sup> | -                  | -                   | -                  | -                   | -                  |
| 2.4 GHz RADIO sleep timer | O       |         | O       |         | O                |                   | O                  | O                | O                  | O                | O                  | O                   | O                  | -                   | -                  |
| BOR                       | Y       |         | Y       |         | Y                | Y                 | Y                  | Y                | Y                  | Y                | Y                  | Y                   | Y                  | Y                   | Y                  |
| PVD                       | O       |         | O       |         | O                | O                 | O                  | O                | O                  | O                | O                  | -                   | -                  | -                   | -                  |
| HSI16                     | O       |         | O       |         | O <sup>(8)</sup> | -                 | -                  | O <sup>(8)</sup> | -                  | O <sup>(8)</sup> | -                  | -                   | -                  | -                   | -                  |
| HSE32                     | O       |         | O       |         | O <sup>(9)</sup> | -                 | -                  | -                | -                  | -                | -                  | -                   | -                  | -                   | -                  |
| LSI                       | O       |         | O       |         | O                | -                 | -                  | O                | -                  | O                | -                  | O                   | -                  | O                   | -                  |
| LSE                       | O       |         | O       |         | O                | -                 | -                  | O                | -                  | O                | -                  | O                   | -                  | O                   | -                  |
| HSECSS                    | O       |         | O       |         | O                | -                 | O                  | -                | -                  | -                | -                  | -                   | -                  | -                   | -                  |
| LSECSS                    | O       |         | O       |         | O                |                   | O                  | O                | O                  | O                | O                  | O                   | O                  | O                   | O                  |
| IWDG                      | O       |         | O       |         | O                | O                 | O                  | O                | O                  | O                | O                  | O                   | O                  | O                   | O                  |
| RTC                       | O       |         | O       |         | O                | O                 | O                  | O                | O                  | O                | O                  | O                   | O                  | O                   | O                  |
| TAMP tamper pins          | Up to 6 |         | Up to 6 |         | Up to 6          | O                 | O                  | Up to 6          | O                  | Up to 6          | O                  | Up to 6             | O                  | Up to 6             | O                  |
| GPIO pins                 | O       |         | O       |         | O                | O                 | O                  | O                | O                  | O                | O                  | O/R <sup>(10)</sup> | O <sup>(11)</sup>  | O/R <sup>(10)</sup> | O <sup>(11)</sup>  |
| USARTx (x = 1..3)         | O       |         | O       |         | O                | O <sup>(12)</sup> | O                  | O                | O <sup>(12)</sup>  | -                | -                  | -                   | -                  | -                   | -                  |
| LPUART1                   | O       |         | O       |         | O                | O <sup>(12)</sup> | O                  | O                | O <sup>(12)</sup>  | O                | O <sup>(12)</sup>  | -                   | -                  | -                   | -                  |
| I2Cx (x = 1, 2, 4)        | O       |         | O       |         | O                | O <sup>(13)</sup> | O                  | O                | O <sup>(13)</sup>  | -                | -                  | -                   | -                  | -                   | -                  |
| I2C3                      | O       |         | O       |         | O                | O <sup>(13)</sup> | O                  | O                | O <sup>(13)</sup>  | O                | O <sup>(13)</sup>  | -                   | -                  | -                   | -                  |
| SPiX (x = 1, 2)           | O       |         | O       |         | O                | O <sup>(14)</sup> | O                  | O                | O <sup>(14)</sup>  | -                | -                  | -                   | -                  | -                   | -                  |
| SPI3                      | O       |         | O       |         | O                | O <sup>(14)</sup> | O                  | O                | O <sup>(14)</sup>  | O                | O <sup>(14)</sup>  | -                   | -                  | -                   | -                  |



Table 10. Functionalities depending on the working mode<sup>(1)</sup> (continued)

| Peripheral                    | Run     |         | Sleep   |         | Stop 0            |         |                    | Stop 1            |                    | Stop 2            |                    | Standby retention |                    | Standby           |                    |
|-------------------------------|---------|---------|---------|---------|-------------------|---------|--------------------|-------------------|--------------------|-------------------|--------------------|-------------------|--------------------|-------------------|--------------------|
|                               | Range 1 | Range 2 | Range 1 | Range 2 | Range 1           | Range 2 | Wake-up capability | -                 | Wake-up capability | -                 | Wake-up capability | -                 | Wake-up capability | -                 | Wake-up capability |
| ADC4                          | O       |         | O       |         | O                 |         | O <sup>(15)</sup>  | O                 | O <sup>(15)</sup>  | -                 | -                  | -                 | -                  | -                 | -                  |
| COMPx (x = 1, 2)              | O       |         | O       |         | O                 |         | O                  | O                 | O                  | -                 | -                  | -                 | -                  | -                 | -                  |
| LPTIM1                        | O       |         | O       |         | O                 |         | O <sup>(16)</sup>  | O                 | O <sup>(16)</sup>  | O                 | O <sup>(16)</sup>  | -                 | -                  | -                 | -                  |
| LPTIM2                        | O       |         | O       |         | O                 |         | O <sup>(16)</sup>  | O                 | O <sup>(16)</sup>  | -                 | -                  | -                 | -                  | -                 | -                  |
| GPDMA1                        | O       |         | O       |         | O                 |         | O <sup>(17)</sup>  | R                 | -                  | -                 | -                  | -                 | -                  | -                 | -                  |
| USB OTG                       | O       | -       | O       | -       | R                 | -       | O                  | -                 | -                  | -                 | -                  | -                 | -                  | -                 | -                  |
| TIMx (x = 1, 2, 3, 4, 16, 17) | O       |         | O       |         | R                 |         | -                  | R                 | -                  | -                 | -                  | -                 | -                  | -                 | -                  |
| SAI1                          | O       |         | O       |         | R                 |         | -                  | R                 | -                  | -                 | -                  | -                 | -                  | -                 | -                  |
| TSC                           | O       |         | O       |         | R                 |         | -                  | R                 | -                  | -                 | -                  | -                 | -                  | -                 | -                  |
| RNG                           | O       |         | O       |         | R                 |         | -                  | R                 | -                  | -                 | -                  | -                 | -                  | -                 | -                  |
| AES and SAES                  | O       |         | O       |         | R                 |         | -                  | R                 | -                  | -                 | -                  | -                 | -                  | -                 | -                  |
| PKA                           | O       |         | O       |         | R                 |         | -                  | R                 | -                  | -                 | -                  | -                 | -                  | -                 | -                  |
| HASH                          | O       |         | O       |         | R                 |         | -                  | R                 | -                  | -                 | -                  | -                 | -                  | -                 | -                  |
| CRC                           | O       |         | O       |         | R                 |         | -                  | R                 | -                  | -                 | -                  | -                 | -                  | -                 | -                  |
| HSEM                          | O       |         | R       |         | R                 |         | -                  | R                 | -                  | -                 | -                  | -                 | -                  | -                 | -                  |
| GTZC_TZSC                     | O       |         | R       |         | R                 |         | -                  | R                 | -                  | R                 | -                  | -                 | -                  | -                 | -                  |
| GTZC_TZIC                     | O       |         | R       |         | R                 |         | -                  | R                 | -                  | R                 | -                  | -                 | -                  | -                 | -                  |
| GTZC_MPCBB1                   | O       |         | R       |         | R                 |         | -                  | R                 | -                  | R                 | -                  | -                 | -                  | -                 | -                  |
| GTZC_MPCBB2                   | O       |         | R       |         | R                 |         | -                  | R                 | -                  | R                 | -                  | -                 | -                  | -                 | -                  |
| GTZC_MPCBB6                   | O       |         | R       |         | R                 |         | -                  | R                 | -                  | R                 | -                  | -                 | -                  | -                 | -                  |
| WWDG                          | O       |         | O       |         | R                 |         | -                  | R                 | -                  | R                 | -                  | -                 | -                  | -                 | -                  |
| SysTick timer                 | O       |         | O       |         | R                 |         | -                  | R                 | -                  | R                 | -                  | -                 | -                  | -                 | -                  |
| DBGMCU                        | O       |         | O       |         | O <sup>(18)</sup> |         | -                  | O <sup>(18)</sup> | -                  | O <sup>(18)</sup> | -                  | O <sup>(19)</sup> | -                  | O <sup>(19)</sup> | -                  |

1. Legend: Y = yes (enabled). O = optional (disabled by default, can be enabled by software). R = retained, - = not available.  
Gray cells highlight the wake-up capability in each mode.

- The flash memory can be configured in power-down mode. By default, it is not in power-down mode.
- The SRAMs can be powered on or off independently.
- Parity error interrupt or NMI wake-up from Stop mode.
- PWR voltage scaling is reset to range 2.
- RCC sysclk source is reset to HSI16.
- PTACONV interface signal levels can be retained on GPIOs.

8. Some peripherals with autonomous mode and wake-up from Stop capability can request HSI16 to be enabled. In this case, the oscillator is woken up by the peripheral, and is automatically put off when no peripheral needs it.
9. The 2.4 GHz RADIO peripheral in autonomous mode request HSE32 to be enabled. In this case, the oscillator is kept active by the peripheral, and is automatically put off when it no longer needs it.
10. I/O levels can be retained with pull-up, pull-down, or floating.
11. There are 16 wake-up pins available.
12. UART and LPUART reception and transmission are functional and autonomous in Stop mode in asynchronous and in SPI master modes, and generate a wake-up interrupt on transfer events.
13. I2C reception and transmission is functional and autonomous in Stop mode and generates a wake-up interrupt on transfer events.
14. SPI reception and transmission is functional and autonomous in Stop mode and generates a wake-up interrupt on transfer events.
15. A/D conversion is functional and autonomous in Stop mode, and generates a wake-up interrupt on conversion events.
16. LPTIM is functional and autonomous in Stop mode, and generates a wake-up interrupt on events.
17. GPDMA transfers are functional and autonomous in Stop 0 mode, and generates a wake-up interrupt on transfer events.
18. DBGMCU remains accessible through AP0.
19. DBGMCU remains accessible through AP0 when CDBGPWRUPREQ is set.

### 3.12.3 Reset mode

To improve the consumption under reset, the I/Os state under and after reset is “analog state” (the I/O Schmitt trigger is disabled). In addition, the internal reset pull-up is deactivated when the reset source is internal.

### 3.12.4 PWR TrustZone security

When TrustZone security is activated by the TZEN option bit, the PWR is switched in TrustZone security mode.

The PWR TrustZone security secures the following configuration:

- Low-power mode
- WKUP (wake-up) pins
- Voltage detection
- Backup domain control

Some of the PWR configuration bits security is defined by the security of other peripherals:

- The VOS (voltage scaling) configuration is secure when the system clock selection is secure in RCC.
- The I/O Standby mode retention configuration is secure when the corresponding GPIO is secure.

## 3.13 Reset and clock controller (RCC)

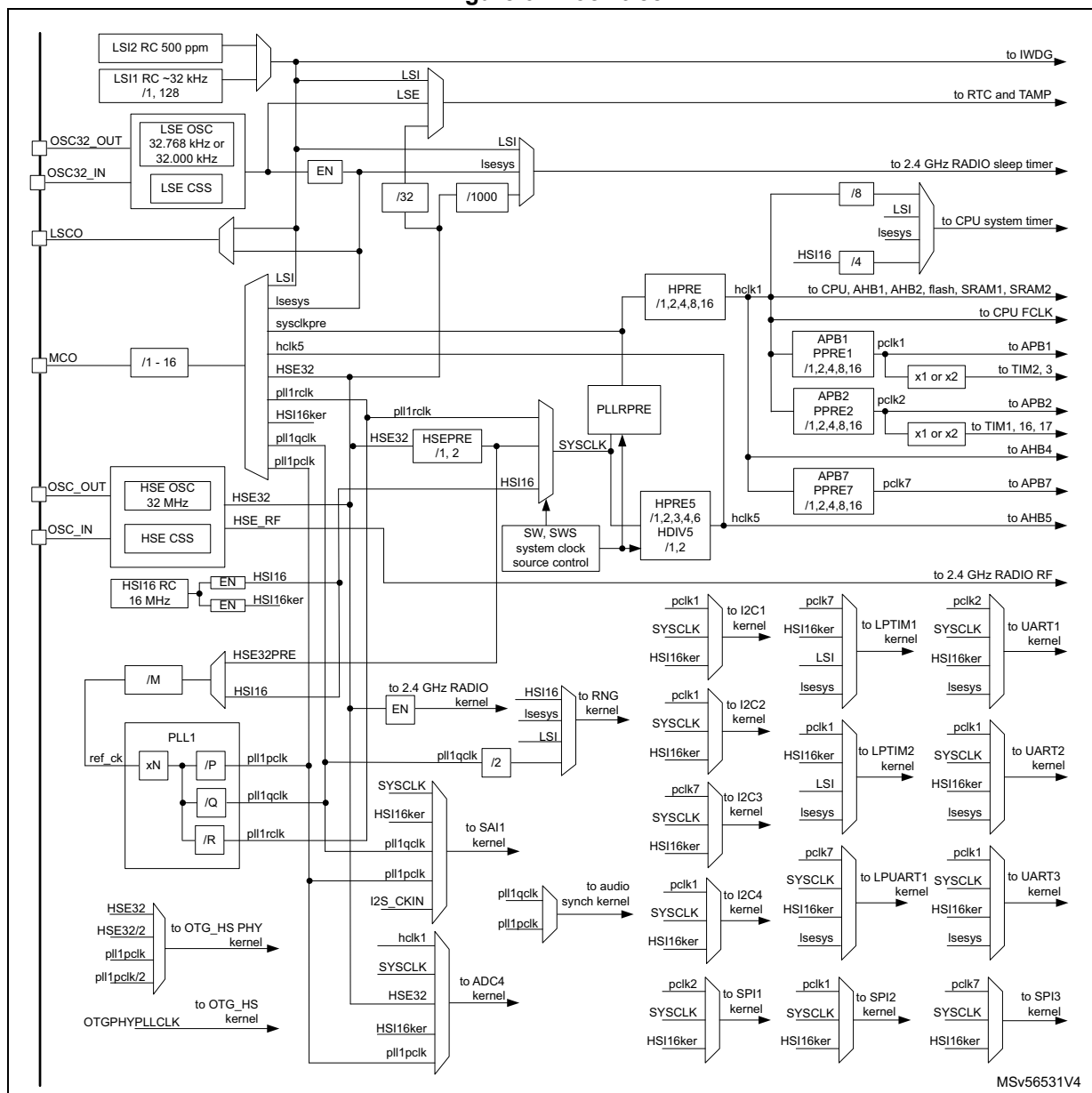
The RCC (reset and clock controller) manages device and peripheral reset and distributes the clocks coming from the different oscillators to the core and to the peripherals. It also manages the clock gating for low-power modes and ensures the clock robustness. It features:

- Device reset source monitoring.

- Individual peripheral reset control.
- Clock prescaler: to get the best trade-off between speed and current consumption, the clock frequency to the CPU and peripherals can be adjusted by a programmable prescaler.
- Clock selection system: clock sources can be changed safely on-the-fly in Run mode through a configuration register.
- Clock management: in order to reduce the power consumption, the clock controller can stop the clock to the core, individual peripherals or memory.
- System clock source: different clock sources can be used to drive the system clock SYSCLK:
  - HSE32 (32 MHz high-speed external crystal oscillator), trimmable by software. The HSE32 can also be used with an external clock.
  - HSI16 (16 MHz high-speed internal RC oscillator), trimmable by software.
  - System PLL, can be fed by HSE32 or HSI16 with a maximum output frequency at 100 MHz.
- Auxiliary clock source: two ultra-low-power clock sources that can be used to drive e.g. the real-time clock:
  - LSE (32.000 kHz or 32.768 kHz low-speed external crystal oscillator), supporting programmable drive capability modes. The LSE can also be configured in bypass mode for an external clock.
  - LSI (~32 kHz low-speed internal RC oscillators), also used to drive the independent watchdog.  
The LSI1 clock absolute accuracy is  $\pm 5\%$ , it can be divided by 128 to output a 250 Hz source clock.  
The LSI2 clock has a high stability,  $\pm 500$  ppm. It can be used to drive the 2.4 GHz RADIO sleep timer.
- Peripheral clock sources: several peripherals have their own independent kernel clock whatever the system clock. The PLL has three independent outputs allowing the highest flexibility and can generate clocks for the ADC, SAI, USB OTG and the RNG.
- Startup clock: after reset, the microcontroller restarts by default with the HSI16. The prescaler ratio and clock source can be changed by the application program as soon as the code execution starts.
- CSS (Clock security systems): these features can be enabled by software.
  - If a HSE32 clock failure occurs, the system clock automatically switches to HSI16 and a software interrupt is generated if enabled.
  - LSE failure can also be detected and generates an interrupt, in this case the clock switches to LSI.
- Clock-out capability:
  - MCO (microcontroller clock output): outputs one of the internal clocks for external use by the application. (only available in Run, Sleep and Stop mode)
  - LSCO (low-speed clock output): outputs LSI or LSE in all operating modes.

Several prescalers allow AHB and APB frequencies configuration. The maximum frequency of the AHB and the APB clock domains is 100 MHz, except for AHB5 domain, which is limited to maximum 32 MHz.

Figure 6. Clock tree



### 3.13.1 RCC TrustZone security

When the TrustZone security is activated by the TZEN option bit, the RCC is switched in TrustZone security mode.

The RCC TrustZone security secures some RCC system configuration and peripheral configuration from being read or modified by nonsecure accesses: when a peripheral is secure, the related peripheral clock, reset, clock source selection and clock enable during low-power modes control bits are secure.

A peripheral is in secure state:

- For securable peripherals, when the corresponding SEC security bit is set in the TZSC (TrustZone security controller).
- For TrustZone-aware peripherals, when a security feature of the peripheral is enabled through dedicated peripheral bits.

## 3.14 General-purpose input/output (GPIO)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain), as input (with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions.

After reset, all GPIOs are in analog mode to reduce power consumption.

The I/Os alternate function configuration can be locked, if needed, following a specific sequence, to avoid spurious writing to the I/Os registers.

The GPIO allows dynamic I/O control in Stop 0 mode thanks to GPDMA1. All I/Os can be configured and controlled as input or output (open-drain or push-pull depending on GPIO configuration).

When enabled in the PWR, latest I/Os output level can be retained by pulling the I/Os high or low before entering Standby mode. I/O levels are retained after exit from Standby mode, until they are reconfigured by software.

### 3.14.1 GPIO using PD6 and PD7

PD6 and PD7 provide USB OTG\_HS functions, but they cannot be used for any other function, including GPIO. When USB OTG\_HS is not used, PD6 and PD7 must be kept in analog mode.

### 3.14.2 GPIO TrustZone security

Each I/O pin of GPIO port can be individually configured as secure. When the selected I/O pin is configured as secure, its corresponding configuration bits for alternate function, mode selection, I/O data are secure against a nonsecure access. The associated registers bit access is restricted to a secure software only. After reset, all GPIO ports are secure.

## 3.15 System configuration controller (SYSCFG)

The main purpose of the SYSCFG (system configuration controller) are the following:

- Managing robustness features
- Configuring FPU interrupts
- Enabling/disabling the I<sup>2</sup>C fast-mode plus (FMP) high-drive mode of some I/Os and booster for I/Os analog switches
- Managing the I/O compensation
- Provides memory erase status
- Communication channel with the RSS

### 3.15.1 SYSCFG TrustZone security

When TrustZone security is activated by the TZEN option bit, the SYSCFG is switched in TrustZone security mode.

The SYSCFG TrustZone security secures the following configuration:

- FPU interrupt configuration
- Robustness features
- I/O compensation and memory erase status

Some of the SYSCFG configuration bits security is defined by the security of other peripherals:

- The FMP high-drive mode of some I/Os configuration is secure when the corresponding GPIO is secure.
- The booster for I/Os analog switches configuration is secure when the ADC4 is secure.

### 3.16 Peripheral interconnect matrix

Several peripherals have direct connections between them, enabling autonomous communication between them, and saving CPU resources (and power consumption). In addition, these hardware connections allow fast and predictable latency.

Depending on the peripherals, these interconnections can operate in Run, Sleep and Stop modes.

### 3.17 General purpose direct memory access controller (GPDMA)

The general purpose direct memory access (GPDMA) controller is a bus master and system peripheral.

The GPDMA is used to perform programmable data transfers between memory-mapped peripherals and/or memories via linked-lists, upon the control of an off-loaded CPU.

The GPDMA main features are:

- Dual bidirectional AHB master
- Memory-mapped data transfers from a source to a destination:
  - Peripheral-to-memory
  - Memory-to-peripheral
  - Memory-to-memory
  - Peripheral-to-peripheral
- Autonomous data transfers during Run, Sleep and Stop 0 modes
- Transfers arbitration based on a four-grade programmed priority at a channel level:
  - One high-priority traffic class, for time-sensitive channels (queue 3)
  - Three low-priority traffic classes, with a weighted round-robin allocation for nontime-sensitive channels (queues 0, 1, 2)
- Per channel event generation, on any of the following events: transfer complete or half transfer complete or data transfer error or user setting error, and/or update linked-list item error or completed suspension

- Per channel interrupt generation, with separately programmed interrupt enable per event
- Eight concurrent DMA channels:
  - Per channel FIFO for queuing source and destination transfers
  - Intra-channel DMA transfers chaining via programmable linked-list into memory, supporting two execution modes: run-to-completion and link step mode
  - Intra-channel and inter-channel DMA transfers chaining via programmable DMA input triggers connection to DMA task completion events
- Per linked-list item within a channel:
  - Separately programmed source and destination transfers
  - Programmable data handling between source and destination: byte-based reordering, packing or unpacking, padding or truncation, sign extension and left/right realignment
  - Programmable number of data bytes to be transferred from the source, defining the block level
  - Linear source and destination addressing: either fixed or contiguously incremented addressing, programmed at a block level, between successive single transfers
  - Programmable DMA request and trigger selection
  - Programmable DMA half-transfer and transfer complete events generation
  - Pointer to the next linked-list item and its data structure in memory, with automatic update of the DMA linked-list control registers
- Debug:
  - Channel suspend and resume support
  - Channel status reporting including FIFO level and event flags
- TrustZone support:
  - Support for secure and nonsecure DMA transfers, independently at a first channel level, and independently at a source/destination and link sub-levels
  - Secure and nonsecure interrupts reporting, resulting from any of the respectively secure and nonsecure channels
  - TrustZone-aware AHB slave port, protecting any DMA secure resource (register, register field) from a nonsecure access
- Privileged/unprivileged support:
  - Support for privileged and unprivileged DMA transfers, independently at a channel level
  - Privileged-aware AHB slave port.

Table 11. GPDMA1 channels implementation and usage

| Channel x  | Hardware parameters |                   | Features   |
|------------|---------------------|-------------------|--|
|            | dma_fifo_size[x]    | dma_addressing[x] |  |
| x = 0 to 5 | 2                   | 0                 | Channel x is implemented with: <ul style="list-style-type: none"> <li>– a FIFO of 8 bytes, 2 words</li> <li>– fixed/contiguously incremented addressing</li> </ul> These channels may be also used for GPDMA transfers, between an APB or AHB peripheral and SRAM.           |
| x = 6 to 7 | 4                   | 0                 | Channel x is implemented with: <ul style="list-style-type: none"> <li>– a FIFO of 32 bytes, 8 words</li> <li>– fixed/contiguously incremented addressing</li> </ul> These channels may be also used for GPDMA transfers, between a demanding AHB or APB peripheral and SRAM. |

Table 12. GPDMA1 autonomous mode and wake-up in low-power modes

| Feature                     | Low-power modes     |
|-----------------------------|---------------------|
| Autonomous mode and wake-up | Sleep, Stop 0 modes |

## 3.18 Interrupts and events

### 3.18.1 Nested vectored interrupt controller (NVIC)

The devices embed a nested vectored interrupt controller (NVIC) that is able to manage 16 priority levels and to handle up to 70 maskable interrupt vectors plus the 16 interrupt vectors of the Cortex-M33.

The NVIC benefits are the following:

- closely coupled NVIC giving low-latency interrupt processing
- interrupt entry vector table address passed directly to the core
- early processing of interrupts
- processing of late arriving higher priority interrupts
- support for tail chaining
- processor state automatically saved
- interrupt entry restored on interrupt exit with no instruction overhead
- TrustZone support: NVIC registers banked across secure and nonsecure states

The NVIC hardware block provides flexible interrupt management features with minimal interrupt latency.

### 3.18.2 Extended interrupt/event controller (EXTI)

The extended interrupts and event controller (EXTI) manages the individual CPU and system wake-up through configurable event inputs. It provides wake-up requests to the



power control, and generates an interrupt request to the CPU NVIC and events to the CPU event input.

The EXTI wake-up requests allow the system to be woken up from Stop modes.

The interrupt request and event request generation can also be used in Run and Sleep modes. The EXTI also includes the peripheral interconnect EXTI multiplexer I/O port selection.

The EXTI main features are the following:

- All event inputs allowed to wake up the system
- Configurable events (signals from I/Os or peripherals able to generate a pulse)
  - Selectable active trigger edge
  - Interrupt pending status register bit independent for the rising and falling edge
  - Individual interrupt and event generation mask, used for conditioning the CPU wake-up, interrupt and event generation
  - Software trigger possibility
- TrustZone secure events
  - The access to control and configuration bits of secure input events can be made secure
- EXTI I/O port selection for peripheral interconnect use.

### 3.19 Cyclic redundancy check calculation unit (CRC)

The CRC is used to get a CRC code using a configurable generator with polynomial value and size.

Among other applications, the CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a mean to verify the flash memory integrity.

The CRC calculation unit helps to compute a signature of the software during runtime, that can be ulteriorly compared with a reference signature generated at link-time and that can be stored at a given memory location.

### 3.20 Analog-to-digital converter (ADC4)

The devices embed one 12-bit successive approximation analog-to-digital converter.

**Table 13. ADC features**

| ADC modes/features <sup>(1)</sup>            | ADC4     |
|--|----------|
| Resolution                                   | 12 bits  |
| Maximum sampling speed for 12-bit resolution | 2.5 Msps |
| Hardware offset calibration                  | X        |
| Hardware linearity calibration               | -        |
| Single-ended inputs                          | X        |
| Differential inputs                          | -        |

Table 13. ADC features (continued)

| ADC modes/features <sup>(1)</sup> | ADC4       |
|-----------------------------------|------------|
| Injected channel conversion       | -          |
| Oversampling                      | Up to x256 |
| Data register                     | 16 bits    |
| DMA support                       | X          |
| Autonomous mode                   | X          |
| Offset compensation               | -          |
| Gain compensation                 | -          |
| Number of analog watchdogs        | 3          |
| Wake-up from Stop mode            | X          |

1. X = supported.

ADC4 has up to 19 multiplexed channels, allowing it to measure signals from up to 10 external and 3 internal sources (the other channels are reserved). The conversion of the various channels can be performed in Single, Continuous, Scan or Discontinuous mode. The result of is stored in a left-aligned or right-aligned 16-bit data register.

The analog watchdog feature allows the application to detect if the input voltage goes outside the user-defined higher or lower thresholds.

An efficient low-power mode is implemented to allow very low consumption at low frequency. The ADC4 is autonomous in low-power modes down to Stop modes.

A built-in hardware oversampler allows analog performances to be improved while off-loading the related computational burden from the CPU.

The ADC4 main features are:

- High performance
  - 12-, 10-, 8- or 6-bit configurable resolution
  - ADC conversion time: 0.4  $\mu$ s for 12-bit resolution (2.5 MHz), faster conversion times obtained by lowering resolution
  - Self-calibration
  - Programmable sampling time
  - Data alignment with built-in data coherency
  - DMA support
- Low-power
  - PCLK frequency reduced for low-power operation while still keeping optimum ADC performance
  - Wait mode: ADC overrun prevented in applications with low frequency PCLK
  - Auto-off mode: ADC automatically powered off except during the active conversion phase, dramatically reducing the ADC power consumption
  - Autonomous mode: in low-power modes (down to Stop 1), the ADC4 automatically switches on when a trigger occurs to start conversion, and it automatically switches off after conversion. Data are transferred to SRAM with DMA.
  - ADC4 interrupts wake up the device down to Stop 1 mode.

- Analog input channels
  - Up to 10 external analog inputs
  - One channel for the internal temperature sensor ( $V_{\text{SENSE}}$ )
  - One channel for the internal reference voltage ( $V_{\text{REFINT}}$ )
  - One channel for the internal digital core voltage ( $V_{\text{CORE}}$ )
- Start-of-conversion can be initiated:
  - By software
  - By hardware triggers with configurable polarity (timer events or GPIO input events)
- Conversion modes
  - Conversion of a single channel or scan of a sequence of channels
  - Selected inputs converted once per trigger in Single mode
  - Selected inputs converted continuously in Continuous mode
  - Discontinuous mode
- Interrupt generation at the end of sampling, end of conversion, end of sequence conversion, and in case of analog watchdog or overrun events, with wake-up from Stop capability
- Three analog watchdogs
- ADC supply requirements: 1.62 to 3.6 V
- ADC input range:  $V_{\text{SSA}} < V_{\text{IN}} < V_{\text{DDA}}$

*Note:* The ADC4 analog block clock frequency after the ADC4 prescaler must be between 140 kHz and 55 MHz.

*Note:*  $V_{\text{SSA}}$  is connected to package pin VSS.

### 3.20.1 Temperature sensor ( $V_{\text{SENSE}}$ )

The temperature sensor generates a voltage  $V_{\text{SENSE}}$  that varies linearly with temperature. The temperature sensor is internally connected to ADC4 input channel that is used to convert the sensor output voltage into a digital value.

The sensor provides good linearity but it must be calibrated to obtain a good accuracy of the temperature measurement. As the offset of the temperature sensor varies from chip to chip due to process variation, the uncalibrated internal temperature sensor is suitable for applications that detect temperature changes only.

To improve the accuracy of the temperature sensor measurement, each device is individually factory-calibrated by ST. The temperature sensor factory calibration data are stored by STMicroelectronics in the system memory area, accessible in read-only mode.

**Table 14. Temperature sensor calibration values**

| Calibration value name | Description   | Memory address            |
|------------------------|---|---------------------------|
| TS_CAL1                | Temperature sensor ADC4 12-bit raw data acquired at $(30 \pm 5) ^\circ\text{C}$ , $V_{\text{DDA}} = 3.0 \text{ V}$ ( $\pm 10 \text{ mV}$ )  | 0x0BFA 0710 - 0x0BFA 0711 |
| TS_CAL2                | Temperature sensor ADC4 12-bit raw data acquired at $(130 \pm 5) ^\circ\text{C}$ , $V_{\text{DDA}} = 3.0 \text{ V}$ ( $\pm 10 \text{ mV}$ ) | 0x0BFA 0742 - 0x0BFA 0743 |

### 3.20.2 Internal voltage reference ( $V_{REFINT}$ )

The internal voltage reference voltage  $V_{REFINT}$  provides a stable (bandgap) voltage for the ADC and comparators. The  $V_{REFINT}$  is internally connected to ADC4 input channel that is used to convert the voltage into a digital value.

The precise voltage of  $V_{REFINT}$  is individually measured for each part by STMicroelectronics during production test and stored in the system memory area. It is accessible in read-only mode.

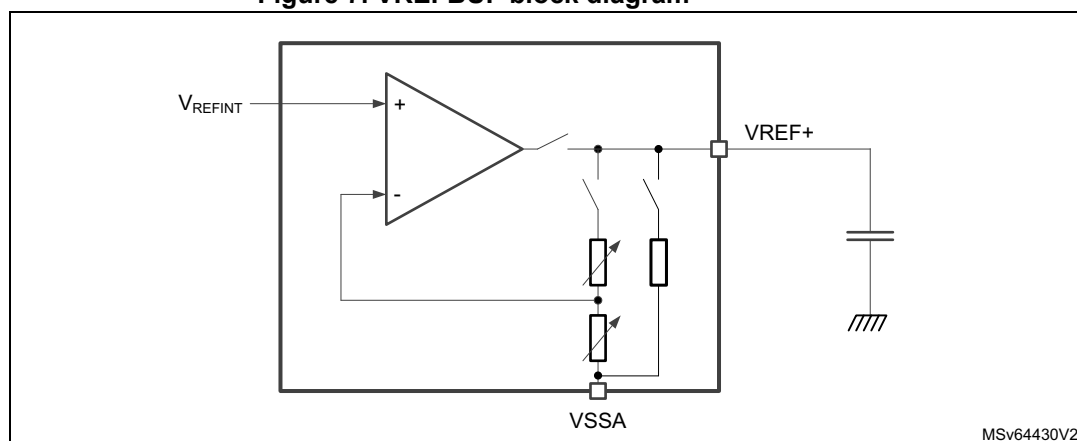
**Table 15. Internal voltage reference calibration values**

| Calibration value name | Description   | Memory address            |
|------------------------|---|---------------------------|
| VREFINT_CAL            | Internal voltage reference ADC4 12-bit raw data acquired at $(30 \pm 5) ^\circ\text{C}$ , $V_{DDA} = 3.0 \text{ V} (\pm 10 \text{ mV})$ | 0x0BFA 07A5 - 0x0BFA 07A6 |

### 3.21 Voltage reference buffer (VREFBUF)

The devices embed a voltage reference buffer (VREFBUF) that can be used as voltage reference for the ADC and external components through the VREF+ pin.

**Figure 7. VREFBUF block diagram**



The internal VREFBUF supports four voltages between 1.5 and 2.5 V, for more information see VREFBUF characteristics.

When the VREFBUF is disabled, an external voltage reference can be provided through the VREF+ pin.

### 3.22 Comparators (COMP)

The devices embed two rail-to-rail comparators, COMP1 and COMP2, with programmable reference voltage (internal or external), hysteresis and speed (low-speed for low-power) and with selectable output polarity.

The reference voltage can be one of the following:

- internal reference voltage or sub-multiple (1/4, 1/2, 3/4).
- external reference voltage on GPIO in function COMPx\_INM.

All comparators can wake up from Stop 0 and Stop 1 modes, generate interrupts and breaks for the timers and can also be combined into a window comparator.

### 3.23 Touch sensing controller (TSC)

The TSC (touch sensing controller) provides a simple solution to add capacitive sensing functionality to any application. A capacitive sensing technology is able to detect finger presence near an electrode that is protected from direct touch by a dielectric (glass, plastic or other). The capacitive variation introduced by the finger (or any conductive object) is measured using a proven implementation based on a surface charge transfer acquisition principle.

The TSC is fully supported by the STMTouch touch sensing firmware library that is free to use and allows touch sensing functionality to be implemented reliably in the end application.

The TSC main features are the following:

- Proven and robust surface charge transfer acquisition principle
- Support of up to 24 capacitive sensing channels
- Up to eight capacitive sensing channels can be acquired in parallel offering a very good response time
- Spread spectrum feature to improve system robustness in noisy environments
- Full hardware management of the charge transfer acquisition sequence
- Programmable charge transfer frequency
- Programmable sampling capacitor I/O pin
- Programmable channel I/O pin
- Programmable max count value to avoid long acquisition when a channel is faulty
- Dedicated end of acquisition and max count error flags with interrupt capability
- One sampling capacitor for up to three capacitive sensing channels to reduce the system components
- Compatible with proximity, touchkey, linear and rotary touch sensor implementation
- Designed to operate with STMTouch touch sensing firmware library

*Note:* The number of capacitive sensing channels is dependent on the packages and subject to I/O availability.

### 3.24 True random number generator (RNG)

The RNG is a true random number generator that provides full entropy outputs to the application as 32-bit samples. It is composed of a live entropy source (analog) and an internal conditioning component.

The RNG is a NIST SP 800-90B compliant entropy source that can be used to construct a nondeterministic random bit generator (NDRBG).

The true random generator:

- Delivers 32-bit true random numbers, produced by an analog entropy source conditioned by a NIST SP800-90B approved conditioning stage
- Can be used as entropy source to construct a nondeterministic random bit generator (NDRBG)
- Produces four 32-bit random samples every 412 AHB clock cycles if  $f_{\text{AHB}} < 77 \text{ MHz}$  (256 RNG clock cycles otherwise)
- Embeds start-up and NIST SP800-90B approved continuous health tests (repetition count and adaptive proportion tests), associated with specific error management
- Can be disabled to reduce power consumption, or enabled with an automatic low-power mode (default configuration)
- Has an AHB slave peripheral, accessible through 32-bit word single accesses only (else an AHB bus error is generated, and the write accesses are ignored)

### 3.25 Secure advanced encryption standard hardware accelerator (SAES) and encryption standard hardware accelerator (AES)

The devices embed two AES accelerators: SAES and AES. The SAES with hardware unique key embeds protection against differential power analysis (DPA) and related side channel attacks. The SAES can share its current key register information with the faster AES using a dedicated hardware bus.

The SAES and the AES can be used to both encrypt and decrypt data using the AES algorithm. It is a fully compliant implementation of the advanced encryption standard (AES) as defined by Federal Information Processing Standards Publication (FIPS PUB 197, Nov 2001).

Multiple chaining modes are supported for key sizes of 128 or 256 bits. ECB, CBC, CTR, CCM, GCM and GMAC chaining is supported by both SAES and AES.

SAES and AES support DMA single transfers for incoming and outgoing data (two DMA channels required).

The SAES supports the selection of all the following key sources, while the AES support only the first:

- 256-bit software key, written by the application in the key registers (write only)
- 256-bit DHUK (derived hardware unique key), computed inside the SAES engine from a nonvolatile OTP based RHUK (root hardware unique key)
- 256-bit BHK (boot hardware key), stored in tamper-resistant secure backup registers, written by a secure code during boot. Once written, this key cannot be read or write by any application until the next product reset.
- XOR of DHUK (provisioned chip secret) and BHK (software secret)

DHUK, BHK and their XOR are not visible by any software (even secure).

*Note: 128-bit key size can also be selected.*

*BHK key is cleared in case of tamper or RDP regression.*

*When the SAES is secure (respectively nonsecure), DHUK secure (respectively nonsecure) is used.*

The SAES peripheral is connected by hardware to the true random number generator RNG (for side-channel resistance).

The SAES and AES peripherals support:

- Compliant implementation of standard NIST *Special Publication 197, Advanced Encryption Standard (AES)* and *Special Publication 800-38A, Recommendation for Block Cipher Modes of Operation*
- 128-bit data block processing
- Support for cipher keys length of 128- and 256-bit
- Encryption and decryption with multiple chaining modes:
  - Electronic codebook (ECB) mode
  - Cipher block chaining (CBC) mode
  - Counter (CTR) mode
  - Galois counter mode (GCM)
  - Galois message authentication code (GMAC) mode
  - Counter with CBC-MAC (CCM) mode
- 528 or 743 clock cycle latency in ECB encryption mode for SAES processing one 128-bit block of data with, respectively, 128- or 256-bit key
- 51 or 75 clock cycle latency in ECB encryption mode for AES processing one 128-bit block of data with, respectively, 128- or 256-bit key
- Integrated round key scheduler to compute the last round key for AES ECB/CBC decryption
- 256-bit register for storing the cryptographic key (four 32-bit registers), with key atomicity enforcement
- 128-bit registers for storing initialization vectors (four 32-bit registers)
- One 32-bit input buffer and one 32-bit output buffer
- Automatic data flow control with support of single-transfer direct memory access (DMA) using two channels (one for incoming data, one for processed data)
- Data swapping logic to support 1-, 8-, 16- or 32-bit data
- Possibility for software to suspend a message if the SAES/AES needs to process another message with a higher priority (suspend/resume operation)
- SAES additional features:
  - Security context enforcement for keys
  - Hardware secret key encryption/ decryption (wrapped key mode) and sharing with faster AES peripheral (Shared key mode)
  - Protection against DPA (differential power analysis) and related side-channel attacks
  - Optional hardware loading of two hardware secret keys (BHK, DHUK) that can be XORed together

On top of standard AES encryption and decryption with a key loaded by software, SAES peripheral makes possible the following advanced use cases:

- Allow or deny the sharing of a key between a secure and a nonsecure application, enforced by hardware
- Encrypt once a key using side-channel resistant AES, then share it to a faster AES engine by decrypting it (Shared key mode)
- On-chip encrypted storage using secret DHUK

- Transport key generation by encrypting the device public unique ID with the application secret BHK
- Binding of device secure storage keys, using the secret derived hardware unique key (DHUK) XORed with the secret boot hardware key (BHK). If BHK is lost, the whole device secure storage is lost.

**Note:** *Encrypted storage or derived keys that are using DHUK or BHK, cannot be used anymore when a security breach is detected.*

**Table 16. AES/SAES features**

| AES/SAES modes/features <sup>(1)</sup> | AES | SAES |
|--|-----|------|
| ECB, CBC chaining                      | X   | X    |
| CTR, CCM, GCM chaining                 | X   | X    |
| AES 128-bit ECB encryption in cycles   | 51  | 528  |
| DHUK and BHK key selection             | -   | X    |
| Side-channel attacks resistance        | -   | X    |
| Shared key between SAES and AES        | X   |      |

1. X = supported.

### 3.26 HASH hardware accelerator (HASH)

The HASH is a fully compliant implementation of the secure hash algorithm (SHA-1, SHA2-224, SHA-256), the MD5 (message-digest algorithm 5) hash algorithm and the keyed-hash message authentication code (HMAC) algorithm. HMAC is suitable for applications requiring message authentication.

The HASH computes Federal information processing standards (FIPS) approved digests of length of 160, 224, 256 bits, for messages of up to  $(2^{64} - 1)$  bits. It also computes 128 bits digests for the MD5 algorithm.

The HASH main features are:

- Suitable for data authentication applications, compliant with:
  - Federal Information Processing Standards Publication FIPS PUB 180-4, *Secure Hash Standard* (SHA-1 and SHA-2 family)
  - Federal Information Processing Standards Publication FIPS PUB 186-4, *Digital Signature Standard* (DSS)
  - Internet Engineering Task Force (IETF) Request For Comments RFC 1321, *MD5 Message-Digest Algorithm*
  - Internet Engineering Task Force (IETF) Request For Comments RFC 2104, *HMAC: Keyed-Hashing for Message Authentication* and Federal Information Processing Standards Publication FIPS PUB 198-1, *The Keyed-Hash Message Authentication Code* (HMAC)
- Fast computation of SHA-1, SHA2-224, SHA-256, and MD5
  - 82 (respectively 66) clock cycles for processing one 512-bit block of data using SHA-1 (respectively SHA-256) algorithm
  - 66 clock cycles for processing one 512-bit block of data using MD5 algorithm



- Corresponding 32-bit words of the digest from consecutive message blocks are added to each other to form the digest of the whole message
  - Automatic 32-bit words swapping to comply with the internal little-endian representation of the input bit string
  - Word swapping supported: bits, bytes, half-words and 32-bit words
- Automatic padding to complete the input bit string to fit digest minimum block size of 512 bits ( $16 \times 32$  bits)
- Single 32-bit input register associated to an internal input FIFO of sixteen 32-bit words, corresponding to one block size
- AHB slave peripheral, accessible through 32-bit word accesses only (else an AHB error is generated)
- $8 \times 32$ -bit words (H0 to H7) for output message digest
- Automatic data flow control with support of direct memory access (DMA) using one channel. Single or fixed burst of 4 supported.
- Interruptible message digest computation, on a per-32-bit word basis
  - Re-loadable digest registers
  - Hashing computation suspend/resume mechanism, including using DMA

### 3.27 Public key accelerator (PKA)

The PKA is intended for the computation of cryptographic public key primitives, specifically those related to RSA, DH (Diffie-Hellmann) or (ECC) elliptic curve cryptography over GF(p) (Galois fields). To achieve high performance at a reasonable cost, these operations are executed in the Montgomery domain.

All needed computations are performed within the accelerator, so no further hardware/software elaboration is needed to process the inputs or the outputs.

The PKA main features are:

- Acceleration of RSA, DH and ECC over GF(p) operations, based on the Montgomery method for fast modular multiplications. More specifically:
  - RSA modular exponentiation, RSA CRT (Chinese remainder theorem) exponentiation
  - ECC scalar multiplication, point on curve check, complete addition, double base ladder, projective to affine
  - ECDSA signature generation and verification
- Capability to handle operands up to 4160 bits for RSA/DH and 640 bits for ECC
- Arithmetic and modular operations such as addition, subtraction, multiplication, modular reduction, modular inversion, comparison, and Montgomery multiplication
- Built-in Montgomery domain inward and outward transformations
- Protection against DPA (differential power analysis) and related side-channel attacks.

## 3.28 Timers and watchdogs

The devices include one advanced control timer, up to five general-purpose timers, two low-power timers, two watchdog timers and two SysTick timers.

[Table 17](#) compares the features of the advanced control, general-purpose and basic timers.

**Table 17. Timer feature comparison**

| Timer type       | Timer        | Counter resolution | Counter type      | Prescaler factor                | DMA request generation | Capture/compare channels | Complementary outputs |
|------------------|--------------|--------------------|-------------------|---------------------------------|------------------------|--------------------------|-----------------------|
| Advanced control | TIM1         | 16 bits            | Up, down, Up/down | Any integer between 1 and 65536 | Yes                    | 4                        | 3                     |
| General-purpose  | TIM2, TIM4   | 32 bits            | Up, down, Up/down |                                 |                        | 4                        | No                    |
|                  | TIM3,        | 16 bits            |                   |                                 |                        | 4                        | No                    |
|                  | TIM16, TIM17 |                    | Up                |                                 |                        | 1                        | 1                     |

### 3.28.1 Advanced-control timers (TIM1)

The advanced-control timers can each be seen as a three-phase PWM multiplexed on six channels. They have complementary PWM outputs with programmable inserted dead-times. They can also be seen as complete general-purpose timers.

The four independent channels can be used for:

- Input capture
- Output compare
- PWM generation (edge- or center-aligned modes) with full modulation capability (0 - 100%)
- One-pulse mode output

In Debug mode, the advanced-control timer counter can be frozen and the PWM outputs disabled in order to turn off any power switches driven by these outputs.

Many features are shared with the general-purpose TIMx timers (described in the next section) using the same architecture, so the advanced-control timers can work together with the TIMx timers via the *Timer Link* feature for synchronization or event chaining.

### 3.28.2 General-purpose timers (TIM2, TIM3, TIM4, TIM16, TIM17)

There are up to five synchronizable general-purpose timers embedded in the device (see [Table 17](#) for differences). Each general-purpose timer can be used to generate PWM outputs, or act as a simple time base.

- TIM2, TIM3 and TIM4
  - They are full-featured general-purpose timers with TIM2 and TIM4 32-bit auto-reload up/downcounter, TIM3 16-bit auto-reload up/downcounter, all with 16-bit prescaler.
  - These timers feature four independent channels for input capture/output compare, PWM or one-pulse mode output. They can work together, or with the other general-purpose timers via the *Timer Link* feature for synchronization or event chaining.
  - The counters can be frozen in Debug mode.
  - All have independent DMA request generation and support quadrature encoders.
- TIM16 and 17
  - They are general-purpose timers with mid-range features.
  - They have 16-bit auto-reload upcounters and 16-bit prescalers. and have one channel and one complementary channel.
  - All channels can be used for input capture/output compare, PWM or one-pulse mode output.
  - The timers can work together via the *Timer Link* feature for synchronization or event chaining. The timers have independent DMA request generation.
  - The counters can be frozen in Debug mode.
  - All have independent DMA request generation.

### 3.28.3 Low-power timers (LPTIM1, LPTIM2)

The devices embed two low-power timers. These timers have an independent clock and are running in Stop mode if they are clocked by HSI16, LSE, LSI or an external clock. They are able to wake up the system from Stop mode.

LPTIM1, LPTIM2 are active in Stop modes. Only LPTIM1 is active in Stop 2 mode.

The low-power timer supports the following features:

- 16-bit up counter with 16-bit autoreload register
- 3-bit prescaler with following possible dividing factors (1, 2, 4, 8, 16, 32, 64, 128)
- Selectable clock
  - Internal clock sources: LSE, LSI, HSI16 or APB clock
  - External clock source over LPTIM input (working with no LP oscillator running, used by *Pulse Counter* application)
- 16-bit ARR autoreload register
- 16-bit capture/compare register
- Continuous/One-shot mode
- Selectable software/hardware input trigger
- Programmable digital glitch filter
- Configurable output: pulse, PWM
- Configurable I/O polarity

- Encoder mode
- Repetition counter
- Up to two independent channels for:
  - Input capture
  - PWM generation (edge-aligned mode)
  - One-pulse mode output
- Interrupt generation on ten events
- DMA request generation on the following events:
  - Update event
  - Input capture

#### 3.28.4 Infrared interface (IRTIM)

An infrared interface (IRTIM) for remote control is available on the device. It can be used with an infrared LED to perform remote control functions. It uses internal connections with TIM16 and TIM17.

#### 3.28.5 Independent watchdog (IWDG)

The independent watchdog is based on a 12-bit downcounter and a 10-bit prescaler. It is clocked from the independent LSI and, as it operates independently from the main clock, it can operate in Stop and Standby modes. It can be used either as a watchdog to reset the device when a problem occurs, or as a free running timer for application timeout management. It is hardware or software enabled through the option bytes. The counter can be frozen in low-power and Debug mode.

#### 3.28.6 Window watchdog (WWDG)

The window watchdog is based on a 7-bit downcounter that can be set as free running. It can be used as a watchdog to reset the device when a problem occurs. It is clocked from the main clock. It has an early warning interrupt capability and the counter can be frozen in Debug mode.

#### 3.28.7 SysTick timer

The Cortex-M33 with TrustZone embeds two SysTick timers.

When TrustZone is activated, two SysTick timer are available:

- SysTick, secure instance
- SysTick, nonsecure instance

When TrustZone is disabled, only one SysTick timer is available.

This timer (secure or nonsecure) is dedicated to real-time operating systems, but can also be used as a standard down counter. It features:

- A 24-bit down counter
- Autoreload capability
- Maskable system interrupt generation when the counter reaches 0
- Programmable clock source

### 3.29 Real-time clock (RTC)

The real-time clock (RTC) is an independent BCD timer/counter. The RTC provides a time-of-day clock/calendar with programmable alarm interrupts.

As long as the VDD supply voltage remains in the operating range, the RTC never stops, regardless of the device status (Run mode, low-power mode or under reset).

The RTC supports the following features:

- Calendar with subsecond, seconds, minutes, hours (12 or 24 format), weekday, date, month, year, in binary-coded decimal (BCD) format
- Binary mode with 32-bit free-running counter
- Automatic correction for 28, 29 (leap year), 30, and 31 days of the month
- Two programmable alarms
- On-the-fly correction from 1 to 32767 RTC clock pulses. This can be used to synchronize it with a reference clock
- Reference clock detection: a more precise second source clock (50 or 60 Hz) can be used to enhance the calendar precision
- Digital calibration circuit with 0.95 ppm resolution, to compensate for quartz crystal inaccuracy
- Timestamp feature that can be used to save the calendar content. This function can be triggered by an event on the timestamp pin, or by a tamper event
- 17-bit auto-reload wake-up timer (WUT) for periodic events with programmable resolution and period
- TrustZone support:
  - RTC fully securable
  - Alarm A, alarm B, wake-up timer and timestamp individual secure or nonsecure configuration
  - Alarm A, alarm B, wake-up timer and timestamp individual privileged protection

The RTC is supplied from the V<sub>DD</sub> supply.

The RTC clock sources can be one of the following:

- LSE, used as 32.768 kHz external crystal oscillator
- LSE, with external resonator or oscillator
- LSI, internal low-power RC oscillator (with typical frequency of 32 kHz)
- HSE32, high-speed external clock divided by a prescaler in the RCC.

The RTC is functional in all low-power modes when it is clocked by the LSE or LSI.

All RTC events (alarm, wake-up timer, timestamp) can generate an interrupt and wake up the device from the low-power modes.

### 3.30 Tamper and backup registers (TAMP)

The anti-tamper detection circuit is used to protect sensitive data from external attacks. 32 32-bit backup registers are retained in all low-power modes. The backup registers, as well as other secrets in the device, are protected by this anti-tamper detection circuit with six tamper pins and nine internal tampers. The external tamper pins can be configured for level

detection with or without filtering, or active tamper that increases the security level by auto checking that the tamper pins are not externally opened or shorted.

TAMP main features:

- A tamper detection can erase the backup registers, SRAM2, ICACHE and cryptographic peripherals.
- 32 32-bit backup registers:
  - The backup registers (TAMP\_BKPxR) are implemented in the Backup domain that remains powered-on by  $V_{DD}$  power.
- Up to six tamper pins for six external tamper detection events:
  - Active tamper mode: continuous comparison between tamper output and input to protect from physical open-short attacks
  - Flexible active tamper I/O management: from three meshes (each input associated to its own exclusive output) to five meshes (single output shared for up to five tamper inputs)
  - Passive tampers: ultra-low-power edge or level detection with internal pull-up hardware management
  - Configurable digital filter
- Nine internal tamper events to protect against transient or environmental perturbation attacks:
  - LSE monitoring
  - RTC calendar overflow
  - JTAG/SWD access if RDP different from 0
  - Monotonic counter overflow
  - Cryptographic peripherals fault (RNG, SAES, AES, PKA)
  - Independent watchdog reset when tamper flag is already set
  - Three ADC4 watchdogs
- Each tamper can be configured in two modes:
  - Hardware mode: immediate erase of secrets on tamper detection, including backup registers erase
  - Software mode: erase of secrets following a tamper detection launched by software
- Any tamper detection can generate a RTC time stamp event.
- TrustZone support:
  - Tamper secure or nonsecure configuration.
  - Backup registers configuration in three configurable-size areas:
    - a read/write secure area
    - a write secure/read nonsecure area
    - a read/write nonsecure area
  - Secret boot hardware key (BHK) only usable by secure SAES peripheral, stored in backup registers, protected against read and write access
- Tamper configuration and backup registers privilege protection
- Monotonic counter

### 3.31 Inter-integrated circuit interface (I2C)

The device embeds up to four I2C, refer to [Table 18](#) for the features implementation.

The I<sup>2</sup>C bus interface handles communications between the microcontroller and the serial I<sup>2</sup>C bus. It controls all I<sup>2</sup>C bus-specific sequencing, protocol, arbitration and timing.

The I2C peripheral supports:

- I<sup>2</sup>C-bus specification and user manual rev. 5 compatibility:
  - Controller and target modes, multicontroller capability
  - Standard-mode (Sm), with a bit rate up to 100 Kbit/s
  - Fast-mode (Fm), with a bit rate up to 400 Kbit/s
  - Fast-mode Plus (Fm+), with a bit rate up to 1 Mbit/s and 20 mA output drive I/Os
  - 7-bit and 10-bit addressing mode, multiple 7-bit slave addresses
  - Programmable setup and hold times
  - Optional clock stretching
- System management bus (SMBus) specification rev 3.0 compatibility:
  - Hardware packet error checking (PEC) generation and verification with ACK control
  - Address resolution protocol (ARP) support
  - SMBus alert
- Power system management protocol (PMBus) specification rev 1.3 compatibility
- Independent clock: a choice of independent clock sources allowing the I2C communication speed to be independent from the PCLK reprogramming
- Autonomous functionality in Stop modes with wake-up from Stop capability
- Programmable analog and digital noise filters
- 1-byte buffer with DMA capability

**Table 18. I2C implementation**

| I2C features <sup>(1)</sup>                                  | I2C1 | I2C2 | I2C3 | I2C4 |
|--|------|------|------|------|
| Standard-mode (up to 100 Kbit/s)                             | X    | X    | X    | X    |
| Fast-mode (up to 400 Kbit/s)                                 | X    | X    | X    | X    |
| Fast-mode Plus with 20 mA output drive I/Os (up to 1 Mbit/s) | X    | X    | X    | X    |
| Programmable analog and digital noise filters                | X    | X    | X    | X    |
| SMBus/PMBus hardware support                                 | X    | X    | X    | X    |
| Independent clock  | X    | X    | X    | X    |
| Autonomous in Stop 0, 1 modes with wake-up capability        | X    | X    | X    | X    |
| Wake-up capability in Stop 2 mode                            | -    | -    | X    | -    |

1. X: supported

### 3.32 Universal synchronous/asynchronous receiver transmitter (USART) and low-power universal asynchronous receiver transmitter (LPUART)

The devices have up to three embedded universal synchronous receiver transmitters (USART1, USART2, USART3) and one low-power universal asynchronous receiver transmitter (LPUART1).

**Table 19. USART and LPUART features**

| USART modes/features <sup>(1)</sup>                   | USART1           | USART2 | USART3 | LPUART1 |
|---|------------------|--------|--------|---------|
| Hardware flow control for modem                       | X                | X      | X      | X       |
| Continuous communication using DMA                    | X                | X      | X      | X       |
| Multiprocessor communication                          | X                | X      | X      | X       |
| Synchronous mode (master/slave)                       | X                | X      | X      | -       |
| Smartcard mode  | X                | X      | X      | -       |
| Single-wire half-duplex communication                 | X                | X      | X      | X       |
| IrDA SIR ENDEC block                                  | X                | X      | X      | -       |
| LIN mode  | X                | X      | X      | -       |
| Dual-clock domain, wake-up from Stop modes            | X                | X      | X      | X       |
| Dual-clock domain, wake-up from Stop 2 modes          | -                | -      | -      | X       |
| Receiver timeout interrupt                            | X                | X      | X      | -       |
| Modbus communication                                  | X                | X      | X      | -       |
| Auto-baud rate detection                              | X                | X      | X      | -       |
| Driver enable   | X                | X      | X      | X       |
| USART data length                                     | 7, 8, and 9 bits |        |        |         |
| Tx/Rx FIFO  | X                | X      | X      | X       |
| Tx/Rx FIFO size                                       | 8 bytes          |        |        |         |
| Autonomous in Stop 0, 1 modes with wake-up capability | X                | X      | X      | X       |
| Wake-up capability in Stop 2 mode                     | -                | -      | -      | X       |

1. X = supported.

#### 3.32.1 USART

The USART offers a flexible means to perform full-duplex data exchange with external equipments requiring an industry standard NRZ asynchronous serial data format. A very wide range of baud rates can be achieved through a fractional baud rate generator.

The USART supports both synchronous one-way and half-duplex single-wire communications, as well as LIN (local interconnection network), Smartcard protocol, IrDA (infrared data association) SIR ENDEC specifications, and modem operations (CTS/RTS). Multiprocessor communications are also supported.

High-speed data communications up to 20 Mbauds are possible by using the direct memory access (DMA) for multibuffer configuration.



The USART main features are:

- Full-duplex asynchronous communication
- NRZ standard format (mark/space)
- Configurable oversampling method by 16 or 8 to achieve the best compromise between speed and clock tolerance
- Baud rate generator systems
- Two internal FIFOs for transmit and receive data  
Each FIFO can be enabled/disabled by software and come with a status flag.
- A common programmable transmit and receive baud rate
- Dual-clock domain with dedicated kernel clock for peripherals independent from PCLK
- Auto baud rate detection
- Programmable data word length (7, 8 or 9 bits)
- Programmable data order with MSB-first or LSB-first shifting
- Configurable stop bits (1 or 2 stop bits)
- Synchronous Master/Slave mode and clock output/input for synchronous communications
- SPI slave transmission underrun error flag
- Single-wire half-duplex communications
- Continuous communications using DMA
- Received/transmitted bytes are buffered in reserved SRAM using centralized DMA
- Separate enable bits for transmitter and receiver
- Separate signal polarity control for transmission and reception
- Swappable Tx/Rx pin configuration
- Hardware flow control for modem and RS-485 transceiver
- Communication control/error detection flags
- Parity control:
  - Transmits parity bit
  - Checks parity of received data byte
- Interrupt sources with flags
- Multiprocessor communications: wake-up from Mute mode by idle line detection or address mark detection
- Autonomous functionality in Stop mode with wake-up from stop capability
- LIN master synchronous break send capability and LIN slave break detection capability
  - 13-bit break generation and 10/11-bit break detection when USART is hardware configured for LIN
- IrDA SIR encoder decoder supporting 3/16-bit duration for Normal mode
- Smartcard mode
  - Supports the T = 0 and T = 1 asynchronous protocols for smartcards as defined in the ISO/IEC 7816-3 standard
  - 0.5 and 1.5 stop bits for Smartcard operation
- Support for Modbus communication
  - Timeout feature
  - CR/LF character recognition

### 3.32.2 LPUART

The LPUART supports bidirectional asynchronous serial communication with minimum power consumption. It also supports half-duplex single-wire communication and modem operations (CTS/RTS). It allows multiprocessor communication.

Only a 32.768 kHz clock (LSE) is needed to allow LPUART communication up to 9600 baud. Therefore, even in Stop mode, the LPUART can wait for an incoming frame while having an extremely low energy consumption. Higher-speed clock can be used to reach higher baudrates.

The LPUART interface can be served by the DMA controller.

The LPUART main features are:

- Full-duplex asynchronous communications
- NRZ standard format (mark/space)
- Programmable baud rate
- From 300 to 9600 baud/s using a 32.768 kHz clock source
- Higher baud rates can be achieved by using a higher frequency clock source
- Two internal FIFOs to transmit and receive data (each FIFO can be enabled/disabled by software and come with status flags for FIFOs states)
- Dual-clock domain with dedicated kernel clock for peripherals independent from PCLK
- Programmable data word length (7 or 8 or 9 bits)
- Programmable data order with MSB-first or LSB-first shifting
- Configurable stop bits (1 or 2 stop bits)
- Single-wire half-duplex communications
- Continuous communications using DMA
- Received/transmitted bytes are buffered in reserved SRAM using centralized DMA
- Separate enable bits for transmitter and receiver
- Separate signal polarity control for transmission and reception
- Swappable Tx/Rx pin configuration
- Hardware flow control for modem and RS-485 transceiver
- Transfer detection flags:
  - Receive buffer full
  - Transmit buffer empty
  - Busy and end of transmission flags
- Parity control:
  - Transmits parity bit
  - Checks parity of received data byte
- Four error detection flags:
  - Overrun error
  - Noise detection
  - Frame error
  - Parity error
- Interrupt sources with flags

- Multiprocessor communications: wake-up from Mute mode by idle line detection or address mark detection
- Autonomous functionality in Stop modes with wake-up.

### 3.33 Serial peripheral interface (SPI)

The devices embed up to three serial peripheral interfaces (SPI) that can be used to communicate with external devices while using the specific synchronous protocol. The SPI protocol supports half-duplex, full-duplex and simplex synchronous, serial communication with external devices.

The interface can be configured as master or slave and can operate in multislave or multimaster configurations. The device configured as master provides communication clock (SCK) to the slave device. The slave select (SS) and ready (RDY) signals can be applied optionally just to setup communication with concrete slave and to assure it handles the data flow properly. The Motorola data format is used by default, but some other specific modes are supported as well.

The SPI main features are:

- Full-duplex synchronous transfers on three lines
- Half-duplex synchronous transfer on two lines (with bidirectional data line)
- Simplex synchronous transfers on two lines (with unidirectional data line)
- 4-bit to 32-bit data size selection or fixed to 8-bit and 16-bit only
- Multimaster or multislave mode capability
- Dual-clock domain, separated clock for the peripheral kernel that can be independent of PCLK
- Baud rate prescaler up to kernel frequency/2 or bypass from RCC in master mode
- Protection of configuration and setting
- Hardware or software management of SS for both master and slave
- Adjustable minimum delays between data and between SS and data flow
- Configurable SS signal polarity and timing, MISO and MOSI swap capability
- Programmable clock polarity and phase
- Programmable data order with MSB-first or LSB-first shifting
- Programmable number of data within a transaction to control SS and CRC
- Dedicated transmission and reception flags with interrupt capability
- SPI Motorola and TI formats support
- Hardware CRC feature can secure communication at the end of transaction by:
  - Adding CRC value in Tx mode
  - Automatic CRC error checking for Rx mode
- Error detection with interrupt capability in case of data overrun, CRC error, data underrun at slave, mode fault at master
- Two 16 x or 8 x 8-bit embedded Rx and TxFIFOs with DMA capability
- Programmable number of data in transaction
- Configurable FIFO thresholds (data packing)
- Configurable behavior at slave underrun condition (support of cascaded circular buffers)

- Autonomous functionality in Stop modes (handling of the transaction flow and required clock distribution) with wake-up from stop capability
- Optional status pin RDY signaling the slave device ready to handle the data flow.

**Table 20. SPI features**

| <b>Feature<sup>(1)</sup></b>                             | <b>SPI1, SPI2<br/>(full feature set instances)</b>       | <b>SPI3<br/>(limited feature set instance)</b>           |
|--|--|--|
| Data size  | Configurable from 4- to 32-bit                           | 8- and 16-bit  |
| CRC computation  | CRC polynomial length,<br>configurable from 5- to 33-bit | CRC polynomial length,<br>configurable from 9- to 17-bit |
| Size of FIFOs  | 16 x 8-bit   | 8 x 8-bit  |
| Number of transfered data                                | Unlimited, expandable                                    | Up to 1024, no data counter                              |
| Autonomous in Stop 0, 1 modes<br>with wake-up capability | X  | X  |
| Wake-up capability in Stop 2 mode                        | -  | X  |

1. X: supported

### 3.34 Serial audio interfaces (SAI)

The devices embed one SAI, see [Table 21](#) for its features. The SAI bus interface handles communications between the microcontroller and the serial audio protocol.

The SAI peripheral supports:

- Two independent audio sub-blocks that can be transmitters or receivers with their respective FIFOs
- 8-word integrated FIFOs for each audio sub-block
- Synchronous or Asynchronous mode between the audio sub-blocks
- Master or slave configuration independent for both audio sub-blocks
- Clock generator for each audio block to target independent audio frequency sampling when both audio sub-blocks are configured in master mode
- Data size configurable: 8-, 10-, 16-, 20-, 24- and 32-bit
- Peripheral with large configurability and flexibility allowing to target as example the following audio protocol: I<sup>2</sup>S, LSB or MSB-justified, PCM/DSP, TDM, AC'97 and SPDIF out
- Up to 16 slots available with configurable size and with the possibility to select which ones are active in the audio frame
- Number of bits by frame may be configurable
- Frame synchronization active level configurable (offset, bit length, level)
- First active bit position in the slot is configurable
- LSB first or MSB first for data transfer
- Mute mode
- Stereo/mono audio frame capability
- Communication clock strobing edge configurable (SCK)
- Error flags with associated interrupts if enabled respectively
  - Overrun and underrun detection
  - Anticipated frame synchronization signal detection in Slave mode
  - Late frame synchronization signal detection in Slave mode
  - Codec not ready for the AC'97 mode in reception
- Interruption sources when enabled:
  - Errors
  - FIFO requests
- DMA interface with two dedicated channels to handle access to the dedicated integrated FIFO of each SAI audio sub-block

**Table 21. SAI implementation**

| Features  | SAI1 |
|---|------|
| I <sup>2</sup> S, LSB or MSB-justified, PCM/DSP, TDM, AC'97 | X    |
| Mute mode   | X    |
| Stereo/mono audio frame capability                          | X    |
| 16 slots  | X    |
| Data size configurable: 8-, 10-, 16-, 20-, 24-, and 32-bit  | X    |

Table 21. SAI implementation (continued)

| Features  | SAI1        |
|-----------|-------------|
| FIFO size | X (8 words) |
| SPDIF     | X           |
| PDM       | X           |

### 3.35 USB on-the-go high-speed (USB OTG)

The devices embed an USB OTG high-speed device/host peripheral with integrated transceivers. This peripheral is compliant with the USB 2.0 specification. It has software-configurable endpoint setting, and supports suspend/resume.

This interface requires a precise 60 MHz clock that is generated from the internal USB OTG HS PHY PLL (the clock source must use the HSE crystal oscillator).

The USB OTG HS features are:

- USB-IF certified to the Universal Serial Bus Specification Rev 2.0
- On-chip high-speed PHY
- Full support (PHY)
  - Integrated support for A-B device identification (ID line)
  - Supports monitoring of  $V_{BUS}$  levels with internal comparators
- Software-configurable to operate as USB high-speed device/host role device
- Supports HS/FS SOF and LS keep-alives with
  - SOF pulse PAD connectivity
  - SOF pulse internal connection to timer (TIMx)
  - Configurable framing period
  - Configurable end of frame interrupt
- Internal DMA with thresholding support and software selectable AHB burst type in DMA mode
- Power saving features, such as system stop during USB OTG suspend, switch-off of clock domains internal to the digital core, PHY and DFIFO power management
- Dedicated RAM of 4 Kbytes with advanced FIFO control:
  - Configurable partitioning of RAM space into different FIFOs for flexible and efficient use of RAM
  - Each FIFO able to hold multiple packets
  - Dynamic memory allocation
  - Configurable FIFO sizes that are not powers of two to allow the use of contiguous memory locations
- Max guaranteed USB bandwidth for up to one frame (1 ms) without system intervention

Host-mode features:

- External charge pump for  $V_{BUS}$  voltage generation
- Up to 16 host channels (pipes): each channel is dynamically reconfigurable to allocate any type of USB transfer
- Built-in hardware scheduler holding:

- Up to 16 interrupt plus isochronous transfer requests in the periodic hardware queue
- Up to 16 control plus bulk transfer requests in the nonperiodic hardware queue
- Management of a shared Rx FIFO, a periodic Tx FIFO and a nonperiodic Tx FIFO for efficient usage of the USB data RAM

Peripheral-mode features:

- 1 bidirectional control endpoint0
- 8 IN endpoints (EPs) configurable to support bulk, interrupt or isochronous transfers
- 8 OUT endpoints configurable to support bulk, interrupt or isochronous transfers
- Management of a shared Rx FIFO and a Tx-OUT FIFO for efficient usage of the USB data RAM
- Management of up to 9 dedicated Tx-IN FIFOs (one for each active IN EP) to put less load on the application
- Support for the soft disconnect feature

## 3.36 Development support

### 3.36.1 Serial-wire/JTAG debug port (SWJ-DP)

The Arm SWJ-DP interface is embedded and is a combined JTAG and serial-wire debug port that enables either a serial wire debug or a JTAG probe to be connected to the target.

Debug is performed using two pins only instead of five required by the JTAG (JTAG pins can be re-used as GPIO with alternate function): the JTAG TMS and TCK pins are shared with SWDIO and SWCLK, respectively, and a specific sequence on the TMS pin is used to switch between JTAG-DP and SW-DP.

### 3.36.2 Embedded Trace Macrocell (ETM)

The Arm embedded trace macrocell (ETM) provides a greater visibility of the instruction and data flow inside the CPU core by streaming compressed data at a very high rate from the device through a small number of ETM pins to an external hardware trace port analyzer (TPA) device.

Real-time instruction and data flow activity is recorded and then formatted for display on the host computer that runs the debugger software. PTA hardware is commercially available from common development tools vendors.

The ETM operates with third party debugger software tools.

# 4 Pinout, pin description, and alternate functions

## 4.1 Pinout/ballout schematics

Figure 8. UFQFPN48\_USB pinout

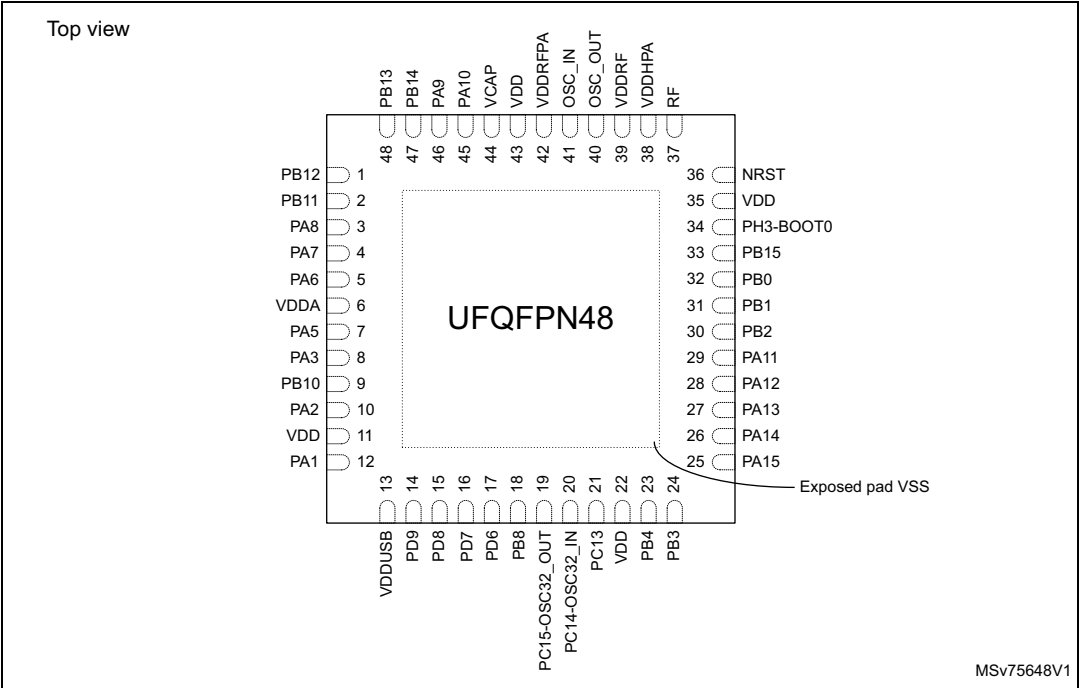


Figure 9. UFQFPN48\_SMPS pinout

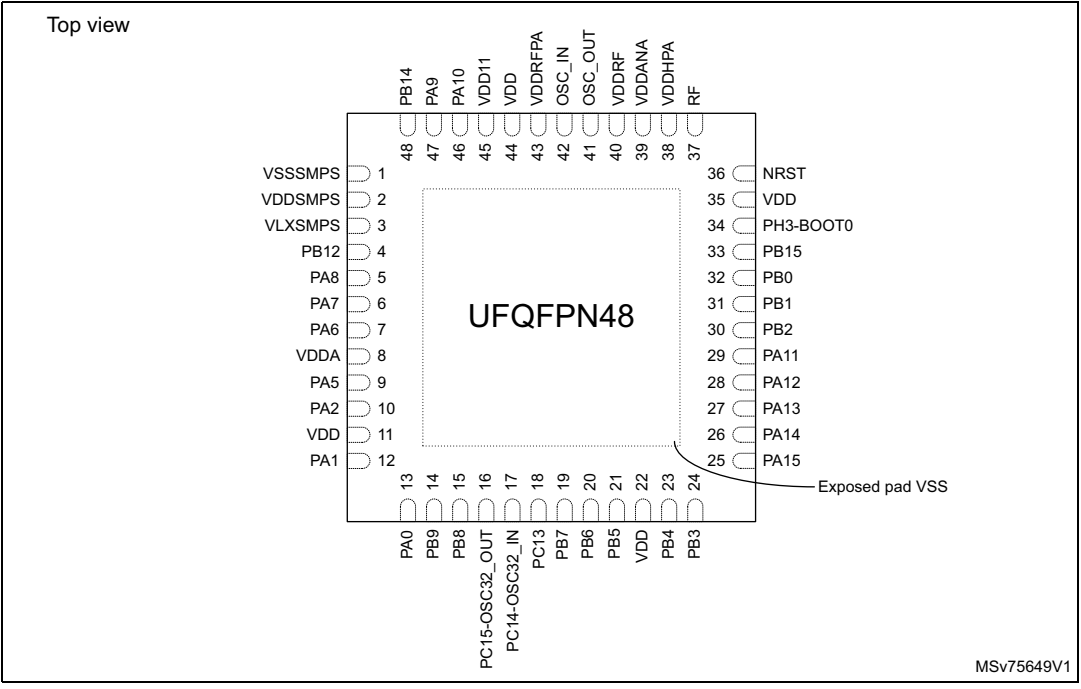




Figure 10. UFQFPN48\_SMPS\_USB pinout

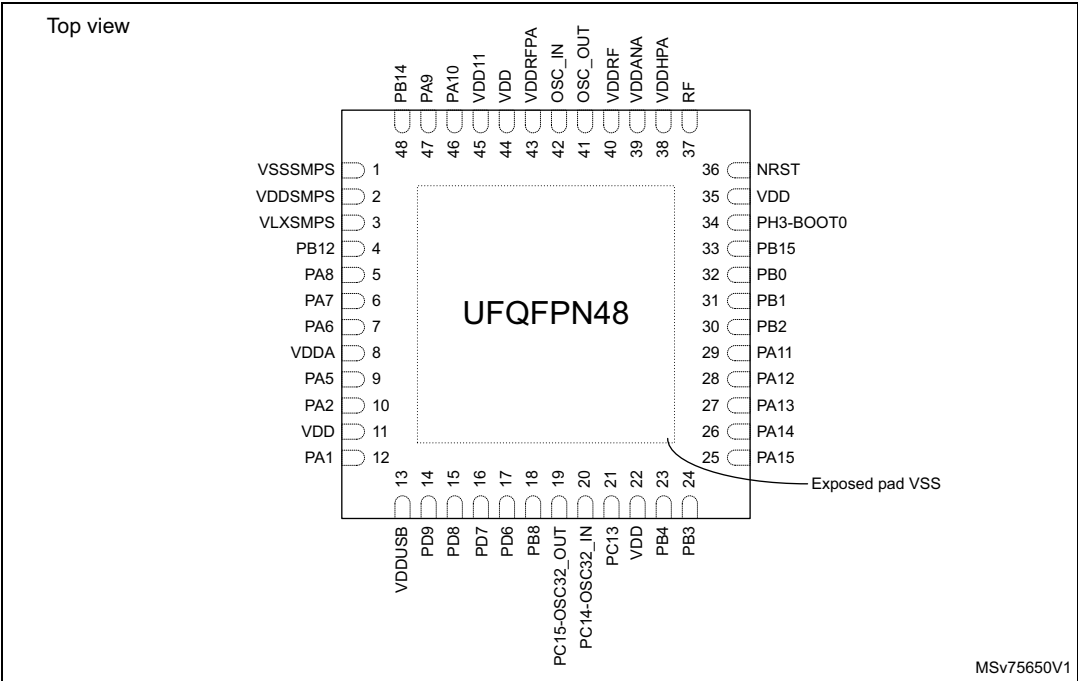


Figure 11. VFQFPN68\_SMPS\_USB pinout

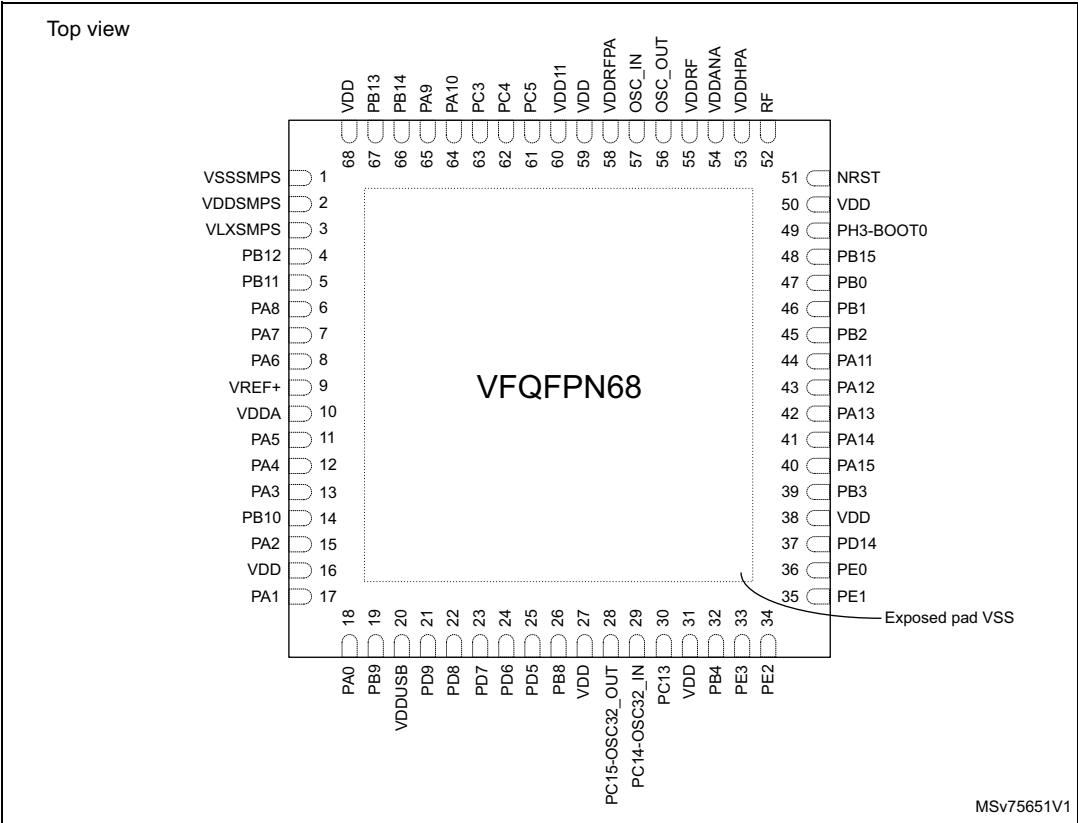


Figure 12. Thin WLCSP88\_USB ballout

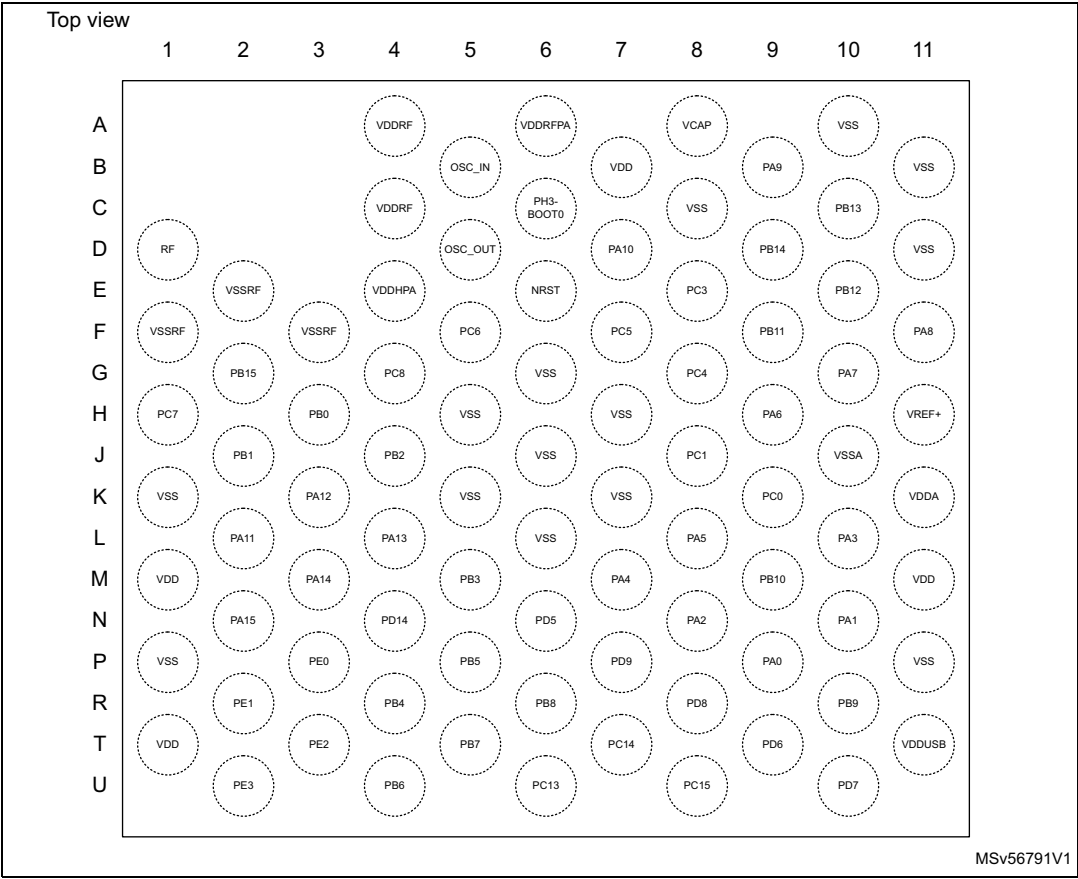


Figure 13. Thin WLCSP88\_SMPS\_USB ballout

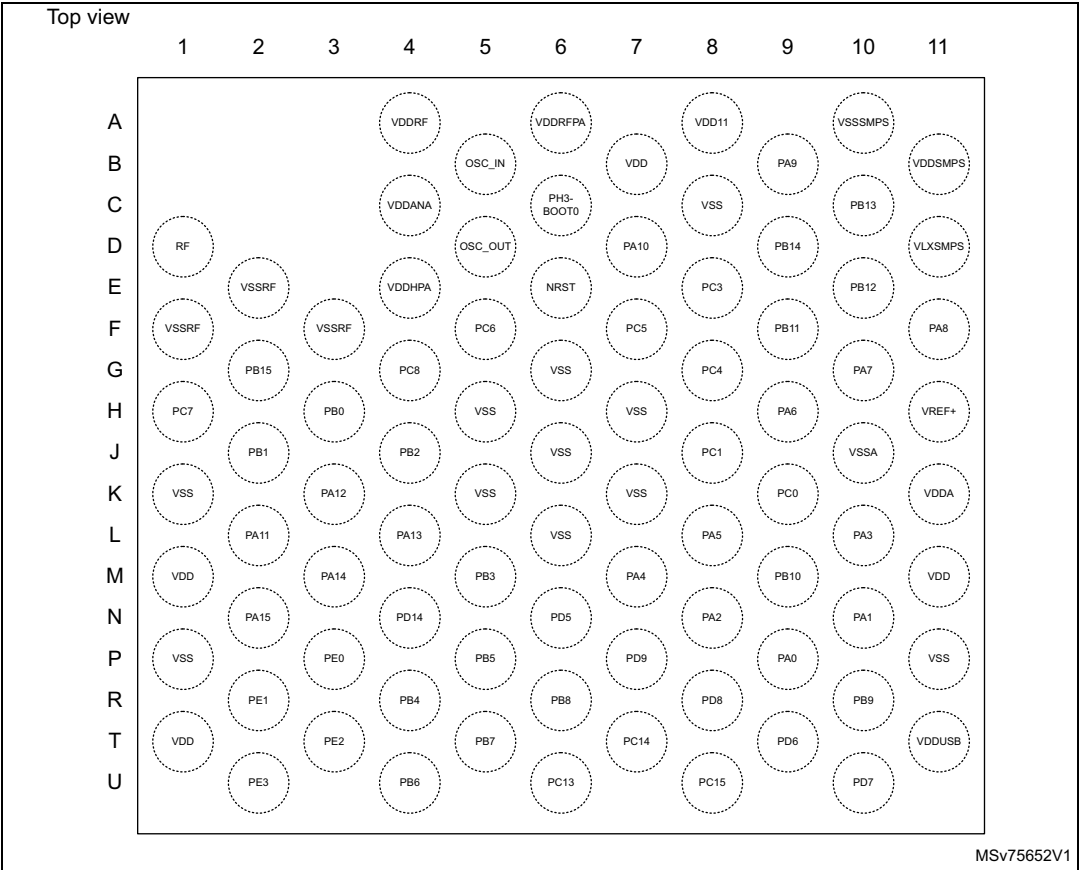


Figure 14. UFBGA121\_USB ballout

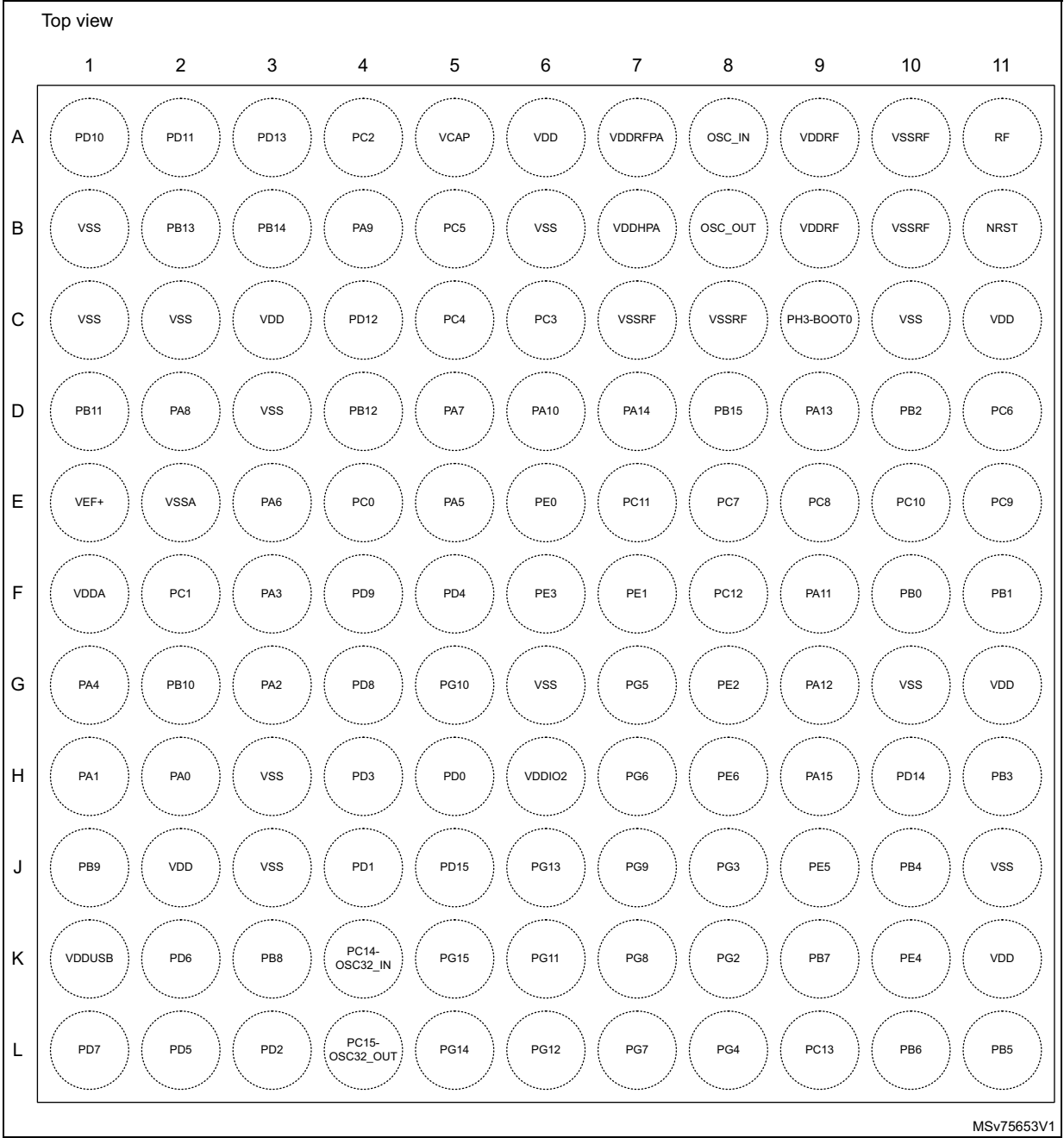
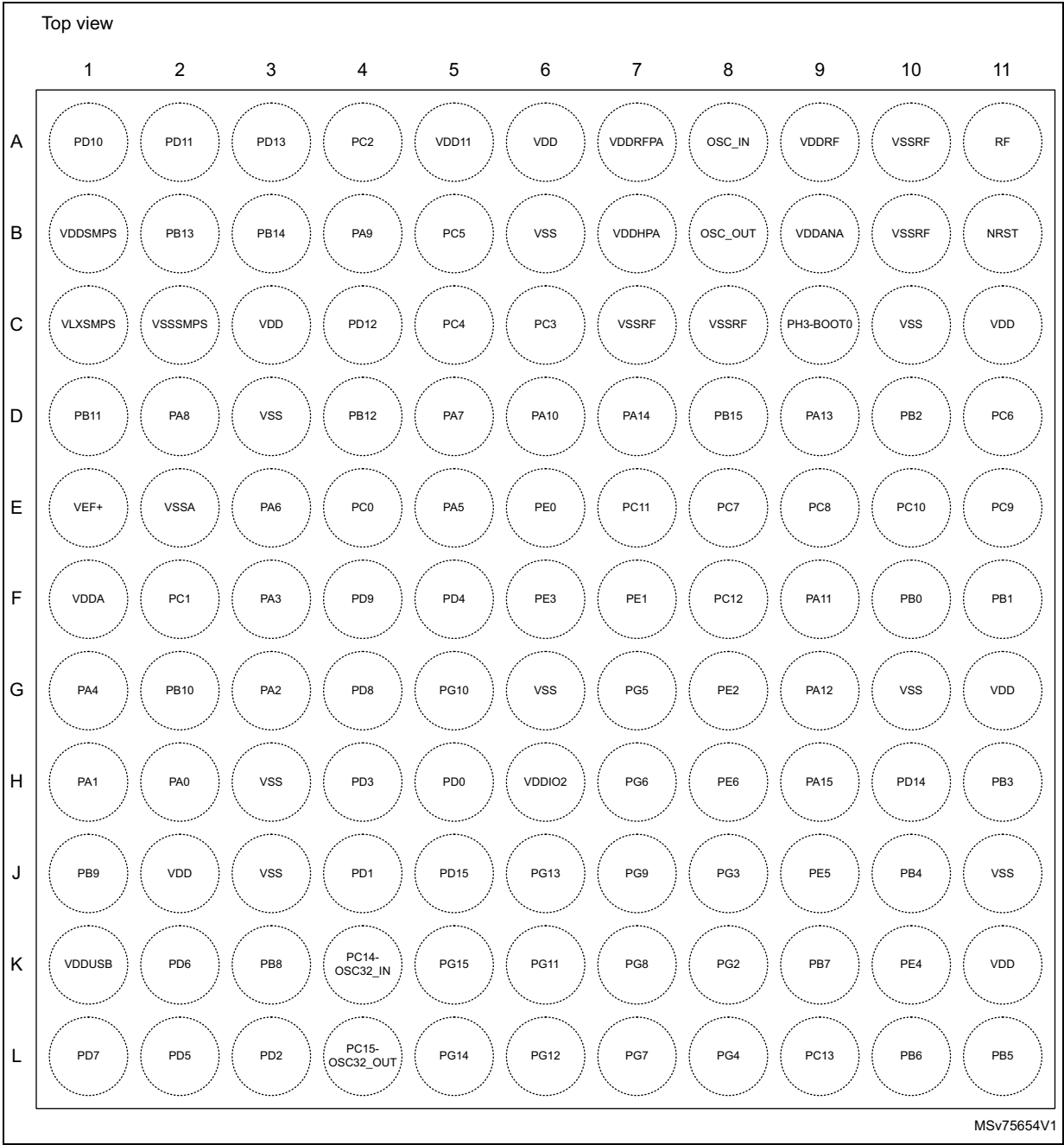


Figure 15. UFBGA121\_SMPS\_USB ballout



## 4.2 Pin description

**Table 22. Legend/abbreviations used in the pinout table**

| Name          |                      | Abbreviation  | Definition   |
|---------------|----------------------|---|--|
| Pin name      |                      | Unless otherwise specified in brackets below the pin name, the pin function during and after reset is the same as the actual pin name |  |
| Pin type      |                      | S   | Supply pin   |
|               |                      | I   | Input only pin   |
|               |                      | I/O   | Input / output pin   |
| I/O structure |                      | FT  | 5 V-tolerant I/O   |
|               |                      | TT  | 3.6 V-tolerant I/O   |
|               |                      | RF  | RF I/O   |
|               |                      | RST   | Bidirectional reset pin with weak pull-up resistor           |
|               |                      | Option for TT or FT I/Os <sup>(1)</sup>   |  |
|               |                      | _a  | I/O with analog switch function supplied by V <sub>DDA</sub> |
|               |                      | _f  | I/O, Fm+ capable   |
|               |                      | _h  | I/O with high-speed low voltage mode                         |
|               |                      | _s  | I/O, supplied only by V <sub>DDIO2</sub>                     |
|               |                      | _u  | I/O with USB function supplied by V <sub>DDUSB</sub>         |
| Notes         |                      | Unless otherwise specified by a note, all I/Os are set as analog inputs during and after reset.                                       |  |
| Pin functions | Alternate functions  | Functions selected through GPIOx_AFR registers  |  |
|               | Additional functions | Functions directly selected/enabled through peripheral registers  |  |

1. The related I/O structures in [Table 23](#) are a concatenation of various options. Examples: FT\_a, FT\_fa, FT\_f.

Table 23. Device pin definitions

| Pin number   |                  |                      |                      |                     |                           |              |                      | Name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional functions                   |
|--------------|------------------|----------------------|----------------------|---------------------|---------------------------|--------------|----------------------|-----------------------------------|----------|---------------|-------|--|--|
| UFQFPN48 USB | UFQFPN48<br>SMPS | UFQFPN48<br>SMPS USB | VFQFPN68<br>SMPS USB | Thin WLCSP88<br>USB | Thin WLCSP88-<br>SMPS USB | UFBGA121 USB | UFBGA121<br>SMPS USB |                                   |          |               |       |  |  |
| -            | -                | -                    | -                    | A10                 | -                         | C2           | -                    | VSS                               | S        | -             | -     | -  | -                                      |
| -            | 1                | 1                    | 1                    | -                   | A10                       | -            | C2                   | VSSSMPS                           | S        | -             | -     | -  | -                                      |
| -            | -                | -                    | -                    | B11                 | -                         | B1           | -                    | VSS                               | S        | -             | -     | -  | -                                      |
| -            | 2                | 2                    | 2                    | -                   | B11                       | -            | B1                   | VDDSMPS                           | S        | -             | -     | -  | -                                      |
| -            | -                | -                    | -                    | D11                 | -                         | C1           | -                    | VSS                               | S        | -             | -     | -  | -                                      |
| -            | 3                | 3                    | 3                    | -                   | D11                       | -            | C1                   | VLXSMPS                           | S        | -             | -     | -  | -                                      |
| 1            | 4                | 4                    | 4                    | E10                 | E10                       | D4           | D4                   | PB12                              | I/O      | FT            | -     | TIM2_CH1, TIM2_ETR, I2C2_SMBA, SPI1_RDY,<br>SPI2_NSS, USART1_TX, USART3_CK,<br>TSC_SYNC, SAI1_SD_A, TIM3_ETR, EVENTOUT | -                                      |
| 2            | -                | -                    | 5                    | F9                  | F9                        | D1           | D1                   | PB11                              | I/O      | FT_f          | -     | LPTIM1_CH1, LPTIM1_ETR, I2C4_SDA,<br>I2C2_SDA, SPI2_RDY, USART3_RX,<br>LPUART1_TX, EVENTOUT                            | -                                      |
| 3            | 5                | 5                    | 6                    | F11                 | F11                       | D2           | D2                   | PA8                               | I/O      | FT_a          | -     | MCO, TIM2_CH2, LPTIM1_CH2, SPI3_RDY,<br>USART1_RX, TSC_G1_IO1, OTG_SOF,<br>SAI1_FS_A, EVENTOUT                         | ADC4_IN1                               |
| 4            | 6                | 6                    | 7                    | G10                 | G10                       | D5           | D5                   | PA7                               | I/O      | FT_fa         | -     | TIM2_CH3, I2C3_SDA, SPI3_SCK, USART1_CTS,<br>USART3_TX, TSC_G1_IO2, COMP1_OUT,<br>SAI1_SCK_A, EVENTOUT                 | ADC4_IN2, WKUP8,<br>TAMP_IN1/TAMP_OUT2 |
| 5            | 7                | 7                    | 8                    | H9                  | H9                        | E3           | E3                   | PA6                               | I/O      | FT_fa         | -     | CSTOP, TIM2_CH4, SAI1_CK2, I2C3_SCL,<br>SPI3_RDY, USART1_RTS_DE, USART3_CTS,<br>TSC_G1_IO3, SAI1_MCLK_A, EVENTOUT      | ADC4_IN3, WKUP7                        |
| -            | -                | -                    | -                    | J10                 | J10                       | E2           | E2                   | VSSA                              | S        | -             | -     | -  | -                                      |
| -            | -                | -                    | 9                    | H11                 | H11                       | E1           | E1                   | VREF+                             | S        | -             | -     | -  | -                                      |
| 6            | 8                | 8                    | 10                   | K11                 | K11                       | F1           | F1                   | VDDA                              | S        | -             | -     | -  | -                                      |



Table 23. Device pin definitions (continued)

| Pin number   |                  |                      |                      |                     |                           |              |                      | Name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional functions                    |
|--------------|------------------|----------------------|----------------------|---------------------|---------------------------|--------------|----------------------|-----------------------------------|----------|---------------|-------|---|---|
| UFQFPN48 USB | UFQFPN48<br>SMPS | UFQFPN48<br>SMPS USB | VFQFPN68<br>SMPS USB | Thin WLCSP88<br>USB | Thin WLCSP88-<br>SMPS USB | UFBGA121 USB | UFBGA121<br>SMPS USB |                                   |          |               |       |   |   |
| -            | -                | -                    | -                    | J8                  | J8                        | F2           | F2                   | PC1                               | I/O      | FT_f          | -     | LPTIM1_CH1, SPI2_MOSI, I2C3_SDA,<br>LPUART1_TX, SAI1_SD_A, EVENTOUT   | -                                       |
| -            | -                | -                    | -                    | K9                  | K9                        | E4           | E4                   | PC0                               | I/O      | FT_f          | -     | LPTIM1_IN1, I2C3_SCL, SPI2_RDY, LPUART1_RX,<br>LPTIM2_IN1, EVENTOUT   | -                                       |
| 7            | 9                | 9                    | 11                   | L8                  | L8                        | E5           | E5                   | PA5                               | I/O      | FT_a          | -     | CSLEEP, TIM2_CH1, TIM2_ETR, SAI1_D2,<br>SPI3_NSS, USART1_CK, USART3_RX,<br>TSC_G1_IO4, AUDIOCLK, LPTIM2_ETR,<br>EVENTOUT        | ADC4_IN4, WKUP6                         |
| -            | -                | -                    | 12                   | M7                  | M7                        | G1           | G1                   | PA4                               | I/O      | FT_a          | -     | USART1_CTS, TSC_G4_IO1, AUDIOCLK,<br>TIM16_CH1, EVENTOUT  | ADC4_IN5, WKUP2,<br>TAMP_IN6/TAMP_OUT3  |
| 8            | -                | -                    | 13                   | L10                 | L10                       | F3           | F3                   | PA3                               | I/O      | FT_a          | -     | USART1_RTS_DE, TSC_G4_IO2, TIM16_CH1N,<br>EVENTOUT  | ADC4_IN6, WKUP5                         |
| 9            | -                | -                    | 14                   | M9                  | M9                        | G2           | G2                   | PB10                              | I/O      | FT_a          | -     | I2C4_SCL, I2C2_SCL, SPI2_SCK, USART1_CK,<br>USART3_TX, TSC_G4_IO3, TIM16_BKIN,<br>EVENTOUT                                      | -                                       |
| 10           | 10               | 10                   | 15                   | N8                  | N8                        | G3           | G3                   | PA2                               | I/O      | FT_a          | -     | TIM1_BKIN, TIM3_CH1, SAI1_D1,<br>USART1_RTS_DE, LPUART1_TX, TSC_G4_IO4,<br>TIM16_CH1, EVENTOUT                                  | COMP1_INP1,<br>ADC4_IN7, WKUP4,<br>LSCO |
| -            | -                | -                    | -                    | P11                 | P11                       | H3           | H3                   | VSS                               | S        | -             | -     | -   | -                                       |
| 11           | 11               | 11                   | 16                   | M11                 | M11                       | J2           | J2                   | VDD                               | S        | -             | -     | -   | -                                       |
| 12           | 12               | 12                   | 17                   | N10                 | N10                       | H1           | H1                   | PA1                               | I/O      | FT_a          | -     | TIM1_CH1N, TIM3_CH2, SAI1_CK1, SPI1_RDY,<br>SPI3_MISO, USART1_CK, LPUART1_RX,<br>TSC_G2_IO1, LPTIM2_CH2, TIM17_CH1,<br>EVENTOUT | COMP1_INM1,<br>ADC4_IN8, WKUP3          |
| -            | 13               | -                    | 18                   | P9                  | P9                        | H2           | H2                   | PA0                               | I/O      | FT_a          | -     | LPTIM1_IN1, TIM1_CH2N, TIM3_CH3, SPI3_SCK,<br>LPUART1_CTS, TSC_G2_IO2, TIM3_ETR,<br>EVENTOUT                                    | COMP2_INP1,<br>ADC4_IN9, WKUP1          |



Table 23. Device pin definitions (continued)

| Pin number   |                  |                      |                      |                     |                           |              |                      | Name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional functions            |
|--------------|------------------|----------------------|----------------------|---------------------|---------------------------|--------------|----------------------|-----------------------------------|----------|---------------|-------|---|---------------------------------|
| UFQFPN48 USB | UFQFPN48<br>SMPS | UFQFPN48<br>SMPS USB | VFQFPN68<br>SMPS USB | Thin WLCSP88<br>USB | Thin WLCSP88-<br>SMPS USB | UFBGA121 USB | UFBGA121<br>SMPS USB |                                   |          |               |       |   |                                 |
| -            | 14               | -                    | 19                   | R10                 | R10                       | J1           | J1                   | PB9                               | I/O      | FT_a          | -     | TIM1_CH3N, TIM3_CH4, IR_OUT, SPI2_NSS,<br>SPI3_MISO, LPUART1_RTS_DE, TSC_G2_IO3,<br>TIM4_CH4, LPTIM2_IN1, TIM16_CH1, EVENTOUT | COMP2_INM1,<br>ADC4_IN10, WKUP8 |
| 13           | -                | 13                   | 20                   | T11                 | T11                       | K1           | K1                   | VDDUSB                            | S        | -             | -     | -   | -                               |
| 14           | -                | 14                   | 21                   | P7                  | P7                        | F4           | F4                   | PD9                               | I/O      | FT_u          | -     | USART2_TX, USART3_TX, EVENTOUT  | OTG_VBUS                        |
| 15           | -                | 15                   | 22                   | R8                  | R8                        | G4           | G4                   | PD8                               | I/O      | FT_u          | -     | USART2_CK, OTG_ID, EVENTOUT   | -                               |
| 16           | -                | 16                   | 23                   | U10                 | U10                       | L1           | L1                   | PD7                               | I/O      | TT            | -     | -   | OTG_HSDM                        |
| 17           | -                | 17                   | 24                   | T9                  | T9                        | K2           | K2                   | PD6                               | I/O      | TT            | -     | -   | OTG_HSDP                        |
| -            | -                | -                    | 25                   | N6                  | N6                        | L2           | L2                   | PD5                               | I/O      | FT            | -     | SAI1_D1, SPI3_MOSI, USART2_RX, SAI1_SD_A,<br>EVENTOUT   | -                               |
| 18           | 15               | 18                   | 26                   | R6                  | R6                        | K3           | K3                   | PB8                               | I/O      | FT_a          | -     | LPTIM1_ETR, TIM1_CH1, TIM3_ETR,<br>USART2_RX, SPI3_MOSI, TSC_G2_IO4,<br>COMP1_OUT, TIM4_CH3, TIM16_CH1N,<br>EVENTOUT          | PVD_IN                          |
| -            | -                | -                    | -                    | -                   | -                         | F5           | F5                   | PD4                               | I/O      | FT            | -     | LPTIM2_IN2, USART3_RX, EVENTOUT   | -                               |
| -            | -                | -                    | -                    | -                   | -                         | H4           | H4                   | PD3                               | I/O      | FT_a          | -     | SPI2_SCK, SPI2_MISO, USART2_CTS,<br>TSC_G8_IO1, EVENTOUT  | -                               |
| -            | -                | -                    | -                    | -                   | -                         | L3           | L3                   | PD2                               | I/O      | FT            | -     | TIM3_ETR, USART3_RTS_DE, TSC_SYNC,<br>EVENTOUT  | -                               |
| -            | -                | -                    | 27                   | -                   | -                         | -            | -                    | VDD                               | S        | -             | -     | -   | -                               |
| 19           | 16               | 19                   | 28                   | U8                  | U8                        | L4           | L4                   | PC15-<br>OSC32_OUT                | I/O      | FT            | -     | EVENTOUT  | OSC32_OUT                       |
| 20           | 17               | 20                   | 29                   | T7                  | T7                        | K4           | K4                   | PC14-OSC32_IN                     | I/O      | FT            | -     | EVENTOUT  | OSC32_IN                        |
| -            | -                | -                    | -                    | -                   | -                         | J4           | J4                   | PD1                               | I/O      | FT_a          | -     | SPI2_SCK, TSC_G8_IO2, EVENTOUT  | -                               |



Table 23. Device pin definitions (continued)

| Pin number   |                  |                      |                      |                     |                           |              |                      | Name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional functions |
|--------------|------------------|----------------------|----------------------|---------------------|---------------------------|--------------|----------------------|-----------------------------------|----------|---------------|-------|---|----------------------|
| UFQFPN48 USB | UFQFPN48<br>SMPS | UFQFPN48<br>SMPS USB | VFQFPN68<br>SMPS USB | Thin WLCSP88<br>USB | Thin WLCSP88-<br>SMPS USB | UFBGA121 USB | UFBGA121<br>SMPS USB |                                   |          |               |       |   |                      |
| -            | -                | -                    | -                    | -                   | -                         | H5           | H5                   | PD0                               | I/O      | FT_a          | -     | SPI2_NSS, TSC_G8_IO3, EVENTOUT                              | -                    |
| -            | -                | -                    | -                    | -                   | -                         | J5           | J5                   | PD15                              | I/O      | FT_a          | -     | TSC_G8_IO4, TIM4_CH4, EVENTOUT                              | -                    |
| -            | -                | -                    | -                    | -                   | -                         | K5           | K5                   | PG15                              | I/O      | FT_hs         | -     | LPTIM1_CH1, I2C1_SMBA, EVENTOUT                             | -                    |
| -            | -                | -                    | -                    | -                   | -                         | L5           | L5                   | PG14                              | I/O      | FT_hfs        | -     | LPTIM1_CH2, I2C1_SCL, EVENTOUT                              | -                    |
| -            | -                | -                    | -                    | -                   | -                         | H6           | H6                   | VDDIO2                            | S        | -             | -     | -   | -                    |
| -            | -                | -                    | -                    | K7                  | K7                        | G6           | G6                   | VSS                               | S        | -             | -     | -   | -                    |
| -            | -                | -                    | -                    | -                   | -                         | J6           | J6                   | PG13                              | I/O      | FT_hfs        | -     | I2C1_SDA, SPI3_RDY, USART1_CK, EVENTOUT                     | -                    |
| -            | -                | -                    | -                    | -                   | -                         | L6           | L6                   | PG12                              | I/O      | FT_hs         | -     | LPTIM1_ETR, SPI3_NSS, USART1_RTS_DE,<br>SAI1_SD_A, EVENTOUT | -                    |
| -            | -                | -                    | -                    | -                   | -                         | K6           | K6                   | PG11                              | I/O      | FT_hs         | -     | LPTIM1_IN2, SPI3_MOSI, USART1_CTS,<br>SAI1_MCLK_A, EVENTOUT | -                    |
| -            | -                | -                    | -                    | -                   | -                         | G5           | G5                   | PG10                              | I/O      | FT_hs         | -     | LPTIM1_IN1, SPI3_MISO, USART1_RX,<br>SAI1_FS_A, EVENTOUT    | -                    |
| -            | -                | -                    | -                    | -                   | -                         | J7           | J7                   | PG9                               | I/O      | FT_hs         | -     | SPI3_SCK, USART1_TX, SAI1_SCK_A,<br>EVENTOUT                | -                    |
| -            | -                | -                    | -                    | -                   | -                         | K7           | K7                   | PG8                               | I/O      | FT_hfs        | -     | I2C3_SDA, LPUART1_RX, EVENTOUT                              | -                    |
| -            | -                | -                    | -                    | -                   | -                         | L7           | L7                   | PG7                               | I/O      | FT_hfs        | -     | SAI1_CK1, I2C3_SCL, LPUART1_TX,<br>SAI1_MCLK_A, EVENTOUT    | -                    |
| -            | -                | -                    | -                    | -                   | -                         | H7           | H7                   | PG6                               | I/O      | FT_hs         | -     | I2C3_SMBA, SPI1_RDY, LPUART1_RTS_DE,<br>EVENTOUT            | -                    |
| -            | -                | -                    | -                    | -                   | -                         | G7           | G7                   | PG5                               | I/O      | FT_hs         | -     | SPI1_NSS, LPUART1_CTS, SAI1_SD_B,<br>EVENTOUT               | -                    |
| -            | -                | -                    | -                    | -                   | -                         | L8           | L8                   | PG4                               | I/O      | FT_hs         | -     | SPI1_MOSI, SAI1_MCLK_B, EVENTOUT                            | -                    |

Table 23. Device pin definitions (continued)

| Pin number   |                  |                      |                      |                     |                           |              |                      | Name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional functions                              |
|--------------|------------------|----------------------|----------------------|---------------------|---------------------------|--------------|----------------------|-----------------------------------|----------|---------------|-------|--|---|
| UFQFPN48 USB | UFQFPN48<br>SMPS | UFQFPN48<br>SMPS USB | VFQFPN68<br>SMPS USB | Thin WLCSP88<br>USB | Thin WLCSP88-<br>SMPS USB | UFBGA121 USB | UFBGA121<br>SMPS USB |                                   |          |               |       |  |   |
| -            | -                | -                    | -                    | -                   | -                         | J8           | J8                   | PG3                               | I/O      | FT_hs         | -     | SPI1_MISO, SAI1_FS_B, EVENTOUT   | -   |
| -            | -                | -                    | -                    | -                   | -                         | K8           | K8                   | PG2                               | I/O      | FT_hs         | -     | SPI1_SCK, SAI1_SCK_B, EVENTOUT   | -   |
| -            | -                | -                    | -                    | L6                  | L6                        | J3           | J3                   | VSS                               | S        | -             | -     | -  | -   |
| 21           | 18               | 21                   | 30                   | U6                  | U6                        | L9           | L9                   | PC13                              | I/O      | FT_a          | -     | TIM1_BKIN2, TSC_G5_IO1, EVENTOUT   | WKUP2, RTC_TS/<br>RTC_OUT1,<br>TAMP_IN4/TAMP_OUT5 |
| -            | 19               | -                    | -                    | T5                  | T5                        | K9           | K9                   | PB7                               | I/O      | FT_a          | -     | TIM1_CH4N, TSC_G5_IO2, TIM4_CH2,<br>SAI1_SD_B, EVENTOUT  | WKUP5,<br>TAMP_IN5/TAMP_OUT4                      |
| -            | -                | -                    | -                    | -                   | -                         | H8           | H8                   | PE6                               | I/O      | FT            | -     | TIM3_CH4, SAI1_D1, SAI1_SD_A, EVENTOUT   | -   |
| -            | 20               | -                    | -                    | U4                  | U4                        | L10          | L10                  | PB6                               | I/O      | FT_a          | -     | TIM2_CH1, TIM2_ETR, TSC_G5_IO3, TIM4_CH1,<br>SAI1_SCK_B, EVENTOUT  | WKUP3   |
| -            | -                | -                    | -                    | -                   | -                         | J9           | J9                   | PE5                               | I/O      | FT            | -     | TIM3_CH3, SAI1_CK2, SAI1_SCK_A, EVENTOUT   | -   |
| -            | 21               | -                    | -                    | P5                  | P5                        | L11          | L11                  | PB5                               | I/O      | FT_a          | -     | TIM3_CH1, SAI1_D2, LPUART1_TX, TSC_G5_IO4,<br>SAI1_FS_B, EVENTOUT  | -   |
| -            | -                | -                    | -                    | -                   | -                         | K10          | K10                  | PE4                               | I/O      | FT            | -     | TIM3_CH2, SAI1_D2, SAI1_FS_A, EVENTOUT   | -   |
| 22           | 22               | 22                   | 31                   | -                   | -                         | K11          | K11                  | VDD                               | S        | -             | -     | -  | -   |
| -            | -                | -                    | -                    | K5                  | K5                        | J11          | J11                  | VSS                               | S        | -             | -     | -  | -   |
| 23           | 23               | 23                   | 32                   | R4                  | R4                        | J10          | J10                  | PB4(NJRST)                        | I/O      | FT_a          | (1)   | NJTRST, TIM1_CH3, LPTIM2_IN2, USART2_RX,<br>SPI1_SCK, TSC_G3_IO1, PTA_PRIORITY,<br>PTA_ACTIVE, SAI1_MCLK_B, TIM17_CH1,<br>EVENTOUT | -   |
| -            | -                | -                    | 33                   | U2                  | U2                        | F6           | F6                   | PE3                               | I/O      | FT_ha         | -     | TRACED2, TIM3_CH1, TSC_G7_IO1, SAI1_SD_B,<br>EVENTOUT  | -   |



Table 23. Device pin definitions (continued)

| Pin number   |                  |                      |                      |                     |                           |              |                      | Name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional functions |
|--------------|------------------|----------------------|----------------------|---------------------|---------------------------|--------------|----------------------|-----------------------------------|----------|---------------|-------|--|----------------------|
| UFQFPN48 USB | UFQFPN48<br>SMPS | UFQFPN48<br>SMPS USB | VFQFPN68<br>SMPS USB | Thin WLCSP88<br>USB | Thin WLCSP88-<br>SMPS USB | UFBGA121 USB | UFBGA121<br>SMPS USB |                                   |          |               |       |  |                      |
| -            | -                | -                    | 34                   | T3                  | T3                        | G8           | G8                   | PE2                               | I/O      | FT_ha         | -     | TRACED1, TIM3_ETR, SAI1_CK1, TSC_G7_IO2,<br>SAI1_MCLK_A, EVENTOUT  | -                    |
| -            | -                | -                    | 35                   | R2                  | R2                        | F7           | F7                   | PE1                               | I/O      | FT_ha         | -     | TRACED0, TSC_G7_IO3, TIM17_CH1, EVENTOUT   | -                    |
| -            | -                | -                    | 36                   | P3                  | P3                        | E6           | E6                   | PE0                               | I/O      | FT_ha         | -     | TRACECLK, TSC_G7_IO4, TIM4_ETR,<br>TIM16_CH1, EVENTOUT   | -                    |
| -            | -                | -                    | 37                   | N4                  | N4                        | H10          | H10                  | PD14                              | I/O      | FT_h          | -     | TRACED3, TIM4_CH3, EVENTOUT  | -                    |
| -            | -                | -                    | -                    | P1                  | P1                        | G10          | G10                  | VSS                               | S        | -             | -     | -  | -                    |
| -            | -                | -                    | 38                   | T1                  | T1                        | G11          | G11                  | VDD                               | S        | -             | -     | -  | -                    |
| 24           | 24               | 24                   | 39                   | M5                  | M5                        | H11          | H11                  | PB3<br>(JTDO/TRACES<br>WO)        | I/O      | FT_fa         | -     | JTDO/TRACESWO, TIM1_CH4, LPTIM1_IN2,<br>USART2_CK, I2C1_SDA, SPI1_MISO,<br>TSC_G3_IO2, PTA_ACTIVE, TIM17_CH1N,<br>EVENTOUT           | -                    |
| 25           | 25               | 25                   | 40                   | N2                  | N2                        | H9           | H9                   | PA15<br>(JTDI)                    | I/O      | FT_fa         | (1)   | JTDI, TIM1_ETR, LPTIM1_CH2, USART2_RTS_DE,<br>I2C1_SCL, SPI1_MOSI, USART3_RTS_DE,<br>TSC_G3_IO3, PTA_STATUS, TIM17_BKIN,<br>EVENTOUT | -                    |
| 26           | 26               | 26                   | 41                   | M3                  | M3                        | D7           | D7                   | PA14<br>(JTCK/SWCLK)              | I/O      | FT            | (1)   | JTCK/SWCLK, USART2_TX, I2C4_SMBA,<br>OTG_SOF/PTA_STATUS, COMP2_OUT,<br>EVENTOUT  | TAMP_IN3/TAMP_OUT6   |
| 27           | 27               | 27                   | 42                   | L4                  | L4                        | D9           | D9                   | PA13<br>(JTMS/SWDIO)              | I/O      | FT            | (1)   | JTMS/SWDIO, IR_OUT, PTA_PRIORITY,<br>EVENTOUT  | -                    |
| 28           | 28               | 28                   | 43                   | K3                  | K3                        | G9           | G9                   | PA12                              | I/O      | FT_a          | -     | TIM1_CH2, USART2_TX, SPI1_NSS, TSC_G3_IO4,<br>PTA_STATUS, RF_ANTSW0, COMP2_OUT,<br>EVENTOUT  | WKUP6                |
| 29           | 29               | 29                   | 44                   | L2                  | L2                        | F9           | F9                   | PA11.                             | I/O      | FT            | -     | TIM1_CH1, USART2_RX, RF_ANTSW1,<br>LPTIM2_CH1, EVENTOUT  | -                    |

Table 23. Device pin definitions (continued)

| Pin number   |                  |                      |                      |                     |                           |              |                      | Name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Alternate functions  | Additional functions |
|--------------|------------------|----------------------|----------------------|---------------------|---------------------------|--------------|----------------------|-----------------------------------|----------|---------------|-------|--|----------------------|
| UFQFPN48 USB | UFQFPN48<br>SMPS | UFQFPN48<br>SMPS USB | VFQFPN68<br>SMPS USB | Thin WLCSP88<br>USB | Thin WLCSP88-<br>SMPS USB | UFBGA121 USB | UFBGA121<br>SMPS USB |                                   |          |               |       |  |                      |
| -            | -                | -                    | -                    | M1                  | M1                        | C11          | C11                  | VDD                               | S        | -             | -     | -  | -                    |
| -            | -                | -                    | -                    | K1                  | K1                        | -            | -                    | VSS                               | S        | -             | -     | -  | -                    |
| 30           | 30               | 30                   | 45                   | J4                  | J4                        | D10          | D10                  | PB2                               | I/O      | FT_f          | -     | TIM1_CH1N, USART2_CTS, I2C1_SCL, I2C3_SCL,<br>RF_ANTSW2, EVENTOUT  | WKUP1, RTC_OUT2      |
| 31           | 31               | 31                   | 46                   | J2                  | J2                        | F11          | F11                  | PB1                               | I/O      | FT_f          | -     | TIM1_CH2N, USART2_RTS_DE, I2C1_SDA,<br>I2C3_SDA, USART3_RTS_DE, EVENTOUT                                       | WKUP4                |
| 32           | 32               | 32                   | 47                   | H3                  | H3                        | F10          | F10                  | PB0                               | I/O      | FT            | -     | -TIM1_CH3N, LPTIM2_IN2, USART2_TX,<br>SPI2_MOSI, USART3_CK, EVENTOUT   | -                    |
| -            | -                | -                    | -                    | -                   | -                         | F8           | F8                   | PC12                              | I/O      | FT            | -     | SPI3_MOSI, USART3_CK, EVENTOUT   | -                    |
| -            | -                | -                    | -                    | -                   | -                         | E7           | E7                   | PC11                              | I/O      | FT            | -     | SPI3_MISO, USART3_RX, EVENTOUT   | -                    |
| -            | -                | -                    | -                    | -                   | -                         | E10          | E10                  | PC10                              | I/O      | FT            | -     | SPI3_SCK, USART3_TX, EVENTOUT  | -                    |
| -            | -                | -                    | -                    | -                   | -                         | E11          | E11                  | PC9                               | I/O      | FT            | -     | TIM3_CH4, USART2_TX, EVENTOUT  | -                    |
| -            | -                | -                    | -                    | G4                  | G4                        | E9           | E9                   | PC8                               | I/O      | FT            | -     | TIM3_CH3, USART2_RX, EVENTOUT  | -                    |
| -            | -                | -                    | -                    | H1                  | H1                        | E8           | E8                   | PC7                               | I/O      | FT            | -     | CSTOP, TIM3_CH2, USART2_RTS_DE,<br>LPTIM2_CH2, EVENTOUT  | -                    |
| -            | -                | -                    | -                    | J6                  | J6                        | -            | -                    | VSS                               | S        | -             | -     | -  | -                    |
| -            | -                | -                    | -                    | F5                  | F5                        | D11          | D11                  | PC6                               | I/O      | FT            | -     | CSLEEP, TIM3_CH1, EVENTOUT   | -                    |
| 33           | 33               | 33                   | 48                   | G2                  | G2                        | D8           | D8                   | PB15                              | I/O      | TT            | -     | TIM1_BKIN2, USART2_CTS, I2C1_SMBA,<br>I2C3_SMBA, LPUART1_CTS, PTA_GRANT,<br>RF_EXT_PABYP, TIM16_BKIN, EVENTOUT | -                    |
| 34           | 34               | 34                   | 49                   | C6                  | C6                        | C9           | C9                   | PH3-BOOT0                         | I/O      | TT            | -     | PTA_GRANT, RF_EXT_PABYP, EVENTOUT  | TAMP_IN2/TAMP_OUT1   |
| 35           | 35               | 35                   | 50                   | -                   | -                         | -            | -                    | VDD                               | S        | -             | -     | -  | -                    |
| -            | -                | -                    | -                    | H5                  | H5                        | C10          | C10                  | VSS                               | S        | -             | -     | -  | -                    |



Table 23. Device pin definitions (continued)

| Pin number   |                  |                      |                      |                     |                           |              |                      | Name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Alternate functions                                | Additional functions |
|--------------|------------------|----------------------|----------------------|---------------------|---------------------------|--------------|----------------------|-----------------------------------|----------|---------------|-------|--|----------------------|
| UFQFPN48 USB | UFQFPN48<br>SMPS | UFQFPN48<br>SMPS USB | VFQFPN68<br>SMPS USB | Thin WLCSP88<br>USB | Thin WLCSP88-<br>SMPS USB | UFBGA121 USB | UFBGA121<br>SMPS USB |                                   |          |               |       |  |                      |
| 36           | 36               | 36                   | 51                   | E6                  | E6                        | B11          | B11                  | NRST                              | I/O      | RST           | -     | -  | -                    |
| -            | -                | -                    | -                    | G6                  | G6                        | -            | -                    | VSS                               | S        | -             | -     | -  | -                    |
| -            | -                | -                    | -                    | F1                  | F1                        | B10          | B10                  | VSSRF                             | S        | -             | -     | -  | -                    |
| 37           | 37               | 37                   | 52                   | D1                  | D1                        | A11          | A11                  | RF                                | I/O      | RF            | -     | -  | -                    |
| -            | -                | -                    | -                    | E2                  | E2                        | A10          | A10                  | VSSRF                             | S        | -             | -     | -  | -                    |
| 38           | 38               | 38                   | 53                   | E4                  | E4                        | B7           | B7                   | VDDHPA                            | S        | -             | -     | -  | -                    |
| -            | 39               | 39                   | 54                   | -                   | C4                        | -            | B9                   | VDDANA                            | S        | -             | -     | -  | -                    |
| -            | -                | -                    | -                    | C4                  | -                         | B9           | -                    | VDDRF                             | S        | -             | -     | -  | -                    |
| 39           | 40               | 40                   | 55                   | A4                  | A4                        | A9           | A9                   | VDDRF                             | S        | -             | -     | -  | -                    |
| -            | -                | -                    | -                    | F3                  | F3                        | C7           | C7                   | VSSRF                             | S        | -             | -     | -  | -                    |
| -            | -                | -                    | -                    | -                   | -                         | C8           | C8                   | VSSRF                             | S        | -             | -     | -  | -                    |
| 40           | 41               | 41                   | 56                   | D5                  | D5                        | B8           | B8                   | OSC_OUT                           | O        | RF            | -     | -  | -                    |
| 41           | 42               | 42                   | 57                   | B5                  | B5                        | A8           | A8                   | OSC_IN                            | I        | RF            | -     | -  | -                    |
| 42           | 43               | 43                   | 58                   | A6                  | A6                        | A7           | A7                   | VDDRFPA                           | S        | -             | -     | -  | -                    |
| 43           | 44               | 44                   | 59                   | B7                  | B7                        | A6           | A6                   | VDD                               | S        | -             | -     | -  | -                    |
| -            | -                | -                    | -                    | C8                  | C8                        | B6           | B6                   | VSS                               | S        | -             | -     | -  | -                    |
| -            | 45               | 45                   | 60                   | -                   | A8                        | -            | A5                   | VDD11                             | S        | -             | -     | -  | -                    |
| 44           | -                | -                    | -                    | A8                  | -                         | A5           | -                    | VCAP                              | S        | -             | -     | -  | -                    |
| -            | -                | -                    | 61                   | F7                  | F7                        | B5           | B5                   | PC5                               | I/O      | FT            | -     | TIM1_CH4N, SAI1_D3, USART3_RX, SAI1_SD_B, EVENTOUT | -                    |

Table 23. Device pin definitions (continued)

| Pin number   |                  |                      |                      |                     |                           |              |                      | Name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Alternate functions   | Additional functions |
|--------------|------------------|----------------------|----------------------|---------------------|---------------------------|--------------|----------------------|-----------------------------------|----------|---------------|-------|---|----------------------|
| UFQFPN48 USB | UFQFPN48<br>SMPS | UFQFPN48<br>SMPS USB | VFQFPN68<br>SMPS USB | Thin WLCSP88<br>USB | Thin WLCSP88-<br>SMPS USB | UFBGA121 USB | UFBGA121<br>SMPS USB |                                   |          |               |       |   |                      |
| -            | -                | -                    | 62                   | G8                  | G8                        | C5           | C5                   | PC4                               | I/O      | FT            | -     | TIM3_CH2, SAI1_D2, SPI3_MISO, USART3_TX, SAI1_FS_A, LPTIM2_CH2, EVENTOUT                            | -                    |
| -            | -                | -                    | 63                   | E8                  | E8                        | C6           | C6                   | PC3                               | I/O      | FT            | -     | LPTIM1_ETR, TIM3_CH1, SAI1_D1, SPI2_MOSI, SPI3_MOSI, SAI1_SD_A, LPTIM2_ETR, EVENTOUT                | -                    |
| 45           | 46               | 46                   | 64                   | D7                  | D7                        | D6           | D6                   | PA10                              | I/O      | FT            | -     | TIM3_CH1, SAI1_D1, SPI2_NSS, LPUART1_RX, EVENTOUT   | -                    |
| -            | -                | -                    | -                    | -                   | -                         | A4           | A4                   | PC2                               | I/O      | FT            | -     | LPTIM1_IN2, SPI2_MISO, EVENTOUT   | -                    |
| 46           | 47               | 47                   | 65                   | B9                  | B9                        | B4           | B4                   | PA9                               | I/O      | FT            | -     | TIM3_CH2, SAI1_CK1, SPI2_MISO, SPI2_SCK, LPUART1_RTS_DE, EVENTOUT                                   | -                    |
| -            | -                | -                    | -                    | -                   | -                         | A3           | A3                   | PD13                              | I/O      | FT_fa         | -     | I2C4_SDA, TSC_G6_IO4, TIM4_CH2, LPTIM2_CH1, EVENTOUT  | -                    |
| -            | -                | -                    | -                    | -                   | -                         | C4           | C4                   | PD12                              | I/O      | FT_fa         | -     | I2C4_SCL, USART3_RTS_DE, TSC_G6_IO3, TIM4_CH1, LPTIM2_IN1, EVENTOUT                                 | -                    |
| 47           | 48               | 48                   | 66                   | D9                  | D9                        | B3           | B3                   | PB14                              | I/O      | FT_a          | -     | RTC_REFIN, TIM3_CH3, I2C2_SDA, SPI2_MISO, USART1_TX, USART3_RTS_DE, TSC_G6_IO1, SAI1_SD_A, EVENTOUT | WKUP7                |
| -            | -                | -                    | -                    | -                   | -                         | A2           | A2                   | PD11                              | I/O      | FT            | -     | I2C4_SMB, USART3_CTS, LPTIM2_ETR, EVENTOUT  | -                    |
| -            | -                | -                    | -                    | -                   | -                         | A1           | A1                   | PD10                              | I/O      | FT            | -     | LPTIM2_CH2, USART3_CK, EVENTOUT   | -                    |
| 48           | -                | -                    | 67                   | C10                 | C10                       | B2           | B2                   | PB13                              | I/O      | FT_a          | -     | TIM3_CH4, I2C2_SCL, SPI2_SCK, USART3_CTS, TSC_G6_IO2, EVENTOUT                                      | -                    |
| -            | -                | -                    | -                    | H7                  | H7                        | D3           | D3                   | VSS                               | S        | -             | -     | -   | -                    |

Table 23. Device pin definitions (continued)

| Pin number   |                  |                      |                      |                     |                           |              |                      | Name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|--------------|------------------|----------------------|----------------------|---------------------|---------------------------|--------------|----------------------|-----------------------------------|----------|---------------|-------|---------------------|----------------------|
| UFQFPN48 USB | UFQFPN48<br>SMPS | UFQFPN48<br>SMPS USB | VFQFPN68<br>SMPS USB | Thin WLCSP88<br>USB | Thin WLCSP88-<br>SMPS USB | UFBGA121 USB | UFBGA121<br>SMPS USB |                                   |          |               |       |                     |                      |
| -            | -                | -                    | 68                   | -                   | -                         | C3           | C3                   | VDD                               | S        | -             | -     | -                   | -                    |
| 49           | 49               | 49                   | 69                   | -                   | -                         | -            | -                    | VSS (exposed<br>pad)              | S        | -             | -     | -                   | -                    |

1. After reset, this pin is configured as JTAG/SWD alternate functions. The internal pull-up on PA15, PA13, and PB4 pins, and the internal pull-down on PA14 pin are activated.





## 4.3 Alternate functions

Table 24. Alternate functions (AF0 to AF7)<sup>(1)</sup>

| Port |      | AF0        | AF1               | AF2                   | AF3                       | AF4                | AF5               | AF6             | AF7           |
|------|------|------------|-------------------|-----------------------|---------------------------|--------------------|-------------------|-----------------|---------------|
|      |      | LPTIM1/SYS | LPTIM1/<br>TIM1/2 | LPTIM1/2/<br>TIM1/2/3 | I2C4/SAI1/SPI2/<br>USART2 | I2C1/2/3/4/<br>OTG | I2C4/<br>SPI1/2/3 | I2C3/<br>SPI2/3 | USART1/2/3    |
| A    | PA0  | LPTIM1_IN1 | TIM1_CH2N         | TIM3_CH3              | -                         | -                  | -                 | SPI3_SCK        | -             |
|      | PA1  | -          | TIM1_CH1N         | TIM3_CH2              | SAI1_CK1                  | -                  | SPI1_RDY          | SPI3_MISO       | USART1_CK     |
|      | PA2  | -          | TIM1_BKIN         | TIM3_CH1              | SAI1_D1                   | -                  | -                 | -               | USART1_RTS_DE |
|      | PA3  | -          | -                 | -                     | -                         | -                  | -                 | -               | USART1_RTS_DE |
|      | PA4  | -          | -                 | -                     | -                         | -                  | -                 | -               | USART1_CTS    |
|      | PA5  | CSLEEP     | TIM2_CH1          | TIM2_ETR              | SAI1_D2                   | -                  | -                 | SPI3_NSS        | USART1_CK     |
|      | PA6  | CSTOP      | TIM2_CH4          | -                     | SAI1_CK2                  | I2C3_SCL           | -                 | SPI3_RDY        | USART1_RTS_DE |
|      | PA7  | -          | TIM2_CH3          | -                     | -                         | I2C3_SDA           | -                 | SPI3_SCK        | USART1_CTS    |
|      | PA8  | MCO        | TIM2_CH2          | LPTIM1_CH2            | -                         | -                  | -                 | SPI3_RDY        | USART1_RX     |
|      | PA9  | -          | -                 | TIM3_CH2              | SAI1_CK1                  | -                  | SPI2_MISO         | SPI2_SCK        | -             |
|      | PA10 | -          | -                 | TIM3_CH1              | SAI1_D1                   | -                  | -                 | SPI2_NSS        | -             |
|      | PA11 | -          | TIM1_CH1          | -                     | USART2_RX                 | -                  | -                 | -               | -             |
|      | PA12 | -          | TIM1_CH2          | -                     | USART2_TX                 | -                  | SPI1_NSS          | -               | -             |
|      | PA13 | JTMS/SWDIO | IR_OUT            | -                     | -                         | -                  | -                 | -               | -             |
|      | PA14 | JTCK/SWCLK | -                 | -                     | USART2_TX                 | OTG_SOF            | I2C4_SMBA         | -               | -             |
|      | PA15 | JTDI       | TIM1_ETR          | LPTIM1_CH2            | USART2_RTS_DE             | I2C1_SCL           | SPI1_MOSI         | -               | USART3_RTS_DE |

Table 24. Alternate functions (AF0 to AF7)<sup>(1)</sup> (continued)

| Port |      | AF0               | AF1               | AF2                   | AF3                       | AF4                | AF5               | AF6             | AF7           |
|------|------|-------------------|-------------------|-----------------------|---------------------------|--------------------|-------------------|-----------------|---------------|
|      |      | LPTIM1/SYS        | LPTIM1/<br>TIM1/2 | LPTIM1/2/<br>TIM1/2/3 | I2C4/SAI1/SPI2/<br>USART2 | I2C1/2/3/4/<br>OTG | I2C4/<br>SPI1/2/3 | I2C3/<br>SPI2/3 | USART1/2/3    |
| B    | PB0  | -                 | TIM1_CH3N         | LPTIM2_IN2            | USART2_TX                 | -                  | SPI2_MOSI         | -               | USART3_CK     |
|      | PB1  | -                 | TIM1_CH2N         | -                     | USART2_RTS_DE             | I2C1_SDA           | -                 | I2C3_SDA        | USART3_RTS_DE |
|      | PB2  | -                 | TIM1_CH1N         | -                     | USART2_CTS                | I2C1_SCL           | -                 | I2C3_SCL        | -             |
|      | PB3  | JTDO/<br>TRACESWO | TIM1_CH4          | LPTIM1_IN2            | USART2_CK                 | I2C1_SDA           | SPI1_MISO         | -               | -             |
|      | PB4  | NJTRST            | TIM1_CH3          | LPTIM2_IN2            | USART2_RX                 | -                  | SPI1_SCK          | -               | -             |
|      | PB5  | -                 | -                 | TIM3_CH1              | SAI1_D2                   | -                  | -                 | -               | -             |
|      | PB6  | -                 | TIM2_CH1          | TIM2_ETR              | -                         | -                  | -                 | -               | -             |
|      | PB7  | -                 | TIM1_CH4N         | -                     | -                         | -                  | -                 | -               | -             |
|      | PB8  | LPTIM1_ETR        | TIM1_CH1          | TIM3_ETR              | USART2_RX                 | -                  | -                 | SPI3_MOSI       | -             |
|      | PB9  | -                 | TIM1_CH3N         | TIM3_CH4              | IR_OUT                    | -                  | SPI2_NSS          | SPI3_MISO       | -             |
|      | PB10 | -                 | -                 | -                     | I2C4_SCL                  | I2C2_SCL           | SPI2_SCK          | -               | USART1_CK     |
|      | PB11 | LPTIM1_CH1        | -                 | LPTIM1_ETR            | I2C4_SDA                  | I2C2_SDA           | SPI2_RDY          | -               | USART3_RX     |
|      | PB12 | -                 | TIM2_CH1          | TIM2_ETR              | -                         | I2C2_SMBA          | SPI1_RDY          | SPI2_NSS        | USART1_TX     |
|      | PB13 | -                 | -                 | TIM3_CH4              | -                         | I2C2_SCL           | SPI2_SCK          | -               | USART3_CTS    |
|      | PB14 | RTC_REFIN         | -                 | TIM3_CH3              | -                         | I2C2_SDA           | SPI2_MISO         | -               | USART1_TX     |
|      | PB15 | -                 | TIM1_BKIN2        | -                     | USART2_CTS                | I2C1_SMBA          | -                 | I2C3_SMBA       | -             |

Table 24. Alternate functions (AF0 to AF7)<sup>(1)</sup> (continued)

| Port |      | AF0        | AF1               | AF2                   | AF3                       | AF4                | AF5               | AF6             | AF7           |
|------|------|------------|-------------------|-----------------------|---------------------------|--------------------|-------------------|-----------------|---------------|
|      |      | LPTIM1/SYS | LPTIM1/<br>TIM1/2 | LPTIM1/2/<br>TIM1/2/3 | I2C4/SAI1/SPI2/<br>USART2 | I2C1/2/3/4/<br>OTG | I2C4/<br>SPI1/2/3 | I2C3/<br>SPI2/3 | USART1/2/3    |
| C    | PC0  | -          | LPTIM1_IN1        | -                     | -                         | I2C3_SCL           | SPI2_RDY          | -               | -             |
|      | PC1  | -          | LPTIM1_CH1        | -                     | SPI2_MOSI                 | I2C3_SDA           | -                 | -               | -             |
|      | PC2  | -          | LPTIM1_IN2        | -                     | -                         | -                  | SPI2_MISO         | -               | -             |
|      | PC3  | -          | LPTIM1_ETR        | TIM3_CH1              | SAI1_D1                   | -                  | SPI2_MOSI         | SPI3_MOSI       | -             |
|      | PC4  | -          | -                 | TIM3_CH2              | SAI1_D2                   | -                  | -                 | SPI3_MISO       | USART3_TX     |
|      | PC5  | -          | TIM1_CH4N         | -                     | SAI1_D3                   | -                  | -                 | -               | USART3_RX     |
|      | PC6  | CSLEEP     | -                 | TIM3_CH1              | -                         | -                  | -                 | -               | -             |
|      | PC7  | CSTOP      | -                 | TIM3_CH2              | -                         | -                  | -                 | -               | USART2_RTS_DE |
|      | PC8  | -          | -                 | TIM3_CH3              | -                         | -                  | -                 | -               | USART2_RX     |
|      | PC9  | -          | -                 | TIM3_CH4              | -                         | -                  | -                 | -               | USART2_TX     |
|      | PC10 | -          | -                 | -                     | -                         | -                  | -                 | SPI3_SCK        | USART3_TX     |
|      | PC11 | -          | -                 | -                     | -                         | -                  | -                 | SPI3_MISO       | USART3_RX     |
|      | PC12 | -          | -                 | -                     | -                         | -                  | -                 | SPI3_MOSI       | USART3_CK     |
|      | PC13 | -          | -                 | TIM1_BKIN2            | -                         | -                  | -                 | -               | -             |
|      | PC14 | -          | -                 | -                     | -                         | -                  | -                 | -               | -             |
|      | PC15 | -          | -                 | -                     | -                         | -                  | -                 | -               | -             |

Table 24. Alternate functions (AF0 to AF7)<sup>(1)</sup> (continued)

| Port |      | AF0        | AF1               | AF2                   | AF3                       | AF4                | AF5               | AF6             | AF7           |
|------|------|------------|-------------------|-----------------------|---------------------------|--------------------|-------------------|-----------------|---------------|
|      |      | LPTIM1/SYS | LPTIM1/<br>TIM1/2 | LPTIM1/2/<br>TIM1/2/3 | I2C4/SAI1/SPI2/<br>USART2 | I2C1/2/3/4/<br>OTG | I2C4/<br>SPI1/2/3 | I2C3/<br>SPI2/3 | USART1/2/3    |
| D    | PD0  | -          | -                 | -                     | -                         | -                  | SPI2_NSS          | -               | -             |
|      | PD1  | -          | -                 | -                     | -                         | -                  | SPI2_SCK          | -               | -             |
|      | PD2  | -          | -                 | TIM3_ETR              | -                         | -                  | -                 | -               | USART3_RTS_DE |
|      | PD3  | -          | -                 | -                     | SPI2_SCK                  | -                  | SPI2_MISO         | -               | USART2_CTS    |
|      | PD4  | -          | -                 | LPTIM2_IN2            | -                         | -                  | -                 | -               | USART3_RX     |
|      | PD5  | -          | -                 | -                     | SAI1_D1                   | -                  | SPI3_MOSI         | -               | USART2_RX     |
|      | PD6  | -          | -                 | -                     | -                         | -                  | -                 | -               | -             |
|      | PD7  | -          | -                 | -                     | -                         | -                  | -                 | -               | -             |
|      | PD8  | -          | -                 | -                     | -                         | -                  | -                 | -               | USART2_CK     |
|      | PD9  | -          | -                 | -                     | USART2_TX                 | -                  | -                 | -               | USART3_TX     |
|      | PD10 | -          | -                 | LPTIM2_CH2            | -                         | -                  | -                 | -               | USART3_CK     |
|      | PD11 | -          | -                 | -                     | -                         | I2C4_SMBA          | -                 | -               | USART3_CTS    |
|      | PD12 | -          | -                 | -                     | -                         | I2C4_SCL           | -                 | -               | USART3_RTS_DE |
|      | PD13 | -          | -                 | -                     | -                         | I2C4_SDA           | -                 | -               | -             |
|      | PD14 | TRACED3    | -                 | -                     | -                         | -                  | -                 | -               | -             |
|      | PD15 | -          | -                 | -                     | -                         | -                  | -                 | -               | -             |
| E    | PE0  | TRACECLK   | -                 | -                     | -                         | -                  | -                 | -               | -             |
|      | PE1  | TRACED0    | -                 | -                     | -                         | -                  | -                 | -               | -             |
|      | PE2  | TRACED1    | -                 | TIM3_ETR              | SAI1_CK1                  | -                  | -                 | -               | -             |
|      | PE3  | TRACED2    | -                 | TIM3_CH1              | -                         | -                  | -                 | -               | -             |
|      | PE4  | -          | -                 | TIM3_CH2              | SAI1_D2                   | -                  | -                 | -               | -             |
|      | PE5  | -          | -                 | TIM3_CH3              | SAI1_CK2                  | -                  | -                 | -               | -             |
|      | PE6  | -          | -                 | TIM3_CH4              | SAI1_D1                   | -                  | -                 | -               | -             |

Table 24. Alternate functions (AF0 to AF7)<sup>(1)</sup> (continued)

| Port |      | AF0        | AF1               | AF2                   | AF3                       | AF4                | AF5               | AF6             | AF7           |
|------|------|------------|-------------------|-----------------------|---------------------------|--------------------|-------------------|-----------------|---------------|
|      |      | LPTIM1/SYS | LPTIM1/<br>TIM1/2 | LPTIM1/2/<br>TIM1/2/3 | I2C4/SAI1/SPI2/<br>USART2 | I2C1/2/3/4/<br>OTG | I2C4/<br>SPI1/2/3 | I2C3/<br>SPI2/3 | USART1/2/3    |
| G    | PG2  | -          | -                 | -                     | -                         | -                  | SPI1_SCK          | -               | -             |
|      | PG3  | -          | -                 | -                     | -                         | -                  | SPI1_MISO         | -               | -             |
|      | PG4  | -          | -                 | -                     | -                         | -                  | SPI1_MOSI         | -               | -             |
|      | PG5  | -          | -                 | -                     | -                         | -                  | SPI1_NSS          | -               | -             |
|      | PG6  | -          | -                 | -                     | -                         | I2C3_SMBA          | SPI1_RDY          | -               | -             |
|      | PG7  | -          | -                 | -                     | SAI1_CK1                  | I2C3_SCL           | -                 | -               | -             |
|      | PG8  | -          | -                 | -                     | -                         | I2C3_SDA           | -                 | -               | -             |
|      | PG9  | -          | -                 | -                     | -                         | -                  | -                 | SPI3_SCK        | USART1_TX     |
|      | PG10 | -          | LPTIM1_IN1        | -                     | -                         | -                  | -                 | SPI3_MISO       | USART1_RX     |
|      | PG11 | -          | LPTIM1_IN2        | -                     | -                         | -                  | -                 | SPI3_MOSI       | USART1_CTS    |
|      | PG12 | -          | LPTIM1_ETR        | -                     | -                         | -                  | -                 | SPI3_NSS        | USART1_RTS_DE |
|      | PG13 | -          | -                 | -                     | -                         | I2C1_SDA           | -                 | SPI3_RDY        | USART1_CK     |
|      | PG14 | -          | LPTIM1_CH2        | -                     | -                         | I2C1_SCL           | -                 | -               | -             |
|      | PG15 | -          | LPTIM1_CH1        | -                     | -                         | I2C1_SMBA          | -                 | -               | -             |
| H    | PH3  | -          | -                 | -                     | -                         | -                  | -                 | -               | -             |

1. For AF8 to AF15 refer to [Table 25](#).

Table 25. Alternate functions (AF8 to AF15)<sup>(1)</sup>

| Port | AF8                |                | AF9        | AF10         | AF11      | AF12                 | AF13                 | AF14                  | AF15     |
|------|--------------------|----------------|------------|--------------|-----------|----------------------|----------------------|-----------------------|----------|
|      | LPUART1/<br>USART3 |                | TSC        | OTG/PTA      | RF        | COMP1/2/<br>PTA/TIM4 | LPTIM2/SAI1/<br>TIM4 | LPTIM2/<br>TIM3/16/17 | EVENTOUT |
| A    | PA0                | LPUART1_CTS    | TSC_G2_IO2 | -            | -         | -                    | -                    | TIM3_ETR              | EVENTOUT |
|      | PA1                | LPUART1_RX     | TSC_G2_IO1 | -            | -         | -                    | LPTIM2_CH2           | TIM17_CH1             | EVENTOUT |
|      | PA2                | LPUART1_TX     | TSC_G4_IO4 | -            | -         | -                    | -                    | TIM16_CH1             | EVENTOUT |
|      | PA3                | -              | TSC_G4_IO2 | -            | -         | -                    | -                    | TIM16_CH1N            | EVENTOUT |
|      | PA4                | -              | TSC_G4_IO1 | -            | -         | -                    | AUDIOCLK             | TIM16_CH1             | EVENTOUT |
|      | PA5                | USART3_RX      | TSC_G1_IO4 | -            | -         | -                    | AUDIOCLK             | LPTIM2_ETR            | EVENTOUT |
|      | PA6                | USART3_CTS     | TSC_G1_IO3 | -            | -         | -                    | SAI1_MCLK_A          | -                     | EVENTOUT |
|      | PA7                | USART3_TX      | TSC_G1_IO2 | -            | -         | COMP1_OUT            | SAI1_SCK_A           | -                     | EVENTOUT |
|      | PA8                | -              | TSC_G1_IO1 | OTG_SOF      | -         | -                    | SAI1_FS_A            | -                     | EVENTOUT |
|      | PA9                | LPUART1_RTS_DE | -          | -            | -         | -                    | -                    | -                     | EVENTOUT |
|      | PA10               | LPUART1_RX     | -          | -            | -         | -                    | -                    | -                     | EVENTOUT |
|      | PA11               | -              | -          | -            | RF_ANTSW1 | -                    | -                    | LPTIM2_CH1            | EVENTOUT |
|      | PA12               | -              | TSC_G3_IO4 | PTA_STATUS   | RF_ANTSW0 | COMP2_OUT            | -                    | -                     | EVENTOUT |
|      | PA13               | -              | -          | PTA_PRIORITY | -         | -                    | -                    | -                     | EVENTOUT |
|      | PA14               | -              | -          | PTA_STATUS   | -         | COMP2_OUT            | -                    | -                     | EVENTOUT |
|      | PA15               | -              | TSC_G3_IO3 | PTA_STATUS   | -         | -                    | -                    | TIM17_BKIN            | EVENTOUT |

Table 25. Alternate functions (AF8 to AF15)<sup>(1)</sup> (continued)

| Port |      | AF8                | AF9        | AF10         | AF11        | AF12                 | AF13                 | AF14                  | AF15     |
|------|------|--------------------|------------|--------------|-------------|----------------------|----------------------|-----------------------|----------|
|      |      | LPUART1/<br>USART3 | TSC        | OTG/PTA      | RF          | COMP1/2/<br>PTA/TIM4 | LPTIM2/SAI1/<br>TIM4 | LPTIM2/<br>TIM3/16/17 | EVENTOUT |
| B    | PB0  | -                  | -          | -            | -           | -                    | -                    | -                     | EVENTOUT |
|      | PB1  | -                  | -          | -            | -           | -                    | -                    | -                     | EVENTOUT |
|      | PB2  | -                  | -          | -            | RF_ANTSW2   | -                    | -                    | -                     | EVENTOUT |
|      | PB3  | -                  | TSC_G3_IO2 | PTA_ACTIVE   | -           | -                    | -                    | TIM17_CH1N            | EVENTOUT |
|      | PB4  | -                  | TSC_G3_IO1 | PTA_PRIORITY | -           | PTA_ACTIVE           | SAI1_MCLK_B          | TIM17_CH1             | EVENTOUT |
|      | PB5  | LPUART1_TX         | TSC_G5_IO4 | -            | -           | -                    | SAI1_FS_B            | -                     | EVENTOUT |
|      | PB6  | -                  | TSC_G5_IO3 | -            | -           | TIM4_CH1             | SAI1_SCK_B           | -                     | EVENTOUT |
|      | PB7  | -                  | TSC_G5_IO2 | -            | -           | TIM4_CH2             | SAI1_SD_B            | -                     | EVENTOUT |
|      | PB8  | -                  | TSC_G2_IO4 | -            | -           | COMP1_OUT            | TIM4_CH3             | TIM16_CH1N            | EVENTOUT |
|      | PB9  | LPUART1_RTS_DE     | TSC_G2_IO3 | -            | -           | TIM4_CH4             | LPTIM2_IN1           | TIM16_CH1             | EVENTOUT |
|      | PB10 | USART3_TX          | TSC_G4_IO3 | -            | -           | -                    | -                    | TIM16_BKIN            | EVENTOUT |
|      | PB11 | LPUART1_TX         | -          | -            | -           | -                    | -                    | -                     | EVENTOUT |
|      | PB12 | USART3_CK          | TSC_SYNC   | -            | -           | -                    | SAI1_SD_A            | TIM3_ETR              | EVENTOUT |
|      | PB13 | -                  | TSC_G6_IO2 | -            | -           | -                    | -                    | -                     | EVENTOUT |
|      | PB14 | USART3_RTS_DE      | TSC_G6_IO1 | -            | -           | -                    | SAI1_SD_A            | -                     | EVENTOUT |
|      | PB15 | LPUART1_CTS        | -          | PTA_GRANT    | RF_EXTPABYP | -                    | -                    | TIM16_BKIN            | EVENTOUT |

Table 25. Alternate functions (AF8 to AF15)<sup>(1)</sup> (continued)

| Port |      | AF8                | AF9        | AF10    | AF11 | AF12                 | AF13                 | AF14                  | AF15     |
|------|------|--------------------|------------|---------|------|----------------------|----------------------|-----------------------|----------|
|      |      | LPUART1/<br>USART3 | TSC        | OTG/PTA | RF   | COMP1/2/<br>PTA/TIM4 | LPTIM2/SAI1/<br>TIM4 | LPTIM2/<br>TIM3/16/17 | EVENTOUT |
| C    | PC0  | LPUART1_RX         | -          | -       | -    | -                    | -                    | LPTIM2_IN1            | EVENTOUT |
|      | PC1  | LPUART1_TX         | -          | -       | -    | -                    | SAI1_SD_A            | -                     | EVENTOUT |
|      | PC2  | -                  | -          | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PC3  | -                  | -          | -       | -    | -                    | SAI1_SD_A            | LPTIM2_ETR            | EVENTOUT |
|      | PC4  | -                  | -          | -       | -    | -                    | SAI1_FS_A            | LPTIM2_CH2            | EVENTOUT |
|      | PC5  | -                  | -          | -       | -    | -                    | SAI1_SD_B            | -                     | EVENTOUT |
|      | PC6  | -                  | -          | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PC7  | -                  | -          | -       | -    | -                    | -                    | LPTIM2_CH2            | EVENTOUT |
|      | PC8  | -                  | -          | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PC9  | -                  | -          | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PC10 | -                  | -          | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PC11 | -                  | -          | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PC12 | -                  | -          | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PC13 | -                  | TSC_G5_IO1 | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PC14 | -                  | -          | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PC15 | -                  | -          | -       | -    | -                    | -                    | -                     | EVENTOUT |



Table 25. Alternate functions (AF8 to AF15)<sup>(1)</sup> (continued)

| Port |      | AF8                | AF9        | AF10    | AF11 | AF12                 | AF13                 | AF14                  | AF15     |
|------|------|--------------------|------------|---------|------|----------------------|----------------------|-----------------------|----------|
|      |      | LPUART1/<br>USART3 | TSC        | OTG/PTA | RF   | COMP1/2/<br>PTA/TIM4 | LPTIM2/SAI1/<br>TIM4 | LPTIM2/<br>TIM3/16/17 | EVENTOUT |
| D    | PD0  | -                  | TSC_G8_IO3 | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PD1  | -                  | TSC_G8_IO2 | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PD2  | -                  | TSC_SYNC   | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PD3  | -                  | TSC_G8_IO1 | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PD4  | -                  | -          | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PD5  | -                  | -          | -       | -    | -                    | SAI1_SD_A            | -                     | EVENTOUT |
|      | PD6  | -                  | -          | -       | -    | -                    | -                    | -                     | -        |
|      | PD7  | -                  | -          | -       | -    | -                    | -                    | -                     | -        |
|      | PD8  | -                  | -          | OTG_ID  | -    | -                    | -                    | -                     | EVENTOUT |
|      | PD9  | -                  | -          | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PD10 | -                  | -          | -       | -    | -                    | -                    | -                     | EVENTOUT |
|      | PD11 | -                  | -          | -       | -    | -                    | -                    | LPTIM2_ETR            | EVENTOUT |
|      | PD12 | -                  | TSC_G6_IO3 | -       | -    | -                    | TIM4_CH1             | LPTIM2_IN1            | EVENTOUT |
|      | PD13 | -                  | TSC_G6_IO4 | -       | -    | -                    | TIM4_CH2             | LPTIM2_CH1            | EVENTOUT |
|      | PD14 | -                  | -          | -       | -    | -                    | TIM4_CH3             | -                     | EVENTOUT |
|      | PD15 | -                  | TSC_G8_IO4 | -       | -    | -                    | TIM4_CH4             | -                     | EVENTOUT |
| E    | PE0  | -                  | TSC_G7_IO4 | -       | -    | -                    | TIM4_ETR             | TIM16_CH1             | EVENTOUT |
|      | PE1  | -                  | TSC_G7_IO3 | -       | -    | -                    | -                    | TIM17_CH1             | EVENTOUT |
|      | PE2  | -                  | TSC_G7_IO2 | -       | -    | -                    | SAI1_MCLK_A          | -                     | EVENTOUT |
|      | PE3  | -                  | TSC_G7_IO1 | -       | -    | -                    | SAI1_SD_B            | -                     | EVENTOUT |
|      | PE4  | -                  | -          | -       | -    | -                    | SAI1_FS_A            | -                     | EVENTOUT |
|      | PE5  | -                  | -          | -       | -    | -                    | SAI1_SCK_A           | -                     | EVENTOUT |
|      | PE6  | -                  | -          | -       | -    | -                    | SAI1_SD_A            | -                     | EVENTOUT |

Table 25. Alternate functions (AF8 to AF15)<sup>(1)</sup> (continued)

| Port |      | AF8                | AF9 | AF10      | AF11        | AF12                 | AF13                 | AF14                  | AF15     |
|------|------|--------------------|-----|-----------|-------------|----------------------|----------------------|-----------------------|----------|
|      |      | LPUART1/<br>USART3 | TSC | OTG/PTA   | RF          | COMP1/2/<br>PTA/TIM4 | LPTIM2/SAI1/<br>TIM4 | LPTIM2/<br>TIM3/16/17 | EVENTOUT |
| G    | PG2  | -                  | -   | -         | -           | -                    | SAI1_SCK_B           | -                     | EVENTOUT |
|      | PG3  | -                  | -   | -         | -           | -                    | SAI1_FS_B            | -                     | EVENTOUT |
|      | PG4  | -                  | -   | -         | -           | -                    | SAI1_MCLK_B          | -                     | EVENTOUT |
|      | PG5  | LPUART1_CTS        | -   | -         | -           | -                    | SAI1_SD_B            | -                     | EVENTOUT |
|      | PG6  | LPUSRT1_RTS_DE     | -   | -         | -           | -                    | -                    | -                     | EVENTOUT |
|      | PG7  | LPUART1_TX         | -   | -         | -           | -                    | SAI1_MCLK_A          | -                     | EVENTOUT |
|      | PG8  | LPUART1_RX         | -   | -         | -           | -                    | -                    | -                     | EVENTOUT |
|      | PG9  | -                  | -   | -         | -           | -                    | SAI1_SCK_A           | -                     | EVENTOUT |
|      | PG10 | -                  | -   | -         | -           | -                    | SAI1_FS_A            | -                     | EVENTOUT |
|      | PG11 | -                  | -   | -         | -           | -                    | SAI1_MCLK_A          | -                     | EVENTOUT |
|      | PG12 | -                  | -   | -         | -           | -                    | SAI1_SD_A            | -                     | EVENTOUT |
|      | PG13 | -                  | -   | -         | -           | -                    | -                    | -                     | EVENTOUT |
|      | PG14 | -                  | -   | -         | -           | -                    | -                    | -                     | EVENTOUT |
|      | PG15 | -                  | -   | -         | -           | -                    | -                    | -                     | EVENTOUT |
| H    | PH3  | -                  | -   | PTA_GRANT | RF_EXTPABYP | -                    | -                    | -                     | EVENTOUT |

1. For AF0 to AF7 refer to [Table 24](#).

## 5 Electrical characteristics

### 5.1 Parameter conditions

Unless otherwise specified, all voltages are referenced to  $V_{SS}$ .

#### 5.1.1 Minimum and maximum values

Unless otherwise specified, the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at  $T_A = 25\text{ }^{\circ}\text{C}$  and  $T_A = T_A \text{ max}$  (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes and are not tested in production. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation (mean  $\pm 3\sigma$ ).

#### 5.1.2 Typical values

Unless otherwise specified, typical data are based on  $T_A = 25\text{ }^{\circ}\text{C}$  and supply voltage  $V_{DD} = V_{DDA} = V_{DDRF} = 3\text{ V}$ . They are only given as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error lower than or equal to the value indicated (mean  $\pm 2\sigma$ ).

#### 5.1.3 Typical curves

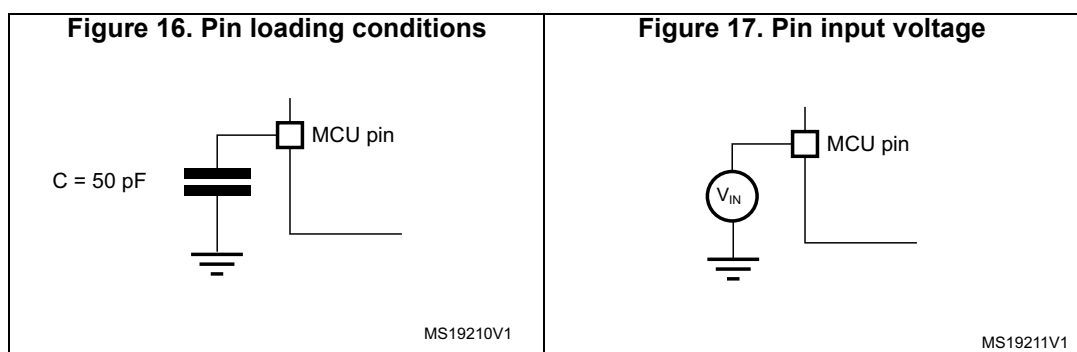
Unless otherwise specified, all typical curves are given only as design guidelines, and are not tested.

#### 5.1.4 Loading capacitor

Unless otherwise specified, the loading conditions used for pin parameter measurement are shown in [Figure 16](#).

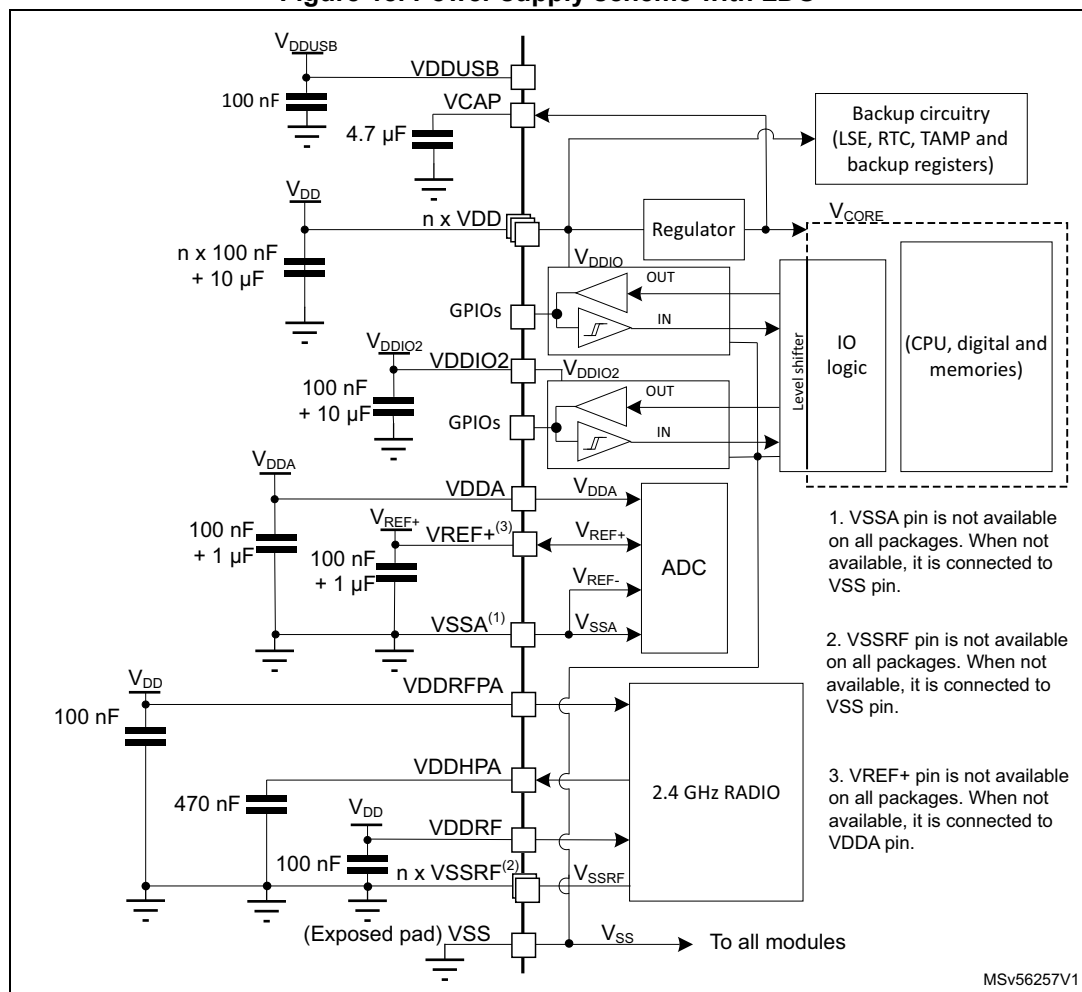
#### 5.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in [Figure 17](#).



## 5.1.6 Power supply scheme

Figure 18. Power supply scheme with LDO



**Figure 19. Power supply scheme with SMPS**

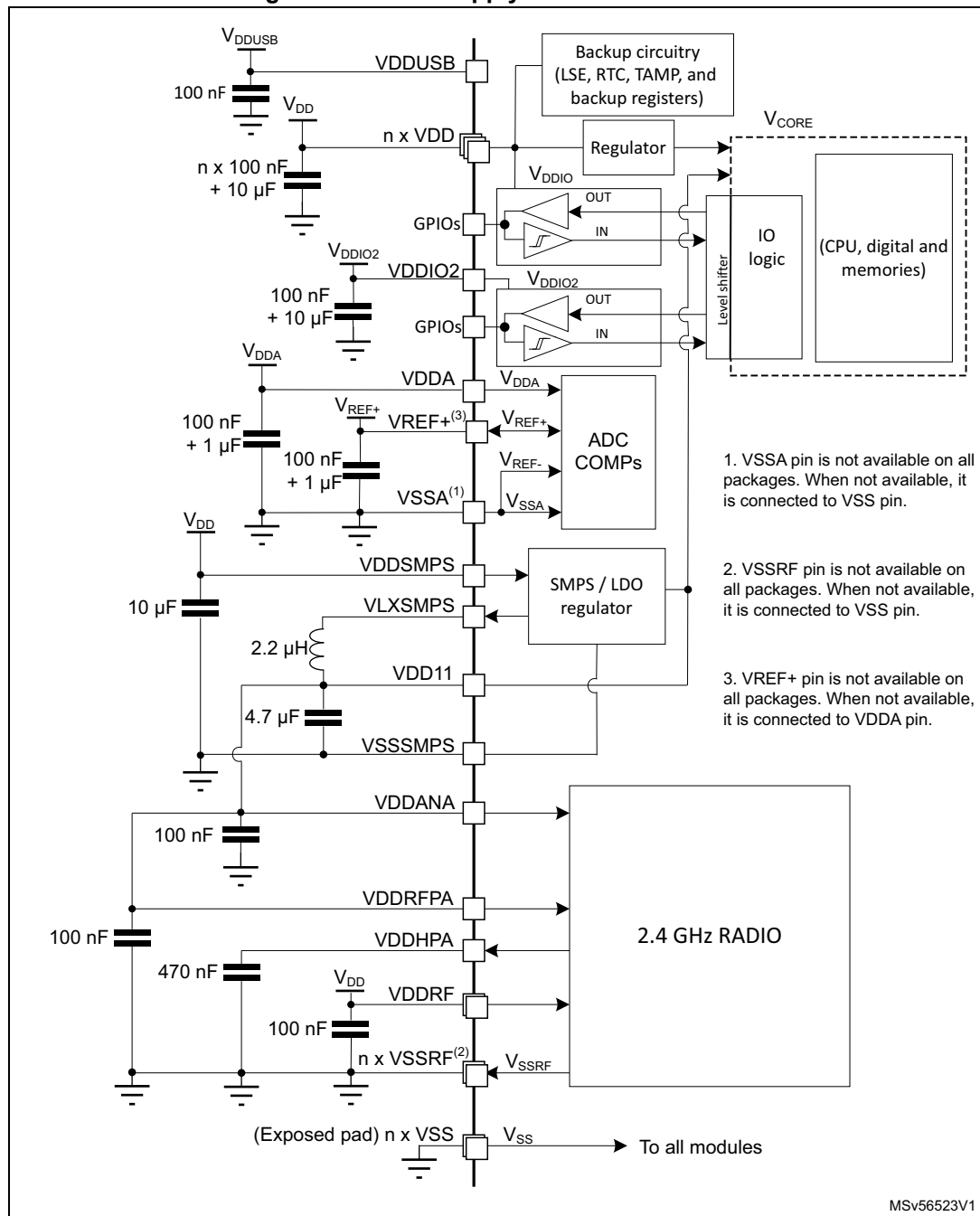
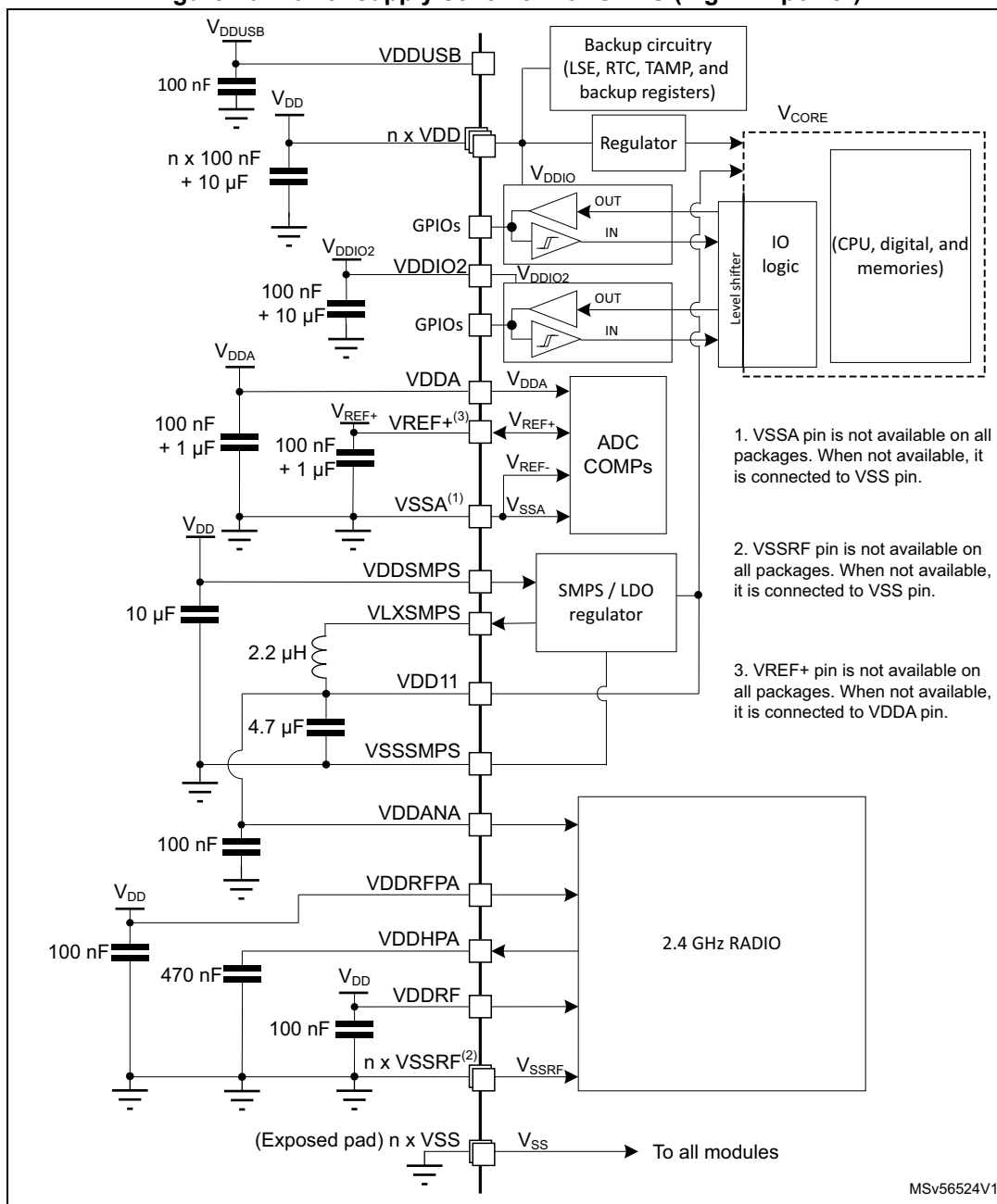


Figure 20. Power supply scheme with SMPS (high RF power)



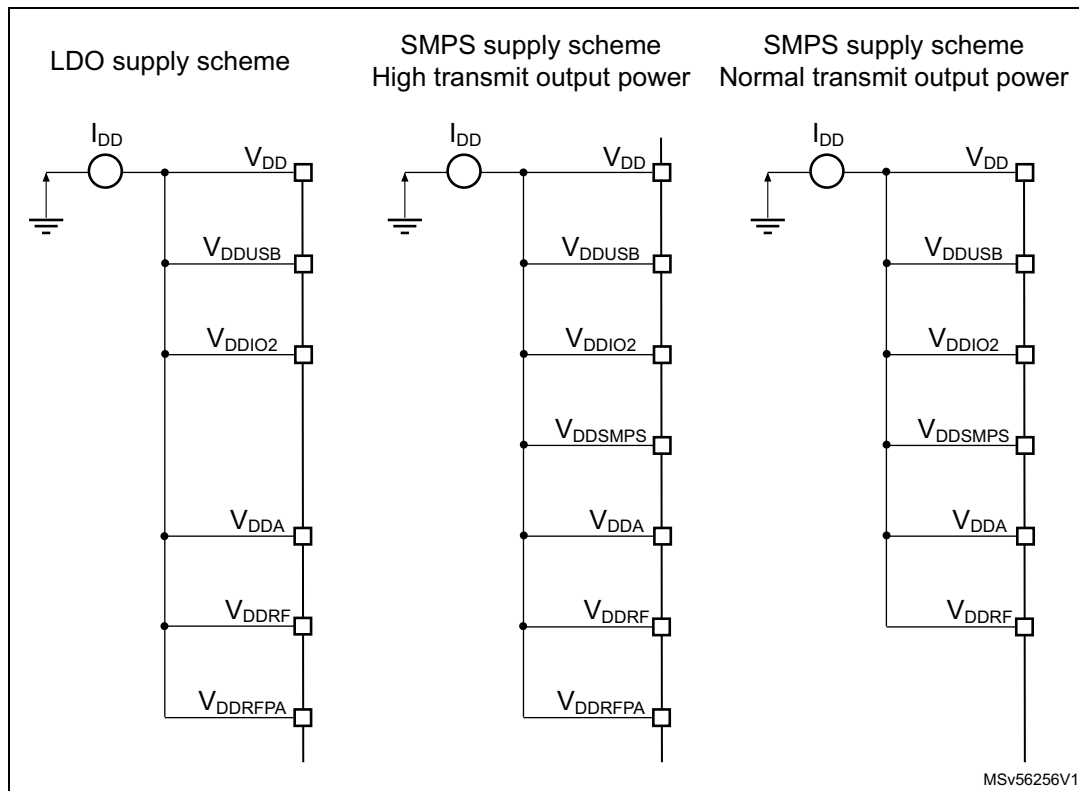
**Caution:** Each power supply pair ( $V_{DD} / V_{SS}$ ,  $V_{DDA} / V_{SS}$ ,  $V_{DDRFPA} / V_{SS}$ ,  $V_{DDRF} / V_{SS}$ ) must be decoupled with filtering ceramic capacitors as shown. These capacitors must be placed as close as possible to (or below) the appropriate pins to ensure correct device functionality.

**Caution:**  $V_{DD}$  and  $V_{DDRF}$  must be connected to the same supply.

### 5.1.7 Current consumption measurement

The  $I_{DD}$  parameters in the tables in the next sections represent the total MCU consumption, including the current supplying  $V_{DD}$ ,  $V_{DDIO2}$ ,  $V_{DDUSB}$ ,  $V_{DDA}$ ,  $V_{DDRF}$ ,  $V_{DDRFPA}$ , and  $V_{DDSMPS}$  (if the device embeds the SMPS), or the total 2.4 GHz RADIO current supplying  $V_{DDRF}$  and  $V_{DDRFPA}$ .

Figure 21. Current consumption measurement scheme



## 5.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in [Table 26](#), [Table 27](#), and [Table 28](#) can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods can affect device reliability. Device mission profile (application conditions) is compliant with JEDEC JESD47 Qualification Standard, extended mission profiles are available on demand.

Table 26. Voltage characteristics<sup>(1)</sup>

| Symbol               | Ratings  | Min            | Max   | Unit |
|----------------------|--|----------------|---|------|
| $V_{DDX} - V_{SS}$   | External main supply voltage (including $V_{DDUSB}$ , $V_{DDA}$ , $V_{DDRF}$ , $V_{DDRFPA}$ , $V_{DDANA}$ , $V_{DDSMPS}$ ) | -0.3           | 4.0   | V    |
| $V_{DDIOX} - V_{SS}$ | I/O supply when HSLV = 0 (including $V_{DD}$ , $V_{DDIO2}$ )   |                | 4.0   |      |
|                      | I/O supply when HSLV = 1 (including $V_{DD}$ , $V_{DDIO2}$ )   |                | 2.75  |      |
| $V_{IN}^{(2)}$       | Input voltage on FT_ (any option) pins   | $V_{SS} - 0.3$ | $\min(\min(V_{DD}, V_{DDIO2}, V_{DDUSB}, V_{DDA}) + 4.0, 6.0)^{(3)(4)}$ |      |
|                      | Input voltage on any other pin   |                | 4.0   |      |
| $ \Delta V_{DDx} $   | Variations between different VDDX power pins of the same domain  | -              | 50.0  | mV   |
| $ V_{SSx} - V_{SS} $ | Variations between all the different ground pins   | -              | 50.0  |      |

1. All main power ( $V_{DD}$ ,  $V_{DDIO2}$ ,  $V_{DDUSB}$ ,  $V_{DDA}$ ,  $V_{DDRF}$ ,  $V_{DDRFPA}$ ,  $V_{DDANA}$ ,  $V_{DDSMPS}$ ) and ground ( $V_{SS}$ ,  $V_{SSA}$ ,  $V_{SSRF}$ ,  $V_{SSSMPS}$ ) pins must always be connected to the external power supply, in the permitted range.
2.  $V_{IN}$  maximum must always be respected. Refer to [Table 27](#) for the maximum allowed injected current values.
3. To sustain a voltage higher than 4 V, the internal pull-up/pull-down resistors must be disabled.
4. This formula applies only to power supplies related to the I/O structure described by the pin definition table.

Table 27. Current characteristics

| Symbol                  | Ratings   | Max   | Unit |
|-------------------------|---|-------|------|
| $\sum I_{V_{DD}}$       | Total current into sum of all $V_{DD}$ power lines (source) <sup>(1)</sup>      | 200   | mA   |
| $\sum I_{V_{SS}}$       | Total current out of sum of all $V_{SS}$ ground lines (sink) <sup>(1)</sup>     | 200   |      |
| $I_{V_{DD}(PIN)}$       | Maximum current into each $V_{DD}$ power pin (source) <sup>(1)</sup>            | 100   |      |
| $I_{V_{SS}(PIN)}$       | Maximum current out of each $V_{SS}$ ground pin (sink) <sup>(1)</sup>           | 100   |      |
| $I_{IO}$                | Output current sunk by any I/O and control pin                                  | 20    |      |
| $\sum I_{(PIN)}$        | Total output current sunk by sum of all I/Os and control pins <sup>(2)</sup>    | 120   |      |
|                         | Total output current sourced by sum of all I/Os and control pins <sup>(2)</sup> | 120   |      |
| $I_{INJ(PIN)}^{(3)(4)}$ | Injected current on FT_xxx, TT_xx, RST pins                                     | -5/+0 |      |
| $\sum  I_{INJ(PIN)} $   | Total injected current (sum of all I/Os and control pins) <sup>(5)</sup>        | ±25   |      |

1. All main power ( $V_{DD}$ ,  $V_{DDIO2}$ ,  $V_{DDUSB}$ ,  $V_{DDA}$ ,  $V_{DDRF}$ ,  $V_{DDRFPA}$ ,  $V_{DDANA}$ ,  $V_{DDSMPS}$ ) and ground ( $V_{SS}$ ,  $V_{SSA}$ ,  $V_{SSRF}$ ,  $V_{SSSMPS}$ ) pins must always be connected to the external power supplies, in the permitted range.
2. This current consumption must be correctly distributed over all I/Os and control pins. The total output current must not be sunk/sourced between two consecutive power supply pins.
3. Positive injection (when  $V_{IN} > V_{DD}$ ) is not possible on these I/Os and does not occur for input voltages lower than the specified maximum value.
4. A negative injection is induced by  $V_{IN} < V_{SS}$ .  $I_{INJ(PIN)}$  must never be exceeded. Refer also to [Table 26](#) for the maximum allowed input voltage values.
5. When several inputs are submitted to a current injection, the maximum  $\sum |I_{INJ(PIN)}|$  is the absolute sum of the negative injected currents (instantaneous values).



Table 28. Thermal characteristics

| Symbol     | Ratings                      | Value       | Unit |
|------------|------------------------------|-------------|------|
| $T_{STG}$  | Storage temperature range    | -65 to +150 | °C   |
| $T_{JMAX}$ | Maximum junction temperature | 140         |      |

## 5.3 Operating conditions

### 5.3.1 Summary of main performance

Table 29. Main performance at  $V_{DD} = 3.3\text{ V}$ 

| Parameter |                                |     | Test conditions  | Typ    | Unit          |
|-----------|--------------------------------|-----|--|--------|---------------|
| $I_{DD}$  | Core current consumption       |     | Standby (64 Kbytes RAM retention)  | 1.15   | $\mu\text{A}$ |
|           |                                |     | Stop 1   | 9.67   |               |
|           |                                |     | Stop 2   | 5.30   |               |
|           |                                |     | Sleep ( $V_{DD} = 3.0\text{ V}$ , 16 MHz)  | 0.25   | mA            |
|           |                                |     | Run (100 MHz)  | 4.40   |               |
|           |                                |     | Radio BLE Rx 1 Mbps <sup>(1)</sup>   | 4.26   |               |
|           |                                |     | Radio BLE Tx 0 dBm output power <sup>(1)</sup>   | 5.94   |               |
| $I_{DD}$  | Peripheral current consumption | BLE | Advertising using Standby mode <sup>(2)</sup><br>(Tx = 0 dBm; Period 1.28 s; 31 bytes, 3 channels) | 13.334 | $\mu\text{A}$ |
|           |                                |     | Advertising using Standby mode <sup>(2)</sup><br>(Tx = 0 dBm, 6 bytes; period 10.24 s, 3 channels) | 4.544  |               |

1. Power consumption including RF subsystem and digital processing.

2. Power consumption integrated over 100 s, including Cortex-M33, 2.4 GHz RADIO subsystem and digital processing.

### 5.3.2 General operating conditions

Table 30. General operating conditions

| Symbol              | Parameter  | Conditions                       | Min                 | Typ | Max  | Unit |
|---------------------|--|----------------------------------|---------------------|-----|------|------|
| V <sub>DD</sub>     | Standard operating voltage                           | V <sub>DD</sub> GPIO HSLV = 0    | 1.71 <sup>(1)</sup> | -   | 3.6  | V    |
|                     |  | V <sub>DD</sub> GPIO HSLV = 1    |                     | -   | 2.75 |      |
| V <sub>DDIO2</sub>  | Supply voltage for PG I/O port                       | V <sub>DDIO2</sub> GPIO HSLV = 0 | 1.08                | -   | 3.6  | V    |
|                     |  | V <sub>DDIO2</sub> GPIO HSLV = 1 |                     | -   | 2.75 |      |
| V <sub>DDUSB</sub>  | USB supply voltage                                   | USB used                         | 3.0                 | -   | 3.6  | V    |
|                     |  | USB not used                     | 0                   | -   |      |      |
| V <sub>DDSMPS</sub> | Supply voltage for internal SMPS step-down converter | -                                | V <sub>DD</sub>     |     |      | V    |

Table 30. General operating conditions (continued)

| Symbol             | Parameter  | Conditions   | Min  | Typ  | Max  | Unit             |
|--------------------|--|--|------|------|--|------------------|
| $V_{DDA}$          | Analog supply voltage  | ADC used   | 1.62 | -    | 3.6  | V                |
|                    |  | COMP used  | 1.58 | -    |  |                  |
|                    |  | ADC, COMP not used   | 0    | -    |  |                  |
| $V_{DDRF}$         | RF operating voltage   | -  | 1.71 | -    | 3.6  | V                |
| $V_{DDRFPA}$       | RF power amplifier operating voltage   | $V_{DDRFPA}$ supply must be equal or lower than $V_{DDRF}$ .   | 1.15 | -    | 3.6  | V                |
| $V_{DDANA}$        | RF analog supply   | $V_{DDANA}$ supply must be equal or lower than $V_{DDRF}$ .  | 1.15 | -    | 3.6  | V                |
| $V_{IN}$           | I/O input voltage  | All I/Os FT <sub>1</sub> (any option) pins   | -0.3 | -    | $\min(\min(V_{DD}, V_{DDIO2}, V_{DDA}) + 3.6, 5.5)^{(2)(3)}$ |                  |
|                    |  | TT I/O pins  |      |      | $V_{DD} + 0.3$   |                  |
| $V_{CORE}$         | Internal regulator ON  | Range 1  | 1.15 | 1.21 | 1.27   |                  |
|                    |  | Range 2  | 0.81 | 0.90 | 0.99   |                  |
| $f_{HCLK}$         | Internal AHB1, AHB2, and AHB4 clock frequency  | Range 1  | -    | -    | 100  | MHz              |
|                    |  | Range 2  | -    | -    | 16   |                  |
| $f_{PCLK}$         | Internal APB1, APB2, and APB7 clock frequency  | Range 1  | -    | -    | 100  |                  |
|                    |  | Range 2  | -    | -    | 16   |                  |
| $f_{HCLK5}$        | Internal AHB5 clock frequency  | Range 1  | -    | -    | 32   | MHz              |
|                    |  | Range 2  | -    | -    | 12   |                  |
| $\Delta f_{HCLK1}$ | Internal AHB1, AHB2 and AHB4 clock incremental frequency step <sup>(4)</sup>                                     | -  | -    | -    | 84   | MHz              |
| $P_D$              | Power dissipation at $T_A = 85^\circ\text{C}$ (suffix 6 version) or $T_A = 105^\circ\text{C}$ (suffix 7 version) | See <a href="#">Section 6.6</a> for appropriate thermal resistance and package. Power dissipation is calculated according to ambient temperature ( $T_A$ ), maximum junction temperature ( $T_J$ ), and selected thermal resistance. |      |      |  | mW               |
| $T_A$              | Ambient temperature (suffix 6 version)   | Max power dissipation  | -40  | -    | 85   | $^\circ\text{C}$ |
|                    |  | Low-power dissipation <sup>(5)</sup>   |      |      | 105  |                  |
|                    | Ambient temperature (suffix 7 version)   | Max power dissipation  | -40  | -    | 105  |                  |
|                    |  | Low-power dissipation <sup>(5)</sup>   |      |      | 125  |                  |
| $T_J$              | Junction temperature range   | Suffix 6 version   | -40  | -    | 105  | $^\circ\text{C}$ |
|                    |  | Suffix 7 version <sup>(6)</sup>  |      |      | 125  |                  |

1. When RESET is released functionality is guaranteed down to  $V_{BORx}$  min.

2. Applies only on the power supplies related to the I/O structure described by the pin definition table. The maximum I/O input voltage is the smallest value between  $\min(V_{DD}, V_{DDIO2}, V_{DDA}, V_{DDUSB}) + 3.6\text{ V}$  and  $5.5\text{ V}$ .

3. For operation with voltages higher than  $\min(V_{DD}, V_{DDIO2}, V_{DDA}, V_{DDUSB}) + 3.6\text{ V}$  the internal pull-up and pull-down resistors must be disabled.

4. Without system clock frequency step limiting.

- In low-power dissipation state,  $T_A$  can be extended to this range as long as  $T_J$  does not exceed  $T_{J\max}$  (see [Section 6.6](#)).
- Junction temperature above 105 °C must be limited to 30% of 10 years life time.

### 5.3.3 RF characteristics

**Table 31. Generic RF transmitter characteristics<sup>(1)</sup>**

| Symbol          | Parameter  |                     | Test conditions   | Standard | Min | Typ   | Max | Unit |
|-----------------|--|---------------------|---|----------|-----|-------|-----|------|
| $P_{txmax}$     | Maximum output power                                 |                     | $V_{DDRFPA} \geq 2.50\text{ V}$   | -        | -   | 9.5   | -   | dBm  |
|                 |  |                     | $V_{DDRFPA} \geq 1.71\text{ V}$   | -        | -   | 7.5   | -   |      |
| $P_{txmin}$     | Minimum output power                                 |                     | -   | -        | -   | -20   | -   |      |
| $\Delta P_{tx}$ | Output power step                                    |                     | -   | -        | -   | 1     | -   |      |
| $P_{freqband}$  | Output power $\pm$ variation over the frequency band |                     | $P_{txmax}$ max setting   | -        | -   | 0.4   | -   | dB   |
| $P_{temp}$      | Output power $\pm$ variation over the temperature    |                     | $P_{txmax}$ max setting<br>$-40\text{ °C} \leq T_J \leq +105\text{ °C}$ | -        | -   | 2.9   | -   |      |
| $P_{2ndHARM}$   | Second harmonic                                      |                     | $P_{txmax}$ max setting   | -        | -   | -69.5 | -   | dBm  |
| $P_{3rdHARM}$   | Third harmonic                                       |                     | $P_{txmax}$ max setting   | -        | -   | -70.5 | -   |      |
| $OBSE_{1Mbps}$  | Out of band spurious emission 1 Mbps                 | $< 1\text{ GHz}$    | $P_{txmax}$ max setting   | (2)      | -   | -51   | -   |      |
|                 |  | $\geq 1\text{ GHz}$ | $P_{txmax}$ max setting   |          | -   | -43   | -   |      |
| $OBSE_{2Mbps}$  | Out of band spurious emission 2 Mbps                 | $< 1\text{ GHz}$    | $P_{txmax}$ max setting   | (2)      | -   | -54   | -   |      |
|                 |  | $\geq 1\text{ GHz}$ | $P_{txmax}$ max setting   |          | -   | -45   | -   |      |

- Evaluated by characterization, not tested in production, unless otherwise specified. Measured in conducted mode, based on reference design (see AN5165), using output power specific external RF filter and impedance matching networks to interface with a 50  $\Omega$  antenna.
- Suitable for systems targeting compliance with worldwide radio-frequency regulations ETSI EN 300 328 and EN 300 440 Class 2 (Europe), FCC CFR47 Part 15 (US), and ARIB STD-T66 (Japan).

**Table 32. Generic RF receiver characteristics<sup>(1)</sup>**

| Symbol        | Parameter          | Test conditions | Standard | Min | Typ     | Max | Unit |
|---------------|--------------------|-----------------|----------|-----|---------|-----|------|
| $Rssi_{max}$  | RSSI maximum value | -               | -        | -   | -32     | -   | dBm  |
| $Rssi_{min}$  | RSSI minimum value | -               | -        | -   | -75     | -   |      |
| $Rssi_{accu}$ | RSSI accuracy      | -               | -        | -   | $\pm 6$ | -   | dB   |

- Evaluated by characterization, not tested in production, unless otherwise specified. Measured in conducted mode, based on reference design (see AN5165), using output power specific external RF filter and impedance matching networks to interface with a 50  $\Omega$  antenna.

**Table 33. RF Bluetooth® LE characteristics**

| Symbol     | Parameter                        | Test conditions | Min  | Typ | Max  | Unit |
|------------|----------------------------------|-----------------|------|-----|------|------|
| $F_{op}$   | Frequency channel operating band | -               | 2402 | -   | 2480 | MHz  |
| $\Delta F$ | Delta frequency                  | -               | -    | 250 | -    | kHz  |

Table 33. RF Bluetooth® LE characteristics (continued)

| Symbol | Parameter          | Test conditions | Min   | Typ | Max | Unit |
|--------|--------------------|-----------------|-------|-----|-----|------|
| Rgfsk  | On air data rate   | -               | 0.125 | -   | 2   | Mbps |
| PLLres | RF channel spacing | -               | -     | 2   | -   | MHz  |

Table 34. RF transmitter Bluetooth® LE characteristics<sup>(1)</sup>

| Symbol                 | Parameter                               |         | Test conditions                | Standard  | Min   | Typ   | Max   | Unit          |
|------------------------|---|---------|--------------------------------|-----------|-------|-------|-------|---------------|
| BW6dB <sub>1Mbps</sub> | 6 dB signal bandwidth                   |         | P <sub>txmax</sub> max setting | -         | -     | 665   | -     | kHz           |
| BW6dB <sub>2Mbps</sub> | 6 dB signal bandwidth                   |         | P <sub>txmax</sub> max setting | -         | -     | 1142  | -     |               |
| IBSE <sub>1Mbps</sub>  | In band spurious emission               | 2 MHz   | -                              | -20       | -     | -41   | -20   | dBm           |
|                        |   | ≥ 3 MHz | -                              | -30       | -     | -47.5 | -30   |               |
| IBSE <sub>2Mbps</sub>  | In band spurious emission               | 4 MHz   | -                              | -20       | -     | -42.5 | -20   | dBm           |
|                        |   | 5 MHz   | -                              | -20       | -     | -44   | -20   |               |
|                        |   | ≥ 6 MHz | -                              | -30       | -     | -45   | -30   |               |
| f <sub>d</sub>         | Frequency drift                         |         | -                              | ±50       | -50   | -     | +50   | kHz           |
| dr <sub>max</sub>      | Maximum drift rate                      | Uncoded | -                              | ±20       | -20   | -     | +20   | kHz/<br>50 μs |
|                        |   | Coded   | -                              | ±19.2     | -19.2 | -     | +19.2 |               |
| f <sub>o</sub>         | Frequency offset                        |         | -                              | ±150      | -150  | -     | +150  | kHz           |
| Δf <sub>1Mbps</sub>    | Frequency deviation average 1 Mbps      |         | -                              | 225 - 275 | 225   | -     | 275   |               |
| Δf <sub>1Mbps</sub>    | Frequency deviation average 2 Mbps      |         | -                              | 450 - 550 | 450   | -     | 550   |               |
| Δf <sub>1CodedS8</sub> | Frequency deviation average Coded S = 8 |         | -                              | 225 - 275 | 225   | -     | 275   |               |
| Δf <sub>2Mbps</sub>    | Frequency deviation 99.9% 1 Mbps        |         | -                              | 185       | 185   | -     | -     |               |
| Δf <sub>2Mbps</sub>    | Frequency deviation 99.9% 2 Mbps        |         | -                              | 370       | 370   | -     | -     |               |

1. Evaluated by characterization, not tested in production, unless otherwise specified. Measured in conducted mode, based on reference design (see AN5165), using output power specific external RF filter and impedance matching networks to interface with a 50 Ω antenna.

Table 35. RF receiver Bluetooth® LE characteristics <sup>(1)</sup>

| Symbol                                  | Parameter   | Test conditions                           | Standard | Min | Typ  | Max | Unit |
|---|---|---|----------|-----|------|-----|------|
| P <sub>rxmax</sub>                      | Maximum input signal  | PER ≤ 30.8%                               | -10      | -   | 6    | -   | dBm  |
| P <sub>sens2Mbps</sub> <sup>(2)</sup>   | Sensitivity 2 Mbps  | SMPS bypass <sup>(3)</sup>                | -70      | -   | -93  | -   |      |
|   |   | SMPS on <sup>(3)</sup>                    |          | -   |      | -   |      |
| P <sub>sens1Mbps</sub> <sup>(2)</sup>   | Sensitivity 1 Mbps  | SMPS bypass <sup>(3)</sup>                | -70      | -   | -96  | -   |      |
|   |   | SMPS on <sup>(3)</sup>                    |          | -   |      | -   |      |
| P <sub>sens500kbps</sub> <sup>(2)</sup> | Sensitivity 500 kbps  | SMPS bypass <sup>(3)</sup>                | -75      | -   | -99  | -   |      |
|   |   | SMPS on <sup>(3)</sup>                    |          | -   |      | -   |      |
| P <sub>sens125kbps</sub> <sup>(2)</sup> | Sensitivity 125 kbps  | SMPS bypass <sup>(3)</sup>                | -82      | -   | -102 | -   |      |
|   |   | SMPS on <sup>(3)</sup>                    |          | -   |      | -   |      |
| P <sub>IMD1Mbps</sub>                   | Intermodulation 1 Mbps  | f <sub>2</sub> - f <sub>1</sub>   = 3 MHz | -50      | -50 | -37  | -   |      |
|   |   | f <sub>2</sub> - f <sub>1</sub>   = 4 MHz |          | -50 | -27  | -   |      |
|   |   | f <sub>2</sub> - f <sub>1</sub>   = 5 MHz |          | -50 | -28  | -   |      |
| P <sub>OBB1Mbps</sub>                   | Out of band blocking (for desired signal at -67 dBm and 1 Mbps) | 30 to 2000 MHz                            | -30      | -30 | -10  | -   | dBm  |
|   |   | 2000 to 2399 MHz                          | -35      | -35 | -22  | -   |      |
|   |   | 2484 to 2999 MHz                          | -35      | -35 | -15  | -   |      |
|   |   | 3 to 12.75 GHz                            | -30      | -30 | -10  | -   |      |
| P <sub>IMD2Mbps</sub>                   | Intermodulation 2 Mbps  | f <sub>2</sub> - f <sub>1</sub>   = 3 MHz | -50      | -50 | -37  | -   |      |
|   |   | f <sub>2</sub> - f <sub>1</sub>   = 4 MHz |          | -50 | -30  | -   |      |
|   |   | f <sub>2</sub> - f <sub>1</sub>   = 5 MHz |          | -50 | -30  | -   |      |
| P <sub>OBB2Mbps</sub>                   | Out of band blocking (for desired signal at -67 dBm and 2 Mbps) | 30 to 2000 MHz                            | -30      | -30 | -10  | -   |      |
|   |   | 2000 to 2399 MHz                          | -35      | -35 | -33  | -   |      |
|   |   | 2484 to 2999 MHz                          | -35      | -35 | -19  | -   |      |
|   |   | 3 to 12.75 GHz                            | -30      | -30 | -10  | -   |      |

Table 35. RF receiver Bluetooth® LE characteristics <sup>(1)</sup> (continued)

| Symbol                   | Parameter                              | Test conditions    | Standard | Min | Typ | Max | Unit |
|--------------------------|--|--------------------|----------|-----|-----|-----|------|
| C/I <sub>co125kbps</sub> | Co-channel rejection 125 kbps          | -                  | 12       | -   | 3   | -   | dB   |
| C/I <sub>125kbps</sub>   | Adjacent channel interference 125 kbps | Adj = ±1 MHz       | 6        | -   | -2  | 6   |      |
|                          |  | Adj = 2 MHz        | -26      | -   | -38 | -26 |      |
|                          |  | Adj-Image = -2 MHz | -18      | -   | -27 | -18 |      |
|                          |  | Adj ≥ 3 MHz        | -36      | -   | -43 | -36 |      |
|                          |  | Adj = -3 MHz       | -24      | -   | -28 | -24 |      |
|                          |  | Adj ≤ -4 MHz       | -36      | -   | -43 | -36 |      |
| C/I <sub>co250kbps</sub> | Co-channel rejection 250 kbps          | -                  | 17       | -   | 5   | 17  |      |
| C/I <sub>500kbps</sub>   | Adjacent channel interference 500 kbps | Adj = ±1 MHz       | 11       | -   | -2  | 11  |      |
|                          |  | Adj = 2 MHz        | -21      | -   | -34 | -21 |      |
|                          |  | Adj-Image = -2 MHz | -13      | -   | -26 | -13 |      |
|                          |  | Adj ≥ 3 MHz        | -31      | -   | -39 | -31 |      |
|                          |  | Adj = -3 MHz       | -19      | -   | -27 | -19 |      |
|                          |  | Adj ≤ -4 MHz       | -31      | -   | -37 | -31 |      |
| C/I <sub>co1Mbps</sub>   | Co-channel rejection 1 Mbps            | -                  | 21       | -   | 8   | 21  |      |
| C/I <sub>1Mbps</sub>     | Adjacent channel interference 1 Mbps   | Adj = ±1 MHz       | 15       | -   | 0   | 15  |      |
|                          |  | Adj = 2 MHz        | -17      | -   | -38 | -17 |      |
|                          |  | Adj-Image = -2 MHz | -9       | -   | -23 | -9  |      |
|                          |  | Adj ≥ 3 MHz        | -27      | -   | -36 | -27 |      |
|                          |  | Adj = -3 MHz       | -15      | -   | -27 | -15 |      |
|                          |  | Adj ≤ -4 MHz       | -27      | -   | -38 | -27 |      |
| C/I <sub>co2Mbps</sub>   | Co-channel rejection 2 Mbps            | -                  | 21       | -   | 8   | 21  |      |
| C/I <sub>2Mbps</sub>     | Adjacent channel interference 2 Mbps   | Adj = ±2 MHz       | 15       | -   | 0   | 15  | dB   |
|                          |  | Adj = 4 MHz        | -17      | -   | -35 | -17 |      |
|                          |  | Adj-Image = -4 MHz | -9       | -   | -23 | -9  |      |
|                          |  | Adj = ≥ 6 MHz      | -27      | -   | -33 | -27 |      |
|                          |  | Adj = -6 MHz       | -15      | -   | -26 | -15 |      |
|                          |  | Adj = ≤ -8 MHz     | -27      | -   | -34 | -27 |      |

1. Evaluated by characterization, not tested in production, unless otherwise specified. Measured in conducted mode, based on reference design (see AN5165), using output power specific external RF filter and impedance matching networks to interface with a 50 Ω antenna.
2. With ideal transmitter.
3. The payload length used in all receiver tests is 37 bytes which means that the limit for each parameter is reached for a BER of 0.1% (PER of 30.8%), as defined in the Bluetooth® LE core specification.

**Table 36. RF Bluetooth® LE power consumption for  $V_{DD} = 3.3\text{ V}^{(1)(2)}$** 

| Symbol   | Parameter   | Typ   | Unit |
|----------|---|-------|------|
| $I_{tx}$ | Tx 0 dBm output power consumption (LDO)                                 | 11.39 | mA   |
|          | Tx 0 dBm output power consumption (SMPS ON, VDDRFPA connected to VDD)   | 6.16  |      |
|          | Tx 0 dBm output power consumption (SMPS ON, VDDRFPA connected to VDD11) | 5.94  |      |
|          | Tx +10 dBm output power consumption (LDO)                               | 22.38 |      |
|          | Tx +10 dBm output power consumption (SMPS ON, VDDRFPA connected to VDD) | 21.18 |      |
| $I_{rx}$ | Rx consumption 1 Mbps (LDO)   | 7.83  |      |
|          | Rx consumption 1 Mbps (SMPS ON, VDDRFPA connected to VDD)               | 5.33  |      |
|          | Rx consumption 1 Mbps (SMPS ON, VDDRFPA connected to VDD11)             | 4.26  |      |
|          | Rx consumption 2 Mbps (LDO)   | 8.53  |      |
|          | Rx consumption 2 Mbps (SMPS ON, VDDRFPA connected to VDD)               | 8     |      |
|          | Rx consumption 2 Mbps (SMPS ON, VDDRFPA connected to VDD11)             | 5     |      |

1. Evaluated by characterization, not tested in production, unless otherwise specified.
2. Power consumption including 2.4 GHz RADIO subsystem and digital processing.

### 5.3.4 RF IEEE802.15.4 characteristics

**Table 37. RF IEEE802.15.4 characteristics<sup>(1)</sup>**

| Symbol     | Parameter                        | Conditions | Standard | Min  | Typ | Max  | Unit |
|------------|----------------------------------|------------|----------|------|-----|------|------|
| $F_{op}$   | Frequency channel operating band | -          | -        | 2405 | -   | 2480 | MHz  |
| $\Delta F$ | Delta frequency                  | -          | -        | -    | 5   | -    |      |
| Roqpsk     | On air data rate                 | -          | -        | -    | 250 | -    | kbps |
| PLLres     | RF channel spacing               | -          | -        | -    | 5   | -    | MHz  |

1. Guaranteed by characterization results, unless otherwise specified. Measured in conducted mode, based on reference design (see AN5165), using output power specific external RF filter and impedance matching networks to interface with a 50  $\Omega$  antenna.

**Table 38. RF transmitter IEEE802.15.4 characteristics<sup>(1)</sup>**

| Symbol          | Parameter  | Test conditions   | Standard | Min | Typ | Max | Unit |
|-----------------|--|---|----------|-----|-----|-----|------|
| $P_{txmax}$     | Maximum output power                                 | $V_{DDRFPA} \geq 2.50\text{ V}$   | -        | -   | 9.5 | -   | dBm  |
|                 |  | $V_{DDRFPA} \geq 1.71\text{ V}$   | -        | -   | 7.5 | -   |      |
| $P_{txmin}$     | Minimum output power                                 | -   | -        | -   | -15 | -   |      |
| $\Delta P_{tx}$ | Output power step                                    | -   | -        | 0.5 | 1   | 2   | dB   |
| $P_{freqband}$  | Output power $\pm$ variation over the frequency band | $P_{txmax}$ max setting   | -        | -   | 0.5 | -   |      |
| $P_{temp}$      | Output power $\pm$ variation over the temperature    | $P_{txmax}$ max setting<br>$-40\text{ }^{\circ}\text{C} \leq T_J \leq +130\text{ }^{\circ}\text{C}$ | -        | -   | 2.5 | -   |      |

**Table 38. RF transmitter IEEE802.15.4 characteristics<sup>(1)</sup> (continued)**

| Symbol               | Parameter       | Test conditions                | Standard | Min | Typ   | Max | Unit |
|----------------------|-----------------|--------------------------------|----------|-----|-------|-----|------|
| P <sub>2ndHARM</sub> | Second harmonic | P <sub>txmax</sub> max setting | -        | -   | -69.5 | -   | dBm  |
| P <sub>3rdHARM</sub> | Third harmonic  | P <sub>txmax</sub> max setting | -        | -   | -70.5 | -   |      |

1. Evaluated by characterization, not tested in production, unless otherwise specified. Measured in conducted mode, based on reference design (see AN5165), using output power specific external RF filter and impedance matching networks to interface with a 50  $\Omega$  antenna.

**Table 39. RF receiver IEEE802.15.4 characteristics<sup>(1)</sup>**

| Symbol                   | Parameter                      | Conditions    | Standard | Min | Typ  | Max | Unit |
|--------------------------|--------------------------------|---------------|----------|-----|------|-----|------|
| P <sub>rxmax</sub>       | Maximum input signal           | PER $\leq$ 1% | -20      | -   | -20  | -   | dBm  |
| P <sub>sens250kbps</sub> | Sensitivity 250 kbps (LDO)     | PER $\leq$ 1% | -85      | -   | -100 | -   |      |
|                          | Sensitivity 250 kbps (SMPS ON) |               | -85      | -   | -100 | -   |      |
| C/I <sub>adj</sub>       | Adjacent channel rejection     | -             | 0        | -   | 10   | -   | dB   |
| C/I <sub>alt</sub>       | Alternate channel rejection    | -             | 30       | -   | 30   | -   |      |

1. Guaranteed by characterization results, unless otherwise specified. Measured in conducted mode, based on reference design (see AN5165), using output power specific external RF filter and impedance matching networks to interface with a 50  $\Omega$  antenna.

**Table 40. RF IEEE802.15.4 power consumption for V<sub>DD</sub> = 3.3 V<sup>(1)(2)</sup>**

| Symbol          | Parameter   | Typ   | Unit |
|-----------------|---|-------|------|
| I <sub>tx</sub> | Tx 0 dBm output power consumption (LDO)                                 | 15.37 | mA   |
|                 | Tx 0 dBm output power consumption (SMPS ON, VDDRFPA connected to VDD)   | 7.84  |      |
|                 | Tx 0 dBm output power consumption (SMPS ON, VDDRFPA connected to VDD11) | 7.62  |      |
|                 | Tx +10 dBm output power consumption (LDO)                               | 28.39 |      |
|                 | Tx +10 dBm output power consumption (SMPS ON, VDDRFPA connected to VDD) | 25.48 |      |
| I <sub>rx</sub> | Rx consumption (LDO)  | 11.31 |      |
|                 | Rx consumption (SMPS ON, VDDRFPA connected to VDD)                      | 6.99  |      |
|                 | Rx consumption (SMPS ON, VDDRFPA connected to VDD11)                    | 5.95  |      |

1. Guaranteed by characterization results, unless otherwise specified.  
 2. Power consumption including 2.4 GHz RADIO subsystem and digital processing.

### 5.3.5 Operating conditions at power-up/power-down

The parameters in [Table 41](#) are evaluated by characterization under ambient temperature and supply voltage conditions summarized in [Table 30](#).



Table 41. Operating conditions at power-up/power-down<sup>(1)</sup>

| Symbol    | Parameter               | Conditions                   | Min | Max      | Unit            |
|-----------|-------------------------|------------------------------|-----|----------|-----------------|
| $t_{VDD}$ | $V_{DD}$ rise time rate | -                            | 0   | $\infty$ | $\mu\text{s/V}$ |
|           | $V_{DD}$ fall time rate | ULPMEN = 0                   | 20  | $\infty$ |                 |
|           |                         | Standby mode with ULPMEN = 1 | 250 | $\infty$ | ms/V            |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

### 5.3.6 Embedded reset and power control block characteristics

The parameters in [Table 42](#) are derived under ambient temperature and supply voltage conditions summarized in [Table 30](#).

Table 42. Embedded reset and power control block characteristics

| Symbol               | Parameter  | Conditions       | Min  | Typ  | Max  | Unit          |
|----------------------|--|------------------|------|------|------|---------------|
| $t_{RSTTEMPO}^{(1)}$ | Reset temporization after $V_{BOR0}$ threshold detection | $V_{DD}$ rising  | -    | -    | 900  | $\mu\text{s}$ |
| $V_{BOR0}^{(2)}$     | Brown-out reset threshold 0                              | $V_{DD}$ rising  | 1.60 | 1.66 | 1.71 | V             |
|                      |  | $V_{DD}$ falling | 1.58 | 1.64 | 1.69 |               |
| $V_{BOR1}^{(2)}$     | Brown-out reset threshold 1                              | $V_{DD}$ rising  | 1.98 | 2.08 | 2.17 |               |
|                      |  | $V_{DD}$ falling | 1.90 | 2.00 | 2.10 |               |
| $V_{BOR2}^{(2)}$     | Brown-out reset threshold 2                              | $V_{DD}$ rising  | 2.18 | 2.29 | 2.39 |               |
|                      |  | $V_{DD}$ falling | 2.08 | 2.18 | 2.25 |               |
| $V_{BOR3}^{(2)}$     | Brown-out reset threshold 3                              | $V_{DD}$ rising  | 2.48 | 2.59 | 2.70 |               |
|                      |  | $V_{DD}$ falling | 2.39 | 2.50 | 2.61 |               |
| $V_{BOR4}^{(2)}$     | Brown-out reset threshold 4                              | $V_{DD}$ rising  | 2.76 | 2.88 | 3.00 |               |
|                      |  | $V_{DD}$ falling | 2.67 | 2.79 | 2.90 |               |

Table 42. Embedded reset and power control block characteristics (continued)

| Symbol                     | Parameter  | Conditions       | Min  | Typ  | Max  | Unit    |
|----------------------------|--|------------------|------|------|------|---------|
| $V_{PVD0}^{(2)}$           | Programmable voltage detector threshold 0  | $V_{DD}$ rising  | 2.03 | 2.13 | 2.23 | V       |
|                            |  | $V_{DD}$ falling | 1.93 | 2.03 | 2.12 |         |
| $V_{PVD1}^{(2)}$           | PVD threshold 1  | $V_{DD}$ rising  | 2.18 | 2.29 | 2.39 |         |
|                            |  | $V_{DD}$ falling | 2.08 | 2.18 | 2.28 |         |
| $V_{PVD2}^{(2)}$           | PVD threshold 2  | $V_{DD}$ rising  | 2.33 | 2.44 | 2.55 |         |
|                            |  | $V_{DD}$ falling | 2.23 | 2.34 | 2.44 |         |
| $V_{PVD3}^{(2)}$           | PVD threshold 3  | $V_{DD}$ rising  | 2.47 | 2.59 | 2.70 |         |
|                            |  | $V_{DD}$ falling | 2.39 | 2.50 | 2.61 |         |
| $V_{PVD4}^{(2)}$           | PVD threshold 4  | $V_{DD}$ rising  | 2.60 | 2.72 | 2.83 |         |
|                            |  | $V_{DD}$ falling | 2.50 | 2.62 | 2.73 |         |
| $V_{PVD5}^{(2)}$           | PVD threshold 5  | $V_{DD}$ rising  | 2.76 | 2.88 | 3.00 |         |
|                            |  | $V_{DD}$ falling | 2.66 | 2.78 | 2.90 |         |
| $V_{PVD6}^{(2)}$           | PVD threshold 6  | $V_{DD}$ rising  | 2.83 | 2.96 | 3.08 |         |
|                            |  | $V_{DD}$ falling | 2.76 | 2.88 | 3.00 |         |
| $V_{hyst\_BOR0}^{(2)}$     | BOR0 hysteresis voltage  | -                | -    | 20   | -    | mV      |
| $V_{hyst\_BOR\_PVD}^{(2)}$ | BOR1, 2, 3, 4 and PVD hysteresis voltage   | -                | -    | 80   | -    |         |
| $t_{sampling\_BOR0}^{(2)}$ | BOR0 ultra-low-power sampling monitoring period  | ULPMEN = 1       | -    | 12   | 30   | ms      |
| $I_{DD\_BOR\_PVD}^{(1)}$   | BOR1, 2, 3, 4 and PVD consumption from $V_{DD}$ , and additional BOR0 consumption for ULPMEN = 0 vs. ULPMEN = 1 <sup>(3)</sup> | -                | -    | 1.7  | 2.5  | $\mu A$ |

1. Specified by design, not tested in production.

2. Evaluated by characterization, not tested in production.

3. BOR0 is enabled in all modes, its consumption is therefore included in the supply current characteristics tables.

### 5.3.7 Embedded voltage reference

The parameters in [Table 43](#) are derived under ambient temperature and supply voltage conditions summarized in [Table 30](#).

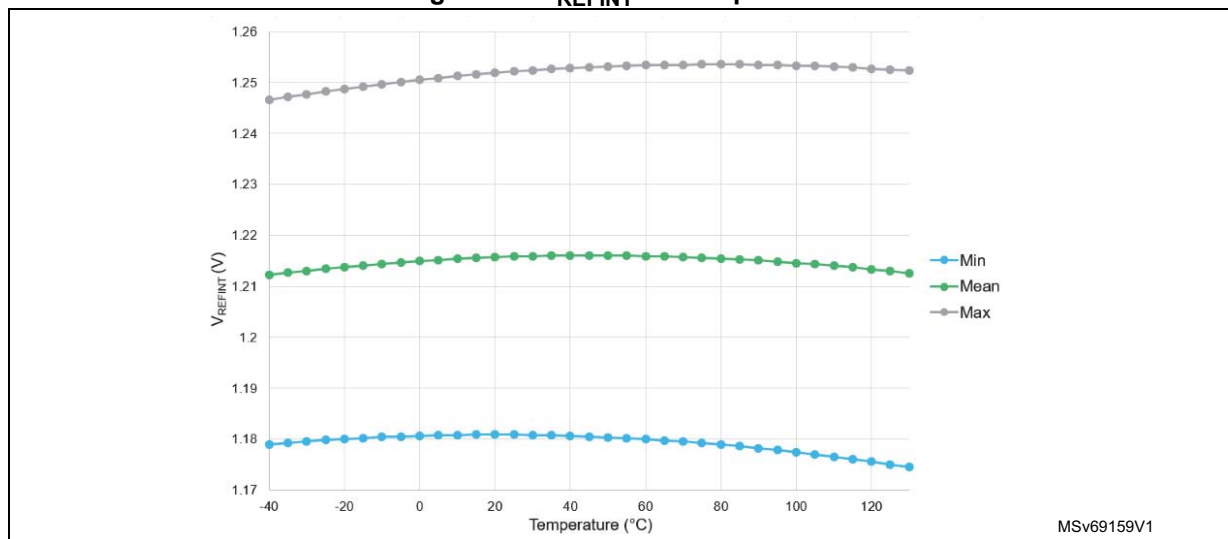
Table 43. Embedded internal voltage reference

| Symbol                     | Parameter   | Conditions                  | Min   | Typ   | Max   | Unit    |
|----------------------------|---|-----------------------------|-------|-------|-------|---------|
| $V_{REFINT}^{(1)}$         | Internal reference voltage                                    | Range 1                     | 1.175 | 1.215 | 1.255 | V       |
|                            |   | Range 2 and low-power modes | 1.170 | 1.215 | 1.260 | -       |
| $t_{S\_vrefint}^{(2)(3)}$  | ADC sampling time when reading the internal reference voltage | -                           | 4     | -     | -     | $\mu s$ |
| $t_{start\_vrefint}^{(3)}$ | Start time of reference voltage buffer when ADC is enabled    | -                           | -     | 4     | 6     | -       |

Table 43. Embedded internal voltage reference (continued)

| Symbol                     | Parameter   | Conditions   | Min | Typ | Max  | Unit             |
|----------------------------|---|--|-----|-----|------|------------------|
| $I_{DD(VREFINTBUF)}^{(3)}$ | $V_{REFINT}$ buffer consumption from $V_{DD}$ when converted by ADC | -  | -   | 1.5 | 2.1  | $\mu A$          |
| $\Delta V_{REFINT}^{(4)}$  | Internal reference voltage spread over the temperature range        | $V_{DD} = 3 V$   | -   | 6   | 11.5 | mV               |
| $T_{Coeff}^{(4)}$          | Average temperature coefficient                                     | $-40\text{ }^{\circ}C \leq T_J \leq +130\text{ }^{\circ}C$ | -   | 40  | 125  | ppm/ $^{\circ}C$ |
| $A_{Coeff}^{(3)}$          | Long term stability   | 1000 hours, $T_J = 25\text{ }^{\circ}C$                    | -   | 400 | 1000 | ppm              |
| $V_{DDCoeff}^{(4)}$        | Voltage coefficient   | $3.0 V \leq V_{DD} \leq 3.6 V$                             | -   | 500 | 2900 | ppm/V            |

1.  $V_{REFINT}$  does not take into account package and soldering effects.
2. The shortest sampling time for the application can be determined by multiple iterations.
3. Specified by design, not tested in production.
4. Evaluated by characterization, not tested in production.

Figure 22.  $V_{REFINT}$  vs. temperature

### 5.3.8 Supply current characteristics

The current consumption is measured as described in [Section 5.1.7](#). It depends upon several parameters, such as operating voltage, ambient temperature, I/O pin loading, device software configuration, operating frequency, I/O pin switching rate, program location in memory, and executed binary code.

### Typical and maximum current consumption

The MCU is put under the following conditions:

- All I/O pins are in analog input mode
- All peripherals are disabled, except when otherwise mentioned
- The flash memory and SRAM access time is adjusted with the minimum wait states number, depending upon the  $f_{HCLK}$  frequency (refer to tables in the reference manual).
- When the peripherals are enabled  $f_{PCLKx} = f_{HCLK1}$
- The voltage scaling is adjusted to  $f_{HCLK}$  frequency as follows:
  - Voltage range 1 for  $16\text{ MHz} < f_{HCLK1} \leq 100\text{ MHz}$  and  $12\text{ MHz} < f_{HCLK5} \leq 32\text{ MHz}$
  - Voltage range 2 for  $f_{HCLK1} \leq 16\text{ MHz}$  and  $f_{HCLK5} \leq 12\text{ MHz}$

The parameters given in [Table 44](#) and [Table 45](#) are evaluated by characterization under ambient temperature and supply voltage conditions summarized in [Table 30](#).

**Table 44. Current consumption in Run modes on LDO, code with data processing running from flash memory, Cache ON (1-way), prefetch OFF,  $V_{DD} = 3.3\text{ V}^{(1)(2)(3)}$**

| Symbol        | Parameter                  | Conditions  |                 |             | Typ   |       |       | Unit |
|---------------|----------------------------|---|-----------------|-------------|-------|-------|-------|------|
|               |                            | -   | Voltage scaling | $f_{HCLK1}$ | 25 °C | 55 °C | 85 °C |      |
| $I_{DD(Run)}$ | Supply current in Run mode | $f_{HCLK1} = f_{HSI16} = 16\text{ MHz}$                 | Range 2         | 16 MHz      | 1.11  | 1.18  | 1.40  | mA   |
|               |                            | $f_{HCLK1} = f_{HSE32} = 32\text{ MHz}$                 | Range 1         | 32 MHz      | 3.03  | 3.19  | 3.57  |      |
|               |                            | $f_{HCLK1} = \text{HSE32} + \text{PLL} > 32\text{ MHz}$ |                 | 100 MHz     | 7.76  | 7.94  | 8.35  |      |

1. Evaluated by characterization, not tested in production, unless otherwise specified.
2. Reduced code used for characterization.
3. All peripherals disabled, SRAM1 and SRAM2 enabled.

**Table 45. Current consumption in Run modes on SMPS, code with data processing running from flash memory, Cache ON (1-way), prefetch OFF,  $V_{DD} = 3.3\text{ V}^{(1)(2)(3)}$**

| Symbol        | Parameter                  | Conditions  |                 |             | Typ   |       |       | Unit |
|---------------|----------------------------|---|-----------------|-------------|-------|-------|-------|------|
|               |                            | -   | Voltage scaling | $f_{HCLK1}$ | 25 °C | 55 °C | 85 °C |      |
| $I_{DD(Run)}$ | Supply current in Run mode | $f_{HCLK1} = f_{HSI16} = 16\text{ MHz}$                 | Range 2         | 16 MHz      | 0.56  | 0.59  | 0.68  | mA   |
|               |                            | $f_{HCLK1} = f_{HSE32} = 32\text{ MHz}$                 | Range 1         | 32 MHz      | 2.01  | 2.12  | 2.35  |      |
|               |                            | $f_{HCLK1} = \text{HSE32} + \text{PLL} > 32\text{ MHz}$ |                 | 100 MHz     | 4.40  | 4.53  | 4.77  |      |

1. Guaranteed by characterization results, unless otherwise specified.
2. Reduced code used for characterization results
3. All peripherals disabled, SRAM1 and SRAM2 enabled.

**Table 46. Current consumption in Run mode on LDO, with different codes running from flash memory, Cache ON (2-way), Prefetch OFF<sup>(1)</sup>**

| Symbol               | Parameter                  | Conditions  |   |              | Typ   |       |       | Unit | Typ    |        |        | Unit   |
|----------------------|----------------------------|---|---|--------------|-------|-------|-------|------|--------|--------|--------|--------|
|                      |                            |   |   |              | 25 °C |       |       |      | 25 °C  |        |        |        |
|                      |                            | -   | Voltage scaling   | Code         | 1.8 V | 3.0 V | 3.3 V |      | 1.8 V  | 3.0 V  | 3.3 V  |        |
| I <sub>DD(Run)</sub> | Supply current in Run mode | All peripherals disabled, SRAM1 and SRAM2 enabled | Range 2, f <sub>HCLK1</sub> = f <sub>HSI16</sub> = 16 MHz | Reduced code | 1.16  | 1.16  | 1.16  | mA   | 72.68  | 72.50  | 72.58  | µA/MHz |
|                      |                            |   |   | Coremark®    | 1.17  | 1.17  | 1.18  |      | 73.13  | 73.38  | 73.50  |        |
|                      |                            |   |   | SecureMark   | 1.22  | 1.22  | 1.22  |      | 76.25  | 76.13  | 76.19  |        |
|                      |                            |   |   | Fibonacci    | 1.11  | 1.11  | 1.12  |      | 69.38  | 69.38  | 69.69  |        |
|                      |                            |   |   | While(1)     | 0.85  | 0.85  | 0.85  |      | 53.00  | 52.96  | 52.98  |        |
|                      |                            |   | Range 1, f <sub>HCLK1</sub> = f <sub>HSE32</sub> = 32 MHz | Reduced code | 3.09  | 3.16  | 3.17  |      | 96.54  | 98.64  | 99.19  |        |
|                      |                            |   |   | Coremark®    | 3.12  | 3.19  | 3.20  |      | 97.50  | 99.69  | 100.00 |        |
|                      |                            |   |   | SecureMark   | 3.32  | 3.38  | 3.40  |      | 103.59 | 105.63 | 106.25 |        |
|                      |                            |   |   | Fibonacci    | 2.96  | 3.03  | 3.05  |      | 92.50  | 94.69  | 95.31  |        |
|                      |                            |   |   | While(1)     | 2.30  | 2.37  | 2.39  |      | 71.88  | 74.06  | 74.69  |        |
|                      |                            |   | Range 1, f <sub>HCLK1</sub> = HSE32 + PLL at 100 MHz      | Reduced code | 8.14  | 8.21  | 8.23  |      | 81.44  | 82.08  | 82.26  |        |
|                      |                            |   |   | Coremark®    | 8.24  | 8.30  | 8.32  |      | 82.40  | 83.00  | 83.20  |        |
|                      |                            |   |   | SecureMark   | 8.73  | 8.79  | 8.81  |      | 87.30  | 87.90  | 88.10  |        |
|                      |                            |   |   | Fibonacci    | 7.74  | 7.80  | 7.82  |      | 77.40  | 78.00  | 78.20  |        |
|                      |                            |   |   | While(1)     | 5.68  | 5.75  | 5.77  |      | 56.80  | 57.50  | 57.70  |        |

1. Guaranteed by characterization results, unless otherwise specified.



**Table 47. Current consumption in Run mode on SMPS, with different codes running from flash memory, Cache ON (2-way), Prefetch OFF<sup>(1)</sup>**

| Symbol               | Parameter                  | Conditions  |   |              | Typ   |       |       | Unit | Typ   |       |       | Unit   |
|----------------------|----------------------------|---|---|--------------|-------|-------|-------|------|-------|-------|-------|--------|
|                      |                            |   |   |              | 25 °C |       |       |      | 25 °C |       |       |        |
|                      |                            | -   | Voltage scaling   | Code         | 1.8 V | 3.0 V | 3.3 V |      | 1.8 V | 3.0 V | 3.3 V |        |
| I <sub>DD(Run)</sub> | Supply current in Run mode | All peripherals disabled, SRAM1 and SRAM2 enabled | Range 2, f <sub>HCLK1</sub> = f <sub>HSI16</sub> = 16 MHz | Reduced code | 0.80  | 0.60  | 0.58  | mA   | 49.93 | 37.57 | 35.95 | µA/MHz |
|                      |                            |   |   | Coremark®    | 0.81  | 0.61  | 0.58  |      | 50.63 | 38.13 | 36.25 |        |
|                      |                            |   |   | SecureMark   | 0.83  | 0.62  | 0.6   |      | 51.88 | 38.75 | 37.50 |        |
|                      |                            |   |   | Fibonacci    | 0.77  | 0.58  | 0.58  |      | 48.13 | 36.25 | 36.25 |        |
|                      |                            |   |   | While(1)     | 0.61  | 0.48  | 0.46  |      | 38.13 | 30.00 | 28.75 |        |
|                      |                            |   | Range 1, f <sub>HCLK1</sub> = f <sub>HSE32</sub> = 32 MHz | Reduced code | 2.68  | 2.15  | 2.08  |      | 83.75 | 67.19 | 65.00 |        |
|                      |                            |   |   | Coremark®    | 2.7   | 2.16  | 2.09  |      | 84.38 | 67.50 | 65.31 |        |
|                      |                            |   |   | SecureMark   | 2.86  | 2.26  | 2.19  |      | 89.38 | 70.63 | 68.44 |        |
|                      |                            |   |   | Fibonacci    | 2.58  | 2.08  | 2.02  |      | 80.63 | 65.00 | 63.13 |        |
|                      |                            |   |   | While(1)     | 2.06  | 1.73  | 1.7   |      | 64.38 | 54.06 | 53.13 |        |
|                      |                            |   | Range 1, f <sub>HCLK1</sub> = HSE32 + PLL at 100 MHz      | Reduced code | 6.73  | 4.88  | 4.63  |      | 67.27 | 48.80 | 46.25 |        |
|                      |                            |   |   | Coremark®    | 6.80  | 4.93  | 4.67  |      | 68.02 | 49.30 | 46.72 |        |
|                      |                            |   |   | SecureMark   | 7.2   | 5.19  | 4.91  |      | 72.00 | 51.90 | 49.10 |        |
|                      |                            |   |   | Fibonacci    | 6.4   | 4.67  | 4.43  |      | 64.00 | 46.70 | 44.30 |        |
|                      |                            |   |   | While(1)     | 4.77  | 3.59  | 3.43  |      | 47.70 | 35.90 | 34.30 |        |

1. Guaranteed by characterization results, unless otherwise specified.

**Table 48. Current consumption in Sleep modes, flash memory in power-down<sup>(1)(2)</sup>**

| Symbol                 | Parameter                    | Conditions                                       |      |                 |                   | Typ   |       |       | Unit |
|------------------------|------------------------------|--|------|-----------------|-------------------|-------|-------|-------|------|
|                        |                              | -  | -    | Voltage scaling | f <sub>HCLK</sub> | 25 °C | 55 °C | 85 °C |      |
| I <sub>DD(Sleep)</sub> | Supply current in Sleep mode | f <sub>HCLK1</sub> = f <sub>HSI16</sub> = 16 MHz | LDO  | Range 2         | 16 MHz            | 0.44  | 0.51  | 0.68  | mA   |
|                        |                              | f <sub>HCLK1</sub> = f <sub>HSE32</sub> = 32 MHz |      | Range 1         | 32 MHz            | 1.34  | 1.49  | 1.81  |      |
|                        |                              | f <sub>HCLK1</sub> = HSE32 + PLL > 32 MHz        |      |                 | 100 MHz           | 3.06  | 3.22  | 3.55  |      |
|                        |                              | f <sub>HCLK1</sub> = f <sub>HSI16</sub> = 16 MHz | SMPS | Range 2         | 16 MHz            | 0.25  | 0.28  | 0.35  |      |
|                        |                              | f <sub>HCLK1</sub> = f <sub>HSE32</sub> = 32 MHz |      | Range 1         | 32 MHz            | 1.07  | 1.17  | 1.35  |      |
|                        |                              | f <sub>HCLK1</sub> = HSE32 + PLL > 32 MHz        |      |                 | 100 MHz           | 2     | 2.11  | 2.3   |      |

1. Evaluated by characterization, not tested in production, unless otherwise specified.
2. All peripherals disabled.

Table 49. Flash memory static power consumption<sup>(1)</sup>

| Symbol                      | Parameter   | Conditions             | Typ   |       |        | Unit |
|-----------------------------|---|------------------------|-------|-------|--------|------|
|                             |   |                        | 25 °C | 55 °C | 85 °C  |      |
| I <sub>DD</sub> (Flash)     | Static consumption in normal mode                             | PD = 1 versus PD = 0   | 91.47 | 95.63 | 105.26 | μA   |
| I <sub>DD</sub> (Flash_LPM) | Additional static consumption in normal versus low-power mode | LPM = 1 versus LPM = 0 | 51.49 | 52.38 | 53.85  |      |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

Table 50. Current consumption in Stop 0 mode<sup>(1)</sup>

| Symbol                   | Parameter   | Conditions |         |                 | Typ   |        |        | Unit |
|--------------------------|---|------------|---------|-----------------|-------|--------|--------|------|
|                          |   | -          | -       | V <sub>DD</sub> | 25 °C | 55 °C  | 85 °C  |      |
| I <sub>DD</sub> (Stop 0) | Supply current in Stop 0 mode, no retention                                       | LDO        | Range 2 | 1.8 V           | 52.67 | 87.47  | 181.74 | μA   |
|                          |   |            |         | 2.4 V           | 53.06 | 87.95  | 181.50 |      |
|                          |   |            |         | 3.0 V           | 53.68 | 88.78  | 183.20 |      |
|                          |   |            |         | 3.3 V           | 54.36 | 90.19  | 186.04 |      |
|                          |   |            |         | 3.6 V           | 56.07 | 93.76  | 195.24 |      |
|                          | Supply current in Stop 0 mode, all retention (SRAM1 448K + SRAM2 64K + PKA + OTG) |            |         | 1.8 V           | 59.73 | 101.71 | 216.76 |      |
|                          |   |            |         | 2.4 V           | 60.02 | 102.13 | 216.83 |      |
|                          |   |            |         | 3.0 V           | 60.66 | 103.01 | 218.25 |      |
|                          |   |            |         | 3.3 V           | 61.55 | 104.78 | 222.34 |      |
|                          |   |            |         | 3.6 V           | 63.88 | 110.24 | 238.32 |      |
|                          | Supply current in Stop 0 mode, SRAM2 retained                                     |            |         | 1.8 V           | 53.70 | 89.91  | 187.96 |      |
|                          |   |            |         | 2.4 V           | 54.09 | 90.28  | 187.23 |      |
|                          |   |            |         | 3.0 V           | 54.68 | 91.09  | 189.52 |      |
|                          |   |            |         | 3.3 V           | 55.34 | 92.31  | 191.73 |      |
|                          |   |            |         | 3.6 V           | 57.17 | 96.32  | 202.09 |      |
| I <sub>DD</sub> (Stop 0) | Supply current in Stop 0 mode, no retention                                       | SMPS       | Range 2 | 1.8 V           | 18.59 | 39.70  | 99.85  | μA   |
|                          |   |            |         | 2.4 V           | 15.77 | 32.25  | 79.03  |      |
|                          |   |            |         | 3.0 V           | 14.38 | 28.18  | 67.41  |      |
|                          |   |            |         | 3.3 V           | 14.15 | 27.14  | 63.92  |      |
|                          |   |            |         | 3.6 V           | 14.48 | 27.19  | 62.92  |      |
|                          | Supply current in Stop 0 mode, all retention (SRAM1 448K + SRAM2 64K + PKA + OTG) |            |         | 1.8 V           | 22.87 | 48.51  | 122.04 |      |
|                          |   |            |         | 2.4 V           | 19.09 | 39.12  | 96.32  |      |
|                          |   |            |         | 3.0 V           | 17.10 | 33.88  | 81.97  |      |
|                          |   |            |         | 3.3 V           | 16.70 | 32.44  | 77.41  |      |
|                          |   |            |         | 3.6 V           | 16.95 | 32.40  | 76.67  |      |
|                          |   |            |         |                 |       |        |        |      |
|                          |   |            |         |                 |       |        |        |      |
|                          |   |            |         |                 |       |        |        |      |



Table 50. Current consumption in Stop 0 mode<sup>(1)</sup> (continued)

| Symbol                  | Parameter                                     | Conditions |         |                 | Typ   |       |        | Unit |
|-------------------------|---|------------|---------|-----------------|-------|-------|--------|------|
|                         |   | -          | -       | V <sub>DD</sub> | 25 °C | 55 °C | 85 °C  |      |
| I <sub>DD(Stop 0)</sub> | Supply current in Stop 0 mode, SRAM2 retained | SMPS       | Range 2 | 1.8 V           | 19.21 | 41.18 | 103.91 | μA   |
|                         |   |            |         | 2.4 V           | 16.26 | 33.36 | 82.06  |      |
|                         |   |            |         | 3.0 V           | 14.80 | 29.09 | 69.74  |      |
|                         |   |            |         | 3.3 V           | 14.49 | 27.91 | 66.12  |      |
|                         |   |            |         | 3.6 V           | 14.79 | 27.99 | 65.15  |      |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

Table 51. Current consumption in Stop 1 mode<sup>(1)</sup>

| Symbol                  | Parameter   | Conditions |         |                 | Typ   |       |        | Unit |
|-------------------------|---|------------|---------|-----------------|-------|-------|--------|------|
|                         |   | -          | -       | V <sub>DD</sub> | 25 °C | 55 °C | 85 °C  |      |
| I <sub>DD(Stop 1)</sub> | Supply current in Stop 1 mode, no retention, ULPMEN = 1                                       | LDO        | Range 2 | 1.8 V           | 21.81 | 51.00 | 149.93 | μA   |
|                         |   |            |         | 2.4 V           | 21.73 | 53.23 | 149.85 |      |
|                         |   |            |         | 3.0 V           | 25.19 | 56.60 | 150.62 |      |
|                         |   |            |         | 3.3 V           | 24.42 | 54.46 | 157.61 |      |
|                         |   |            |         | 3.6 V           | 26.81 | 57.99 | 160.97 |      |
|                         | Supply current in Stop 1 mode, all retention (SRAM1 448K + SRAM2 64K + PKA + OTG), ULPMEN = 1 |            |         | 1.8 V           | 27.12 | 72.08 | 186.31 |      |
|                         |   |            |         | 2.4 V           | 27.02 | 66.50 | 187.44 |      |
|                         |   |            |         | 3.0 V           | 31.58 | 69.19 | 187.26 |      |
|                         |   |            |         | 3.3 V           | 30.58 | 64.83 | 190.94 |      |
|                         |   |            |         | 3.6 V           | 34.17 | 83.43 | 207.14 |      |
|                         | Supply current in Stop 1 mode, SRAM2 retained, ULPMEN = 1                                     |            |         | 1.8 V           | 22.55 | 52.82 | 156.68 |      |
|                         |   |            |         | 2.4 V           | 22.58 | 54.95 | 157.22 |      |
|                         |   |            |         | 3.0 V           | 26.02 | 58.55 | 155.86 |      |
|                         |   |            |         | 3.3 V           | 25.25 | 56.29 | 164.88 |      |
|                         |   |            |         | 3.6 V           | 27.79 | 60.21 | 169.43 |      |
| I <sub>DD(Stop 1)</sub> | Supply current in Stop 1 mode, no retention, ULPMEN = 1                                       | SMPS       | Range 2 | 1.8 V           | 14.72 | 35.73 | 96.07  | μA   |
|                         |   |            |         | 2.4 V           | 11.59 | 27.87 | 75.11  |      |
|                         |   |            |         | 3.0 V           | 9.78  | 23.52 | 63.13  |      |
|                         |   |            |         | 3.3 V           | 9.33  | 22.29 | 59.53  |      |
|                         |   |            |         | 3.6 V           | 9.38  | 22.04 | 58.17  |      |
|                         | Supply current in Stop 1 mode, all retention (SRAM1 448K + SRAM2 64K + PKA + OTG), ULPMEN = 1 |            |         | 1.8 V           | 19.05 | 44.58 | 118.90 |      |
|                         |   |            |         | 2.4 V           | 14.89 | 34.73 | 92.93  |      |
|                         |   |            |         | 3.0 V           | 12.53 | 29.23 | 77.92  |      |
|                         |   |            |         | 3.3 V           | 11.90 | 27.62 | 73.27  |      |
|                         |   |            |         | 3.6 V           | 11.83 | 27.17 | 71.64  |      |

Table 51. Current consumption in Stop 1 mode<sup>(1)</sup> (continued)

| Symbol                  | Parameter   | Conditions |         |                 | Typ   |       |        | Unit |
|-------------------------|---|------------|---------|-----------------|-------|-------|--------|------|
|                         |   | -          | -       | V <sub>DD</sub> | 25 °C | 55 °C | 85 °C  |      |
| I <sub>DD(Stop 1)</sub> | Supply current in Stop 1 mode, SRAM2 retained, ULPMEN = 1 | SMPS       | Range 2 | 1.8 V           | 15.34 | 37.24 | 100.05 | μA   |
|                         |   |            |         | 2.4 V           | 12.10 | 28.98 | 78.14  |      |
|                         |   |            |         | 3.0 V           | 10.21 | 24.44 | 65.69  |      |
|                         |   |            |         | 3.3 V           | 9.72  | 23.15 | 61.91  |      |
|                         |   |            |         | 3.6 V           | 9.73  | 22.83 | 60.27  |      |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

Table 52. Current consumption in Stop 2 mode<sup>(1)</sup>

| Symbol                  | Parameter   | Conditions |         |                 | Typ   |       |        | Unit |
|-------------------------|---|------------|---------|-----------------|-------|-------|--------|------|
|                         |   | -          | -       | V <sub>DD</sub> | 25 °C | 55 °C | 85 °C  |      |
| I <sub>DD(Stop 2)</sub> | Supply current in Stop 2 mode, no retention, ULPMEN = 1                                       | LDO        | Range 2 | 1.8 V           | 11.95 | 29.37 | 83.93  | μA   |
|                         |   |            |         | 2.4 V           | 12.23 | 30.64 | 87.08  |      |
|                         |   |            |         | 3.0 V           | 12.18 | 29.38 | 86.93  |      |
|                         |   |            |         | 3.3 V           | 18.44 | 31.79 | 87.29  |      |
|                         |   |            |         | 3.6 V           | 19.52 | 33.91 | 91.42  |      |
|                         | Supply current in Stop 2 mode, all retention (SRAM1 448K + SRAM2 64K + PKA + OTG), ULPMEN = 1 |            |         | 1.8 V           | 16.74 | 41.66 | 122.71 |      |
|                         |   |            |         | 2.4 V           | 18.04 | 43.72 | 122.23 |      |
|                         |   |            |         | 3.0 V           | 17.97 | 41.69 | 122.67 |      |
|                         |   |            |         | 3.3 V           | 28.29 | 45.21 | 126.68 |      |
|                         |   |            |         | 3.6 V           | 30.02 | 48.88 | 137.34 |      |
|                         | Supply current in Stop 2 mode, SRAM2 retained, ULPMEN = 1                                     |            |         | 1.8 V           | 12.19 | 31.10 | 88.19  |      |
|                         |   |            |         | 2.4 V           | 13.02 | 32.80 | 92.05  |      |
|                         |   |            |         | 3.0 V           | 13.09 | 31.47 | 94.97  |      |
|                         |   |            |         | 3.3 V           | 19.76 | 34.39 | 92.98  |      |
|                         |   |            |         | 3.6 V           | 20.93 | 36.15 | 99.79  |      |
| I <sub>DD(Stop 2)</sub> | Supply current in Stop 2 mode, no retention, ULPMEN = 1                                       | SMPS       | Range 2 | 1.8 V           | 7.67  | 19.46 | 53.60  | μA   |
|                         |   |            |         | 2.4 V           | 6.03  | 15.24 | 42.00  |      |
|                         |   |            |         | 3.0 V           | 5.12  | 12.97 | 35.74  |      |
|                         |   |            |         | 3.3 V           | 4.98  | 12.46 | 34.01  |      |
|                         |   |            |         | 3.6 V           | 5.26  | 12.74 | 33.94  |      |
|                         | Supply current in Stop 2 mode, all retention (SRAM1 448K + SRAM2 64K + PKA + OTG), ULPMEN = 1 |            |         | 1.8 V           | 12.04 | 28.77 | 78.14  |      |
|                         |   |            |         | 2.4 V           | 9.42  | 22.42 | 61.04  |      |
|                         |   |            |         | 3.0 V           | 7.92  | 18.94 | 51.51  |      |
|                         |   |            |         | 3.3 V           | 7.58  | 18.04 | 48.63  |      |
|                         |   |            |         | 3.6 V           | 7.72  | 18.09 | 48.13  |      |

Table 52. Current consumption in Stop 2 mode<sup>(1)</sup> (continued)

| Symbol                  | Parameter   | Conditions |         |                 | Typ   |       |       | Unit |
|-------------------------|---|------------|---------|-----------------|-------|-------|-------|------|
|                         |   | -          | -       | V <sub>DD</sub> | 25 °C | 55 °C | 85 °C |      |
| I <sub>DD(Stop 2)</sub> | Supply current in Stop 2 mode, SRAM2 retained, ULPMEN = 1 | SMPS       | Range 2 | 1.8 V           | 8.33  | 21.04 | 58.06 | μA   |
|                         |   |            |         | 2.4 V           | 6.53  | 16.45 | 45.37 |      |
|                         |   |            |         | 3.0 V           | 5.54  | 13.98 | 38.42 |      |
|                         |   |            |         | 3.3 V           | 5.36  | 13.38 | 36.56 |      |
|                         |   |            |         | 3.6 V           | 5.63  | 13.60 | 36.14 |      |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

Table 53. Current consumption in Standby retention mode<sup>(1)</sup>

| Symbol                                   | Parameter  | Conditions |   |       | Typ   | -     | -     | Unit |
|--|--|------------|---|-------|-------|-------|-------|------|
|  |  | -          | - | VDD   | 25 °C | 55 °C | 85 °C |      |
| I <sub>DD</sub> (Standby with retention) | Supply current in Standby retention mode, all retention (SRAM1 448K + SRAM2 64K + Radio), ULPMEN = 1 | LDO        | - | 1.8 V | 7.91  | 15.30 | 43.40 | μA   |
|  |  |            |   | 2.4 V | 9.14  | 15.70 | 43.70 |      |
|  |  |            |   | 3.0 V | 8.88  | 17.00 | 46.70 |      |
|  |  |            |   | 3.3 V | 14.20 | 18.40 | 39.40 |      |
|  |  |            |   | 3.6 V | 15.40 | 21.20 | 41.40 |      |
|  | Supply current in Standby retention mode, SRAM2 retained, ULPMEN = 1                                 |            |   | 1.8 V | 4.84  | 4.79  | 12.00 |      |
|  |  |            |   | 2.4 V | 4.13  | 4.94  | 12.10 |      |
|  |  |            |   | 3.0 V | 2.63  | 5.44  | 13.00 |      |
|  |  |            |   | 3.3 V | 2.53  | 6.19  | 14.40 |      |
|  |  |            |   | 3.6 V | 2.30  | 7.45  | 16.00 |      |

Table 53. Current consumption in Standby retention mode<sup>(1)</sup> (continued)

| Symbol                                   | Parameter  | Conditions |      |       | Typ   | -     | -     | Unit |
|--|--|------------|------|-------|-------|-------|-------|------|
|  |  | -          | -    | VDD   | 25 °C | 55 °C | 85 °C |      |
| I <sub>DD</sub> (Standby with retention) | Supply current in Standby retention mode, Radio retained, ULPMEN = 1                                 | LDO        | -    | 1.8 V | 1.37  | 2.86  | 7.51  | μA   |
|  |  |            |      | 2.4 V | 1.49  | 2.97  | 7.64  |      |
|  |  |            |      | 3.0 V | 1.60  | 3.33  | 8.38  |      |
|  |  |            |      | 3.3 V | 1.37  | 3.85  | 9.31  |      |
|  |  |            |      | 3.6 V | 3.15  | 5.03  | 10.30 |      |
|  | Supply current in Standby retention mode, all retention (SRAM1 448K + SRAM2 64K + Radio), ULPMEN = 1 | SMPS       |      | 1.8 V | 5.13  | 10.30 | 26.30 | μA   |
|  |  |            |      | 2.4 V | 4.03  | 8.17  | 20.70 |      |
|  |  |            |      | 3.0 V | 3.45  | 7.07  | 17.70 |      |
|  |  |            |      | 3.3 V | 3.42  | 6.98  | 17.10 |      |
|  |  |            |      | 3.6 V | 3.81  | 7.58  | 16.70 |      |
|  | Supply current in Standby retention mode, SRAM2 retained, ULPMEN = 1                                 |            |      | 1.8 V | 1.32  | 2.96  | 8.17  |      |
|  |  |            |      | 2.4 V | 1.09  | 2.44  | 6.72  |      |
|  |  |            |      | 3.0 V | 1.01  | 2.30  | 6.27  |      |
|  |  |            |      | 3.3 V | 1.15  | 2.52  | 6.51  |      |
|  |  |            |      | 3.6 V | 1.64  | 3.25  | 7.18  |      |
| I <sub>DD</sub> (Standby with retention) | SMPS   | 1.8 V      | 0.78 | 1.77  | 4.99  | μA    |       |      |
|  |  | 2.4 V      | 0.67 | 1.52  | 4.29  |       |       |      |
|  |  | 3.0 V      | 0.67 | 1.54  | 4.28  |       |       |      |
|  |  | 3.3 V      | 0.83 | 1.79  | 4.67  |       |       |      |
|  |  | 3.6 V      | 1.33 | 2.56  | 5.52  |       |       |      |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

Table 54. Current consumption in Standby mode<sup>(1)</sup>

| Symbol                    | Parameter  | Conditions                      |       | Typ   |       |       | Unit |
|---------------------------|--|---------------------------------|-------|-------|-------|-------|------|
|                           |  | -                               | VDD   | 25 °C | 55 °C | 85 °C |      |
| I <sub>DD</sub> (Standby) | Supply current in Standby mode, all peripherals disabled | ULPMEN = 1                      | 1.8 V | 0.12  | 0.37  | 1.43  | μA   |
|                           |  |                                 | 2.4 V | 0.15  | 0.42  | 1.54  |      |
|                           |  |                                 | 3.0 V | 0.22  | 0.60  | 1.99  |      |
|                           |  |                                 | 3.3 V | 0.39  | 0.93  | 2.60  |      |
|                           |  |                                 | 3.6 V | 0.87  | 1.76  | 3.76  |      |
|                           |  | ULPMEN = 0                      | 1.8 V | 1.24  | 1.49  | 2.53  |      |
|                           |  |                                 | 2.4 V | 1.58  | 1.86  | 2.93  |      |
|                           |  |                                 | 3.0 V | 1.97  | 2.36  | 3.67  |      |
|                           |  |                                 | 3.3 V | 2.30  | 2.85  | 4.43  |      |
|                           |  |                                 | 3.6 V | 2.95  | 3.85  | 5.71  |      |
|                           | Supply current in Standby mode, IWDG enabled             | Clocked by LSI1, ULPMEN = 1     | 1.8 V | 0.34  | 0.60  | 1.65  |      |
|                           |  |                                 | 2.4 V | 0.44  | 0.71  | 1.84  |      |
|                           |  |                                 | 3.0 V | 0.59  | 0.97  | 2.36  |      |
|                           |  |                                 | 3.3 V | 0.80  | 1.34  | 3.02  |      |
|                           |  |                                 | 3.6 V | 1.32  | 2.19  | 4.27  |      |
|                           |  | Clocked by LSI1, ULPMEN = 0     | 1.8 V | 1.46  | 1.72  | 2.75  |      |
|                           |  |                                 | 2.4 V | 1.87  | 2.15  | 3.23  |      |
|                           |  |                                 | 3.0 V | 2.34  | 2.73  | 4.04  |      |
|                           |  |                                 | 3.3 V | 2.71  | 3.26  | 4.85  |      |
|                           |  |                                 | 3.6 V | 3.40  | 4.28  | 6.22  |      |
|                           |  | Clocked by LSI1/128, ULPMEN = 1 | 1.8 V | 0.21  | 0.47  | 1.52  |      |
|                           |  |                                 | 2.4 V | 0.26  | 0.52  | 1.65  |      |
|                           |  |                                 | 3.0 V | 0.34  | 0.72  | 2.11  |      |
|                           |  |                                 | 3.3 V | 0.51  | 1.05  | 2.74  |      |
|                           |  |                                 | 3.6 V | 0.99  | 1.86  | 3.94  |      |
|                           |  | Clocked by LSI1/128, ULPMEN = 0 | 1.8 V | 1.33  | 1.59  | 2.62  |      |
|                           |  |                                 | 2.4 V | 1.69  | 1.96  | 3.04  |      |
|                           |  |                                 | 3.0 V | 2.09  | 2.48  | 3.79  |      |
|                           |  |                                 | 3.3 V | 2.42  | 2.97  | 4.57  |      |
|                           |  |                                 | 3.6 V | 3.07  | 3.95  | 5.89  |      |

Table 54. Current consumption in Standby mode<sup>(1)</sup> (continued)

| Symbol                             | Parameter  | Conditions                                   |       | Typ   |       |       | Unit |
|------------------------------------|--|--|-------|-------|-------|-------|------|
|                                    |  | -  | VDD   | 25 °C | 55 °C | 85 °C |      |
| I <sub>DD</sub> (Standby with RTC) | Supply current in Standby mode, no IWDG, RTC enabled | Clocked by LSI1, ULPMEN = 1                  | 1.8 V | 0.33  | 0.59  | 1.65  | μA   |
|                                    |  |  | 2.4 V | 0.44  | 0.71  | 1.83  |      |
|                                    |  |  | 3.0 V | 0.58  | 0.96  | 2.36  |      |
|                                    |  |  | 3.3 V | 0.79  | 1.32  | 3.00  |      |
|                                    |  |  | 3.6 V | 1.30  | 2.17  | 4.25  |      |
|                                    |  | Clocked by LSI1, ULPMEN = 0                  | 1.8 V | 1.45  | 1.71  | 2.75  |      |
|                                    |  |  | 2.4 V | 1.87  | 2.15  | 3.22  |      |
|                                    |  |  | 3.0 V | 2.33  | 2.72  | 4.04  |      |
|                                    |  |  | 3.3 V | 2.70  | 3.24  | 4.83  |      |
|                                    |  |  | 3.6 V | 3.38  | 4.26  | 6.20  |      |
|                                    |  | Clocked by LSI1/128, ULPMEN = 1              | 1.8 V | 0.21  | 0.47  | 1.52  |      |
|                                    |  |  | 2.4 V | 0.26  | 0.52  | 1.65  |      |
|                                    |  |  | 3.0 V | 0.34  | 0.72  | 2.12  |      |
|                                    |  |  | 3.3 V | 0.51  | 1.05  | 2.73  |      |
|                                    |  |  | 3.6 V | 1.00  | 1.86  | 3.94  |      |
|                                    |  | Clocked by LSI1/128, ULPMEN = 0              | 1.8 V | 1.33  | 1.59  | 2.62  |      |
|                                    |  |  | 2.4 V | 1.69  | 1.96  | 3.04  |      |
|                                    |  |  | 3.0 V | 2.09  | 2.48  | 3.80  |      |
|                                    |  |  | 3.3 V | 2.42  | 2.97  | 4.56  |      |
|                                    |  |  | 3.6 V | 3.08  | 3.95  | 5.89  |      |
|                                    |  | Clocked by LSE bypass 32.768 kHz, ULPMEN = 1 | 1.8 V | 0.57  | 0.93  | 2.21  |      |
|                                    |  |  | 2.4 V | 0.66  | 1.03  | 2.42  |      |
|                                    |  |  | 3.0 V | 0.79  | 1.29  | 3.01  |      |
|                                    |  |  | 3.3 V | 0.99  | 1.67  | 3.74  |      |
|                                    |  |  | 3.6 V | 1.53  | 2.57  | 5.18  |      |
|                                    |  | Clocked by LSE bypass 32.768 kHz, ULPMEN = 0 | 1.8 V | 1.69  | 2.05  | 3.31  |      |
|                                    |  |  | 2.4 V | 2.09  | 2.47  | 3.81  |      |
|                                    |  |  | 3.0 V | 2.54  | 3.04  | 4.69  |      |
|                                    |  |  | 3.3 V | 2.91  | 3.59  | 5.57  |      |
|                                    |  |  | 3.6 V | 3.60  | 4.66  | 7.13  |      |

Table 54. Current consumption in Standby mode<sup>(1)</sup> (continued)

| Symbol                             | Parameter  | Conditions   |       | Typ   |       |       | Unit |
|------------------------------------|--|--|-------|-------|-------|-------|------|
|                                    |  | -  | VDD   | 25 °C | 55 °C | 85 °C |      |
| I <sub>DD</sub> (Standby with RTC) | Supply current in Standby mode, no IWDG, RTC enabled | Clocked by LSE crystal 32.768 kHz in medium low-drive, ULP MEN = 1 | 1.8 V | 0.62  | 0.94  | 2.30  | μA   |
|                                    |  |  | 2.4 V | 0.71  | 1.04  | 2.08  |      |
|                                    |  |  | 3.0 V | 0.85  | 1.30  | 2.61  |      |
|                                    |  |  | 3.3 V | 1.08  | 1.69  | 3.27  |      |
|                                    |  |  | 3.6 V | 1.65  | 2.57  | 4.61  |      |
|                                    |  | Clocked by LSE crystal 32.768 kHz in medium low-drive, ULP MEN = 0 | 1.8 V | 1.74  | 2.06  | 3.40  |      |
|                                    |  |  | 2.4 V | 2.14  | 2.48  | 3.47  |      |
|                                    |  |  | 3.0 V | 2.60  | 3.06  | 4.29  |      |
|                                    |  |  | 3.3 V | 2.99  | 3.61  | 5.10  |      |
|                                    |  |  | 3.6 V | 3.73  | 4.66  | 6.56  |      |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

### I/O system current consumption

The current consumption of the I/O system has two components: static and dynamic.

#### I/O static current consumption

All the I/Os used as inputs with pull-up or pull-down generate current consumption when the pin is externally held to the opposite level. The value of this current consumption can be simply computed by using the pull-up/pull-down resistors values given in [Section 5.3.17](#).

For the output pins, any internal or external pull-up or pull-down and external load must also be considered to estimate the current consumption.

An additional current consumption is due to I/Os configured as inputs when an intermediate voltage level is applied externally. This is caused by the input Schmitt trigger circuits used to discriminate the input value. Unless this specific configuration is required by the application, this supply current consumption can be avoided by configuring these I/Os in analog mode. This is the case of ADC input pins, which must be configured as analog inputs.

**Caution:** Any floating input pin can settle to an intermediate voltage level or switch inadvertently, as a result of external electromagnetic noise. To avoid current consumption related to floating pins, they must be configured in analog mode, or forced internally to a definite digital value. This can be done by using pull-up/down resistors, or by configuring the pins in output mode.

**I/O dynamic current consumption**

The I/Os used in application increase the consumption measured previously (see [Table 55](#)). When an I/O pin switches, it uses the current from the I/O supply voltage to supply the pin circuitry, and to charge/discharge the capacitive load (internal and external) connected to it:

$$I_{SW} = V_{DD} \times f_{SW} \times C$$

where:

- $I_{SW}$  is the current sunk by a switching I/O to charge/discharge the capacitive load
- $V_{DD}$  is the I/O supply voltage
- $f_{SW}$  is the I/O switching frequency
- $C$  is the total capacitance seen by the I/O pin:  $C = C_{INT} + C_{EXT} + C_S$ 
  - $C_{INT}$  is the I/O pin capacitance
  - $C_{EXT}$  is any connected external device pin capacitance
  - $C_S$  is the PCB board capacitance

The pin is configured in push-pull output mode, and is toggled by software at a fixed frequency.

**On-chip peripheral current consumption**

The power consumption of the digital part of the peripherals is given in [Table 55](#), while that of the analog part (when applicable) is indicated in the related sections.

The MCU is put under the following conditions:

- All I/O pins are in analog mode
- The given value is calculated by measuring the difference of the current consumptions:
  - when the peripheral is clocked on
  - when the peripheral is clocked off
- The ambient operating temperature and supply voltage conditions summarized in [Table 30](#)



Table 55. Peripheral typical dynamic current consumption<sup>(1)</sup>

| Bus  | Peripheral              | Range 1<br>LDO | Range 2<br>LDO | Range 1<br>SMPS | Range 2<br>SMPS | Unit   |
|------|-------------------------|----------------|----------------|-----------------|-----------------|--------|
| AHB1 | AHB1 bus                | 0.316          | 0.154          | 0.122           | 0.065           | µA/MHz |
|      | SRAM1                   | 1.006          | 0.731          | 0.525           | 0.288           |        |
|      | TSC                     | 1.501          | 1.104          | 0.785           | 0.448           |        |
|      | CRC                     | 0.318          | 0.237          | 0.178           | 0.089           |        |
|      | RAMCFG                  | 0.223          | 0.161          | 0.102           | 0.053           |        |
|      | GPDMA1                  | 2.254          | 1.647          | 1.179           | 0.675           |        |
|      | ICACHE                  | 0.682          | 0.495          | 0.354           | 0.198           |        |
|      | FLASH interface         | 1.981          | 1.464          | 1.038           | 0.585           |        |
|      | GTZC1                   | 0.572          | 0.424          | 0.293           | 0.159           |        |
| AHB2 | AHB2 bus <sup>(2)</sup> | 0.649          | 0.393          | 0.291           | 0.145           |        |
|      | SRAM2                   | 0.284          | 0.225          | 0.179           | 0.090           |        |
|      | PKA                     | 5.695          | 4.209          | 3.004           | 1.721           |        |
|      | HSEM                    | 0.074          | 0.075          | 0.063           | 0.026           |        |
|      | SAES                    | 63.216         | 47.362         | 33.551          | 19.185          |        |
|      | RNG                     | 1.439          | 1.091          | 0.781           | 0.448           |        |
|      | HASH                    | 1.353          | 1.006          | 0.749           | 0.408           |        |
|      | AES                     | 1.605          | 1.205          | 0.868           | 0.486           |        |
|      | GPIOA                   | 0.000          | 0.000          | 0.000           | 0.000           |        |
|      | GPIOB                   | 0.000          | 0.000          | 0.000           | 0.000           |        |
|      | GPIOC                   | 0.000          | 0.000          | 0.000           | 0.000           |        |
|      | PIOD                    | 0.000          | 0.000          | 0.000           | 0.000           |        |
|      | GPIOE                   | 0.000          | 0.000          | 0.000           | 0.000           |        |

Table 55. Peripheral typical dynamic current consumption<sup>(1)</sup> (continued)

| Bus  | Peripheral                              | Range 1<br>LDO | Range 2<br>LDO | Range 1<br>SMPS | Range 2<br>SMPS | Unit   |
|------|---|----------------|----------------|-----------------|-----------------|--------|
| AHB2 | GPIOG                                   | 0.000          | 0.000          | 0.000           | 0.000           | µA/MHz |
|      | GPIOH                                   | 0.000          | 0.000          | 0.000           | 0.000           |        |
|      | USB                                     | 18.539         | 13.828         | 9.916           | 5.581           |        |
| AHB4 | AHB4 bus                                | 0.000          | 0.000          | 0.023           | 0.000           |        |
|      | ADC4 kernel clock domain                | 1.790          | 1.333          | 0.941           | 0.530           |        |
|      | ADC4 bus clock domain                   | 3.380          | 2.447          | 1.737           | 0.989           |        |
|      | PWR                                     | 0.040          | 0.020          | 0.030           | 0.010           |        |
| AHB5 | AHB5 bus and peripherals <sup>(3)</sup> | 0.085          | 0.053          | 0.050           | 0.018           |        |
| APB1 | AHB to APB1 <sup>(4)</sup>              | 0.054          | 0.000          | 0.024           | 0.000           |        |
|      | TIM2                                    | 3.171          | 2.363          | 1.676           | 0.952           |        |
|      | TIM3                                    | 2.670          | 1.994          | 1.418           | 0.803           |        |
|      | TIM4                                    | 2.990          | 2.236          | 1.593           | 0.904           |        |
|      | WWDG                                    | 0.255          | 0.208          | 0.149           | 0.079           |        |
|      | USART2 kernel clock domain              | 3.142          | 2.320          | 1.657           | 0.957           |        |
|      | USART2 bus clock domain                 | 4.604          | 3.434          | 2.520           | 1.388           |        |
|      | USART3 kernel clock domain              | 3.057          | 2.273          | 1.628           | 0.926           |        |
|      | USART3 bus clock domain                 | 4.498          | 3.347          | 2.381           | 1.354           |        |
|      | I2C1 kernel clock domain                | 1.526          | 1.134          | 0.793           | 0.467           |        |
|      | I2C1 bus clock domain                   | 2.270          | 1.713          | 1.213           | 0.697           |        |
|      | I2C2 kernel clock domain                | 1.612          | 1.208          | 0.859           | 0.474           |        |
|      | I2C2 bus clock domain                   | 2.360          | 1.767          | 1.255           | 0.721           |        |
|      | I2C4 kernel clock domain                | 1.647          | 1.227          | 0.869           | 0.486           |        |
|      | I2C4 bus clock domain                   | 2.425          | 1.816          | 1.273           | 0.732           |        |
|      | LPTIM2 kernel clock domain              | 2.898          | 2.171          | 1.539           | 0.881           |        |
|      | LPTIM2 bus clock domain                 | 3.896          | 2.899          | 2.056           | 1.172           |        |
|      | SPI2 kernel clock domain                | 0.562          | 0.412          | 0.294           | 0.168           |        |
|      | SPI2 bus clock domain                   | 1.984          | 1.494          | 1.062           | 0.603           |        |
| APB2 | AHB to APB2 <sup>(4)</sup>              | 0.219          | 0.151          | 0.049           | 0.047           |        |
|      | TIM1                                    | 4.717          | 3.472          | 2.575           | 1.411           |        |
|      | SPI1 kernel clock domain                | 0.543          | 0.408          | 0.299           | 0.163           |        |
|      | SPI1 bus clock domain                   | 2.152          | 1.584          | 1.127           | 0.645           |        |
|      | TIM17                                   | 1.775          | 1.301          | 0.921           | 0.528           |        |

Table 55. Peripheral typical dynamic current consumption<sup>(1)</sup> (continued)

| Bus  | Peripheral                  | Range 1<br>LDO | Range 2<br>LDO | Range 1<br>SMPS | Range 2<br>SMPS | Unit   |
|------|-----------------------------|----------------|----------------|-----------------|-----------------|--------|
| APB2 | TIM16                       | 1.811          | 1.338          | 0.953           | 0.548           | μA/MHz |
|      | USART1 kernel clock domain  | 3.115          | 2.305          | 1.651           | 0.929           |        |
|      | USART1 bus clock domain     | 4.639          | 3.420          | 2.526           | 1.390           |        |
|      | SAI1 kernel clock domain    | 0.864          | 0.641          | 0.458           | 0.266           |        |
|      | SAI1 bus clock domain       | 2.566          | 1.893          | 1.350           | 0.770           |        |
| APB7 | AHB to APB7 <sup>(4)</sup>  | 0.704          | 0.493          | 0.371           | 0.197           |        |
|      | SYSCFG                      | 0.394          | 0.295          | 0.194           | 0.106           |        |
|      | SPI3 kernel clock domain    | 0.553          | 0.404          | 0.285           | 0.161           |        |
|      | SPI3 bus clock domain       | 1.799          | 1.334          | 0.948           | 0.531           |        |
|      | LPUART1 kernel clock domain | 2.243          | 1.667          | 1.187           | 0.682           |        |
|      | LPUART1 bus clock domain    | 3.426          | 2.529          | 1.811           | 1.020           |        |
|      | I2C3 kernel clock domain    | 1.777          | 1.331          | 0.939           | 0.533           |        |
|      | I2C3 bus clock domain       | 2.482          | 1.856          | 1.314           | 0.749           |        |
|      | LPTIM1 kernel clock domain  | 2.930          | 2.190          | 1.553           | 0.890           |        |
|      | LPTIM1 bus clock domain     | 3.945          | 2.915          | 2.080           | 1.181           |        |
|      | COMP                        | 0.217          | 0.154          | 0.115           | 0.058           |        |
|      | RTC/TAMP                    | 1.530          | 1.145          | 0.821           | 0.453           |        |
|      | VREFBUF                     | 0.097          | 0.079          | 0.067           | 0.027           |        |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

2. The AHB bus is automatically active when at least one peripheral is ON on the AHB or associated APB.

3. RADIO inactive.

4. The AHB to APB bridge is automatically active when at least one peripheral is ON on the APB.

### 5.3.9 Wake-up time from low-power modes and voltage scaling transition times

The times given in [Table 56](#) are the latency between the event and the execution of the first user instruction (FSTEN = 1 in PWR\_CR3 if not mentioned differently).

The device goes in Low-power mode after the WFE (Wait For Event) instruction.

Table 56. Low-power mode wake-up timings - LDO<sup>(1)</sup>

| Symbol                             | Parameter  | Conditions   | Typ    | Unit    |
|------------------------------------|--|--------------|--------|---------|
| $t_{WU(Stop\ 0)}$                  | Wake-up time from Stop 0 to Run mode in flash memory, SRAMs retained | FLASHFWU = 0 | 12.98  | $\mu s$ |
|                                    | Wake-up time from Stop 0 to Run mode in SRAM2                        |              | 13.36  |         |
| $t_{WU(Stop\ 1)}$                  | Wake-up time from Stop 1 to Run mode in flash memory, SRAMs retained |              | 27.10  |         |
|                                    | Wake-up time from Stop 1 to Run mode in SRAM2                        |              | 27.66  |         |
| $t_{WU(Stop\ 2)}$                  | Wake-up time from Stop 2 to Run mode in flash memory, SRAMs retained |              | 27.10  |         |
|                                    | Wake-up time from Stop 2 to Run mode in SRAM2                        |              | 27.66  |         |
| $t_{WU(Standby\ with\ retention)}$ | Wake-up time from Standby retention to Run mode in flash memory      |              | 51.49  |         |
|                                    | Wake-up time from Standby to Run mode in SRAM2                       |              | 51.49  |         |
| $t_{WU(Standby)}$                  | Wake-up time from Standby to Run mode in flash memory                | FSTEN = 1    | 104.59 |         |
|                                    |  | FSTEN = 0    | 556.39 |         |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

Table 57. Low-power mode wake-up timings - SMPS<sup>(1)</sup>

| Symbol                             | Parameter  | Conditions   | Typ    | Unit    |
|------------------------------------|--|--------------|--------|---------|
| $t_{WU(Stop\ 0)}$                  | Wake-up time from Stop 0 to Run mode in flash memory, SRAMs retained | FLASHFWU = 0 | 12.92  | $\mu s$ |
|                                    | Wake-up time from Stop 0 to Run mode in SRAM2                        |              | 13.36  |         |
| $t_{WU(Stop\ 1)}$                  | Wake-up time from Stop 1 to Run mode in flash memory, SRAMs retained |              | 20.86  |         |
|                                    | Wake-up time from Stop 1 to Run mode in SRAM2                        |              | 21.24  |         |
| $t_{WU(Stop\ 2)}$                  | Wake-up time from Stop 2 to Run mode in flash memory, SRAMs retained |              | 20.86  |         |
|                                    | Wake-up time from Stop 2 to Run mode in SRAM2                        |              | 21.24  |         |
| $t_{WU(Standby\ with\ retention)}$ | Wake-up time from Standby retention to Run mode in flash memory      |              | 45.19  |         |
|                                    | Wake-up time from Standby to Run mode in SRAM2                       |              | 46.19  |         |
| $t_{WU(Standby)}$                  | Wake-up time from Standby to Run mode in flash memory                | FSTEN = 1    | 104.59 |         |
|                                    |  | FSTEN = 0    | 556.39 |         |

1. Guaranteed by characterization results, unless otherwise specified.

**Table 58. Regulator modes transition times<sup>(1)</sup>**

| Symbol           | Parameter                         | Conditions | Typ  | Unit    |
|------------------|-----------------------------------|------------|------|---------|
| $t_{LDO}$        | SMPS to LDO transition time       | Range 2    | 21.5 | $\mu s$ |
|                  |                                   | Range 1    | 17.2 |         |
| $t_{SMPS}$       | LDO to SMPS transition time       | Range 2    | 21.1 |         |
|                  |                                   | Range 1    | 20.2 |         |
| $t_{VOST}^{(2)}$ | Range 2 to range 1                | LDO        | 47.3 |         |
|                  |                                   | SMPS       | 53.9 |         |
|                  | Range 1 to range 2 <sup>(3)</sup> | LDO        | 39   |         |
|                  |                                   | SMPS       | 39.8 |         |

1. Evaluated by characterization, not tested in production, unless otherwise specified.
2. Time for ACTVOSRDY in PWR\_SVMSR to indicate selected new VOS range.
3. VOSRDY remains at 1 on a transition from range 1 to range 2.

**Table 59. Wake-up time using USART/LPUART<sup>(1)</sup>**

| Symbol                            | Parameter  | Typ | Max                         | Unit    |
|-----------------------------------|--|-----|-----------------------------|---------|
| $t_{WUUSART}$ ,<br>$t_{WULPUART}$ | Wake-up time needed to calculate the maximum USART/LPUART baudrate needed to wake up from Stop mode when USART/LPUART kernel clock source is HSI16 | -   | $t_{su(HSI16)} \text{ max}$ | $\mu s$ |

1. Specified by design, not tested in production.

### 5.3.10 External clock source characteristics

#### High-speed external clock

The high-speed external (HSE32) clock can be supplied with a 32 MHz crystal or a clock source.

The devices include internal programmable capacitances that can be used to trim the crystal frequency, to compensate the PCB parasitic one.

**Table 60. HSE32 crystal requirements<sup>(1)</sup>**

| Symbol     | Parameter   | Conditions    | Min | Typ | Max  | Unit     |
|------------|---|---------------|-----|-----|------|----------|
| $f_{HSE}$  | Oscillator frequency <sup>(2)</sup>   | -             | -   | 32  | -    | MHz      |
| $f_{TOL}$  | Frequency tolerance <sup>(3)</sup><br>includes initial accuracy, stability over temperature, aging, and frequency pulling due to incorrect load capacitance | Bluetooth® LE | -50 | -   | 50   | ppm      |
|            |   | IEEE802.15.4  | -40 | -   | 40   |          |
| $C_L$      | Load capacitance  | -             | 8   | -   | 18   | pF       |
| $C_O$      | Shunt capacitance   | -             | -   | -   | 4    |          |
| ESR        | Equivalent series resistance  | -             | 60  | -   | 150  | $\Omega$ |
| $C_{bank}$ | Capacitor bank range  | -             | 6.6 | -   | 23.6 | pF       |

Table 60. HSE32 crystal requirements<sup>(1)</sup> (continued)

| Symbol                    | Parameter                     | Conditions | Min | Typ | Max | Unit |
|---------------------------|-------------------------------|------------|-----|-----|-----|------|
| C <sub>bank-step</sub>    | Capacitor bank step size      | -          | 215 | 270 | 325 | fF   |
| t <sub>STAB</sub>         | Oscillator stabilization time | -          | -   | 100 | 160 | μs   |
| I <sub>DDRF</sub> (HSE32) | Current consumption           | -          | -   | 205 | -   | μA   |

1. Specified by design, not tested in production.
2. 32 MHz XTAL is specified for two specific references: NX2016SA and NX1612SA.
3. After capacitor bank trimming.

Table 61. HSE32 clock source requirements<sup>(1)</sup>

| Symbol                 | Parameter   | Conditions               | Min | Typ | Max  | Unit             |
|------------------------|---|--------------------------|-----|-----|------|------------------|
| f <sub>HSE32</sub>     | External clock source frequency <sup>(2)</sup>  | -                        | -   | 32  | -    | MHz              |
| f <sub>TOL</sub>       | Frequency tolerance<br>includes initial accuracy, stability over temperature, and aging | Bluetooth® LE            | -50 | -   | 50   | ppm              |
|                        |   | IEEE802.15.4             | -40 | -   | 40   |                  |
| V <sub>HSE32</sub>     | Clock input voltage limits  | Input level              | 0   | -   | 0.9  | V                |
|                        |   | Amplitude <sup>(3)</sup> | 200 | -   | 900  | mV <sub>PP</sub> |
| DuCy <sub>HSE32</sub>  | Duty cycle  | -                        | 45  | -   | 55   | %                |
| Φ <sub>n</sub> (HSE32) | Phase noise for 32 MHz  | Offset = 10 kHz          | -   | -   | -127 | dBc/Hz           |
|                        |   | Offset = 100 kHz         | -   | -   | -135 |                  |
|                        |   | Offset = 1 MHz           | -   | -   | -138 |                  |

1. Specified by design, not tested in production.
2. f<sub>HSE</sub> = 1/t<sub>HSE</sub>.
3. AC coupling is supported (470 pF to 100 nF capacitor).

**Note:** For information about oscillator trimming, refer to AN5042 “Precise HSE frequency and startup time tuning for STM32 wireless MCUs”, available on [www.st.com](http://www.st.com).

### Low-speed external clock

The low-speed external (LSE) clock can be supplied with a crystal or a clock source. The information provided in this section is based on design simulation results, obtained with the typical external components specified in [Table 62](#). In the application, the crystal and the load capacitors must be placed as close as possible to the oscillator pins, to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

Table 62. LSE oscillator characteristics<sup>(1)</sup>

| Symbol           | Parameter                           | Conditions | Min | Typ                    | Max | Unit |
|------------------|-------------------------------------|------------|-----|------------------------|-----|------|
| f <sub>LSE</sub> | Oscillator frequency <sup>(2)</sup> | -          | -   | 32.000<br>or<br>32.768 | -   | kHz  |

Table 62. LSE oscillator characteristics<sup>(1)</sup> (continued)

| Symbol            | Parameter  | Conditions                            | Min  | Typ | Max  | Unit      |
|-------------------|--|---------------------------------------|------|-----|------|-----------|
| $f_{TOL}$         | Frequency tolerance includes initial accuracy, stability over temperature, aging and frequency pulling due to incorrect load capacitance | Bluetooth® LE                         | -500 | -   | 500  | ppm       |
|                   |  | Thread CSL                            | -255 | -   | 255  |           |
| $I_{DD(LSE)}$     | LSE current consumption  | LSEDRV = medium-low drive capability  | -    | 450 | -    | nA        |
|                   |  | LSEDRV = medium-high drive capability | -    | 590 | -    |           |
|                   |  | LSEDRV = high drive capability        | -    | 700 | -    |           |
| $G_{m_{critmax}}$ | Maximum critical crystal Gm  | LSEDRV = medium-low drive capability  | -    | -   | 0.75 | $\mu A/V$ |
|                   |  | LSEDRV = medium-high drive capability | -    | -   | 1.70 |           |
|                   |  | LSEDRV = high drive capability        | -    | -   | 2.70 |           |
| $C_{S\_PARA}$     | Internal stray parasitic capacitance <sup>(3)</sup>  | -                                     | -    | 3   | -    | pF        |
| $t_{SU(LSE)}$     | Startup time <sup>(4)</sup>  | $V_{DD}$ is stabilized                | -    | 2   | -    | s         |

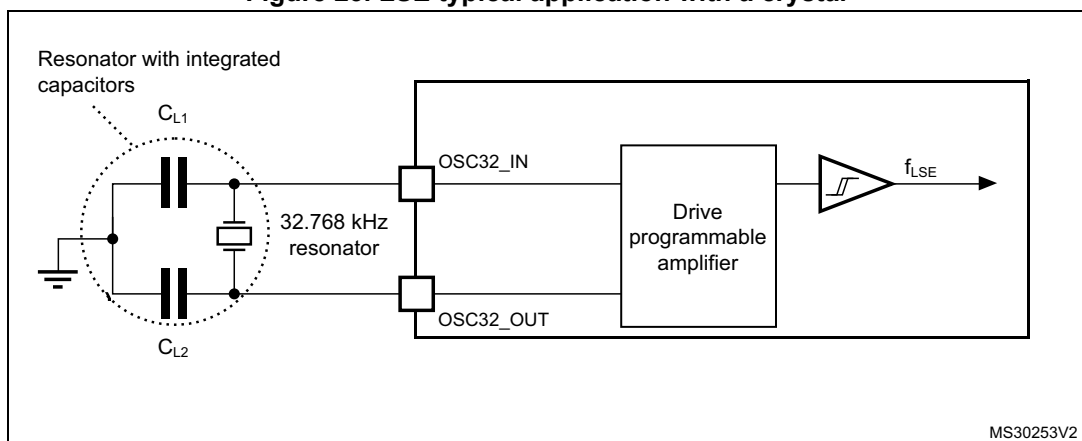
1. Specified by design, not tested in production.

2. For information on selecting the crystal, refer to AN2867 'Oscillator design guide for STM8AF/AL/S, STM32 MCUs and MPUs'.

3.  $C_{S\_PARA}$  is the equivalent capacitance seen by the crystal due to OSC32\_IN and OSC32\_OUT internal parasitic capacitances.

4. Time measured from when the LSE is enabled by software, until a stable LSE oscillation is reached. This value is measured for a standard crystal, and can vary significantly with the crystal used.

Figure 23. LSE typical application with a crystal



**Note:** No external resistors are required between  $OSC32\_IN$  and  $OSC32\_OUT$ , and it is forbidden to add one.

In bypass mode the LSE oscillator is switched off, and the input pin  $OSC32\_IN$  is a standard GPIO.

Table 63. LSE external clock bypass mode characteristics<sup>(1)</sup>

| Symbol                         | Parameter  | Conditions    | Min                 | Typ    | Max                 | Unit |
|--------------------------------|--|---------------|---------------------|--------|---------------------|------|
| $f_{LSE\_ext}$                 | External clock source frequency <sup>(2)</sup>                               | -             | 32.000              | 32.768 | -                   | kHz  |
| $f_{TOL}$                      | Frequency tolerance includes initial accuracy and stability over temperature | Bluetooth® LE | -500                | -      | 500                 | ppm  |
|                                |  | Thread CSL    | -225                | -      | 225                 |      |
| $V_{IL}$                       | OSC32_IN input low level voltage   | -             | -                   | -      | $0.3 \times V_{DD}$ | V    |
| $V_{IH}$                       | OSC32_IN input high level voltage  | -             | $0.7 \times V_{DD}$ | -      | -                   | V    |
| $t_{w(LSEH)}$<br>$t_{w(LSEL)}$ | OSC32_IN input high or low time for square signal                            | -             | 10                  | -      | -                   | μs   |

1. Specified by design, not tested in production.

2.  $f_{LSE} = 1/t_{LSE}$ .

### 5.3.11 Internal clock source characteristics

The parameters given in the following tables are derived under ambient operating temperature and supply voltage conditions summarized in [Table 30](#).

#### High-speed internal (HSI16) RC oscillator

Table 64. HSI16 oscillator characteristics

| Symbol                               | Parameter                           | Conditions   | Min   | Typ | Max   | Unit |
|--------------------------------------|-------------------------------------|--|-------|-----|-------|------|
| $f_{HSI16}$                          | Frequency after factory calibration | $V_{DD} = 3.0\text{ V}$ , $T_J = 30\text{ °C}$<br>calibrated during production               | 15.92 | 16  | 16.08 | MHz  |
|                                      |                                     | $1.71\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,<br>$T_J = -10\text{ to }100\text{ °C}^{(1)}$ | 15.84 | 16  | 16.16 |      |
|                                      |                                     | $1.71\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,<br>$T_J = -40\text{ to }130\text{ °C}^{(1)}$ | 15.65 | 16  | 16.35 |      |
| TRIM <sup>(2)</sup>                  | User trimming step                  | -  | 18    | 29  | 40    | kHz  |
| DuCy <sub>HSI16</sub> <sup>(2)</sup> | Duty cycle                          | -  | 45    | -   | 55    | %    |
| $t_{su(HSI16)}$ <sup>(2)</sup>       | Startup time                        | -  | -     | 2.5 | 3.6   | μs   |
| $t_{stab(HSI16)}$ <sup>(2)</sup>     | Stabilization time                  | -  | -     | 4   | 6     |      |
| $I_{DD(HSI16)}$ <sup>(2)</sup>       | Power consumption                   | -  | -     | 150 | 210   | μA   |

1. Evaluated by characterization, not tested in production, unless otherwise specified. It does not take into account package and soldering effects.

2. Specified by design, not tested in production.



## Low-speed internal (LSI) RC oscillator

Table 65. LSI1 oscillator characteristics

| Symbol                 | Parameter          | Conditions  | Min   | Typ  | Max   | Unit          |
|------------------------|--------------------|---|-------|------|-------|---------------|
| $f_{LSI1}$             | Frequency          | $V_{DD} = 3.0\text{ V}$ , $T_J = 30\text{ }^{\circ}\text{C}$ , LSIPREDIV = 1  | 0.245 | 0.25 | 0.255 | kHz           |
|                        |                    | $V_{DD} = 3.0\text{ V}$ , $T_J = 30\text{ }^{\circ}\text{C}$ , LSIPREDIV = 0  | 31.4  | 32.0 | 32.6  |               |
|                        |                    | $1.71\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ , $T_J = -40\text{ to }85\text{ }^{\circ}\text{C}$ , LSIPREDIV = 0 <sup>(1)</sup> | 30.4  | 32.0 | 33.6  |               |
| $DuCy_{LSI1}$          | Duty cycle         | LSIPREDIV = 1   | -     | 50   | -     | %             |
| $t_{SU(LSI1)}^{(2)}$   | Startup time       | -   | -     | 230  | 260   | $\mu\text{s}$ |
| $t_{STAB(LSI1)}^{(2)}$ | Stabilization time | 5% of final frequency   | -     | 230  | 260   |               |
| $I_{DD(LSI1)}^{(2)}$   | Power consumption  | LSIPREDIV = 0   | -     | 140  | 255   | nA            |
|                        |                    | LSIPREDIV = 1   | -     | 130  | 240   |               |

1. Evaluated by characterization, not tested in production, unless otherwise specified.
2. Specified by design, not tested in production.

Table 66. LSI2 oscillator characteristics

| Symbol                 | Parameter                  | Conditions            | Min  | Typ | Max  | Unit                    |
|------------------------|----------------------------|-----------------------|------|-----|------|-------------------------|
| $f_{LSI2}$             | Frequency                  | -                     | 24   | 32  | 48   | kHz                     |
| $t_{SU(LSI2)}^{(1)}$   | Startup time               | -                     | 550  | -   | 750  | $\mu\text{s}$           |
| $t_{STAB(LSI2)}^{(1)}$ | Stabilization time         | 5% of final frequency | -    | 650 | 1100 |                         |
| $\Delta_{TEMP}^{(2)}$  | Stability over temperature | -                     | -200 | -   | 200  | ppm/ $^{\circ}\text{C}$ |
| $I_{DD(LSI2)}^{(2)}$   | Power consumption          | -                     | -    | 1   | 2    | $\mu\text{A}$           |

1. Specified by design, not tested in production.
2. Evaluated by characterization, not tested in production, unless otherwise specified.

## 5.3.12 PLL characteristics

The parameters given in [Table 67](#) are derived from tests performed at ambient temperature and under the supply voltage conditions summarized in [Table 30](#).

Table 67. PLL characteristics

| Symbol                  | Parameter                    | Conditions      | Min | Typ | Max | Unit          |
|-------------------------|------------------------------|-----------------|-----|-----|-----|---------------|
| $f_{PLL\_IN}^{(1)}$     | PLL input clock              | -               | 4   | -   | 16  | MHz           |
| $DuCy_{PLL\_IN}^{(1)}$  | PLL input clock duty cycle   | -               | 10  | -   | 90  | %             |
| $f_{PLL\_OUT}^{(1)}$    | PLL output clock P, Q, and R | -               | 1   | -   | 100 | MHz           |
| $DuCy_{PLL\_OUT}^{(1)}$ | PLL output clock duty cycle  | Division 1      | 40  | -   | 60  | %             |
| $f_{VCO\_OUT}^{(1)}$    | PLL VCO output               | -               | 128 | -   | 544 | MHz           |
| $t_{LOCK}^{(2)}$        | PLL lock time <sup>(3)</sup> | Integer mode    | -   | 25  | 54  | $\mu\text{s}$ |
|                         |                              | Fractional mode | -   | 40  | 65  |               |

Table 67. PLL characteristics (continued)

| Symbol                              | Parameter  | Conditions                          | Min | Typ  | Max | Unit |
|-------------------------------------|--|-------------------------------------|-----|------|-----|------|
| Jitter <sup>(1)</sup>               | RMS cycle-to-cycle jitter                                      | Integer mode, VCO = 544 MHz         | -   | ±20  | -   | ps   |
|                                     |  | Fractional mode, VCO = 544 MHz      | -   | ±70  | -   |      |
|                                     | RMS period jitter  | Integer mode, VCO = 544 MHz         | -   | ±35  | -   |      |
|                                     |  | Fractional mode, VCO = 544 MHz      | -   | ±45  | -   |      |
|                                     | Long-term jitter <sup>(4)</sup><br>f <sub>PLL_IN</sub> = 8 MHz | Integer mode, VCO = 544 MHz         | -   | ±160 | -   |      |
|                                     |  | Fractional mode, VCO = 544 MHz      | -   | ±170 | -   |      |
| I <sub>DD(PLL)</sub> <sup>(1)</sup> | PLL power consumption on V <sub>DD</sub> with LDO              | VCO freq = 100 MHz                  | -   | 370  | -   | μA   |
|                                     |  | VCO freq = 200 MHz                  | -   | 460  | -   |      |
|                                     |  | VCO freq = 336 MHz                  | -   | 710  | -   |      |
|                                     |  | VCO freq = 544 MHz                  | -   | 1100 | -   |      |
|                                     | PLL power consumption on V <sub>DD</sub> with SMPS.            | VCO freq = 100 MHz, 1 clock output  | -   | 260  | -   | μA   |
|                                     |  | VCO freq = 100 MHz, 3 clock outputs | -   | 270  | -   |      |
|                                     |  | VCO freq = 200 MHz, 1 clock output  | -   | 320  | -   |      |
|                                     |  | VCO freq = 336 MHz, 1 clock output  | -   | 470  | -   |      |
|                                     |  | VCO freq = 544 MHz, 1 clock output  | -   | 730  | -   |      |

1. Specified by design, not tested in production.
2. Evaluated by characterization, not tested in production, unless otherwise specified.
3. Lock time is the duration until PLL1RDY flag (2% of final frequency).
4. Measured on 5000 cycles.

### 5.3.13 Flash memory characteristics

Table 68. Flash memory characteristics

| Symbol                                 | Parameter                            | Conditions                              | Typ  | Max <sup>(1)</sup> | Unit |
|--|--------------------------------------|---|------|--------------------|------|
| t <sub>prog</sub> <sup>(2)</sup>       | 128-bit programming time             | Normal mode                             | 118  | 118                | μs   |
|  |                                      | Burst mode                              | 48   | 48                 |      |
| t <sub>prog_page</sub> <sup>(2)</sup>  | One 8-Kbyte page programming time    | f <sub>AHB</sub> = 100 MHz, normal mode | 62   | -                  | ms   |
|  |                                      | f <sub>AHB</sub> = 100 MHz, burst mode  | 24.9 | -                  |      |
| t <sub>prog_flash</sub> <sup>(2)</sup> | 1-Mbyte programming time             | f <sub>AHB</sub> = 100 MHz, normal mode | 7930 | -                  |      |
|  |                                      | f <sub>AHB</sub> = 100 MHz, burst mode  | 3180 | -                  |      |
| t <sub>ERASE</sub> <sup>(2)</sup>      | One 8-Kbyte page erase time          | 10 k endurance cycles                   | 1.5  | 2.4                |      |
|  |                                      | 100 k endurance cycles <sup>(3)</sup>   | 1.7  | 3.4                |      |
| t <sub>ME</sub> <sup>(2)</sup>         | Mass erase time (1-Mbyte, one bank)  | 10 k endurance cycles                   | 195  | 308                |      |
|  | Mass erase time (2-Mbyte, two banks) |   | 390  | 616                |      |

Table 68. Flash memory characteristics (continued)

| Symbol         | Parameter                            | Conditions | Typ | Max <sup>(1)</sup> | Unit |
|----------------|--------------------------------------|------------|-----|--------------------|------|
| $I_{DD}^{(4)}$ | Average consumption from $V_{DD}$    | Write mode | 2.1 | -                  | mA   |
|                |                                      | Erase mode | 1.3 | -                  |      |
|                | Maximum current (peak) from $V_{DD}$ | Write mode | 2.6 | -                  |      |
|                |                                      | Erase mode | 3.0 | -                  |      |

1. Evaluated by characterization after cycling, not tested in production.
2. Specified by design, not tested in production, unless otherwise specified.
3. Erase time applies to all pages in user area in flash main memory (only 32 pages can be cycled more than 10 k times)
4. Evaluated by characterization, not tested in production, unless otherwise specified.

Table 69. Flash memory endurance and data retention<sup>(1)</sup>

| Symbol    | Parameter                     | Conditions                   |   | Min | Unit    |
|-----------|-------------------------------|------------------------------|---|-----|---------|
| $N_{END}$ | Endurance                     | Whole user flash             | $T_A = -40$ to $105\text{ }^{\circ}\text{C}$          | 10  | kcycles |
|           |                               | Limited to 32 pages per bank |   | 100 |         |
| $t_{RET}$ | Data retention <sup>(2)</sup> | Whole bank                   | $T_A = 85\text{ }^{\circ}\text{C}$ after 1 kcycles    | 30  |         |
|           |                               |                              | $T_A = 105\text{ }^{\circ}\text{C}$ after 1 kcycles   | 15  |         |
|           |                               |                              | $T_A = 55\text{ }^{\circ}\text{C}$ after 10 kcycles   | 30  |         |
|           |                               |                              | $T_A = 85\text{ }^{\circ}\text{C}$ after 10 kcycles   | 15  |         |
|           |                               |                              | $T_A = 105\text{ }^{\circ}\text{C}$ after 10 kcycles  | 10  |         |
|           |                               | Limited to 32 pages per bank | $T_A = 55\text{ }^{\circ}\text{C}$ after 100 kcycles  | 30  |         |
|           |                               |                              | $T_A = 85\text{ }^{\circ}\text{C}$ after 100 kcycles  | 15  |         |
|           |                               |                              | $T_A = 105\text{ }^{\circ}\text{C}$ after 100 kcycles | 10  |         |

1. Evaluated by characterization, not tested in production, unless otherwise specified.
2. Cycling performed over the whole temperature range.

### 5.3.14 EMC characteristics

Susceptibility tests are performed on a sample basis during device characterization.

#### Functional EMS (electromagnetic susceptibility)

While a simple application is executed on the device (toggling two LEDs through I/O ports), the device is stressed by two electromagnetic events until a failure occurs. The failure is indicated by the LEDs as follows:

- ESD (electrostatic discharge), positive and negative: applied to all device pins until a functional disturbance occurs. This test is compliant with the IEC 61000-4-2 standard.
- FTB (fast transient voltage burst), positive and negative: applied to  $V_{DD}$  and  $V_{SS}$  pins through a 100 pF capacitor, until a functional disturbance occurs. This test is compliant with the IEC 61000-4-4 standard.

A device reset allows normal operations to be resumed.

The test results are given in [Table 70](#). They are based on the EMS levels and classes defined in AN1709 “*EMC design guide for STM8, STM32 and legacy MCUs*”.

**Table 70. EMS characteristics<sup>(1)</sup>**

| Symbol     | Parameter  | Conditions  | Level/Class |
|------------|--|---|-------------|
| $V_{FESD}$ | Voltage limits to apply on any I/O pin to induce a functional disturbance  | $V_{DD} = 3.3\text{ V}$ , $T_A = +25\text{ °C}$ , $f_{HCLK1} = 100\text{ MHz}$ , UFBGA121 conforming to IEC 61000-4-2 | 3B          |
| $V_{EFTB}$ | Fast transient voltage burst limits to apply through 100 pF on $V_{DD}$ and $V_{SS}$ pins to induce a functional disturbance | $V_{DD} = 3.3\text{ V}$ , $T_A = +25\text{ °C}$ , $f_{HCLK1} = 100\text{ MHz}$ , UFBGA121 conforming to IEC 61000-4-4 | 5A          |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

### Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software.

Good EMC performance is highly dependent on the user application, and the software in particular. Therefore, it is recommended that the user applies EMC software optimization and prequalification tests in relation with the requested EMC level.

#### Software recommendations

The software flow must include the management of runaway conditions, such as:

- Corrupted program counter
- Unexpected reset
- Critical data corruption (control registers)

#### Prequalification trials

Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the NRST pin or on the oscillator pins for 1 second.

To complete these trials, ESD stress can be applied directly on the device, over the range of specified values. When an unexpected behavior is detected, the software can be hardened to prevent the occurrence of unrecoverable errors. See AN1015 “*Software techniques for improving microcontrollers EMC performance*” for more details.

### Electromagnetic interference (EMI)

The electromagnetic field emitted by the device is monitored while a simple application is executed (toggling two LEDs through the I/O ports). This emission test is compliant with the IEC 61967-2 standard, which specifies the test board and the pin loading.

Table 71. EMI characteristics for  $f_{HSE} = 32\text{ MHz}$  and  $f_{HCLK} = 100\text{ MHz}$ <sup>(1)</sup>

| Symbol    | Parameter                 | Conditions  | Monitored frequency band | Value | Unit |
|-----------|---------------------------|---|--------------------------|-------|------|
| $S_{EMI}$ | Peak level <sup>(2)</sup> | $V_{DD} = 3.6\text{ V}$ , $T_A = 25\text{ °C}$ ,<br>UFBGA121-SMPS package<br>compliant with IEC 61967-2 | 0.1 MHz to 30 MHz        | 1     | dBμV |
|           |                           |   | 30 MHz to 130 MHz        | 6     |      |
|           |                           |   | 130 MHz to 1 GHz         | 8     |      |
|           |                           |   | 1 GHz to 2 GHz           | 8     |      |
|           | Level <sup>(3)</sup>      |   | EMI level                | 2.5   | -    |

1. Evaluated by characterization, not tested in production.

2. Refer to AN1709, "EMI radiated test" section.

3. Refer to AN1709, "EMI level classification" section.

### 5.3.15 Electrical sensitivity characteristics

Based on three different tests (ESD, latch-up) using specific measurement methods, the device is stressed in order to determine its performance in terms of electrical sensitivity.

#### Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts × (n+1) supply pins). This test conforms to the ANSI/JEDEC standard.

Table 72. ESD absolute maximum ratings<sup>(1)</sup>

| Symbol                | Ratings   | Conditions   | Package      | Class | Max  | Unit |
|-----------------------|---|--|--------------|-------|------|------|
| V <sub>ESD(HBM)</sub> | Electrostatic discharge voltage (human body model)    | T <sub>A</sub> = 25 °C, conforming to ANSI/ESDA/JEDEC JS-001 | All          | 2     | 2000 | V    |
| V <sub>ESD(CDM)</sub> | Electrostatic discharge voltage (charge device model) | T <sub>A</sub> = 25 °C, conforming to ANSI/ESDA/JEDEC JS-002 | UFQFPN48     | C2a   | 500  |      |
|                       |   |  | VFQFPN68     |       |      |      |
|                       |   |  | Thin WLCSP88 | C1    | 250  |      |
|                       |   |  | UFBGA121     | C1    | 250  |      |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

#### Static latch-up

The following complementary static tests are required on three parts to assess the latch-up performance:

- a supply overvoltage is applied to each power supply pin
- a current injection is applied to each input, output and configurable I/O pin.

These tests are compliant with EIA/JESD 78A IC latch-up standard.

Table 73. Electrical sensitivity<sup>(1)</sup>

| Symbol | Parameter             | Conditions                                  | Class |
|--------|-----------------------|---|-------|
| LU     | Static latch-up class | $T_J = 130\text{ °C}$ conforming to JESD78E | 2     |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

### 5.3.16 I/O current injection characteristics

As a general rule, current injection to the I/O pins, due to external voltage below  $V_{SS}$  or above  $V_{DD}$  (for standard, 3.3 V-capable I/O pins) should be avoided during normal product operation. However, in order to give an indication of the robustness of the microcontroller if abnormal injection accidentally happens, some susceptibility tests are performed on a sample basis during device characterization.

#### Functional susceptibility to I/O current injection

While a simple application is executed, the device is stressed by injecting current into the I/O pins programmed in floating input mode. While current is injected into the I/O pin, one at a time, the device is checked for functional failures.

The failure is indicated by an out-of-range parameter, such as an ADC error above a certain limit (higher than 5 LSB ET), out of conventional limits of induced leakage current on adjacent pins (out of the  $-5\ \mu\text{A}/0\ \mu\text{A}$  range) or other functional failure (for example reset occurrence or oscillator frequency deviation).

The characterization results are given in [Table 74](#). The negative/positive induced leakage current is caused by the negative/positive injection.

**Table 74. I/O current injection susceptibility<sup>(1)</sup>**

| Symbol    | Description                  | Functional susceptibility |                    | Unit |
|-----------|------------------------------|---------------------------|--------------------|------|
|           |                              | Negative injection        | Positive injection |      |
| $I_{INJ}$ | Injected current on all pins | 5                         | N/A                | mA   |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

### 5.3.17 I/O port characteristics

#### General input/output characteristics

The parameters given in [Table 75](#) are derived from tests performed at ambient temperature and under the supply voltage conditions summarized in [Table 30](#). All I/Os are designed as CMOS- and TTL-compliant.

**Note:** For information on I/O configuration, refer to AN4899 “STM32 GPIO configuration for hardware settings and low-power consumption”.

**Table 75. I/O static characteristics**

| Symbol          | Parameter                    | Conditions  | Min                 | Typ | Max                 | Unit |
|-----------------|------------------------------|---|---------------------|-----|---------------------|------|
| $V_{IL}$        | I/O input low level voltage  | $1.58\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,<br>$1.08\text{ V} \leq V_{DDIO2} \leq 3.6\text{ V}$ | -                   | -   | $0.3 \times V_{DD}$ | V    |
| $V_{IH}$        | I/O input high level voltage |   | $0.7 \times V_{DD}$ | -   | -                   |      |
| $V_{hys}^{(1)}$ | Input hysteresis             | -   | -                   | 250 | -                   | mV   |

Table 75. I/O static characteristics (continued)

| Symbol          | Parameter   |                      | Conditions  | Min | Typ | Max  | Unit |
|-----------------|---|----------------------|---|-----|-----|------|------|
| $I_{lkg}^{(1)}$ | I/O input leakage current <sup>(2)(3)</sup>       | All I/Os except FT_u | $V_{IN} \leq \text{Max}(V_{DDX})$                                     | -   | -   | 150  | nA   |
|                 |   |                      | $\text{Max}(V_{DDX}) < V_{IN} \leq \text{Max}(V_{DDX}) + 1 \text{ V}$ | -   | -   | 2000 |      |
|                 |   |                      | $\text{Max}(V_{DDX}) + 1 \text{ V} < V_{IN} \leq 5.5 \text{ V}^{(3)}$ | -   | -   | 500  |      |
|                 |   | FT_u I/Os            | $V_{IN} \leq \text{Max}(V_{DDX})$                                     | -   | -   | 200  |      |
|                 |   |                      | $\text{Max}(V_{DDX}) < V_{IN} \leq \text{Max}(V_{DDX}) + 1 \text{ V}$ | -   | -   | 2500 |      |
|                 |   |                      | $\text{Max}(V_{DDX}) + 1 \text{ V} < V_{IN} \leq 5.5 \text{ V}^{(3)}$ | -   | -   | 500  |      |
| $R_{PU}$        | Weak pull-up equivalent resistor <sup>(4)</sup>   |                      | -   | 30  | 40  | 50   | kΩ   |
| $R_{PD}$        | Weak pull-down equivalent resistor <sup>(4)</sup> |                      | -   | 30  | 40  | 50   |      |
| $C_{IO}$        | I/O pin capacitance                               |                      | -   | -   | 5   | -    | pF   |

1. Specified by design, not tested in production.

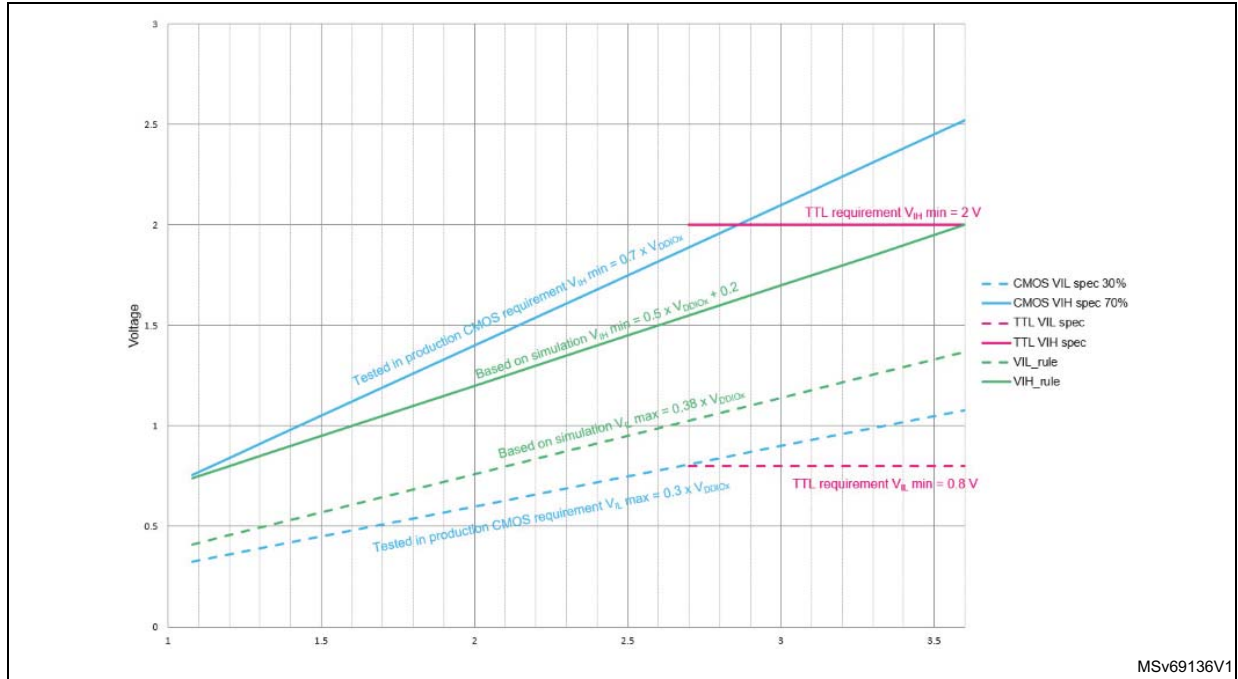
2. This parameter represents the pad leakage of the I/O itself. The total product pad leakage is provided by the following formula:  $I_{Total\_leak\_max} = 10 \mu\text{A} + [\text{number of I/Os where } V_{IN} \text{ is applied on the pad}] \times I_{lkg} \text{ max.}$

3. To sustain a voltage higher than  $\min(V_{DD}, V_{DDIO2}, V_{DDUSB}, V_{DDA}) + 0.3 \text{ V}$ , the internal pull-up and pull-down resistors must be disabled.

4. The pull-up and pull-down resistors are designed with a true resistance in series with a switchable PMOS/NMOS. This PMOS/NMOS contribution to the series resistance is minimal (~10%).

All I/Os are CMOS- and TTL-compliant (no software configuration required). Their characteristics cover more than the strict CMOS-technology or TTL parameters. The coverage of these requirements is shown in [Figure 24](#).

**Figure 24. I/O input characteristics (all I/Os except PH3)**



### Output driving current

The I/Os can sink or source up to  $\pm 8$  mA, up to  $\pm 20$  mA with a relaxed  $V_{OL} / V_{OH}$ .

In the user application, the number of I/O pins that can drive current must be limited to respect the absolute maximum rating specified in [Section 5.2](#).

- The sum of the currents sourced by all the I/Os on  $V_{DD}$ , plus the maximum consumption of the MCU sourced on  $V_{DD}$ , cannot exceed the absolute maximum rating  $\Sigma I_{VDD}$  (see [Table 27](#)).
- The sum of the currents sunk by all the I/Os on  $V_{SS}$ , plus the maximum consumption of the MCU sunk on  $V_{SS}$ , cannot exceed the absolute maximum rating  $\Sigma I_{VSS}$  (see [Table 27](#)).

### Output voltage levels

Unless otherwise specified, the parameters given in [Table 76](#) are at ambient temperature and under the supply voltage conditions summarized in [Table 30](#). All I/Os are CMOS- and TTL-compliant.



Table 76. Output voltage characteristics<sup>(1)</sup>

| Symbol                            | Parameter   | Conditions  | Min                      | Max | Unit |
|-----------------------------------|---|---|--------------------------|-----|------|
| V <sub>OL</sub>                   | Output low level voltage                            | I <sub>IO</sub>   = 8 mA, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V     | -                        | 0.4 | V    |
| V <sub>OH</sub>                   | Output high level voltage                           |   | V <sub>DD</sub> - 0.4    | -   |      |
| V <sub>OL</sub> <sup>(2)</sup>    | Output low level voltage                            | I <sub>IO</sub>   = 20 mA, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V    | -                        | 1.3 |      |
| V <sub>OH</sub> <sup>(2)</sup>    | Output high level voltage                           |   | V <sub>DD</sub> - 1.3    | -   |      |
| V <sub>OL</sub> <sup>(2)</sup>    | Output low level voltage                            | I <sub>IO</sub>   = 4 mA, 1.58 V ≤ V <sub>DD</sub> ≤ 3.6 V    | -                        | 0.4 |      |
| V <sub>OH</sub> <sup>(2)</sup>    | Output high level voltage                           |   | V <sub>DD</sub> - 0.4    | -   |      |
| V <sub>OL</sub> <sup>(2)</sup>    | Output low level voltage                            | I <sub>IO</sub>   = 1 mA, 1.08 V ≤ V <sub>DDIO2</sub> ≤ 3.6 V | -                        | 0.4 |      |
| V <sub>OH</sub> <sup>(2)</sup>    | Output high level voltage                           |   | V <sub>DDIO2</sub> - 0.4 | -   |      |
| V <sub>OLFM+</sub> <sup>(2)</sup> | Output low level voltage for an I/O pin in Fm+ mode | I <sub>IO</sub>   = 20 mA, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V    | -                        | 0.4 |      |
|                                   |   | I <sub>IO</sub>   = 10 mA, 1.58 V ≤ V <sub>DD</sub> ≤ 3.6 V   | -                        | 0.4 |      |
|                                   |   | I <sub>IO</sub>   = 2 mA, 1.08 V ≤ V <sub>DDIO2</sub> ≤ 3.6 V | -                        | 0.4 |      |

1. The I<sub>IO</sub> current sourced or sunk by the device must always respect the absolute maximum rating specified in [Table 26](#), and the sum of the currents sourced or sunk by all the I/Os (I/O ports and control pins) must always respect the absolute maximum ratings ΣI<sub>(PIN)</sub>.
2. Specified by design, not tested in production.

### Output AC characteristics

The definition of output AC characteristics is given in [Figure 25](#), values in [Table 77](#) and [Table 78](#). Unless otherwise specified, the parameters in these tables are at ambient temperature and under the supply voltage conditions summarized in [Table 30](#).

Table 77. Output AC characteristics, HSLV off<sup>(1)(2)</sup>

| Speed <sup>(3)</sup> | Symbol                         | Parameter                 | Conditions   | Min | Max  | Unit |
|----------------------|--------------------------------|---------------------------|--|-----|------|------|
| 00                   | Fmax                           | Maximum frequency         | C <sub>L</sub> = 50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V      | -   | 12.5 | MHz  |
|                      |                                |                           | C <sub>L</sub> = 50 pF, 1.58 V ≤ V <sub>DD</sub> < 2.7 V     | -   | 5    |      |
|                      |                                |                           | C <sub>L</sub> = 50 pF, 1.08 V ≤ V <sub>DDIO2</sub> < 1.58 V | -   | 1    |      |
|                      |                                |                           | C <sub>L</sub> = 10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V      | -   | 12.5 |      |
|                      |                                |                           | C <sub>L</sub> = 10 pF, 1.58 V ≤ V <sub>DD</sub> < 2.7 V     | -   | 5    |      |
|                      |                                |                           | C <sub>L</sub> = 10 pF, 1.08 V ≤ V <sub>DDIO2</sub> < 1.58 V | -   | 1    |      |
|                      | t <sub>r</sub> /t <sub>f</sub> | Output rise and fall time | C <sub>L</sub> = 50 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V      | -   | 17   | ns   |
|                      |                                |                           | C <sub>L</sub> = 50 pF, 1.58 V ≤ V <sub>DD</sub> < 2.7 V     | -   | 33   |      |
|                      |                                |                           | C <sub>L</sub> = 50 pF, 1.08 V ≤ V <sub>DDIO2</sub> < 1.58 V | -   | 85   |      |
|                      |                                |                           | C <sub>L</sub> = 10 pF, 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V      | -   | 12.5 |      |
|                      |                                |                           | C <sub>L</sub> = 10 pF, 1.58 V ≤ V <sub>DD</sub> < 2.7 V     | -   | 25   |      |
|                      |                                |                           | C <sub>L</sub> = 10 pF, 1.08 V ≤ V <sub>DDIO2</sub> < 1.58 V | -   | 50   |      |

Table 77. Output AC characteristics, HSLV off<sup>(1)(2)</sup> (continued)

| Speed <sup>(3)</sup> | Symbol    | Parameter                       | Conditions   | Min | Max  | Unit |
|----------------------|-----------|---------------------------------|--|-----|------|------|
| 01                   | Fmax      | Maximum frequency               | $C_L = 30 \text{ pF}, 2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$    | -   | 55   | MHz  |
|                      |           |                                 | $C_L = 30 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$      | -   | 12.5 |      |
|                      |           |                                 | $C_L = 30 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$  | -   | 2.5  |      |
|                      |           |                                 | $C_L = 10 \text{ pF}, 2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$    | -   | 55   |      |
|                      |           |                                 | $C_L = 10 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$      | -   | 12.5 |      |
|                      |           |                                 | $C_L = 30 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$  | -   | 2.5  |      |
|                      | $t_r/t_f$ | Output rise and fall time       | $C_L = 30 \text{ pF}, 2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$    | -   | 5.8  | ns   |
|                      |           |                                 | $C_L = 30 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$      | -   | 10   |      |
|                      |           |                                 | $C_L = 30 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$  | -   | 18   |      |
|                      |           |                                 | $C_L = 10 \text{ pF}, 2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$    | -   | 4.2  |      |
|                      |           |                                 | $C_L = 10 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$      | -   | 7.5  |      |
|                      |           |                                 | $C_L = 10 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$  | -   | 12   |      |
| 10 <sup>(4)</sup>    | Fmax      | Maximum frequency               | $C_L = 30 \text{ pF}, 2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$    | -   | 100  | MHz  |
|                      |           |                                 | $C_L = 30 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$      | -   | 33   |      |
|                      |           |                                 | $C_L = 30 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$  | -   | 5    |      |
|                      |           |                                 | $C_L = 10 \text{ pF}, 2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$    | -   | 100  |      |
|                      |           |                                 | $C_L = 10 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$      | -   | 40   |      |
|                      |           |                                 | $C_L = 10 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$  | -   | 5    |      |
|                      | $t_r/t_f$ | Output rise and fall time       | $C_L = 30 \text{ pF}, 2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$    | -   | 3.3  | ns   |
|                      |           |                                 | $C_L = 30 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$      | -   | 6.0  |      |
|                      |           |                                 | $C_L = 30 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$  | -   | 13.3 |      |
|                      |           |                                 | $C_L = 10 \text{ pF}, 2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$    | -   | 2.0  |      |
|                      |           |                                 | $C_L = 10 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$      | -   | 4.1  |      |
|                      |           |                                 | $C_L = 10 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$  | -   | 9.2  |      |
| Fm+                  | Fmax      | Maximum frequency               | $C_L = 550 \text{ pF}, 1.08 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$  | -   | 1    | MHz  |
|                      | $t_f$     | Output fall time <sup>(5)</sup> | $C_L = 550 \text{ pF}, 1.58 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$  | -   | 100  | ns   |
|                      |           |                                 | $C_L = 550 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 200  |      |
|                      |           |                                 | $C_L = 100 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 3.6 \text{ V}$     | -   | 50   |      |
|                      |           |                                 | $C_L = 100 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 80   |      |

1. Specified by design, not tested in production.

2. PB15 and PH3 output and input frequencies must not exceed 16 kHz, PC14 and PC15 output and input frequencies must not exceed 250 kHz, for these I/Os OSPEED must be kept at low speed.

3. The I/O speed is configured using the OSPEED bits, Fm+ is configured in SYSCFG. Refer to the product reference manual for the description.

4. I/O compensation system enabled.

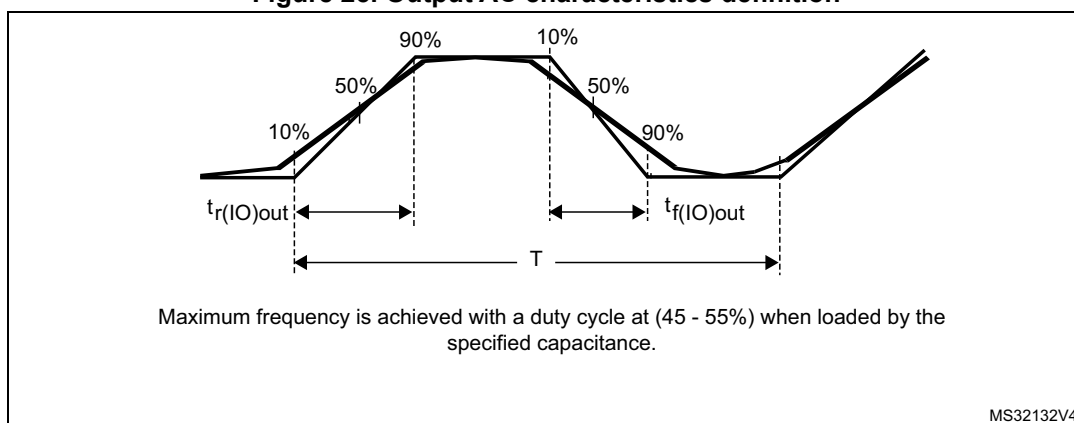
5. The fall time is defined between 70% and 30% of the output waveform, according to the I<sup>2</sup>C specification.

Table 78. Output AC characteristics, HSLV on<sup>(1)(2)</sup>

| Speed <sup>(3)</sup> | Symbol    | Parameter                 | Conditions  | Min | Max  | Unit |
|----------------------|-----------|---------------------------|---|-----|------|------|
| 00                   | Fmax      | Maximum frequency         | $C_L = 50 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$     | -   | 10   | MHz  |
|                      |           |                           | $C_L = 50 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 4    |      |
|                      |           |                           | $C_L = 10 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$     | -   | 15   |      |
|                      |           |                           | $C_L = 10 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 4    |      |
|                      | $t_r/t_f$ | Output rise and fall time | $C_L = 50 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$     | -   | 18   | ns   |
|                      |           |                           | $C_L = 50 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 32   |      |
|                      |           |                           | $C_L = 10 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$     | -   | 12   |      |
|                      |           |                           | $C_L = 10 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 21   |      |
| 01                   | Fmax      | Maximum frequency         | $C_L = 30 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$     | -   | 50   | MHz  |
|                      |           |                           | $C_L = 30 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 10   |      |
|                      |           |                           | $C_L = 10 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$     | -   | 67   |      |
|                      |           |                           | $C_L = 30 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 10   |      |
|                      | $t_r/t_f$ | Output rise and fall time | $C_L = 30 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$     | -   | 5.3  | ns   |
|                      |           |                           | $C_L = 30 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 10.6 |      |
|                      |           |                           | $C_L = 10 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$     | -   | 3.1  |      |
|                      |           |                           | $C_L = 10 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 5.6  |      |
| 10 <sup>(4)</sup>    | Fmax      | Maximum frequency         | $C_L = 30 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$     | -   | 75   | MHz  |
|                      |           |                           | $C_L = 30 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 15   |      |
|                      |           |                           | $C_L = 10 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$     | -   | 100  |      |
|                      |           |                           | $C_L = 10 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 15   |      |
|                      | $t_r/t_f$ | Output rise and fall time | $C_L = 30 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$     | -   | 4.4  | ns   |
|                      |           |                           | $C_L = 30 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 9.6  |      |
|                      |           |                           | $C_L = 10 \text{ pF}, 1.58 \text{ V} \leq V_{DD} < 2.7 \text{ V}$     | -   | 2.2  |      |
|                      |           |                           | $C_L = 10 \text{ pF}, 1.08 \text{ V} \leq V_{DDIO2} < 1.58 \text{ V}$ | -   | 4.7  |      |

- Specified by design, not tested in production.
- PB15 and PH3 output and input frequencies must not exceed 16 kHz, PC14 and PC15 output and input frequencies must not exceed 250 kHz, for these I/Os OSPEED must be kept at low speed.
- The I/O speed is configured using the OSPEED bits, Fm+ is configured in SYSCFG. Refer to the product reference manual for the description.
- I/O compensation system enabled.

Figure 25. Output AC characteristics definition



### 5.3.18 NRST pin characteristics

The NRST pin input driver uses CMOS technology. It is connected to a permanent pull-up resistor,  $R_{PU}$ .

Unless otherwise specified, the parameters given in [Table 79](#) are at ambient temperature and under the supply voltage conditions summarized in [Table 30](#).

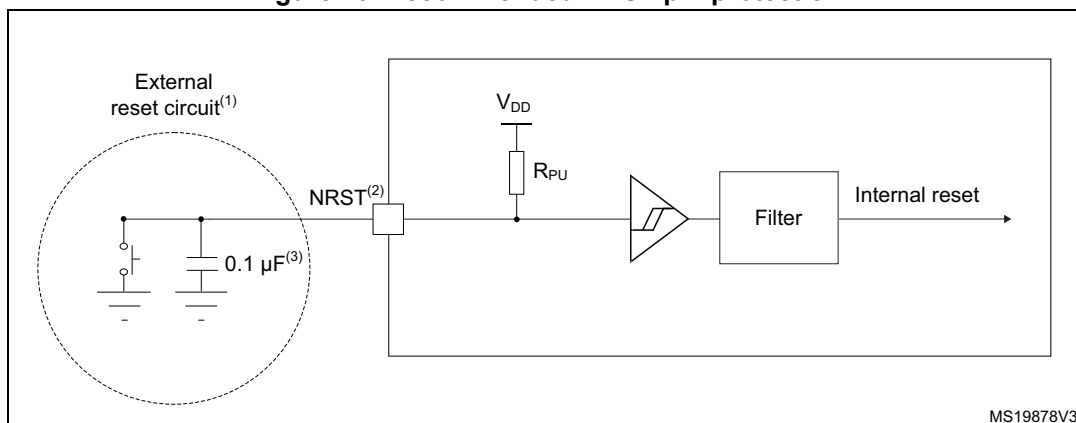
Table 79. NRST pin characteristics<sup>(1)</sup>

| Symbol          | Parameter                                       | Conditions                                      | Min                 | Typ | Max                 | Unit       |
|-----------------|---|---|---------------------|-----|---------------------|------------|
| $V_{IL}(NRST)$  | Input low level voltage                         | -   | -                   | -   | $0.3 \times V_{DD}$ | V          |
| $V_{IH}(NRST)$  | Input high level voltage                        | -   | $0.7 \times V_{DD}$ | -   | -                   |            |
| $V_{hys}(NRST)$ | Schmitt trigger voltage hysteresis              | -   | -                   | 200 | -                   | mV         |
| $R_{PU}$        | Weak pull-up equivalent resistor <sup>(2)</sup> | $V_{IN} = V_{SS}$                               | 30                  | 40  | 50                  | k $\Omega$ |
| $t_F(NRST)$     | Input filtered pulse                            | -   | -                   | -   | 50                  | ns         |
| $t_{NF}(NRST)$  | Input not-filtered pulse                        | $1.71 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$ | 330                 | -   | -                   |            |
|                 |   | $1.58 \text{ V} \leq V_{DD} < 1.71 \text{ V}$   | 1000                | -   | -                   |            |

1. Specified by design, not tested in production.

2. The pull-up is designed with a true resistance in series with a switchable PMOS, whose contribution to the series resistance is minimal (~10%).

Figure 26. Recommended NRST pin protection



1. The reset network protects the device against parasitic resets.
2. The user must ensure that the level on the NRST pin can go below the  $V_{IL(NRST)}$  maximum level specified in [Table 79](#), or the reset is not taken into account by the device.
3. The external capacitor on NRST must be placed as close as possible to the device.

### 5.3.19 Extended interrupt and event controller input (EXTI) characteristics

Pulses on the extended interrupt and event controller inputs must have a minimal length, to guarantee they are detected.

Table 80. EXTI input characteristics<sup>(1)</sup>

| Symbol       | Parameter                        | Conditions | Min | Typ | Max | Unit |
|--------------|----------------------------------|------------|-----|-----|-----|------|
| $t_{(EXTI)}$ | Pulse length to event controller | -          | 20  | -   | -   | ns   |

1. Specified by design, not tested in production.

### 5.3.20 Wake-up pin (WKUP) characteristics

Pulses on the wake-up pin inputs must have a minimal length, to ensure their detection.

Table 81. WKUP input characteristics<sup>(1)</sup>

| Symbol       | Parameter               | Conditions | Min | Typ | Max | Unit |
|--------------|-------------------------|------------|-----|-----|-----|------|
| $t_{(WKUP)}$ | Pulse length to wake up | -          | 20  | -   | -   | ns   |

1. Specified by design, not tested in production.

### 5.3.21 Analog switch booster

Table 82. Analog switches booster characteristics<sup>(1)</sup>

| Symbol          | Parameter            | Min | Typ | Max | Unit |
|-----------------|----------------------|-----|-----|-----|------|
| $V_{DD}$        | Supply voltage       | 1.6 | 1.8 | 3.6 | V    |
| $t_{SU(BOOST)}$ | Booster startup time | -   | -   | 50  | μs   |
| $I_{DD(BOOST)}$ | Booster consumption  | -   | -   | 125 | μA   |

1. Specified by design, not tested in production.

### 5.3.22 12-bit Analog-to-Digital converter (ADC4) characteristics

Unless otherwise specified, the parameters given in the following tables are derived at ambient temperature, and under the  $f_{HCLK}$  frequency and supply voltage conditions summarized in [Table 30](#).

*Note:* It is recommended to perform a calibration after each power-up.

**Table 83. 12-bit ADC4 characteristics <sup>(1)(2)</sup>**

| Symbol              | Parameter                          | Conditions  | Min                                   | Typ | Max        | Unit          |
|---------------------|------------------------------------|---|---------------------------------------|-----|------------|---------------|
| $V_{DDA}$           | Analog supply voltage              | -   | 1.62                                  | -   | 3.6        | V             |
| $V_{REF+}$          | Positive reference voltage         | -   | 1.0                                   | -   | $V_{DDA}$  |               |
| $f_{ADC}$           | ADC clock frequency                | -   | 0.14                                  | -   | 55         | MHz           |
| $DuCy_{ADC}$        | ADC clock duty cycle               | -   | 45                                    | -   | 55         | %             |
| $f_s$               | Sampling rate                      | Resolution 12 bits                                      | 0.010                                 | -   | 2.75       | MSPS          |
|                     |                                    | Resolution 10 bits                                      | 0.012                                 | -   | 3.05       |               |
|                     |                                    | Resolution 8 bits                                       | 0.014                                 | -   | 3.43       |               |
|                     |                                    | Resolution 6 bits                                       | 0.0175                                | -   | 3.92       |               |
| $t_{TRIG}$          | External trigger period            | Resolution 12 bits                                      | 16                                    | -   | -          | $1/f_{ADC}$   |
| $V_{AIN}^{(3)}$     | Conversion voltage range           | -   | 0                                     | -   | $V_{REF+}$ | V             |
| $R_{AIN}^{(4)}$     | External input impedance           | Resolution 12 bits, $T_j = 130\text{ }^{\circ}\text{C}$ | -                                     | -   | 2.2        | $k\Omega$     |
|                     |                                    | Resolution 10 bits, $T_j = 130\text{ }^{\circ}\text{C}$ | -                                     | -   | 6.8        |               |
|                     |                                    | Resolution 8 bits, $T_j = 130\text{ }^{\circ}\text{C}$  | -                                     | -   | 33.0       |               |
|                     |                                    | Resolution 6 bits, $T_j = 130\text{ }^{\circ}\text{C}$  | -                                     | -   | 47.0       |               |
| $C_{ADC}$           | Internal sample and hold capacitor | -   | -                                     | 5   | -          | pF            |
| $t_{ADCVREG\_STUP}$ | ADC voltage regulator startup time | -   | -                                     | -   | 25         | $\mu\text{s}$ |
| $t_{STAB}$          | ADC power-up time                  | -   | $(3 \times 1/f_{ADC}) + 1$ conversion |     |            | cycle         |

Table 83. 12-bit ADC4 characteristics <sup>(1)(2)</sup> (continued)

| Symbol                | Parameter                                       | Conditions   | Min                      | Typ  | Max                      | Unit               |
|-----------------------|---|--|--------------------------|------|--------------------------|--------------------|
| t <sub>OFF_CAL</sub>  | Offset calibration time                         | -  | 82                       |      |                          | 1/f <sub>ADC</sub> |
| t <sub>LATR</sub>     | Trigger conversion latency                      | WAIT = 0, AUTOFF = 0, DPD = 0, f <sub>ADC</sub> = HCLK   | 4                        |      |                          |                    |
|                       |   | WAIT = 0, AUTOFF = 1, DPD = 0, f <sub>ADC</sub> = HCLK/2 | 4                        |      |                          |                    |
|                       |   | WAIT = 0, AUTOFF = 1, DPD = 1, f <sub>ADC</sub> = HCLK/4 | 3.75                     |      |                          |                    |
| t <sub>s</sub>        | Sampling time                                   | -  | 1.5                      | -    | 814.5                    |                    |
| t <sub>CONV</sub>     | Total conversion time (including sampling time) | Resolution = N bits, VREFPROTEN = 0                      | t <sub>s</sub> + N + 0.5 |      |                          |                    |
|                       |   | Resolution = N bits, VREFPROTEN = 1, VREFSECSMP = 0      | t <sub>s</sub> + N + 0.5 | -    | t <sub>s</sub> + N + 1.5 |                    |
|                       |   | Resolution = N bits, VREFPROTEN = 1, VREFSECSMP = 1      | t <sub>s</sub> + N + 0.5 | -    | t <sub>s</sub> + N + 2.5 |                    |
| I <sub>DDA(ADC)</sub> | ADC consumption on V <sub>DDA</sub>             | f <sub>s</sub> = 2.5 Msps                                | -                        | 378  | -                        | μA                 |
|                       |   | f <sub>s</sub> = 1 Msps                                  | -                        | 190  | -                        |                    |
|                       |   | f <sub>s</sub> = 10 ksps                                 | -                        | 10   | -                        |                    |
|                       |   | AUTOFF = 1, DPD = 0, no conversion                       | -                        | 9    | -                        |                    |
|                       |   | AUTOFF = 1, DPD = 1, no conversion                       | -                        | 0.11 | -                        |                    |

1. Specified by design, not tested in production.
2. The voltage booster on the ADC switches must be used when  $V_{\text{DDA}} < 2.4 \text{ V}$  (embedded I/O switches).
3. Depending upon the package,  $V_{\text{REF+}}$  is internally connected to  $V_{\text{DDA}}$  and  $V_{\text{REF-}}$  is internally connected to  $V_{\text{SSA}}$ .
4. The tolerance is two LSBs.

Table 84. Maximum  $R_{\text{AIN}}$  for 12-bit ADC4<sup>(1)(2)(3)</sup>

| Resolution | $R_{\text{AIN}} (\Omega)$ | Sampling time (ns) | Sampling cycles at 35 MHz | Sampling cycles at 55 MHz |
|------------|---------------------------|--------------------|---------------------------|---------------------------|
| 12 bits    | 47                        | 276                | 12.5                      | 19.5                      |
|            | 68                        | 288                |                           |                           |
|            | 100                       | 306                |                           |                           |
|            | 150                       | 336                |                           |                           |

Table 84. Maximum  $R_{AIN}$  for 12-bit ADC4<sup>(1)(2)(3)</sup> (continued)

| Resolution             | R <sub>AIN</sub> (Ω) | Sampling time (ns) | Sampling cycles at 35 MHz | Sampling cycles at 55 MHz |
|------------------------|----------------------|--------------------|---------------------------|---------------------------|
| 12 bits<br>(continued) | 220                  | 377                | 19.5                      | 39.5                      |
|                        | 330                  | 442                |                           |                           |
|                        | 470                  | 526                |                           |                           |
|                        | 680                  | 650                | 39.5                      | 79.5                      |
|                        | 1000                 | 840                |                           |                           |
|                        | 1500                 | 1134               |                           |                           |
|                        | 2200                 | 1643               | 79.5                      | 814.5                     |
|                        | 3300                 | 2395               | 814.5                     |                           |
|                        | 4700                 | 3342               |                           |                           |
|                        | 6800                 | 4754               |                           |                           |
|                        | 10000                | 6840               |                           |                           |
|                        | 15000                | 9967               |                           |                           |
|                        | 22000                | 14068              |                           |                           |
|                        | 33000                | 19933              |                           | N/A                       |
| 10 bits                | 47                   | 86                 | 3.5                       | 7.5                       |
|                        | 68                   | 90                 |                           |                           |
|                        | 100                  | 95                 |                           |                           |
|                        | 150                  | 108                | 7.5                       |                           |
|                        | 220                  | 116                |                           |                           |
|                        | 330                  | 136                |                           |                           |
|                        | 470                  | 161                |                           |                           |
|                        | 680                  | 212                |                           |                           |
|                        | 1000                 | 276                |                           | 12.5                      |
|                        | 1500                 | 376                | 19.5                      | 39.5                      |
|                        | 2200                 | 516                |                           | 79.5                      |
|                        | 3300                 | 735                | 39.5                      |                           |
|                        | 4700                 | 1012               |                           |                           |
|                        | 6800                 | 1423               | 79.5                      | 814.5                     |
|                        | 10000                | 2040               | 814.5                     | 814.5                     |
|                        | 15000                | 2978               |                           |                           |
|                        | 22000                | 4356               |                           |                           |
|                        | 33000                | 6443               |                           |                           |
|                        | 47000                | 8925               |                           |                           |



Table 84. Maximum  $R_{AIN}$  for 12-bit ADC4<sup>(1)(2)(3)</sup> (continued)

| Resolution | R <sub>AIN</sub> (Ω) | Sampling time (ns) | Sampling cycles at 35 MHz | Sampling cycles at 55 MHz |  |
|------------|----------------------|--------------------|---------------------------|---------------------------|--|
| 8 bits     | 47                   | 45                 | 3.5                       | 3.5                       |  |
|            | 68                   | 46                 |                           |                           |  |
|            | 100                  | 48                 |                           |                           |  |
|            | 150                  | 53                 |                           |                           |  |
|            | 220                  | 59                 |                           |                           |  |
|            | 330                  | 69                 |                           |                           |  |
|            | 470                  | 81                 |                           |                           |  |
|            | 680                  | 101                | 7.5                       | 7.5                       |  |
|            | 1000                 | 130                |                           |                           |  |
|            | 1500                 | 177                |                           |                           |  |
|            | 2200                 | 242                | 12.5                      | 12.5                      |  |
|            | 3300                 | 345                |                           |                           |  |
|            | 4700                 | 475                | 19.5                      | 19.5                      |  |
|            | 6800                 | 670                | 39.5                      |                           |  |
|            | 10000                | 963                | 39.5                      | 39.5                      |  |
|            | 15000                | 1417               |                           |                           |  |
|            | 22000                | 2040               | 79.5                      | 79.5                      |  |
|            | 33000                | 2995               |                           |                           |  |
|            | 47000                | 4158               |                           |                           |  |
| 6 bits     | 47                   | 32                 | 1.5                       | 3.5                       |  |
|            | 68                   | 32                 |                           |                           |  |
|            | 100                  | 33                 |                           |                           |  |
|            | 150                  | 35                 |                           |                           |  |
|            | 220                  | 37                 |                           |                           |  |
|            | 330                  | 41                 |                           |                           |  |
|            | 470                  | 49                 | 3.5                       |                           |  |
|            | 680                  | 61                 |                           |                           |  |
|            | 1000                 | 79                 | 7.5                       | 7.5                       |  |
|            | 1500                 | 106                |                           |                           |  |
|            | 2200                 | 146                | 7.5                       | 12.5                      |  |
|            | 3300                 | 207                |                           |                           |  |
|            | 4700                 | 286                | 12.5                      | 19.5                      |  |
|            | 6800                 | 404                | 19.5                      | 39.5                      |  |
|            | 10000                | 584                | 39.5                      |                           |  |

Table 84. Maximum  $R_{AIN}$  for 12-bit ADC4<sup>(1)(2)(3)</sup> (continued)

| Resolution            | $R_{AIN}$ ( $\Omega$ ) | Sampling time (ns) | Sampling cycles at 35 MHz | Sampling cycles at 55 MHz |
|-----------------------|------------------------|--------------------|---------------------------|---------------------------|
| 6 bits<br>(continued) | 22000                  | 1250               | 79.5                      | 79.5                      |
|                       | 33000                  | 1853               |                           | 814.5                     |
|                       | 47000                  | 2607               | 814.5                     |                           |

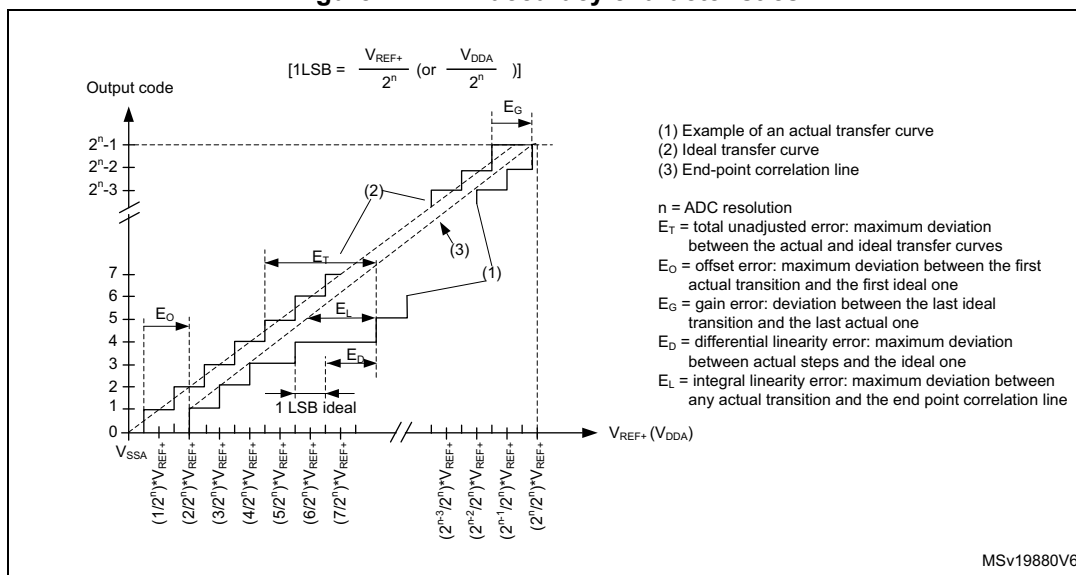
1. Specified by design, not tested in production.
2. BOOSTEN and ANASWVDD configured according to  $V_{DD}$  and  $V_{DDA}$  levels.
3. Values without external capacitance.

Table 85. 12-bit ADC4 accuracy<sup>(1)(2)(3)</sup>

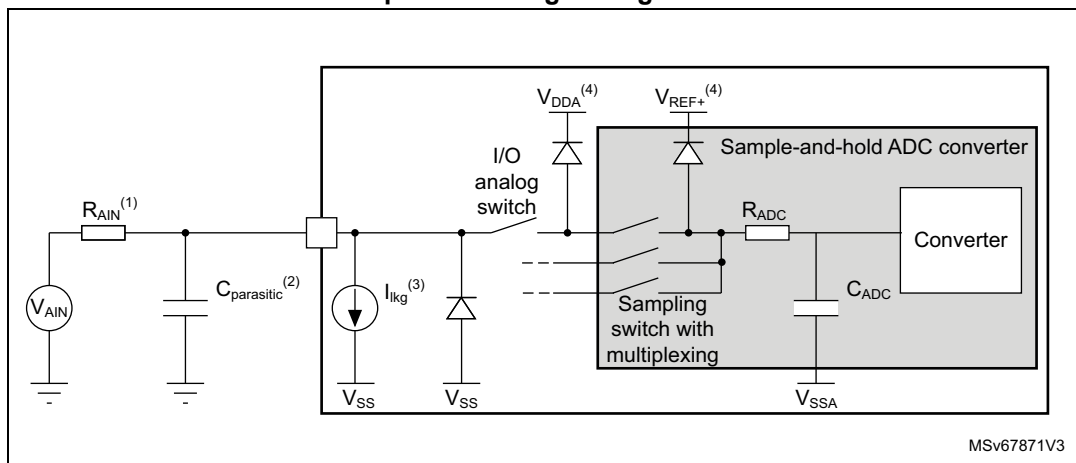
| Symbol | Parameter                            | Conditions | Min  | Typ       | Max       | Unit |
|--------|--------------------------------------|------------|------|-----------|-----------|------|
| ET     | Total unadjusted error               | -          | -    | $\pm 3$   | $\pm 7.5$ | LSB  |
| EO     | Offset error                         |            | -    | $\pm 2$   | $\pm 5.5$ |      |
| EG     | Gain error                           |            | -    | $\pm 2$   | $\pm 6.5$ |      |
| ED     | Differential linearity error         |            | -    | -0.9/+1.0 | -0.9/+1.5 |      |
| EL     | Integral linearity error             |            | -    | $\pm 2$   | $\pm 3.5$ |      |
| ENOB   | Effective number of bits             |            | 9.9  | 10.9      | -         | bits |
| SINAD  | Signal-to-noise and distortion ratio |            | 61.4 | 67.4      | -         | dB   |
| SNR    | Signal-to-noise ratio                |            | 61.6 | 67.5      | -         |      |
| THD    | Total harmonic distortion            |            | -    | -74       | -70       |      |

1. Evaluated by characterization, not tested in production.
2. DC accuracy values are measured after internal calibration.
3. The I/O analog switch voltage booster is enabled when  $V_{DDA} < 2.4$  V (resolution = 12 bits, no oversampling).

Figure 27. ADC accuracy characteristics



**Figure 28. Typical connection diagram when using the ADC with FT/TT pins featuring analog switch function**



1. Refer to [Table 83](#) for the values of  $R_{AIN}$  and  $C_{ADC}$ .
2.  $C_{parasitic}$  represents the PCB capacitance (dependent on soldering and PCB layout quality) plus the pad capacitance (refer to [Table 75](#) for the value of the pad capacitance). A high  $C_{parasitic}$  value downgrades the conversion accuracy. As a remedy, reduce  $f_{ADC}$ .
3. Refer to [Table 75](#) for the values of  $I_{Ikg}$ .
4. Refer to [Figure 18](#), [Figure 19](#), and [Figure 20](#).

### 5.3.23 Temperature sensor characteristics

**Table 86. Temperature sensor characteristics**

| Symbol                                   | Parameter  | Min | Typ | Max | Unit   |
|--|--|-----|-----|-----|--------|
| $T_L^{(1)(2)}$                           | $V_{SENSE}$ linearity with temperature   | -   | -   | 1.3 | °C     |
| Avg_Slope <sup>(3)</sup>                 | Average slope  | 2   | 2.5 | 3.0 | mV/ °C |
| $V_{SENSE30}^{(4)}$                      | $V_{SENSE}$ at $V_{REF+} = V_{DDA} = 3.0\text{ V}$ ( $\pm 10\text{ mV}$ ) and $30\text{ °C}$ ( $\pm 1\text{ °C}$ ) | 700 | 742 | 800 | mV     |
| $(V_{continuous0} - V_{sampling})^{(2)}$ | Voltage difference between continuous and sampling modes <sup>(5)</sup>  | -10 | -   | +4  | mV     |
| $t_{START(TS\_BUF)}^{(2)}$               | Sensor buffer startup time   | -   | 1   | 10  | μs     |
| $t_{S\_temp}^{(2)}$                      | ADC sampling time when reading the temperature   | 13  | -   | -   | μs     |
| $I_{DD(TS)}^{(2)}$                       | Consumption from $V_{DD}$ , when selected by ADC   | -   | 14  | 20  | μA     |

1.  $V_{SENSE}$  linearity depends upon calibration points. When using  $TS\_CALx$  calibration points, linearity within the calibration limits is degraded by  $\pm 5\text{ °C}$ . Linearity outside the calibration limits is degraded more, due to the extrapolation.
2. Specified by design, not tested in production.
3. Evaluated by characterization, not tested in production, unless otherwise specified.
4. The  $V_{SENSE30}$  ADC4 conversion result is stored in the  $TS\_CAL1$  field.
5. The temperature sensor is in continuous mode when the regulator is in range 1, in sampling mode when the regulator is in range 2 or the device is in Stop 1 mode.

### 5.3.24 V<sub>CORE</sub> monitoring characteristics

Table 87. V<sub>CORE</sub> monitoring characteristics<sup>(1)</sup>

| Symbol               | Parameter  | Min | Typ | Max | Unit |
|----------------------|--|-----|-----|-----|------|
| T <sub>S_VCORE</sub> | ADC sampling time when reading the V <sub>CORE</sub> voltage | 1   | -   | -   | μs   |

1. Specified by design, not tested in production.

### 5.3.25 Voltage reference buffer characteristics

Table 88. VREFBUF characteristics<sup>(1)</sup>

| Symbol                                 | Parameter                                 | Conditions   |           | Min                                  | Typ    | Max    | Unit       |
|--|---|--|-----------|--------------------------------------|--------|--------|------------|
| V <sub>DDA</sub>                       | Analog supply voltage                     | Normal mode  | VRS = 000 | 1.8                                  | -      | 3.6    | V          |
|  |   |  | VRS = 001 | 2.1                                  | -      |        |            |
|  |   |  | VRS = 010 | 2.4                                  | -      |        |            |
|  |   |  | VRS = 011 | 2.8                                  | -      |        |            |
|  |   | Degraded mode <sup>(2)</sup>   | VRS = 000 | 1.62                                 | -      | 1.8    |            |
|  |   |  | VRS = 001 |                                      | -      | 2.1    |            |
|  |   |  | VRS = 010 |                                      | -      | 2.4    |            |
|  |   |  | VRS = 011 |                                      | -      | 2.8    |            |
| V <sub>REFBUF_OUT</sub> <sup>(3)</sup> | Voltage reference buffer output           | Normal mode at V <sub>DDA</sub> = 3 V, T <sub>J</sub> = 30 °C, I <sub>load</sub> = 10 μA       | VRS = 000 | 1.496                                | 1.5    | 1.504  | V          |
|  |   |  | VRS = 001 | 1.795                                | 1.8    | 1.805  |            |
|  |   |  | VRS = 010 | 2.042                                | 2.048  | 2.054  |            |
|  |   |  | VRS = 011 | 2.493                                | 2.5    | 2.507  |            |
|  |   | Degraded mode <sup>(2)</sup>   | VRS = 000 | Min (V <sub>DDA</sub> - 0.15, 1.496) | -      | 1.504  |            |
|  |   |  | VRS = 001 | Min (V <sub>DDA</sub> - 0.15, 1.795) | -      | 1.805  |            |
|  |   |  | VRS = 010 | Min (V <sub>DDA</sub> - 0.15, 2.042) | -      | 2.054  |            |
|  |   |  | VRS = 011 | Min (V <sub>DDA</sub> - 0.15, 2.493) | -      | 2.507  |            |
| TRIM                                   | Trim step                                 | -  | 0.1       | 0.175                                | 0.25   | %      |            |
| C <sub>L</sub>                         | Load capacitor <sup>(4)</sup>             | -  | 0.5       | 1.10                                 | 1.50   | μF     |            |
| esr                                    | C <sub>L</sub> equivalent serial resistor | -  | -         | -                                    | 2      | Ω      |            |
| I <sub>load</sub>                      | Static load current                       | -  | -         | -                                    | 4      | mA     |            |
| R <sub>PD</sub>                        | Pull-down resistance                      | -  | -         | -                                    | 400    | Ω      |            |
| I <sub>line_reg</sub>                  | Line regulation                           | V <sub>DDAmin</sub> ≤ V <sub>DDA</sub> ≤ 3.6 V, Normal mode, 500 μA ≤ I <sub>load</sub> ≤ 4 mA |           | ±0.016                               | ±0.033 | ±0.053 | %          |
| I <sub>load_reg</sub>                  | Load regulation <sup>(5)</sup>            | Normal mode, 500 μA ≤ I <sub>load</sub> ≤ 4 mA   |           | -                                    | 50     | 400    | ppm/<br>mA |

Table 88. VREFBUF characteristics<sup>(1)</sup> (continued)

| Symbol                        | Parameter   | Conditions   | Min | Typ | Max                              | Unit                       |
|-------------------------------|---|--|-----|-----|----------------------------------|----------------------------|
| $T_{\text{Coeff}}$            | Temperature coefficient   | $-40\text{ }^{\circ}\text{C} < T_J < +130\text{ }^{\circ}\text{C}$ | -   | -   | $T_{\text{coeff\_vrefint}} + 50$ | ppm/<br>$^{\circ}\text{C}$ |
| PSRR                          | Power supply rejection  | DC   | -   | 65  | -                                | dB                         |
|                               |   | 100 kHz  | -   | 30  | -                                |                            |
| $t_{\text{START}}$            | Startup time  | $C_L = 0.5\text{ }\mu\text{F}$                                     | -   | 110 | 200                              | $\mu\text{s}$              |
|                               |   | $C_L = 1.1\text{ }\mu\text{F}$                                     | -   | 240 | 350                              |                            |
|                               |   | $C_L = 1.5\text{ }\mu\text{F}$                                     | -   | 320 | 500                              |                            |
| $I_{\text{INRUSH}}$           | Control of DC current drive on $V_{\text{REFBUF\_OUT}}$ during startup phase <sup>(6)</sup> | -  | -   | 8   | 11                               | mA                         |
| $I_{\text{DDA}}$<br>(VREFBUF) | Consumption from $V_{\text{DDA}}$   | $I_{\text{load}} = 0\text{ }\mu\text{A}$                           | -   | 14  | 18                               | $\mu\text{A}$              |
|                               |   | $I_{\text{load}} = 500\text{ }\mu\text{A}$                         | -   | 16  | 20                               |                            |
|                               |   | $I_{\text{load}} = 4\text{ mA}$                                    | -   | 42  | 50                               |                            |

1. Specified by design and not tested in production, unless otherwise specified.
2. In degraded mode, the voltage reference buffer cannot accurately maintain the output voltage ( $V_{\text{DDA}}$  - drop voltage).
3. Evaluated by characterization. Not tested in production.
4. The capacitive load must include a 100 nF capacitor to cut off the high-frequency noise.
5. The load regulation value only takes into account the die and package resistance. The parasitic resistance on PCB degrades this value.
6. To correctly control the VREFBUF inrush current during startup phase and scaling change, the  $V_{\text{DDA}}$  voltage must be in the range of [1.8 V-3.6 V], [2.1 V-3.6 V], [2.4 V-3.6 V], and [2.8 V-3.6 V] for, respectively, VRS = 000, 001, 010, and 011.

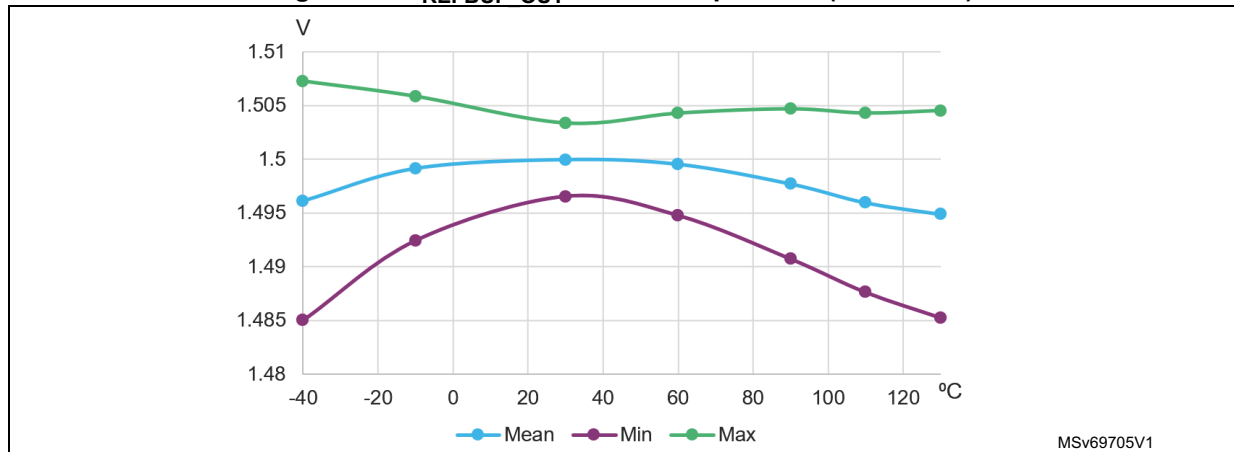
Figure 29.  $V_{\text{REFBUF\_OUT}}$  versus temperature (VRS = 000)

Figure 30.  $V_{\text{REFBUF OUT}}$  versus temperature (VRS = 001)

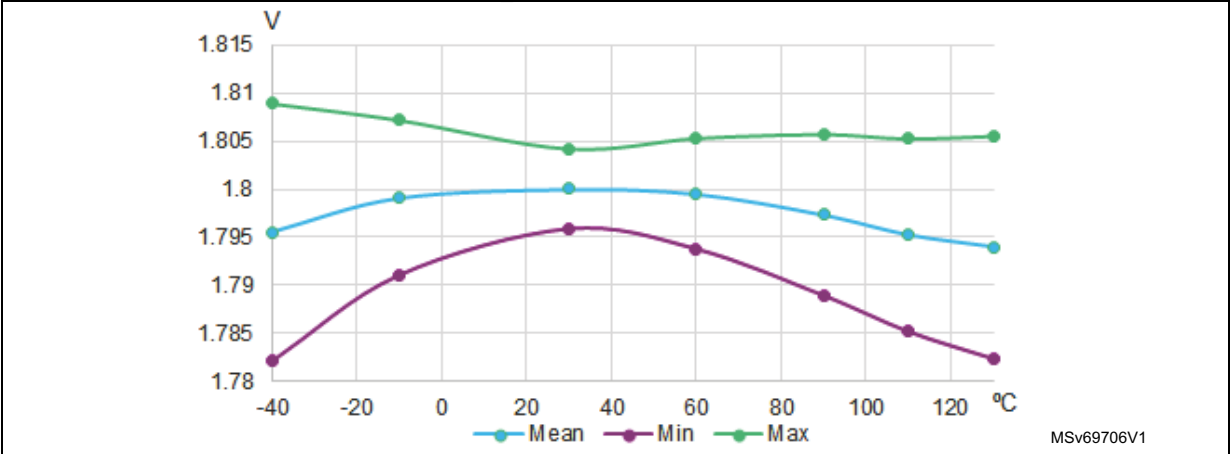


Figure 31.  $V_{\text{REFBUF OUT}}$  versus temperature (VRS = 010)

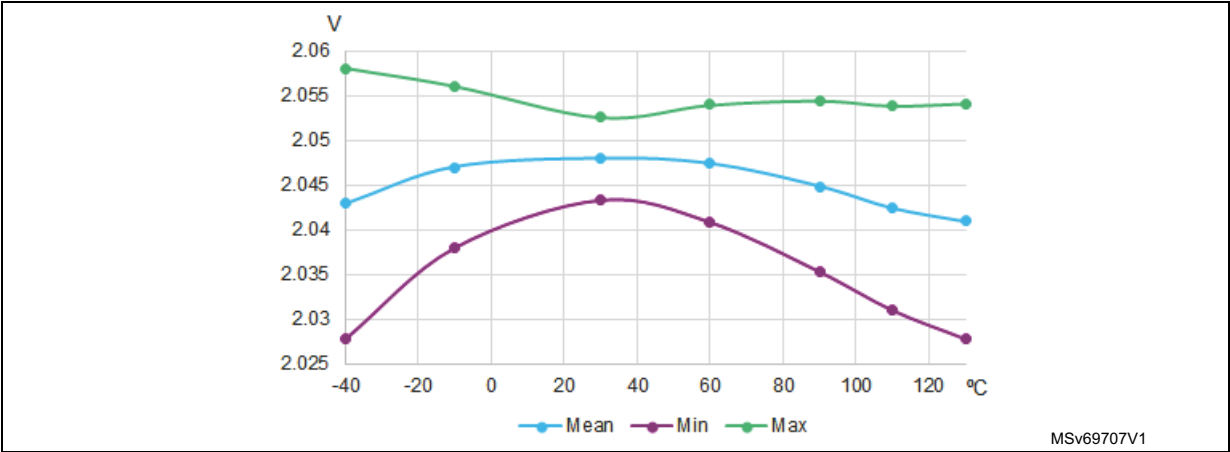
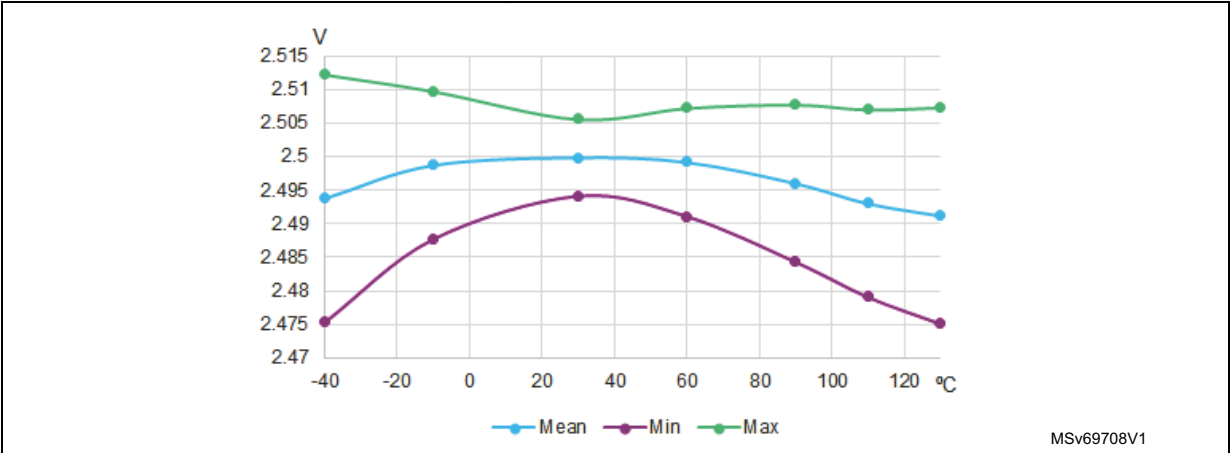


Figure 32.  $V_{\text{REFBUF OUT}}$  versus temperature (VRS = 011)



## 5.3.26 Comparator characteristics

Table 89. COMP characteristics<sup>(1)(2)</sup>

| Symbol                                | Parameter   | Conditions                            |   | Min  | Typ  | Max              | Unit |
|---------------------------------------|---|---------------------------------------|---|------|------|------------------|------|
| V <sub>DDA</sub>                      | Analog supply voltage                                   | -                                     |   | 1.58 | -    | 3.6              | V    |
| V <sub>IN</sub>                       | Input voltage range                                     | -                                     |   | 0    | -    | V <sub>DDA</sub> |      |
| V <sub>REFINT</sub>                   | Scaler input voltage                                    | -                                     |   | (3)  |      |                  | V    |
| V <sub>SC</sub>                       | Scaler offset voltage                                   | -                                     |   | -    | ±5   | ±10              | mV   |
| I <sub>DDA(SCALER)</sub>              | Static consumption from V <sub>DDA</sub>                | Scaler bridge disabled <sup>(4)</sup> |   | -    | 0.20 | 0.25             | µA   |
|                                       |   | Scaler bridge enabled <sup>(5)</sup>  |   | -    | 0.7  | 1                |      |
| t <sub>START_SCALER</sub>             | Scaler startup time                                     | -                                     |   | -    | 130  | 220              | µs   |
| t <sub>START</sub> <sup>(6)</sup>     | Startup time to reach propagation delay specification   | High-speed mode                       |   | -    | -    | 8                | µs   |
|                                       |   | Intermediate mode                     |   | -    | -    | 12               |      |
|                                       |   | Medium mode                           |   | -    | -    | 16               |      |
|                                       |   | Ultra-low-power mode                  |   | -    | -    | 60               |      |
| t <sub>D</sub> <sup>(6)</sup>         | Propagation delay for 200 mV step with 100 mV overdrive | High-speed mode                       |   | -    | 50   | 100              | ns   |
|                                       |   | Intermediate mode                     |   | -    | 240  | 490              |      |
|                                       |   | Medium mode                           |   | -    | 400  | 740              |      |
|                                       |   | Ultra-low-power mode                  |   | -    | 4    | 7.5              | µs   |
| V <sub>offset</sub> <sup>(6)</sup>    | Offset error  | Full common mode range                |   | -    | ±8   | ±20              | mV   |
| V <sub>hys</sub> <sup>(6)</sup>       | Hysteresis  | No hysteresis                         |   | -    | 0    | -                | mV   |
|                                       |   | Low hysteresis                        |   | -    | 13   | -                |      |
|                                       |   | Medium hysteresis                     |   | -    | 26   | -                |      |
|                                       |   | High hysteresis                       |   | -    | 39   | -                |      |
| I <sub>bias</sub> <sup>(6)</sup>      | Input bias current                                      | -                                     |   | (7)  |      |                  | nA   |
| I <sub>DDA(COMP)</sub> <sup>(6)</sup> | Consumption from V <sub>DDA</sub>                       | High-speed mode                       | Static                                      | -    | 43   | 72               | µA   |
|                                       |   |                                       | With 50 kHz ±100 mV overdrive square signal | -    | 44   | 73               |      |
|                                       |   | Intermediate mode                     | Static                                      | -    | 8.5  | 14               |      |
|                                       |   |                                       | With 50 kHz ±100 mV overdrive square signal | -    | 9    | 15               |      |
|                                       |   | Medium mode                           | Static                                      | -    | 4.0  | 7.0              |      |
|                                       |   |                                       | With 50 kHz ±100 mV overdrive square signal | -    | 4.5  | 7.5              |      |
|                                       |   | Ultra-low-power mode                  | Static                                      | -    | 0.38 | 1.05             |      |
|                                       |   |                                       | With 50 kHz ±100 mV overdrive square signal | -    | 1.5  | 2.5              |      |

1. Specified by design, not tested in production, unless otherwise specified.

2. Input capacitance is negligible when compared to the I/O capacitance.

3. Refer to [Table 43: Embedded internal voltage reference](#).
4. No  $V_{REFINT}$  division, includes only buffer consumption.
5.  $V_{REFINT}$  division, includes resistor bridge and buffer consumption.
6. Evaluated by characterization, not tested in production.
7. Mostly I/O leakage when used in analog mode. Refer to  $I_{lkg}$  parameter in [Table 75: I/O static characteristics](#).

### 5.3.27 Timer characteristics

The parameters given in [Table 90](#), [Table 91](#), and [Table 92](#) are specified by design. Refer to [Section 4.3](#) for details on the input/output alternate function characteristics (output compare, input capture, external clock, PWM output).

**Table 90. TIMx<sup>(1)</sup> characteristics<sup>(2)</sup>**

| Symbol          | Parameter                                    | Conditions                      | Min  | Max             | Unit          |
|-----------------|--|---------------------------------|------|-----------------|---------------|
| $t_{res(TIM)}$  | Timer resolution time                        | -                               | 1    | -               | $t_{TIMxCLK}$ |
|                 |  | $f_{TIMxCLK} = 100 \text{ MHz}$ | 10   | -               | ns            |
| $f_{EXT}$       | Timer external clock frequency on CH1 to CH4 | -                               | 0    | $f_{TIMxCLK}/2$ | MHz           |
|                 |  | $f_{TIMxCLK} = 100 \text{ MHz}$ | 0    | 50              |               |
| $Res_{TIM}$     | Timer resolution                             | TIM1, TIM3, TIM16, TIM17        | -    | 16              | bit           |
|                 |  | TIM2, TIM4                      | -    | 32              |               |
| $t_{COUNTER16}$ | 16-bit counter period                        | -                               | 1    | $2^{16}$        | $t_{TIMxCLK}$ |
|                 |  | $f_{TIMxCLK} = 100 \text{ MHz}$ | 0.01 | 655.36          | $\mu s$       |
| $t_{COUNTER32}$ | 32-bit counter period                        | -                               | 1    | $2^{32}$        | $t_{TIMxCLK}$ |
|                 |  | $f_{TIM2CLK} = 100 \text{ MHz}$ | 0,01 | 42.94           | s             |

1. TIMx is used as a general term, where x stands for 1, 2, 3, 4, 16, or 17.
2. Specified by design, not tested in production.

**Table 91. IWDG min/max timeout period at 32 kHz<sup>(1)(2)</sup>**

| Prescaler divider | PR[3:0] bits | Min timeout RL[11:0] = 0x002 | Max timeout RL[11:0] = 0xFF | Unit |
|-------------------|--------------|------------------------------|-----------------------------|------|
| /4                | 0            | 0.325                        | 512                         | ms   |
| /8                | 1            | 0.750                        | 1024                        |      |
| /16               | 2            | 1.500                        | 2048                        |      |
| /32               | 3            | 3.0                          | 4096                        |      |
| /64               | 4            | 6.0                          | 8192                        |      |
| /128              | 5            | 12.0                         | 16384                       |      |
| /256              | 6            | 24.0                         | 32768                       |      |
| /512              | 7            | 48.0                         | 65536                       |      |
| /1024             | Others       | 96.0                         | 131072                      |      |

1. The exact timings depend upon the phasing of the APB interface clock vs. the IWDG kernel clock, hence there is always a full kernel clock period of uncertainty.
2. Specified by design, not tested in production.



Table 92. WWDG min/max timeout value at 100 MHz (PCLK)

| Prescaler divider | WDGTB[2:0] | Min timeout value | Max timeout value | Unit |
|-------------------|------------|-------------------|-------------------|------|
| /1                | 0          | 0.040             | 1.621             | ms   |
| /2                | 1          | 0.081             | 5.242             |      |
| /4                | 2          | 0.163             | 10.485            |      |
| /8                | 3          | 0.327             | 20.971            |      |
| /16               | 4          | 0.655             | 41.943            |      |
| /32               | 5          | 1.310             | 83.886            |      |
| /64               | 6          | 2.621             | 167.772           |      |
| /128              | 7          | 5.242             | 335.544           |      |

### 5.3.28 I2C interface characteristics

The I2C interface meets the timings requirements of the I<sup>2</sup>C-bus specification and user manual rev. 03 for:

- Standard-mode (Sm): bit rate up to 100 kbit/s
- Fast-mode (Fm): bit rate up to 400 kbit/s
- Fast-mode Plus (Fm+): bit rate up to 1 Mbit/s.

The I2C timings requirements are specified by design, not tested in production, when the I2C peripheral is properly configured (refer to product reference manual).

The SDA and SCL I/O requirements are met with the following restriction: the SDA and SCL I/O pins are not “true” open-drain. When configured as open-drain, the PMOS connected between the I/O pin and V<sub>DD</sub> is disabled, but is still present. Only FT\_f I/O pins support Fm+ low level output current maximum requirement. Refer to [Section 5.3.17](#) for I2C I/O characteristics.

All I<sup>2</sup>C SDA and SCL I/Os embed an analog filter, refer to [Table 93](#) for its characteristics.

Table 93. I2C analog filter characteristics<sup>(1)</sup>

| Symbol          | Parameter   | Min               | Max                | Unit |
|-----------------|---|-------------------|--------------------|------|
| t <sub>AF</sub> | Maximum pulse width of spikes suppressed by the analog filter | 50 <sup>(2)</sup> | 190 <sup>(3)</sup> | ns   |

1. Specified by design, not tested in production.
2. Spikes with widths below t<sub>AF</sub> min are filtered.
3. Spikes with widths above t<sub>AF</sub> max are not filtered.

### 5.3.29 USART characteristics

Unless otherwise specified, the parameters given in [Table 94](#) are derived under the ambient temperature,  $f_{PCLKx}$  frequency and  $V_{DD}$  supply voltage conditions summarized in [Table 30](#), with the following configuration:

- Output speed set to  $OSPEEDRy[1:0] = 10$
- Capacitive load  $C_L = 30pF$
- Measurement points are done at  $0.5 V_{DD}$
- I/O compensation cell activated
- Voltage scaling range 1

Refer to [Section 4.3](#) for more details on the input/output alternate function characteristics (NSS, CK, TX, RX for USART).

**Table 94. USART characteristics<sup>(1)</sup>**

| Symbol                       | Parameter              | Conditions  | Min                  | Typ<br>3.3 V     | Max                  | Unit |
|------------------------------|------------------------|---|----------------------|------------------|----------------------|------|
| $f_{CK}$                     | USART clock frequency  | Master mode, $1.71 V \leq V_{DD} \leq 3.6 V$      | -                    | -                | 12.5                 | MHz  |
|                              |                        | Slave receiver, $1.71 V \leq V_{DD} \leq 3.6 V$   | -                    | -                | 33                   |      |
|                              |                        | Slave transmitter, $2.7 V \leq V_{DD} \leq 3.6 V$ | -                    | -                | 32                   |      |
|                              |                        | Slave transmitter, $1.71 V \leq V_{DD} < 2.7 V$   | -                    | -                | 22.5                 |      |
| $t_{su(NSS)}$                | NSS setup time         | Slave mode  | $t_{ker}^{(2)} + 2$  | -                | -                    | ns   |
| $t_{h(NSS)}$                 | NSS hold time          | Slave mode  | 4                    | -                | -                    |      |
| $t_{w(CKH)}$<br>$t_{w(CKL)}$ | CK high and low time   | Master mode                                       | $(1/f_{CK}) / 2 - 1$ | $(1/f_{CK}) / 2$ | $(1/f_{CK}) / 2 + 1$ |      |
| $t_{su(RX)}$                 | Data input setup time  | Master mode                                       | 24                   | -                | -                    |      |
|                              |                        | Slave mode  | 2                    | -                | -                    |      |
| $t_{h(RX)}$                  | Data input hold time   | Master mode                                       | 1                    | -                | -                    |      |
|                              |                        | Slave mode  | 0                    | -                | -                    |      |
| $t_{v(TX)}$                  | Data output valid time | Slave mode, $2.7 V \leq V_{DD} \leq 3.6 V$        | -                    | 13               | 15.5                 |      |
|                              |                        | Slave mode, $1.71 V \leq V_{DD} < 2.7 V$          | -                    |                  | 22                   |      |
|                              |                        | Master mode                                       | -                    | 1                | -                    |      |
| $t_{h(TX)}$                  | Data output hold time  | Slave mode  | 10                   | -                | -                    |      |
|                              |                        | Master mode                                       | 0                    | -                | -                    |      |

1. Evaluated by characterization, not tested in production, unless otherwise specified.

2.  $t_{ker}$  is the `usart_ker_ck_pres` clock period.

Figure 33. USART timing diagram in master mode

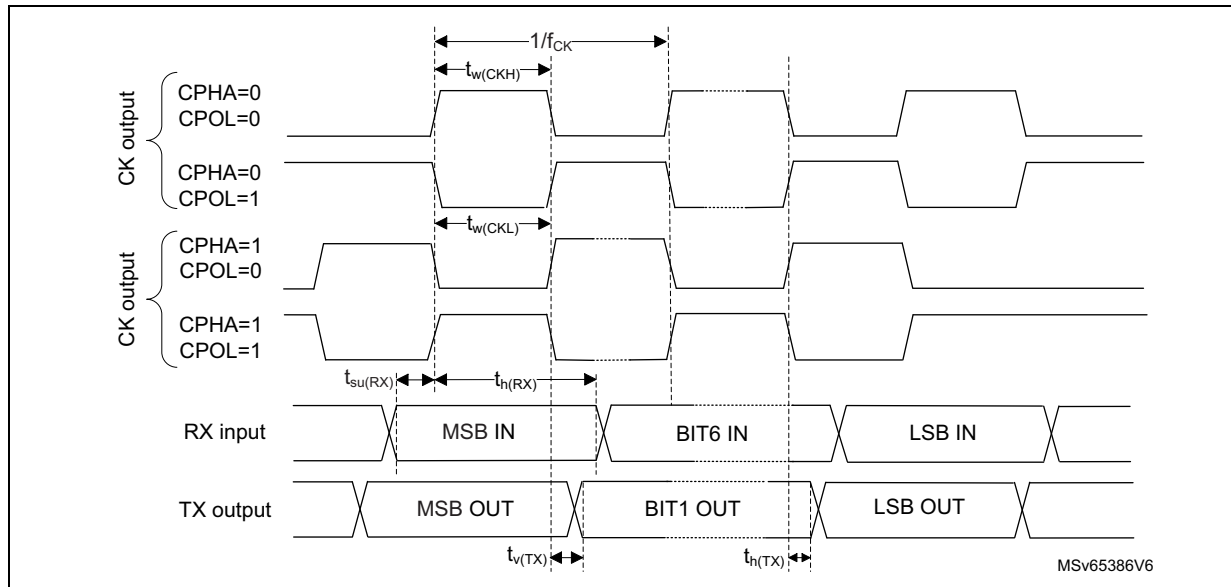
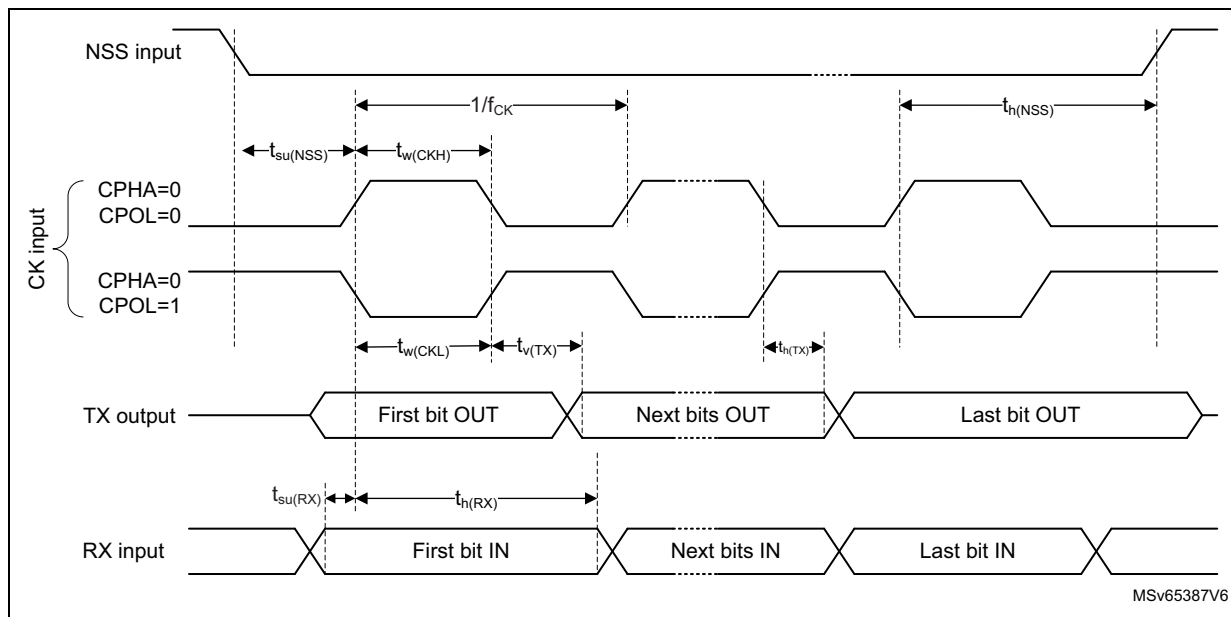


Figure 34. USART timing diagram in slave mode



### 5.3.30 SPI characteristics

Unless otherwise specified, the parameters given in [Table 95](#) are under the ambient temperature,  $f_{PCLKx}$  frequency and supply voltage conditions summarized in [Table 30](#), with the following configuration:

- Output speed is set to  $OSPEEDRy[1:0] = 10$
- Capacitive load  $C_L = 30$  pF
- Measurement points are done at  $0.5 V_{DD}$
- I/O compensation cell activated

Refer to [Section 4.3](#) for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO for SPI).

**Table 95. SPI characteristics<sup>(1)</sup>**

| Symbol                         | Parameter                | Conditions   | Min                   | Typ<br>3.3 V      | Max                   | Unit |
|--------------------------------|--------------------------|--|-----------------------|-------------------|-----------------------|------|
| $f_{SCK}$                      | Clock frequency          | Master receiver mode<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                         | -                     | -                 | 50                    | MHz  |
|                                |                          | Master receiver mode<br>$1.71\text{ V} \leq V_{DD} < 2.7\text{ V}$                           |                       |                   | 33                    |      |
|                                |                          | Master transmitter mode<br>$2.7\text{ V} \leq V_{DD} < 3.6\text{ V}$                         |                       |                   | 50                    |      |
|                                |                          | Master transmitter mode<br>$1.71\text{ V} \leq V_{DD} < 2.7\text{ V}$                        |                       |                   | 33                    |      |
|                                |                          | Slave receiver mode<br>$1.71\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                         |                       |                   | 50                    |      |
|                                |                          | Slave transmitter mode<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,<br>voltage range 1  |                       |                   | 30 <sup>(2)</sup>     |      |
|                                |                          | Slave transmitter mode<br>$1.71\text{ V} \leq V_{DD} < 2.7\text{ V}$ ,<br>voltage range 1    |                       |                   | 21 <sup>(2)</sup>     |      |
|                                |                          | Slave transmitter mode<br>$1.71\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,<br>voltage range 2 |                       |                   | 16                    |      |
| $t_{su(NSS)}$                  | NSS setup time           | Slave mode   | $4 \times T_{pclk}$   | -                 | -                     | ns   |
| $t_{h(NSS)}$                   | NSS hold time            | Slave mode   | $2 \times T_{pclk}$   | -                 | -                     |      |
| $t_{w(SCKH)}$<br>$t_{w(SCKL)}$ | SCK high and low time    | Master mode  | $t_{SCK}^{(3)}/2 - 1$ | $t_{SCK}^{(3)}/2$ | $t_{SCK}^{(3)}/2 + 1$ |      |
| $t_{su(MI)}$                   | Data input setup time    | Master mode  | 2                     | -                 | -                     | ns   |
| $t_{su(SI)}$                   |                          | Slave mode   | 1                     | -                 | -                     |      |
| $t_{h(MI)}$                    | Data input hold time     | Master mode  | 3                     | -                 | -                     |      |
| $t_{h(SI)}$                    |                          | Slave mode   | 1.5                   | -                 | -                     |      |
| $t_{a(SO)}$                    | Data output access time  | Slave mode   | 9.5                   | 13                | 23                    |      |
| $t_{dis(SO)}$                  | Data output disable time |  | 6                     | 8.5               | 12                    |      |

Table 95. SPI characteristics<sup>(1)</sup> (continued)

| Symbol      | Parameter              | Conditions  | Min | Typ<br>3.3 V | Max  | Unit |
|-------------|------------------------|---|-----|--------------|------|------|
| $t_{V(SO)}$ | Data output valid time | Slave mode (after enable edge)<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,<br>voltage range 1 | -   | 12.5         | 16.5 | ns   |
|             |                        | Slave mode (after enable edge)<br>$1.71\text{ V} \leq V_{DD} < 2.7\text{ V}$ ,<br>voltage range 1   | -   | 12.5         | 23.5 |      |
|             |                        | Slave mode (after enable edge)<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,<br>voltage range 2 | -   | 17           | 20.5 |      |
|             |                        | Slave mode (after enable edge)<br>$1.71\text{ V} \leq V_{DD} < 2.7\text{ V}$ ,<br>voltage range 2   | -   | 17           | 27.5 |      |
| $t_{V(MO)}$ |                        | Master mode   | -   | 1            | 2    |      |
| $t_{h(SO)}$ | Data output hold time  | Slave mode  | 8   | -            | -    |      |
| $t_{h(MO)}$ |                        | Master mode   | 0   | -            | -    |      |

1. Evaluated by characterization, not tested in production.
2. Maximum frequency in Slave transmitter mode is determined by the sum of  $t_{V(SO)}$  and  $t_{su(MI)}$ , which must fit into SCK low or high phase preceding the SCK sampling edge. This value can be achieved when SPI communicates with a master having  $t_{su(MI)} = 0$  while  $\text{Duty(SCK)} = 50\%$ .
3.  $t_{SCK} = t_{spi\_ker\_ck} \times \text{baudrate prescaler}$

Figure 35. SPI timing diagram - Slave mode and CPHA = 0

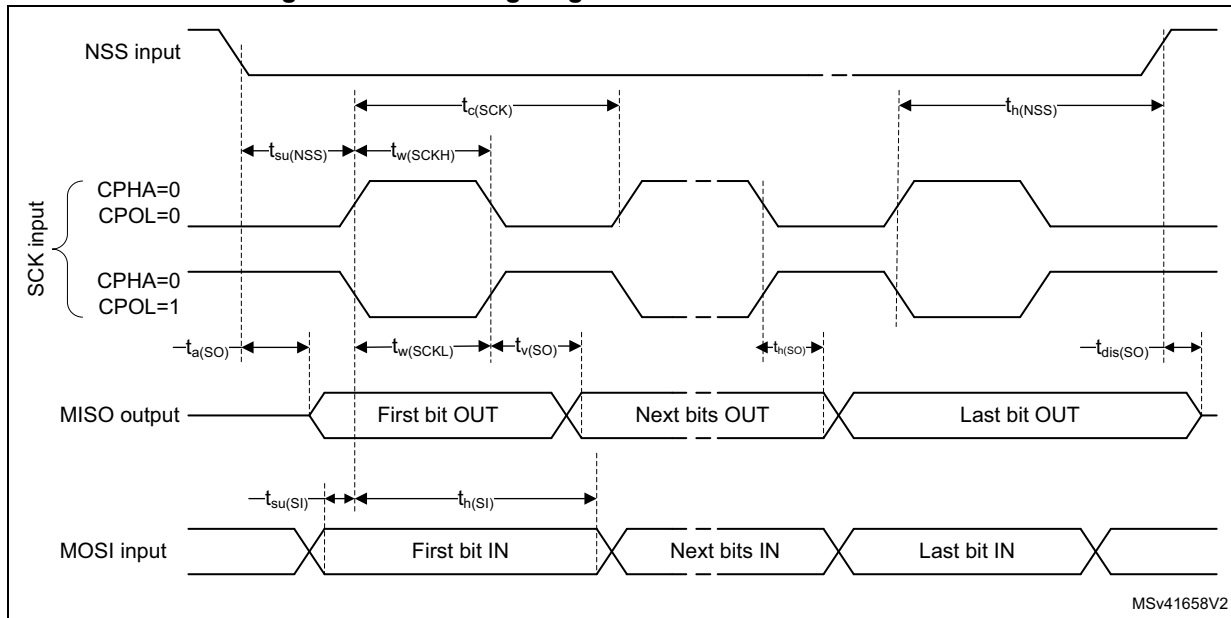


Figure 36. SPI timing diagram - Slave mode and CPHA = 1

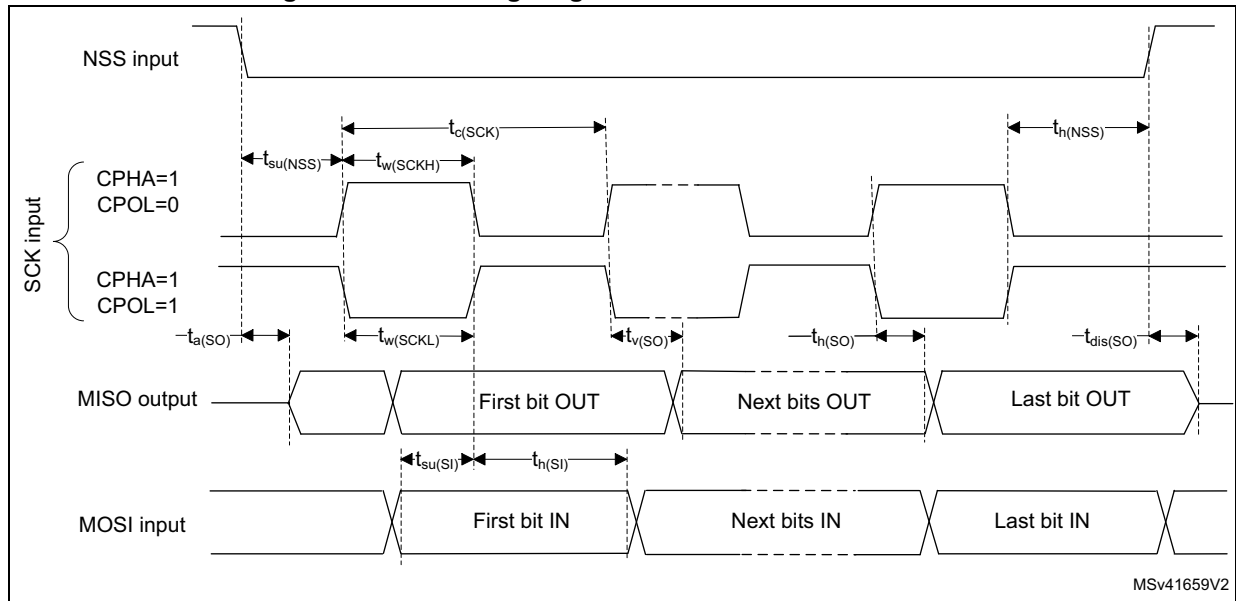
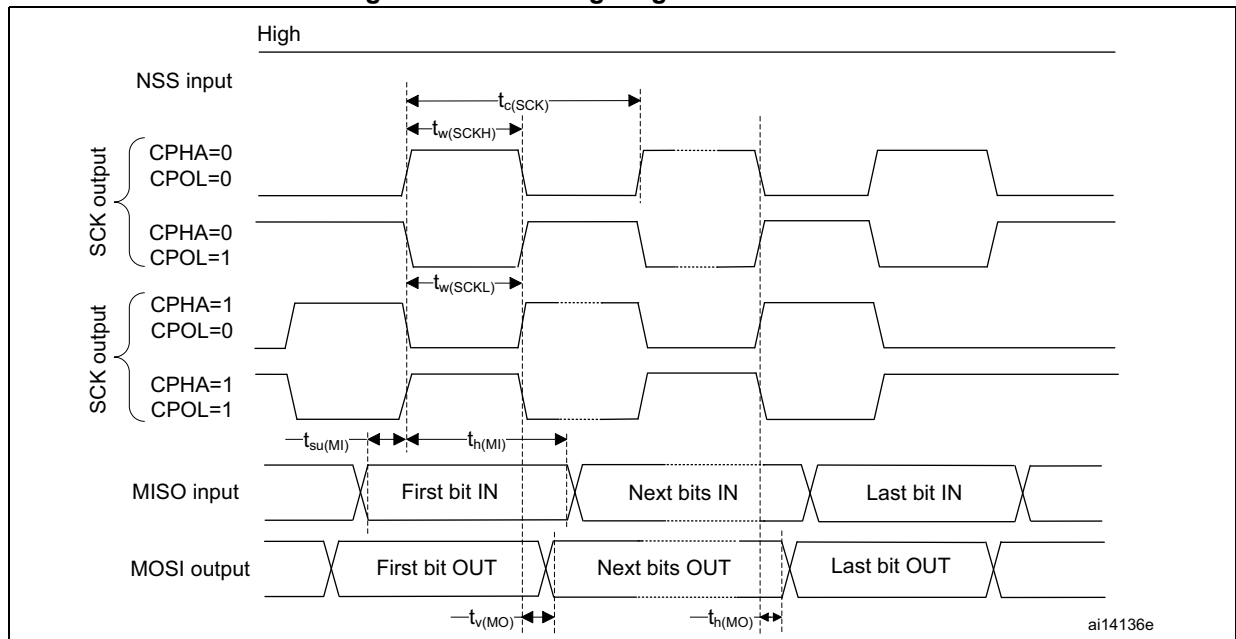


Figure 37. SPI timing diagram - Master mode



### 5.3.31 SAI characteristics

Unless otherwise specified, the parameters given in [Table 96](#) are derived from tests performed under the ambient temperature,  $f_{PCLKx}$  frequency and  $V_{DD}$  supply voltage conditions summarized in [Table 30](#), with the following configuration:

- Output speed is set to  $OSPEEDRy[1:0] = 10$
- Capacitive load  $C_L = 30$  pF
- I/O compensation cell activated
- Measurement points are done at CMOS levels:  $0.5 V_{DD}$

Refer to [Section 4.3](#) for more details on the input/output alternate function characteristics (SCK, SD, WS).

**Table 96. SAI characteristics<sup>(1)(2)</sup>**

| Symbol              | Parameter              | Conditions   | Min  | Max  | Unit |
|---------------------|------------------------|--|------|------|------|
| $f_{MCK}$           | Main clock output      | -  | -    | 50   | MHz  |
| $f_{CK}$            | Clock frequency        | Master transmitter, $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$   | -    | 23   |      |
|                     |                        | Master transmitter, $1.71\text{ V} \leq V_{DD} < 2.7\text{ V}$   | -    | 16.5 |      |
|                     |                        | Master receiver, $1.71\text{ V} \leq V_{DD} \leq 3.6\text{ V}$   | -    | 18   |      |
|                     |                        | Slave transmitter, $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$<br>Voltage range 1                       | -    | 23   |      |
|                     |                        | Slave transmitter, $1.71\text{ V} \leq V_{DD} < 2.7\text{ V}$<br>Voltage range 1                         | -    | 16.5 |      |
|                     |                        | Slave transmitter, $1.71\text{ V} \leq V_{DD} \leq 3.6\text{ V}$<br>Voltage range 2                      | -    | 12.5 |      |
|                     |                        | Slave receiver, $1.71\text{ V} \leq V_{DD} \leq 3.6\text{ V}$  | -    | 50   |      |
| $t_{V(FS)}$         | $F_S$ valid time       | Master mode, $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$  | -    | 19.5 | ns   |
|                     |                        | Master mode, $1.71\text{ V} \leq V_{DD} < 2.7\text{ V}$  | -    | 27.5 |      |
| $t_{su(FS)}$        | $F_S$ setup time       | Slave mode   | 1    | -    |      |
| $t_{h(FS)}$         | $F_S$ hold time        | Master mode  | 11.5 | -    |      |
|                     |                        | Slave mode   | 1    | -    |      |
| $t_{su(SD\_A\_MR)}$ | Data input setup time  | Master receiver  | 3.5  | -    |      |
| $t_{su(SD\_B\_SR)}$ |                        | Slave receiver   | 3    | -    |      |
| $t_{h(SD\_A\_MR)}$  | Data input hold time   | Master receiver  | 3    | -    |      |
| $t_{h(SD\_B\_SR)}$  |                        | Slave receiver   | 2    | -    |      |
| $t_{V(SD\_B\_ST)}$  | Data output valid time | Slave transmitter (after enable edge),<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ , voltage range 1 | -    | 21.5 |      |
|                     |                        | Slave transmitter (after enable edge),<br>$1.71\text{ V} \leq V_{DD} < 2.7\text{ V}$ , voltage range 1   | -    | 30   |      |
|                     |                        | Slave transmitter (after enable edge),<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ , voltage range 2 | -    | 30   |      |
|                     |                        | Slave transmitter (after enable edge),<br>$1.71\text{ V} \leq V_{DD} < 2.7\text{ V}$ , voltage range 2   | -    | 39   |      |
| $t_{h(SD\_B\_ST)}$  | Data output hold time  | Slave transmitter (after enable edge)<br>Voltage range 1   | 12   | -    |      |
|                     |                        | Slave transmitter (after enable edge)<br>Voltage range 2   | 21   | -    |      |

Table 96. SAI characteristics<sup>(1)(2)</sup> (continued)

| Symbol             | Parameter              | Conditions   | Min | Max  | Unit |
|--------------------|------------------------|--|-----|------|------|
| $t_{v(SD\_A\_MT)}$ | Data output valid time | Master transmitter (after enable edge)<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ | -   | 21.5 | ns   |
|                    |                        | Master transmitter (after enable edge)<br>$1.71\text{ V} \leq V_{DD} < 2.7\text{ V}$   | -   | 30   |      |
| $t_{h(SD\_A\_MT)}$ | Data output hold time  | Master transmitter (after enable edge)   | 10  | -    |      |

1. Evaluated by characterization - Not tested in production.

2. APB clock frequency must be at least two times the SAI clock frequency.

Figure 38. SAI master timing waveforms

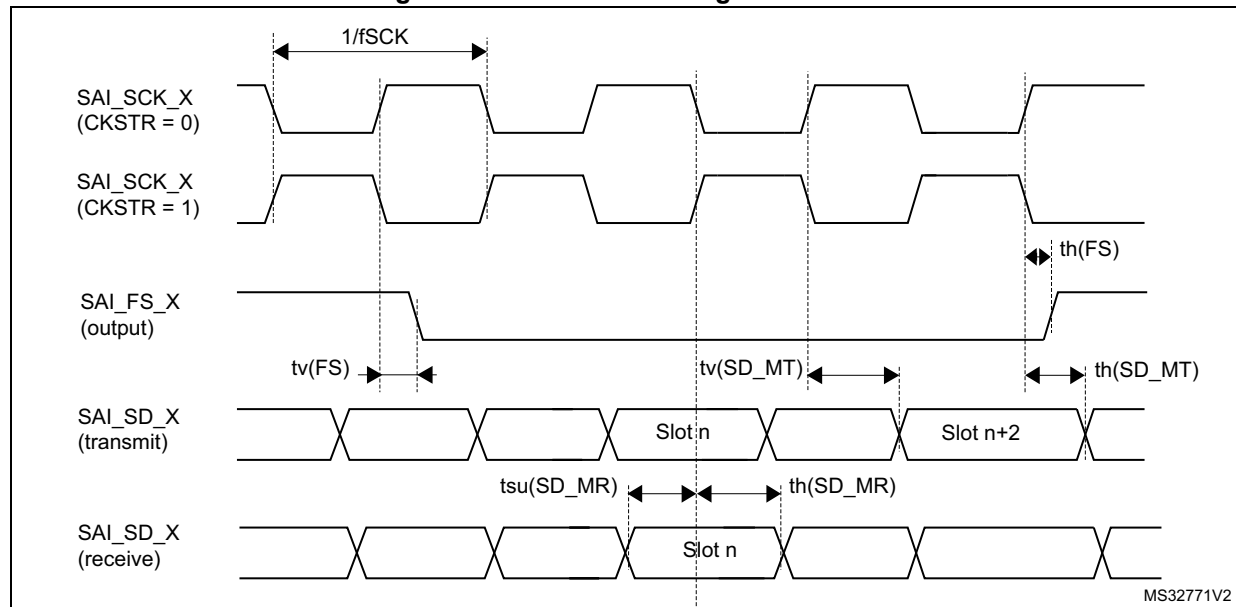
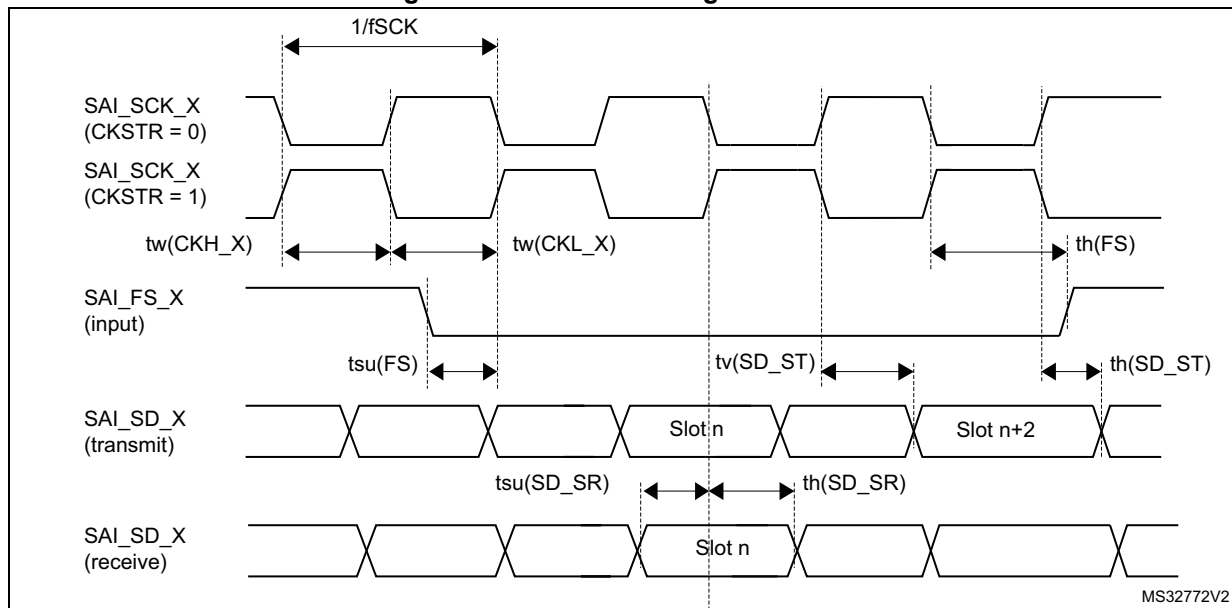




Figure 39. SAI slave timing waveforms



MS32772V2

### 5.3.32 OTG\_HS characteristics

The OTG\_HS controller complies with the following specifications:

- USB On-The-Go supplement, revision 2.0
- Universal Serial Bus revision 2.0 specification
- Battery charging specification, revision 1.2

The parameters given in the following tables are derived from tests performed under temperature up to 120 °C and  $V_{DD}$  supply voltage conditions summarized in [Table 30](#).

Table 97. OTG\_HS electrical characteristics<sup>(1)</sup>

| Symbol      | Parameter  | Condition           | Min                 | Typ  | Max                 | Unit     |
|-------------|--|---------------------|---------------------|------|---------------------|----------|
| $V_{DDUSB}$ | USB transceiver operating voltage  | -                   | 3.0                 | -    | 3.6                 | V        |
| $f_{HCLK}$  | HSE32 oscillator is used to guarantee proper operation of the OTG_HS interface | -                   | -                   | 32   | -                   | MHz      |
| $R_{PUI}$   | Embedded USB_DP pull-up value during idle                                      | -                   | 900                 | 1250 | 1575                | $\Omega$ |
| $R_{PUR}$   | Embedded USB_DP pull-up value during reception                                 | -                   | 1425 <sup>(2)</sup> | 2250 | 3090 <sup>(2)</sup> |          |
| $R_{PD}$    | Embedded USB_DP and USB_DM pull-down value                                     | -                   | 14250               | -    | 24800               |          |
| $Z_{DRV}$   | Output driver impedance <sup>(3)</sup>   | Driving high or low | 40.5 <sup>(2)</sup> | 45   | 49.5 <sup>(2)</sup> |          |
| $t_{ir}$    | Rise time  | $C_L < 5$ pF        | 0.5 <sup>(2)</sup>  | -    | -                   | ns       |
| $t_{if}$    | Fall time  | $C_L < 5$ pF        | 0.5 <sup>(2)</sup>  | -    | -                   |          |
| $t_{irfm}$  | Rise/fall time matching  | -                   | 80 <sup>(2)</sup>   | -    | 125 <sup>(2)</sup>  | %        |

1. Evaluated by characterization. Not tested in production, unless otherwise specified.

2. Specified by design, not tested in production.

3. No external termination series resistors are required on USB\_DP (D+) and USB\_DM (D-). The matching impedance is already included in the embedded driver.

Table 98. OTG\_HS DC electrical characteristics<sup>(1)</sup>

| Symbol               | Parameter   | Condition | Min                | Typ | Max  | Unit |
|----------------------|---|-----------|--------------------|-----|------|------|
| V <sub>hssq</sub>    | High-speed squelch detection threshold              | -         | 100 <sup>(2)</sup> | -   | 150  | mV   |
| V <sub>hdsdc</sub>   | High-speed disconnect detection threshold           | -         | 525                | -   | 625  |      |
| V <sub>hdsif</sub>   | High-speed differential detection threshold         | -         | 100                | -   | -    |      |
| V <sub>hscm</sub>    | High-speed data signaling common mode voltage range | -         | -50                | -   | 500  |      |
| V <sub>hsoi</sub>    | High-speed idle level                               | -         | -10                | -   | 10   |      |
| V <sub>hsoh</sub>    | High-speed data signaling high                      | -         | 360                | -   | 440  |      |
| V <sub>hsol</sub>    | High-speed data signaling low                       | -         | -10                | -   | 10   |      |
| V <sub>hchirpj</sub> | Chirp J level                                       | -         | 700                | -   | 1100 |      |
| V <sub>hchirpk</sub> | Chirp K level                                       | -         | -900               | -   | -500 |      |

1. Evaluated by characterization. Not tested in production.

2. 50 mV test waivers from usb.org have been applied.

Table 99. OTG\_HS PHY BCD electrical characteristics<sup>(1)</sup>

| Symbol                  | Parameter                                       | Min                 | Typ | Max                | Unit |
|-------------------------|---|---------------------|-----|--------------------|------|
| I <sub>DD(USBBCD)</sub> | Primary detection mode consumption              | -                   | 4.9 | 5.7                | mA   |
|                         | Secondary detection mode consumption            | -                   | 4.8 |                    |      |
| R <sub>DAT_LKG</sub>    | Data line leakage resistance                    | 300 <sup>(2)</sup>  | -   | -                  | kΩ   |
| V <sub>DAT_LKG</sub>    | Data line leakage voltage                       | 0.0                 | -   | 3.6 <sup>(2)</sup> | V    |
| R <sub>DCP_DAT</sub>    | Dedicated charging port resistance across D+/D- | -                   | -   | 200 <sup>(2)</sup> | Ω    |
| V <sub>LGC_HI</sub>     | Logic high                                      | 2.0                 | -   | 3.6                | V    |
| V <sub>LGC_LOW</sub>    | Logic low                                       | -                   | -   | 0.8                |      |
| V <sub>LGC</sub>        | Logic threshold                                 | 0.8                 | -   | 2.0                |      |
| V <sub>DAT_REF</sub>    | Data detect voltage                             | 0.25 <sup>(2)</sup> | -   | 0.4 <sup>(2)</sup> |      |
| V <sub>DP_SRC</sub>     | D+ source voltage                               | 0.5                 | -   | 0.7                |      |
| V <sub>DM_SRC</sub>     | D- source voltage                               | 0.5                 | -   | 0.7                |      |
| I <sub>DM_SINK</sub>    | D- sink current                                 | 25                  | -   | 175                | μA   |
| I <sub>DP_SINK</sub>    | D+ sink current                                 | 25                  | -   | 175                |      |
| I <sub>DP_SRC</sub>     | Data contact detect current source              | 7.0                 | -   | 13                 |      |

1. Evaluated by characterization. Not tested in production, unless otherwise specified.

2. Specified by design. Not tested in production.

### 5.3.33 JTAG/SWD interface characteristics

Unless otherwise specified, the parameters given in [Table 100](#) and [Table 101](#) are with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load C = 30 pF
- Measurement points are done at 0.5 x V<sub>DD</sub>
- I/O compensation cell disabled

**Table 100. JTAG characteristics<sup>(1)</sup>**

| Symbol                 | Parameter             | Conditions                     | Min | Typ<br>3.3 V | Max  | Unit |
|------------------------|-----------------------|--------------------------------|-----|--------------|------|------|
| f <sub>TCK</sub>       | TCK clock frequency   | 2.7 ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | -            | 21.5 | MHz  |
|                        |                       | 1.71 ≤ V <sub>DD</sub> < 2.7 V | -   | -            | 16.5 |      |
| t <sub>isu</sub> (TMS) | TMS input setup time  | -                              | 1.5 | -            | -    | ns   |
| t <sub>ih</sub> (TMS)  | TMS input hold time   | -                              | 6   | -            | -    |      |
| t <sub>isu</sub> (TDI) | TDI input setup time  | -                              | 1.5 | -            | -    |      |
| t <sub>ih</sub> (TDI)  | TDI input hold time   | -                              | 4   | -            | -    |      |
| t <sub>ov</sub> (TDO)  | TDO output valid time | 2.7 ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 17           | 23   |      |
|                        |                       | 1.71 ≤ V <sub>DD</sub> < 2.7 V | -   | 17           | 29.5 |      |
| t <sub>oh</sub> (TDO)  | TDO output hold time  | -                              | 13  | -            | -    |      |

1. Evaluated by characterization, not tested in production.

**Table 101. SWD characteristics<sup>(1)</sup>**

| Symbol                   | Parameter               | Conditions                     | Min | Typ<br>3.3 V | Max  | Unit |
|--------------------------|-------------------------|--------------------------------|-----|--------------|------|------|
| f <sub>SWCLK</sub>       | SWCLK clock frequency   | 2.7 ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | -            | 62.5 | MHz  |
|                          |                         | 1.71 ≤ V <sub>DD</sub> < 2.7 V | -   | -            | 34   |      |
| t <sub>isu</sub> (SWDIO) | SWDIO input setup time  | -                              | 1.5 | -            | -    | ns   |
| t <sub>ih</sub> (SWDIO)  | SWDIO input hold time   | -                              | 3.5 | -            | -    |      |
| t <sub>ov</sub> (SWDIO)  | SWDIO output valid time | 2.7 ≤ V <sub>DD</sub> ≤ 3.6 V  | -   | 12           | 16   |      |
|                          |                         | 1.71 ≤ V <sub>DD</sub> < 2.7 V | -   | 12           | 29   |      |
| t <sub>oh</sub> (SWDIO)  | SWDIO output hold time  | -                              | 8.5 | -            | -    |      |

1. Evaluated by characterization, not tested in production.

Figure 40. JTAG timing diagram

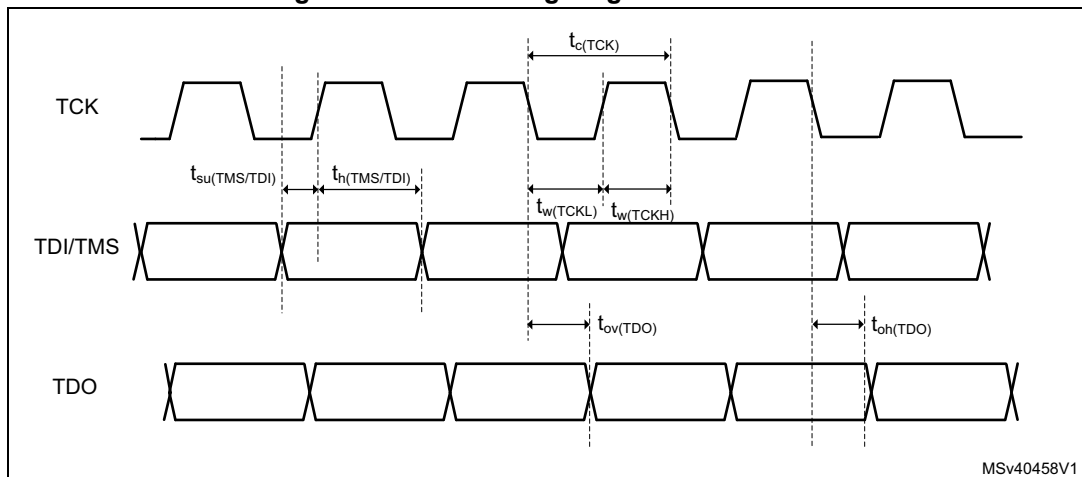
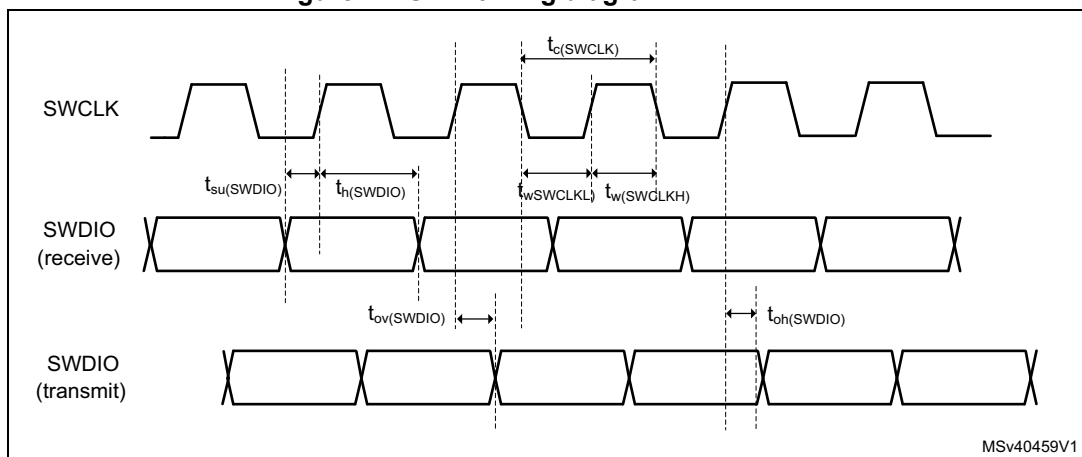


Figure 41. SWD timing diagram



## 6 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 6.1 Device marking

Refer to technical note “Reference device marking schematics for STM32 microcontrollers and microprocessors” (TN1433) available on [www.st.com](http://www.st.com), for the location of pin 1 / ball A1 as well as the location and orientation of the marking areas versus pin 1 / ball A1.

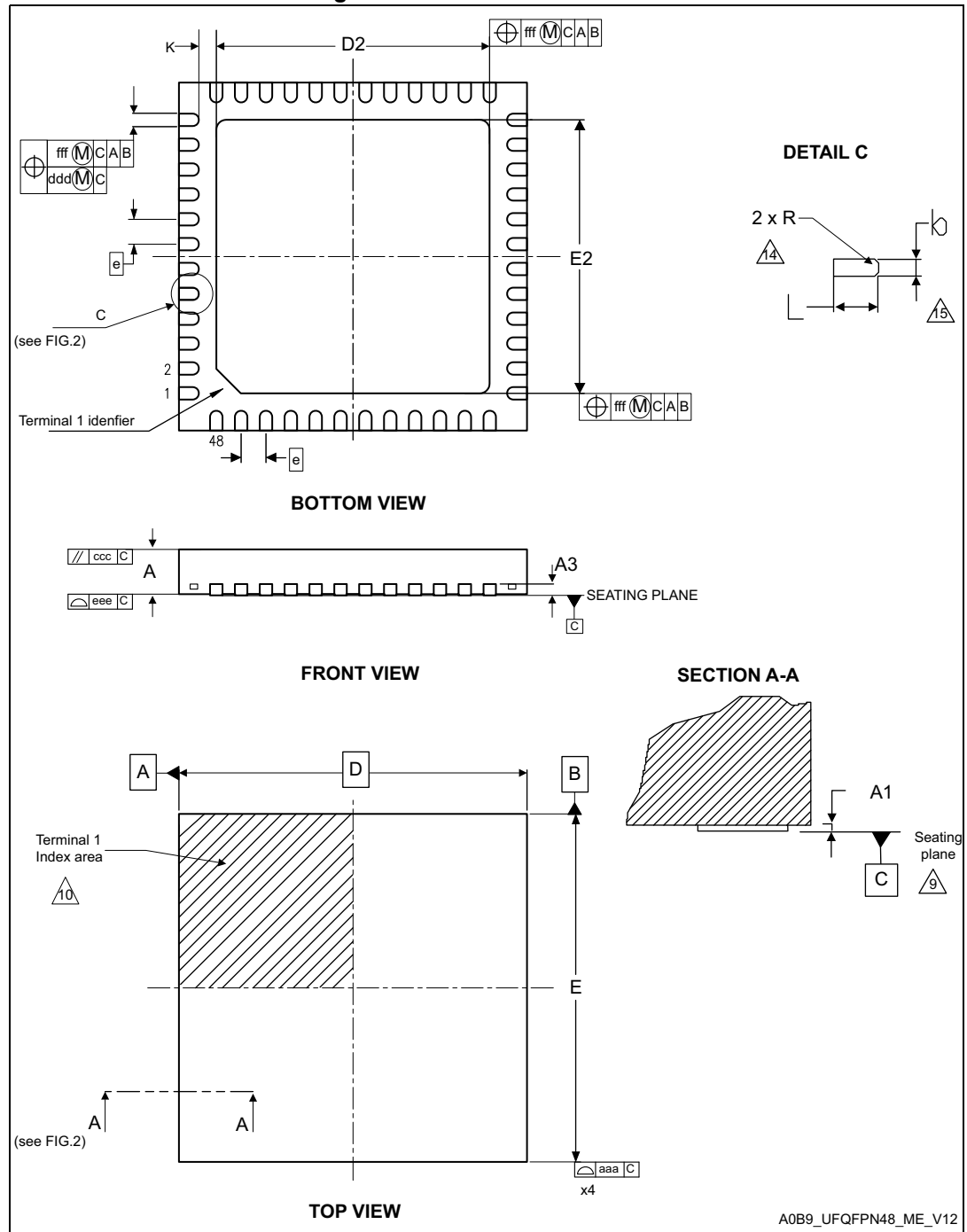
Parts marked as “ES”, “E” or accompanied by an engineering sample notification letter, are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST’s Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

A WLCSP simplified marking example (if any) is provided in the corresponding package information subsection.

## 6.2 UFQFPN48 package information (A0B9)

This UFQFPN is a 48-lead, 7 x 7 mm, 0.5 mm pitch, ultra thin fine pitch quad flat package.

Figure 42. UFQFPN48 – Outline



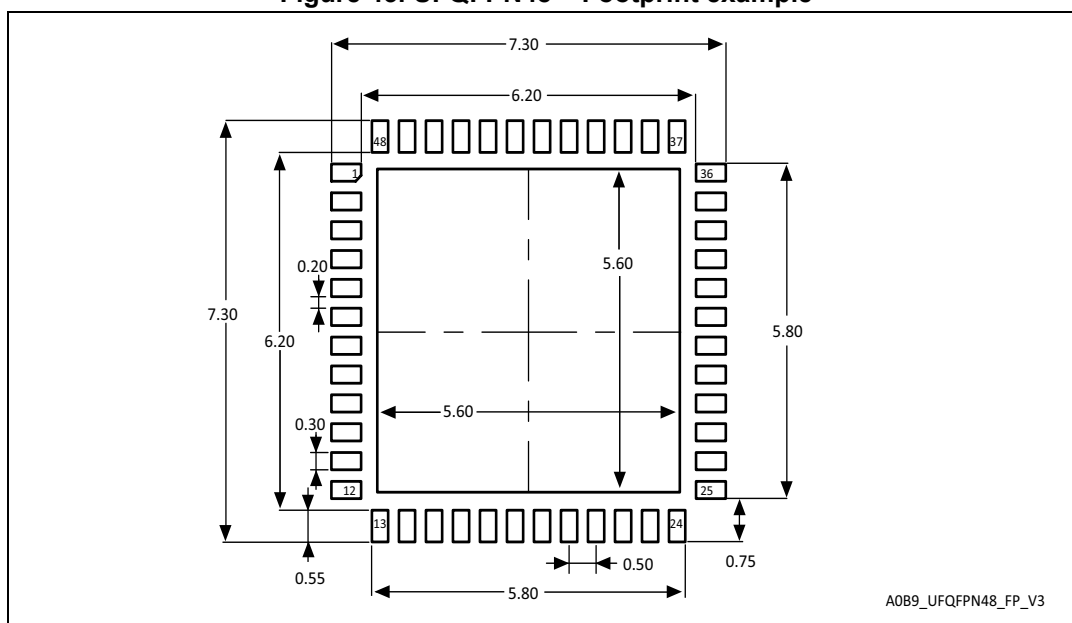
1. Drawing is not to scale.
2. All leads/pads should also be soldered to the PCB to improve the lead/pad solder joint life.
3. There is an exposed die pad on the underside of the UFQFPN48 package. It is recommended to connect and solder this back-side pad to PCB ground.

Table 102. UFQFPN48 – Mechanical data

| Symbol            | millimeters |      |      | inches <sup>(1)</sup> |        |        |
|-------------------|-------------|------|------|-----------------------|--------|--------|
|                   | Min         | Typ  | Max  | Min                   | Typ    | Max    |
| A                 | 0.50        | 0.55 | 0.60 | 0.0197                | 0.0217 | 0.0236 |
| A1                | 0.00        | -    | 0.05 | 0.0000                | -      | 0.0020 |
| b                 | 0.18        | 0.25 | 0.30 | 0.0071                | 0.0098 | 0.0118 |
| D <sup>(2)</sup>  | 7.00 BSC    |      |      | 0.2756 BSC            |        |        |
| D2 <sup>(3)</sup> | 5.50        | 5.60 | 5.70 | 0.2165                | 0.2205 | 0.2244 |
| E <sup>(2)</sup>  | 7.00 BSC    |      |      | 0.2756 BSC            |        |        |
| E2 <sup>(3)</sup> | 5.50        | 5.60 | 5.70 | 0.2165                | 0.2205 | 0.2244 |
| e                 | 0.50 BSC    |      |      | 0.0197 BSC            |        |        |
| N                 | 48          |      |      |                       |        |        |
| L                 | 0.30        | -    | 0.50 | 0.0118                | -      | 0.0197 |
| R                 | 0.10        | -    | -    | 0.0039                | -      | -      |
| aaa               | 0.15        |      |      | 0.0059                |        |        |
| bbb               | 0.10        |      |      | 0.0039                |        |        |
| ccc               | 0.10        |      |      | 0.0039                |        |        |
| ddd               | 0.05        |      |      | 0.0020                |        |        |
| eee               | 0.08        |      |      | 0.0031                |        |        |
| fff               | 0.10        |      |      | 0.0039                |        |        |

1. Values in inches are converted from mm and rounded to four decimal digits.
2. Dimensions D and E do not include mold protrusion, not exceed 0.15 mm.
3. Dimensions D2 and E2 are not in accordance with JEDEC.

Figure 43. UFQFPN48 – Footprint example



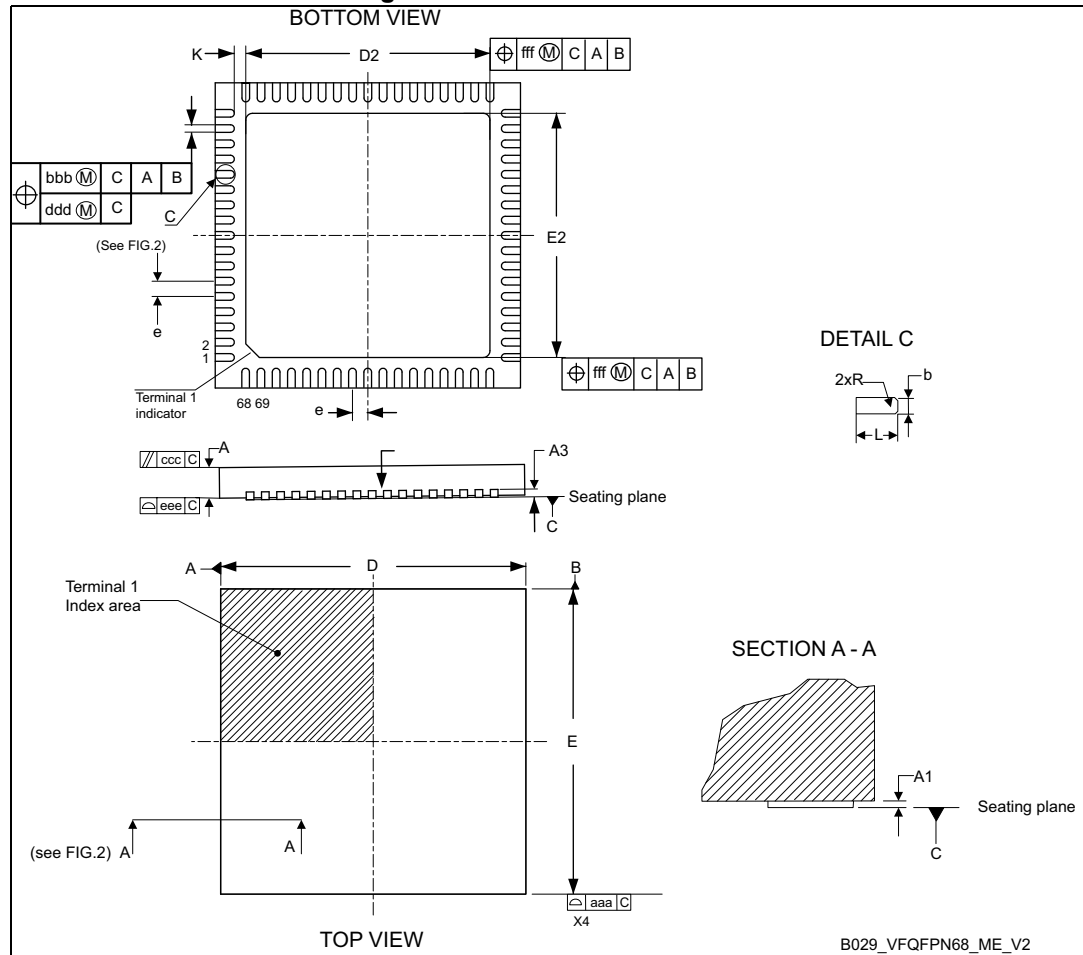
1. Dimensions are expressed in millimeters.



### 6.3 VFQFPN68 package information (B029)

This VFQFPN is a 68 pins, 8 x 8 mm, 0.4 mm pitch, very thin fine pitch quad flat package.

**Figure 44. VFQFPN68 - Outline**



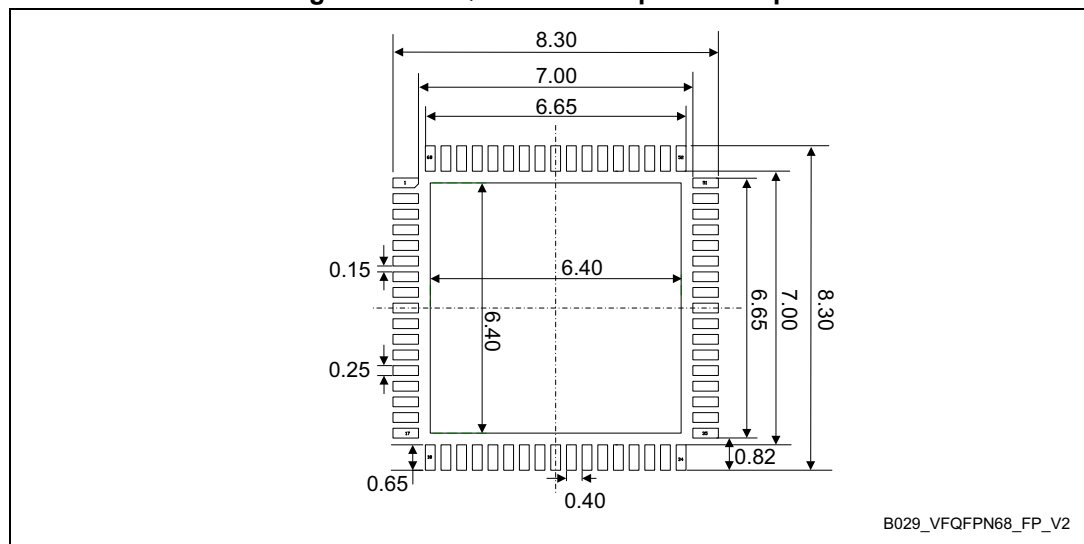
1. VFQFPN stands for Thermally Enhanced Very thin Fine pitch Quad Flat Packages No lead. Sawed version. Very thin profile:  $0.80 < A \leq 1.00\text{mm}$ .
2. The pin #1 identifier must be existed on the top surface of the package by using indentation mark or other feature of package body. Exact shape and size of this feature is optional.

Table 103. VFQFPN68 - Mechanical data

| Symbol | millimeters |      |      | inches <sup>(1)</sup> |        |        |
|--------|-------------|------|------|-----------------------|--------|--------|
|        | Min         | Typ  | Max  | Min                   | Typ    | Max    |
| A      | 0.80        | 0.90 | 1.00 | 0.0315                | 0.0354 | 0.0394 |
| A1     | 0           | -    | 0.05 | 0                     | -      | 0.0020 |
| b      | 0.15        | 0.20 | 0.25 | 0.0059                | 0.0079 | 0.0098 |
| D      | 8.00 BSC    |      |      | 0.3150 BSC            |        |        |
| D2     | 6.30        | 6.40 | 6.50 | 0.2480                | 0.2520 | 0.2559 |
| E      | 8.00 BSC    |      |      | 0.3150 BSC            |        |        |
| E2     | 6.30        | 6.40 | 6.50 | 0.2480                | 0.2520 | 0.2559 |
| e      | 0.40 BSC    |      |      | 0.0157 BSC            |        |        |
| L      | 0.45        | -    | 0.65 | 0.0177                | -      | 0.0256 |
| R      | 0.07        | -    | -    | 0.0028                | -      | -      |
| aaa    | 0.10        |      |      | 0.0039                |        |        |
| bbb    | 0.07        |      |      | 0.0028                |        |        |
| ccc    | 0.10        |      |      | 0.0039                |        |        |
| ddd    | 0.05        |      |      | 0.0020                |        |        |
| eee    | 0.08        |      |      | 0.0031                |        |        |
| fff    | 0.10        |      |      | 0.0039                |        |        |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 45. VFQFPN68 - Footprint example



1. Dimensions are expressed in millimeters.

## 6.4 Thin WLCSP88 package information (B0NJ)

This WLCSP is a 88-ball, 3.78 x 3.46 mm, 0.35 mm pitch, wafer level chip scale package.

**Figure 46. Thin WLCSP88 - Outline**

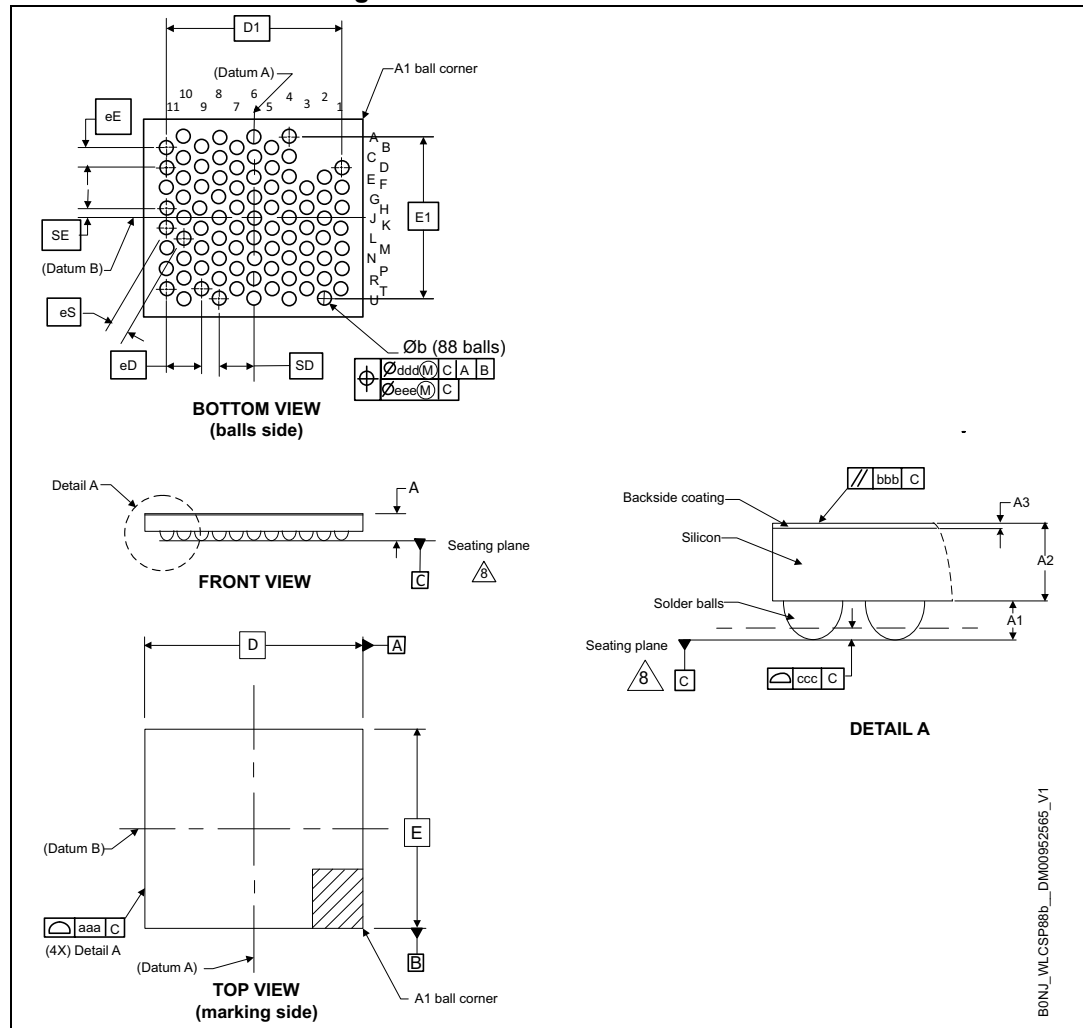


Table 104. Thin WLCSP88 - Mechanical data

| Symbol               | millimeters |       |      | inches <sup>(1)</sup> |        |        |
|----------------------|-------------|-------|------|-----------------------|--------|--------|
|                      | Min         | Typ   | Max  | Min                   | Typ    | Max    |
| A <sup>(2)</sup>     | -           | -     | 0.50 | -                     | -      | 0.0197 |
| A1 <sup>(3)</sup>    | 0.12        | -     | -    | 0.0047                | -      | -      |
| A2                   | -           | 0.30  | -    | -                     | 0.0118 | -      |
| A3                   | -           | 0.025 | -    | -                     | 0.0010 | -      |
| b <sup>(4)</sup>     | 0.20        | 0.23  | 0.25 | 0.0079                | 0.0091 | 0.0098 |
| D <sup>(5)</sup>     | 3.78 BSC    |       |      | 0.1488 BSC            |        |        |
| D1 <sup>(5)</sup>    | 3.03 BSC    |       |      | 0.1193 BSC            |        |        |
| E <sup>(5)</sup>     | 3.46 BSC    |       |      | 0.1362 BSC            |        |        |
| E1 <sup>(5)</sup>    | 2.80 BSC    |       |      | 0.1102 BSC            |        |        |
| eD <sup>(5)(6)</sup> | 0.61 BSC    |       |      | 0.0240 BSC            |        |        |
| eE <sup>(5)(6)</sup> | 0.35 BSC    |       |      | 0.0138 BSC            |        |        |
| eS <sup>(5)(6)</sup> | 0.35 BSC    |       |      | 0.0138 BSC            |        |        |
| N <sup>(7)</sup>     | 88          |       |      |                       |        |        |
| SD <sup>(5)(8)</sup> | 0.61 BSC    |       |      | 0.0240 BSC            |        |        |
| SE <sup>(5)(8)</sup> | 0.175 BSC   |       |      | 0.0069 BSC            |        |        |
| aaa <sup>(9)</sup>   | 0.02        |       |      | 0.0008                |        |        |
| bbb <sup>(9)</sup>   | 0.06        |       |      | 0.0024                |        |        |
| ccc <sup>(9)</sup>   | 0.03        |       |      | 0.0012                |        |        |
| ddd <sup>(9)</sup>   | 0.015       |       |      | 0.0006                |        |        |
| eee <sup>(9)</sup>   | 0.05        |       |      | 0.0020                |        |        |

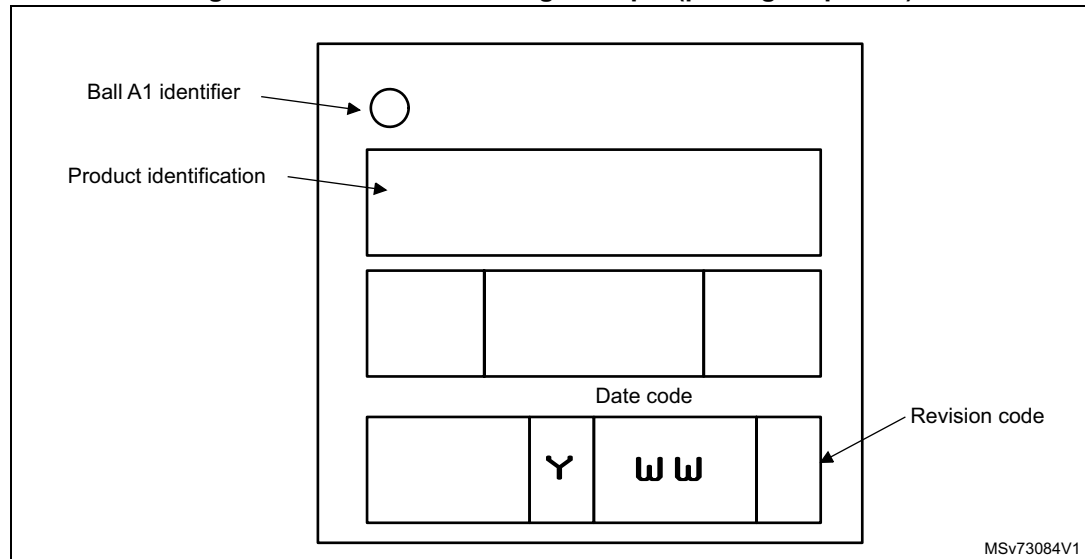
1. Values in inches are converted from mm and rounded to 4 decimal digits.
2. The profile height A is the distance from the seating plane to the highest point on the package. It is measured perpendicular to the seating plane.
3. A1 is defined as the distance from the seating plane to the lowest point on the package body.
4. Dimension b is measured at the maximum diameter of the terminal (ball) in a plane parallel to Datum C.
5. BSC stands for BASIC dimensions. It corresponds to the nominal value and has no tolerance. For tolerances, refer to form and position table. On the drawing, these dimensions are framed. For the tolerances, refer to form and position values.
6. e represents the solder balls grid pitch(es).
7. N represents the total number of balls.
8. Basic dimensions SD & SE are defining the ball matrix position with respect to datums A and B.
9. Tolerance of form and position drawing

**Example of device marking for thin WLCSP88**

*Figure 47* gives an example of the locations and orientation of the marking areas versus ball A1, and allows engineering samples to be identified.

With the device text markings oriented as shown below, ball A1 is always located at top left.

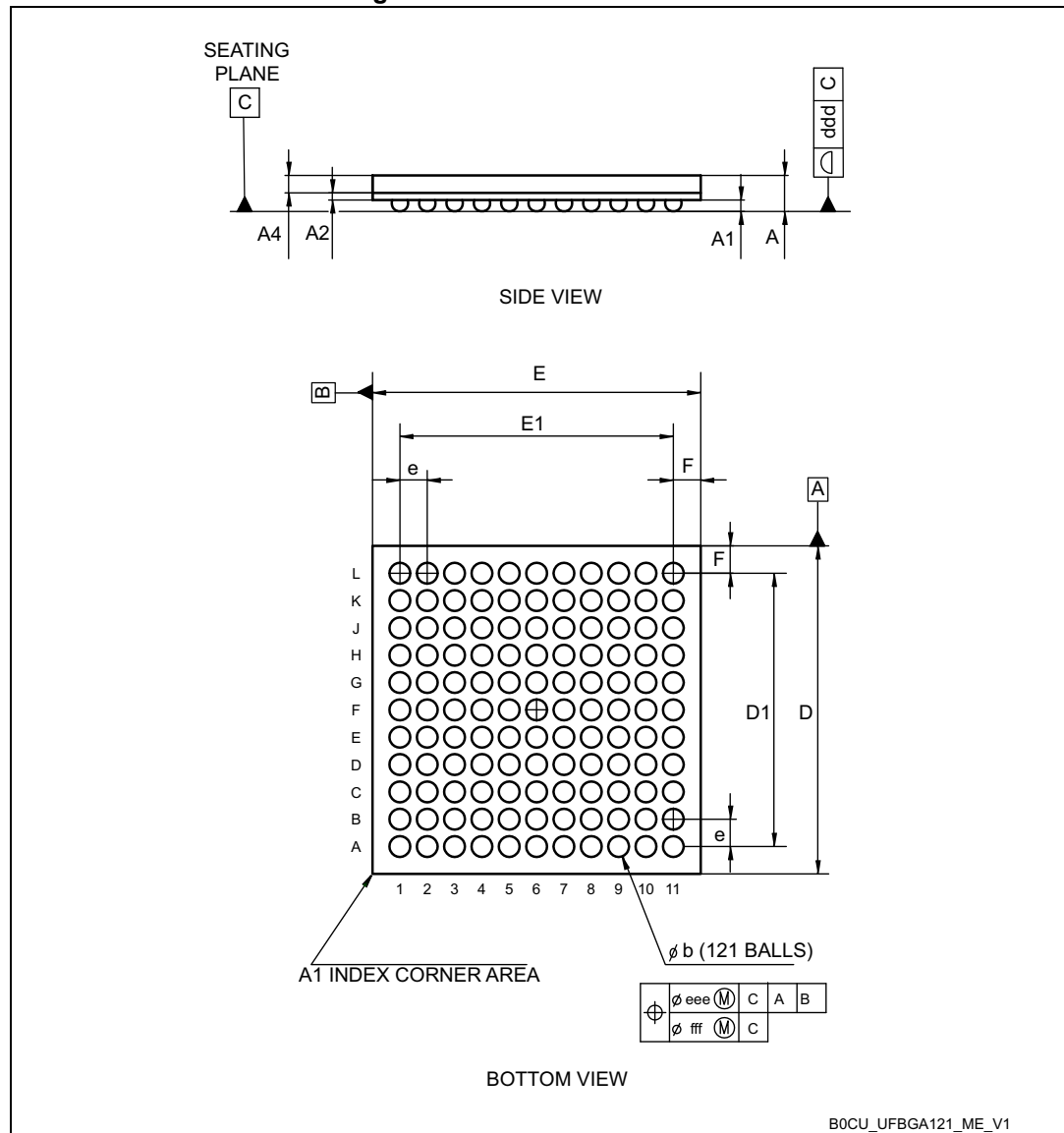
**Figure 47. WLCSP88 marking example (package top view)**



## 6.5 UFBGA121 package information (B0CU)

This UFBGA is a 121-ball, 6 x 6 mm, 0.5 mm pitch, fine pitch, square ball grid array package.

**Figure 48. UFBGA121 - Outline**



1. Drawing is not to scale.
2. - The terminal A1 corner must be identified on the top surface by using a corner chamfer, ink or metalized markings, or other feature of package body or integral heat slug.  
- A distinguishing feature is allowable on the bottom surface of the package to identify the terminal A1 corner. Exact shape of each corner is optional.

Table 105. UFBGA121 - Mechanical data

| Symbol             | millimeters |      |      | inches <sup>(1)</sup> |        |        |
|--------------------|-------------|------|------|-----------------------|--------|--------|
|                    | Min         | Typ  | Max  | Min                   | Typ    | Max    |
| A <sup>(2)</sup>   | -           | -    | 0.60 | -                     | -      | 0.0236 |
| A1                 | -           | -    | 0.11 | -                     | -      | 0.0043 |
| A2                 | -           | 0.13 | -    | -                     | 0.0051 | -      |
| A4                 | -           | 0.32 | -    | -                     | 0.0126 | -      |
| b <sup>(3)</sup>   | 0.24        | 0.29 | 0.34 | 0.0094                | 0.0114 | 0.0134 |
| D                  | 5.85        | 6.00 | 6.15 | 0.2303                | 0.2362 | 0.2421 |
| D1                 | -           | 5.00 | -    | -                     | 0.1969 | -      |
| E                  | 5.85        | 6.00 | 6.15 | 0.2303                | 0.2362 | 0.2421 |
| E1                 | -           | 5.00 | -    | -                     | 0.1969 | -      |
| e                  | -           | 0.50 | -    | -                     | 0.0197 | -      |
| F                  | -           | 0.50 | -    | -                     | 0.0197 | -      |
| ddd                | -           | -    | 0.08 | -                     | -      | 0.0031 |
| eee <sup>(4)</sup> | -           | -    | 0.15 | -                     | -      | 0.0059 |
| fff <sup>(5)</sup> | -           | -    | 0.05 | -                     | -      | 0.0020 |

- Values in inches are converted from mm and rounded to four decimal digits.
- UFBGA stands for Ultra-Thin Profile Fine Pitch Ball Grid Array.
  - Ultra Thin profile:  $0.50 < A \leq 0.65$  mm / Fine pitch:  $e < 1.00$  mm pitch.
  - The total profile height (Dim A) is measured from the seating plane to the top of the component
  - The maximum total package height is calculated by the following methodology:  
 $A \text{ Max} = A1 \text{ Typ} + A2 \text{ Typ} + A4 \text{ Typ} + \sqrt{(A1^2 + A2^2 + A4^2 \text{ tolerance values})}$
- The typical balls diameter before mounting is 0.20 mm
- The tolerance of position that controls the location of the pattern of balls with respect to datum A and B. For each ball there is a cylindrical tolerance zone eee perpendicular to datum C and located on true position with respect to datum A and B as defined by e. The axis perpendicular to datum C of each ball must lie within this tolerance zone.
- The tolerance of position that controls the location of the balls within the matrix with respect to each other. For each ball there is a cylindrical tolerance zone fff perpendicular to datum C and located on true position as defined by e. The axis perpendicular to datum C of each ball must lie within this tolerance zone. Each tolerance zone fff in the array is contained entirely in the respective zone eee above. The axis of each ball must lie simultaneously in both tolerance zones.

Figure 49. UFBGA121 - Footprint example

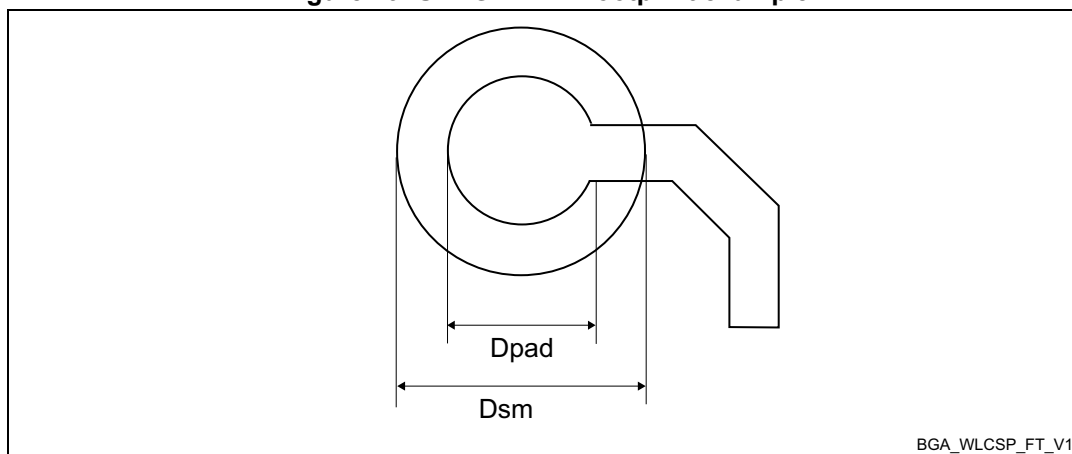


Table 106. UFBGA121 - Example of PCB design rules

| Dimension         | Values   |
|-------------------|--|
| Pitch             | 0.5 mm   |
| Dpad              | 0.225 mm   |
| Dsm               | 0.290 mm typ. (depends on soldermask registration tolerance) |
| Stencil opening   | 0.250 mm   |
| Stencil thickness | 0.100 mm   |

## 6.6 Thermal characteristics

The maximum chip junction temperature ( $T_{Jmax}$ ) must never exceed the specified values.

$T_J$  max (in Celsius degrees) can be calculated using the equation:

$$T_J \text{ max} = T_A \text{ max} + (P_D \text{ max} \times \Theta_{JA})$$

where:

- $T_A$  max is the maximum ambient temperature in °C
- $\Theta_{JA}$  is the package junction-to-ambient thermal resistance, in °C/W
- $P_D$  max is the sum of  $P_{INT}$  max and  $P_{I/O}$  max ( $P_D$  max =  $P_{INT}$  max +  $P_{I/O}$  max)
- $P_{INT}$  max is the product of  $I_{DD}$  and  $V_{DD}$ , expressed in Watt (this is the maximum chip internal power)

$P_{I/O}$  max represents the maximum power dissipation on output pins:

- $P_{I/O} \text{ max} = \sum (V_{OL} \times I_{OL}) + \sum ((V_{DD} - V_{OH}) \times I_{OH})$

taking into account the actual  $V_{OL}$  /  $I_{OL}$  and  $V_{OH}$  /  $I_{OH}$  of the I/Os at low and high level in the application.



Table 107. Package thermal characteristics

| Symbol        | Parameter                           | Package                             | Value | Unit |
|---------------|-------------------------------------|-------------------------------------|-------|------|
| $\Theta_{JA}$ | Thermal resistance junction-ambient | UFQFPN48 - 7 mm x 7 mm              | 28.2  | °C/W |
|               |                                     | VFQFPN68 - 8 mm x 8 mm              | 24.9  |      |
|               |                                     | Thin WLCSP88 -<br>3.78 mm x 3.46 mm | 46.3  |      |
|               |                                     | UFBGA121 - 6 mm x 6 mm              | 40.8  |      |
| $\Theta_{JB}$ | Thermal resistance junction-board   | UFQFPN48 - 7 mm x 7 mm              | 12.4  |      |
|               |                                     | VFQFPN68 - 8 mm x 8 mm              | 10.2  |      |
|               |                                     | Thin WLCSP88 -<br>3.78 mm x 3.46 mm | 23.5  |      |
|               |                                     | UFBGA121 - 6 mm x 6 mm              | 25.0  |      |
| $\Theta_{JC}$ | Thermal resistance junction-case    | UFQFPN48 - 7 mm x 7 mm              | 8.8   |      |
|               |                                     | VFQFPN68 - 8 mm x 8 mm              | 12.3  |      |
|               |                                     | Thin WLCSP88 -<br>3.78 mm x 3.46 mm | 2.5   |      |
|               |                                     | UFBGA121 - 6 mm x 6 mm              | 10.6  |      |

## 7 Ordering information

Example:

STM32 WB A65 C I U 6 TR

### Device family

STM32 = Arm® based 32-bit microcontroller

### Product type

WB = Wireless Bluetooth®

### Device subfamily

A62 = Die A6, reduced set of features

A63 = Die A6, crossover SMPS

A64 = Die A6, full set of features LDO

A65 = Die A6, full set of features SMPS

### Pin count

C = 48 pins

R = 68 pins

M = 88 pins

P = 121 pins

### Flash memory size

I = 2 Mbytes

G = 1 Mbyte

### Package

U = UFQFPN

V = VFQFPN

F = Thin WLCSP

I = UFBGA

### Temperature range

6 = Industrial temperature range, -40 to 85 °C (105 °C junction)

7 = Industrial temperature range, -40 to 105 °C (125 °C junction)

### Packing

TR = tape and reel

xxx = programmed parts

For a list of available options, or for further information on any aspect of this device, contact your nearest ST sales office.

## 8 Important security notice

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## 9 Revision history

**Table 108. Document revision history**

| Date        | Revision | Changes  |
|-------------|----------|--|
| 13-Dec-2024 | 1        | Initial release.   |
| 26-Feb-2025 | 2        | <p>Added <i>Bluetooth® LE</i> features.</p> <p>Updated:</p> <ul style="list-style-type: none"> <li>– All occurrences of Bluetooth Low Energy to Bluetooth® LE</li> <li>– <i>Table 50: Current consumption in Stop 0 mode</i></li> <li>– <i>Table 51: Current consumption in Stop 1 mode</i></li> <li>– <i>Table 52: Current consumption in Stop 2 mode</i></li> <li>– <i>Table 70: EMS characteristics</i></li> <li>– <i>Table 71: EMI characteristics for fHSE = 32 MHz and fHCLK = 100 MHz</i></li> <li>– <i>Table 72: ESD absolute maximum ratings</i></li> </ul>   |
| 03-Jul-2025 | 3        | <p>Updated:</p> <ul style="list-style-type: none"> <li>– <i>Features</i></li> <li>– <i>Table 30: General operating conditions</i></li> <li>– <i>Table 54: Current consumption in Standby mode</i></li> <li>– All occurrences of SLEEP_TIMER to 2.4 GHz RADIO sleep timer</li> <li>– <i>Section 3.12.2: Power supply supervisor</i></li> <li>– <i>Standby mode</i></li> <li>– <i>Table 9: Operating modes overview</i></li> </ul> <p>Added:</p> <ul style="list-style-type: none"> <li>– <i>Section 3.14.1: GPIO using PD6 and PD7</i></li> </ul> <p>Removed all occurrences of “Proprietary protocols” and “Dhrystone”</p> |

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